## STM32F446xx

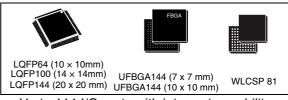


ARM® Cortex®-M4 32b MCU+FPU, 225DMIPS, up to 512kB Flash/128+4KB RAM, USB OTG HS/FS, 17 TIMs, 3 ADCs, 20 comm. interfaces

Datasheet - production data

#### **Features**

- Core: ARM<sup>®</sup> 32-bit Cortex<sup>®</sup>-M4 CPU with FPU, Adaptive real-time accelerator (ART Accelerator<sup>™</sup>) allowing 0-wait state execution from FI ash memory, frequency up to 180 MHz, MPU, 225 DMIPS/1.25 DMIPS/MHz (Dhrystone 2.1), and DSP instructions
- Memories
  - 512 kB of Flash memory
  - 128 KB of SRAM
  - Flexible external memory controller with up to 16-bit data bus: SRAM,PSRAM,SDRAM/LPSDR SDRAM, Flash NOR/NAND memories
  - Dual mode Quad SPI interface
- LCD parallel interface, 8080/6800 modes
- Clock, reset and supply management
  - 1.7 V to 3.6 V application supply and I/Os
  - POR, PDR, PVD and BOR
  - 4-to-26 MHz crystal oscillator
  - Internal 16 MHz factory-trimmed RC (1% accuracy)
  - 32 kHz oscillator for RTC with calibration
  - Internal 32 kHz RC with calibration
- Low power
  - Sleep, Stop and Standby modes
  - V<sub>BAT</sub> supply for RTC, 20×32 bit backup registers + optional 4 KB backup SRAM
- 3×12-bit, 2.4 MSPS ADC: up to 24 channels and 7.2 MSPS in triple interleaved mode
- 2×12-bit D/A converters
- General-purpose DMA: 16-stream DMA controller with FIFOs and burst support
- Up to 17 timers: 2x watchdog, 1x SysTick timer and up to twelve 16-bit and two 32-bit timers up to 180 MHz, each with up to 4 IC/OC/PWM or pulse counter
- Debug mode
  - SWD & JTAG interfaces
  - Cortex<sup>®</sup>-M4 Trace Macrocell™



- Up to 114 I/O ports with interrupt capability
  - Up to 111 fast I/Os up to 90 MHz
  - Up to 112 5 V-tolerant I/Os
- Up to 20 communication interfaces
  - SPDIF-Rx
  - Up to  $4 \times I^2$ C interfaces (SMBus/PMBus)
  - Up to 4 USARTs/2 UARTs (11.25 Mbit/s, ISO7816 interface, LIN, IrDA, modem control)
  - Up to 4 SPIs (45 Mbits/s), 3 with muxed I<sup>2</sup>S for audio class accuracy via internal audio PLL or external clock
  - 2 x SAI (serial audio interface)
  - 2 × CAN (2.0B Active)
  - SDIO interface
  - Consumer electronics control (CEC) I/F
- Advanced connectivity
  - USB 2.0 full-speed device/host/OTG controller with on-chip PHY
  - USB 2.0 high-speed/full-speed device/host/OTG controller with dedicated DMA, on-chip full-speed PHY and ULPI
  - Dedicated USB power rail enabling on-chip PHYs operation throughout the entire MCU power supply range
- 8- to 14-bit parallel camera interface up to 54 Mbytes/s
- · CRC calculation unit
- RTC: subsecond accuracy, hardware calendar
- 96-bit unique ID

**Table 1. Device summary** 

| Reference   | Part number  |
|-------------|--|
| STM32F446xx | STM32F446MC, STM32F446ME,<br>STM32F446RC, STM32F446RE,<br>STM32F446VC, STM32F446VE,<br>STM32F446ZC, STM32F446ZE. |

Contents STM32F446xx

# **Contents**

| 1 | Intro | duction   | . 11 |
|---|-------|---|------|
| 2 | Desc  | ription   | . 12 |
|   | 2.1   | Compatibility with STM32F4 family   | . 14 |
| 3 | Func  | etional overview  | . 17 |
|   | 3.1   | ARM <sup>®</sup> Cortex <sup>®</sup> -M4 with FPU and embedded Flash and SRAM | . 17 |
|   | 3.2   | Adaptive real-time memory accelerator (ART Accelerator™)                      | . 17 |
|   | 3.3   | Memory protection unit  |      |
|   | 3.4   | Embedded Flash memory   | . 18 |
|   | 3.5   | CRC (cyclic redundancy check) calculation unit                                | . 18 |
|   | 3.6   | Embedded SRAM   | . 18 |
|   | 3.7   | Multi-AHB bus matrix  | . 18 |
|   | 3.8   | DMA controller (DMA)  | . 19 |
|   | 3.9   | Flexible memory controller (FMC)  | . 20 |
|   | 3.10  | Quad SPI memory interface (QUADSPI)   | . 20 |
|   | 3.11  | Nested vectored interrupt controller (NVIC)                                   | . 21 |
|   | 3.12  | External interrupt/event controller (EXTI)                                    | . 21 |
|   | 3.13  | Clocks and startup  | . 21 |
|   | 3.14  | Boot modes  | . 22 |
|   | 3.15  | Power supply schemes  | . 22 |
|   | 3.16  | Power supply supervisor   | . 22 |
|   |       | 3.16.1 Internal reset ON  | 22   |
|   |       | 3.16.2 Internal reset OFF   | 22   |
|   | 3.17  | Voltage regulator   | . 23 |
|   |       | 3.17.1 Regulator ON   |      |
|   |       | 3.17.2 Regulator OFF  |      |
|   | 0.40  | 3.17.3 Regulator ON/OFF and internal reset ON/OFF availability                |      |
|   | 3.18  | Real-time clock (RTC), backup SRAM and backup registers                       |      |
|   | 3.19  | Low-power modes   |      |
|   | 3.20  | V <sub>BAT</sub> operation  |      |
|   | 3.21  | Timers and watchdogs  | . 30 |



|   |        | 3.21.1 Advanced-control timers (TIM1, TIM8)                                    |
|---|--------|--|
|   |        | 3.21.2 General-purpose timers (TIMx)   |
|   |        | 3.21.3 Basic timers TIM6 and TIM7  |
|   |        | 3.21.4 Independent watchdog  |
|   |        | 3.21.5 Window watchdog   |
|   |        | 3.21.6 SysTick timer   |
|   | 3.22   | Inter-integrated circuit interface (I <sup>2</sup> C)                          |
|   | 3.23   | Universal synchronous/asynchronous receiver transmitters (USART) 33            |
|   | 3.24   | Serial peripheral interface (SPI)  |
|   | 3.25   | HDMI (high-definition multimedia interface) consumer electronics control (CEC) |
|   | 3.26   | Inter-integrated sound (I <sup>2</sup> S)                                      |
|   | 3.27   | SPDIF-RX Receiver Interface (SPDIFRX)  |
|   | 3.28   | Serial Audio interface (SAI)   |
|   | 3.29   | Audio PLL (PLLI2S)   |
|   | 3.30   | Serial Audio Interface PLL(PLLSAI)   |
|   | 3.31   | Secure digital input/output interface (SDIO)                                   |
|   | 3.32   | Controller area network (bxCAN)  |
|   | 3.33   | Universal serial bus on-the-go full-speed (OTG_FS)                             |
|   | 3.34   | Universal serial bus on-the-go high-speed (OTG_HS)                             |
|   | 3.35   | Digital camera interface (DCMI)  |
|   | 3.36   | General-purpose input/outputs (GPIOs)  |
|   | 3.37   | Analog-to-digital converters (ADCs)  |
|   | 3.38   | Temperature sensor   |
|   | 3.39   | Digital-to-analog converter (DAC)  |
|   | 3.40   | Serial wire JTAG debug port (SWJ-DP)   |
|   | 3.41   | Embedded Trace Macrocell™  |
| 4 | Pinou  | ıt and pin description   |
| 5 | Memo   | ory mapping  |
| 6 | Electr | rical characteristics  |
|   | 6.1    | Parameter conditions   |
|   |        | 6.1.1 Minimum and maximum values   |
|   |        |  |



Contents STM32F446xx

|     | 6.1.2  | Typical values71   |
|-----|--------|--|
|     | 6.1.3  | Typical curves   |
|     | 6.1.4  | Loading capacitor  |
|     | 6.1.5  | Pin input voltage71  |
|     | 6.1.6  | Power supply scheme  |
|     | 6.1.7  | Current consumption measurement                                  |
| 6.2 | Absolu | te maximum ratings   |
| 6.3 | Operat | ing conditions   |
|     | 6.3.1  | General operating conditions                                     |
|     | 6.3.2  | VCAP1/VCAP2 external capacitor                                   |
|     | 6.3.3  | Operating conditions at power-up / power-down (regulator ON) 78  |
|     | 6.3.4  | Operating conditions at power-up / power-down (regulator OFF) 78 |
|     | 6.3.5  | Reset and power control block characteristics                    |
|     | 6.3.6  | Over-drive switching characteristics80                           |
|     | 6.3.7  | Supply current characteristics                                   |
|     | 6.3.8  | Wakeup time from low-power modes                                 |
|     | 6.3.9  | External clock source characteristics                            |
|     | 6.3.10 | Internal clock source characteristics                            |
|     | 6.3.11 | PLL characteristics  |
|     | 6.3.12 | PLL spread spectrum clock generation (SSCG) characteristics 109  |
|     | 6.3.13 | Memory characteristics   |
|     | 6.3.14 | EMC characteristics  |
|     | 6.3.15 | Absolute maximum ratings (electrical sensitivity)                |
|     | 6.3.16 | I/O current injection characteristics                            |
|     | 6.3.17 | I/O port characteristics   |
|     | 6.3.18 | NRST pin characteristics   |
|     | 6.3.19 | TIM timer characteristics  |
|     | 6.3.20 | Communications interfaces  |
|     | 6.3.21 | 12-bit ADC characteristics                                       |
|     | 6.3.22 | Temperature sensor characteristics                               |
|     | 6.3.23 | V <sub>BAT</sub> monitoring characteristics                      |
|     | 6.3.24 | reference voltage  |
|     | 6.3.25 | DAC electrical characteristics                                   |
|     | 6.3.26 | FMC characteristics  |
|     | 6.3.27 | Camera interface (DCMI) timing specifications                    |
|     | 6.3.28 | SD/SDIO MMC card host interface (SDIO) characteristics 170       |
|     | 6.3.29 | RTC characteristics  |



STM32F446xx Contents

| 7    | Pack   | Package information                         |       |  |  |  |  |
|------|--------|---|-------|--|--|--|--|
|      | 7.1    | LQFP64 package information                  | . 173 |  |  |  |  |
|      | 7.2    | LQFP100 package information                 | . 176 |  |  |  |  |
|      | 7.3    | LQFP144 package information                 | . 179 |  |  |  |  |
|      | 7.4    | UFBGA144 7 x 7 mm package information       | . 183 |  |  |  |  |
|      | 7.5    | UFBGA144 10 x 10 mm package information     | . 185 |  |  |  |  |
|      | 7.6    | WLCSP81 package information                 | . 188 |  |  |  |  |
|      | 7.7    | Thermal characteristics                     | . 191 |  |  |  |  |
| 8    | Part   | numbering                                   | . 193 |  |  |  |  |
| Appe | ndix A | Application block diagrams                  | . 194 |  |  |  |  |
|      | A.1    | USB OTG full speed (FS) interface solutions | . 194 |  |  |  |  |
|      | A.2    | USB OTG high speed (HS) interface solutions | . 196 |  |  |  |  |
| 9    | Revi   | sion history                                | . 197 |  |  |  |  |



List of figures STM32F446xx

# List of figures

| Figure 1.  | Compatible board design for LQFP100 package  | 14   |
|------------|--|------|
| Figure 2.  | Compatible board for LQFP64 package  | 15   |
| Figure 3.  | STM32F446xx block diagram  | 16   |
| Figure 4.  | STM32F446xx and Multi-AHB matrix   |      |
| Figure 5.  | Power supply supervisor interconnection with internal reset OFF                    | 23   |
| Figure 6.  | Regulator OFF  | 25   |
| Figure 7.  | Startup in regulator OFF: slow V <sub>DD</sub> slope                               |      |
|            | power-down reset risen after V <sub>CAP 1</sub> /V <sub>CAP 2</sub> stabilization  | 26   |
| Figure 8.  | Startup in regulator OFF mode: fast V <sub>DD</sub> slope                          |      |
| · ·        | power-down reset risen before V <sub>CAP_1</sub> /V <sub>CAP_2</sub> stabilization | 26   |
| Figure 9.  | STM32F446xC/xE LQFP64 pinout   | 40   |
| Figure 10. | STM32F446xC/xE LQFP100 pinout  | 41   |
| Figure 11. | STM32F446xC LQFP144 pinout   | 42   |
| Figure 12. | STM32F446xC/xE WLCSP81 ballout   | 43   |
| Figure 13. | STM32F446xC/xE UFBGA144 ballout  | 44   |
| Figure 14. | Memory map   | 66   |
| Figure 15. | Pin loading conditions   | 71   |
| Figure 16. | Pin input voltage  | 71   |
| Figure 17. | Power supply scheme  | 72   |
| Figure 18. | Current consumption measurement scheme   | 73   |
| Figure 19. | External capacitor C <sub>EXT</sub>  | 78   |
| Figure 20. | Typical V <sub>BAT</sub> current consumption                                       |      |
|            | (RTC ON/backup RAM OFF and LSE in low power mode)                                  | 90   |
| Figure 21. | Typical V <sub>BAT</sub> current consumption                                       |      |
|            | (RTC ON/backup RAM OFF and LSE in high drive mode)                                 |      |
| Figure 22. | High-speed external clock source AC timing diagram                                 |      |
| Figure 23. | Low-speed external clock source AC timing diagram                                  | 103  |
| Figure 24. | Typical application with an 8 MHz crystal  |      |
| Figure 25. | Typical application with a 32.768 kHz crystal                                      |      |
| Figure 26. | LACC <sub>HSI</sub> versus temperature   |      |
| Figure 27. | ACC <sub>LSI</sub> versus temperature  |      |
| Figure 28. | PLL output clock waveforms in center spread mode                                   |      |
| Figure 29. | PLL output clock waveforms in down spread mode                                     |      |
| Figure 30. | FT I/O input characteristics   |      |
| Figure 31. | I/O AC characteristics definition  |      |
| Figure 32. | Recommended NRST pin protection  |      |
| Figure 33. | I <sup>2</sup> C bus AC waveforms and measurement circuit                          | 125  |
| Figure 34. | FMPI <sup>2</sup> C timing diagram and measurement circuit                         | 127  |
| Figure 35. | SPI timing diagram - slave mode and CPHA = 0                                       |      |
| Figure 36. | SPI timing diagram - slave mode and CPHA = 1                                       |      |
| Figure 37. | SPI timing diagram - master mode   | 130  |
| Figure 38. | I <sup>2</sup> S slave timing diagram (Philips protocol)(1)                        | 134  |
| Figure 39. | I <sup>2</sup> S master timing diagram (Philips protocol) <sup>(1)</sup>           |      |
| Figure 40. | SAI master timing waveforms  |      |
| Figure 41. | SAI slave timing waveforms   |      |
| Figure 42. | USB OTG full speed timings: definition of data signal rise and fall time           |      |
| Figure 43. | ULPI timing diagram  |      |
| Figure 11  | ADC accuracy characteristics   | 1/13 |



STM32F446xx List of figures

| Figure 45. | Typical connection diagram using the ADC   | 144 |
|------------|--|-----|
| Figure 46. | Power supply and reference decoupling (V <sub>REF+</sub> not connected to V <sub>DDA</sub> ) |     |
| Figure 47. | Power supply and reference decoupling (V <sub>REF+</sub> connected to V <sub>DDA</sub> )     |     |
| Figure 48. | 12-bit buffered/non-buffered DAC   |     |
| Figure 49. | Asynchronous non-multiplexed SRAM/PSRAM/NOR read waveforms                                   |     |
| Figure 50. | Asynchronous non-multiplexed SRAM/PSRAM/NOR write waveforms                                  |     |
| Figure 51. | Asynchronous multiplexed PSRAM/NOR read waveforms  |     |
| Figure 52. | Asynchronous multiplexed PSRAM/NOR write waveforms   |     |
| Figure 53. | Synchronous multiplexed NOR/PSRAM read timings   |     |
| Figure 54. | Synchronous multiplexed PSRAM write timings  |     |
| Figure 55. | Synchronous non-multiplexed NOR/PSRAM read timings   |     |
| Figure 56. | Synchronous non-multiplexed PSRAM write timings  |     |
| Figure 57. | NAND controller waveforms for read access  |     |
| Figure 58. | NAND controller waveforms for write access   |     |
| Figure 59. | NAND controller waveforms for common memory read access                                      |     |
| Figure 60. | NAND controller waveforms for common memory write access                                     |     |
| Figure 61. | SDRAM read access waveforms (CL = 1)   |     |
| Figure 62. | SDRAM write access waveforms   |     |
| Figure 63. | DCMI timing diagram  |     |
| Figure 64. | SDIO high-speed mode   |     |
| Figure 65. | SD default mode  |     |
| Figure 66. | LQFP64-10x10 mm 64 pin low-profile quad flat package outline                                 |     |
| Figure 67. | LQFP64 Recommended footprint   |     |
| Figure 68. | LQFP64 marking example (package top view)  |     |
| Figure 69. | LQFP100, 14 x 14 mm 100-pin low-profile quad flat package outline                            |     |
| Figure 70. | LQFP100 - 100-pin, 14 x 14 mm low-profile quad flat  |     |
| ga         | recommended footprint  | 177 |
| Figure 71. | LQFP100 marking example (package top view)   |     |
| Figure 72. | LQFP144, 20 x 20 mm, 144-pin low-profile quad flat package outline                           |     |
| Figure 73. | LQFP144 recommended footprint  |     |
| Figure 74. | LQFP144 marking example (package top view)   |     |
| Figure 75. | UFBGA144 - 144-pin, 7 x 7 mm, 0.50 mm pitch, ultra fine pitch ball                           |     |
| 90 0 . 0   | grid array package outline   | 183 |
| Figure 76. | UQFP144 7 x 7 mm marking example (package top view)  |     |
| Figure 77. | UFBGA144 - 144-pin, 10 x 10 mm, 0.80 mm pitch, ultra fine pitch ball                         |     |
|            | grid array package outline   | 185 |
| Figure 78. | UFBGA144 - 144-pin, 10 x 10 mm, 0.80 mm pitch, ultra fine pitch ball                         |     |
| 90 0 . 0   | grid array package recommended footprint   | 186 |
| Figure 79. | UQFP144 10 x 10 mm marking example (package top view)  |     |
| Figure 80. | WLCSP81 - 81-pin, 3.693 x 3.815 mm, 0.4 mm pitch wafer level chip scale                      |     |
| ga e e e . | package outline  | 188 |
| Figure 81. | WLCSP81- 81-pin, 4.4084 x 3.7594 mm, 0.4 mm pitch wafer level chip scale                     |     |
| ga. 0 0 1. | package recommended footprint  | 189 |
| Figure 82. | WLCSP81 10 x 10 mm marking example (package top view)  |     |
| Figure 83. | USB controller configured as peripheral-only and used in Full speed mode                     |     |
| Figure 84. | USB controller configured as host-only and used in full speed mode                           |     |
| Figure 85. | USB controller configured in dual mode and used in full speed mode                           |     |
| Figure 86. | USB controller configured as peripheral, host, or dual-mode                                  |     |
| 94.0 00.   | and used in high speed mode  | 196 |
|            |  |     |



List of tables STM32F446xx

# List of tables

| Table 1.  | Device summary   | 1    |
|-----------|--|------|
| Table 2.  | STM32F446xx features and peripheral counts                                     |      |
| Table 3.  | Voltage regulator configuration mode versus device operating mode              |      |
| Table 4.  | Regulator ON/OFF and internal reset ON/OFF availability                        |      |
| Table 5.  | Voltage regulator modes in stop mode   |      |
| Table 6.  | Timer feature comparison   |      |
| Table 7.  | Comparison of I2C analog and digital filters                                   |      |
| Table 8.  | USART feature comparison   |      |
| Table 9.  | Legend/abbreviations used in the pinout table                                  |      |
| Table 10. | STM32F446xx pin and ball descriptions  |      |
| Table 11. | Alternate function   |      |
| Table 12. | STM32F446xx register boundary addresses  |      |
| Table 13. | Voltage characteristics  |      |
| Table 14. | Current characteristics  |      |
| Table 15. | Thermal characteristics  |      |
| Table 16. | General operating conditions   |      |
| Table 17. | Limitations depending on the operating power supply range                      |      |
| Table 18. | VCAP1/VCAP2 operating conditions   |      |
| Table 19. | Operating conditions at power-up/power-down (regulator ON)                     |      |
| Table 20. | Operating conditions at power-up / power-down (regulator OFF)                  |      |
| Table 21. | reset and power control block characteristics                                  |      |
| Table 22. | Over-drive switching characteristics   |      |
| Table 23. | Typical and maximum current consumption in Run mode, code with data processing |      |
|           | running from Flash memory (ART accelerator enabled except prefetch) or RAM     | . 82 |
| Table 24. | Typical and maximum current consumption in Run mode, code with data processing |      |
|           | running from Flash memory (ART accelerator enabled with prefetch) or RAM       | . 83 |
| Table 25. | Typical and maximum current consumption in Run mode, code with data processing |      |
|           | running from Flash memory (ART accelerator disabled)                           | . 84 |
| Table 26. | Typical and maximum current consumption in Sleep mode                          |      |
| Table 27. | Typical and maximum current consumptions in Stop mode                          |      |
| Table 28. | Typical and maximum current consumptions in Standby mode                       |      |
| Table 29. | Typical and maximum current consumptions in V <sub>BAT</sub> mode              | . 90 |
| Table 30. | Typical current consumption in Run mode, code with data processing             |      |
|           | running from Flash memory or RAM, regulator ON                                 |      |
|           | (ART accelerator enabled except prefetch), VDD=1.7 V                           | . 92 |
| Table 31. | Typical current consumption in Run mode, code with data processing running     |      |
|           | from Flash memory, regulator OFF (ART accelerator enabled except prefetch)     | . 93 |
| Table 32. | Typical current consumption in Sleep mode, regulator ON, VDD=1.7 V             | . 94 |
| Table 33. | Typical current consumption in Sleep mode, regulator OFF                       | . 95 |
| Table 34. | Switching output I/O current consumption                                       | . 96 |
| Table 35. | Peripheral current consumption   | . 98 |
| Table 36. | Low-power mode wakeup timings  | 101  |
| Table 37. | High-speed external user clock characteristics                                 |      |
| Table 38. | Low-speed external user clock characteristics                                  | 102  |
| Table 39. | HSE 4-26 MHz oscillator characteristics  |      |
| Table 40. | LSE oscillator characteristics (f <sub>LSE</sub> = 32.768 kHz)                 |      |
| Table 41. | HSI oscillator characteristics   | 105  |
| Table 42. | LSI oscillator characteristics   | 106  |



STM32F446xx List of tables

| Table 43. | Main PLL characteristics  | 107 |
|-----------|---|-----|
| Table 44. | PLLI2S (audio PLL) characteristics  |     |
| Table 45. | PLLISAI (audio and LCD-TFT PLL) characteristics                             |     |
| Table 46. | SSCG parameters constraint  |     |
| Table 47. | Flash memory characteristics  |     |
| Table 48. | Flash memory programming  | 112 |
| Table 49. | Flash memory programming with V <sub>PP</sub>                               | 112 |
| Table 50. | Flash memory endurance and data retention                                   | 113 |
| Table 51. | EMS characteristics   |     |
| Table 52. | EMI characteristics   |     |
| Table 53. | ESD absolute maximum ratings  |     |
| Table 54. | Electrical sensitivities  |     |
| Table 55. | I/O current injection susceptibility  |     |
| Table 56. | I/O static characteristics  |     |
| Table 57. | Output voltage characteristics  | 120 |
| Table 58. | I/O AC characteristics  |     |
| Table 59. | NRST pin characteristics  | 122 |
| Table 60. | TIMx characteristics  |     |
| Table 61. | I <sup>2</sup> C characteristics  |     |
| Table 62. | FMPI <sup>2</sup> C characteristics   |     |
| Table 63. | SPI dynamic characteristics   | 128 |
| Table 64. | QSPI dynamic characteristics in SDR Mode                                    | 131 |
| Table 65. | QSPI dynamic characteristics in DDR Mode                                    | 131 |
| Table 66. | I <sup>2</sup> S dynamic characteristics                                    | 132 |
| Table 67. | SAI characteristics   | 135 |
| Table 68. | USB OTG full speed startup time   | 136 |
| Table 69. | USB OTG full speed DC electrical characteristics                            | 137 |
| Table 70. | USB OTG full speed electrical characteristics                               | 138 |
| Table 71. | USB HS DC electrical characteristics  | 138 |
| Table 72. | USB HS clock timing parameters  | 138 |
| Table 73. | Dynamic characteristics: USB ULPI   | 139 |
| Table 74. | ADC characteristics   | 140 |
| Table 75. | ADC static accuracy at f <sub>ADC</sub> = 18 MHz                            | 141 |
| Table 76. | ADC static accuracy at f <sub>ADC</sub> = 30 MHz                            | 142 |
| Table 77. | ADC static accuracy at f <sub>ADC</sub> = 36 MHz                            | 142 |
| Table 78. | ADC dynamic accuracy at f <sub>ADC</sub> = 18 MHz - limited test conditions | 142 |
| Table 79. | ADC dynamic accuracy at f <sub>ADC</sub> = 36 MHz - limited test conditions |     |
| Table 80. | Temperature sensor characteristics  |     |
| Table 81. | Temperature sensor calibration values                                       | 146 |
| Table 82. | V <sub>BAT</sub> monitoring characteristics                                 | 146 |
| Table 83. | internal reference voltage  |     |
| Table 84. | Internal reference voltage calibration values                               | 147 |
| Table 85. | DAC characteristics   | 147 |
| Table 86. | Asynchronous non-multiplexed SRAM/PSRAM/NOR -                               |     |
|           | read timings  | 151 |
| Table 87. | Asynchronous non-multiplexed SRAM/PSRAM/NOR read -                          |     |
|           | NWAIT timings   |     |
| Table 88. | Asynchronous non-multiplexed SRAM/PSRAM/NOR write timings                   | 152 |
| Table 89. | Asynchronous non-multiplexed SRAM/PSRAM/NOR write -                         |     |
|           | NWAIT timings   |     |
| Table 90. | Asynchronous multiplexed PSRAM/NOR read timings                             |     |
| Table 91. | Asynchronous multiplexed PSRAM/NOR read-NWAIT timings                       | 154 |
|           |   |     |



List of tables STM32F446xx

| Table 92.  | Asynchronous multiplexed PSRAM/NOR write timings                           | . 156 |
|------------|--|-------|
| Table 93.  | Asynchronous multiplexed PSRAM/NOR write-NWAIT timings                     | . 156 |
| Table 94.  | Synchronous multiplexed NOR/PSRAM read timings                             |       |
| Table 95.  | Synchronous multiplexed PSRAM write timings                                |       |
| Table 96.  | Synchronous non-multiplexed NOR/PSRAM read timings                         |       |
| Table 97.  | Synchronous non-multiplexed PSRAM write timings                            | . 163 |
| Table 98.  | Switching characteristics for NAND Flash read cycles                       | . 165 |
| Table 99.  | Switching characteristics for NAND Flash write cycles                      | . 166 |
| Table 100. | SDRAM read timings   | . 167 |
| Table 101. | LPSDR SDRAM read timings   | . 167 |
| Table 102. | SDRAM write timings  | . 168 |
| Table 103. | LPSDR SDRAM write timings  | . 169 |
| Table 104. | DCMI characteristics   | . 169 |
| Table 105. | Dynamic characteristics: SD / MMC characteristics                          | . 171 |
| Table 106. | Dynamic characteristics: eMMC characteristics VDD = 1.7 V to 1.9 V         | . 172 |
| Table 107. | RTC characteristics  |       |
| Table 108. | LQFP64 – 10 x 10 mm low-profile quad flat package mechanical data          | . 173 |
| Table 109. | LQPF100, 14 x 14 mm 100-pin low-profile quad flat package mechanical data  | . 176 |
| Table 110. | LQFP144, 20 x 20 mm, 144-pin low-profile quad flat package mechanical data | . 180 |
| Table 111. | UFBGA144 - 144-pin, 7 x 7 mm, 0.50 mm pitch, ultra fine pitch ball         |       |
|            | grid array package mechanical data   | . 183 |
| Table 112. | UFBGA144 - 144-pin, 10 x 10 mm, 0.80 mm pitch, ultra fine pitch ball       |       |
|            | grid array package mechanical data   | . 185 |
| Table 113. | UFBGA144 recommended PCB design rules (0.80 mm pitch BGA)                  | . 186 |
| Table 114. | WLCSP81- 81-pin, 3.693 x 3.815 mm, 0.4 mm pitch wafer level chip scale     |       |
|            | package mechanical data  |       |
| Table 115. | WLCSP81 recommended PCB design rules (0.4 mm pitch)                        | . 191 |
| Table 116. | Package thermal characteristics  |       |
| Table 117. | Ordering information scheme  | . 193 |
| Table 118. | Document revision history  | . 197 |

STM32F446xx Introduction

# 1 Introduction

This document provides the description of the STM32F446xx line of microcontrollers.

The STM32F446xx document should be read in conjunction with the STM32F4xx reference manual.

For information on the Cortex<sup>®</sup>-M4 core, please refer to the Cortex<sup>®</sup>-M4 programming manual (PM0214), available from the *www.st.com*.



Description STM32F446xx

## 2 Description

The STM32F446xx devices are based on the high-performance ARM<sup>®</sup> Cortex<sup>®</sup>-M4 32-bit RISC core operating at a frequency of up to 180 MHz. The Cortex-M4 core features a Floating point unit (FPU) single precision which supports all ARM<sup>®</sup> single-precision data-processing instructions and data types. It also implements a full set of DSP instructions and a memory protection unit (MPU) which enhances application security.

The STM32F446xx devices incorporate high-speed embedded memories (Flash memory up to 512 Kbyte, up to 128 Kbyte of SRAM), up to 4 Kbytes of backup SRAM, and an extensive range of enhanced I/Os and peripherals connected to two APB buses, two AHB buses and a 32-bit multi-AHB bus matrix.

All devices offer three 12-bit ADCs, two DACs, a low-power RTC, twelve general-purpose 16-bit timers including two PWM timers for motor control, two general-purpose 32-bit timers.

They also feature standard and advanced communication interfaces.

- Up to four I<sup>2</sup>Cs;
- Four SPIs, three I<sup>2</sup>Ss full simplex. To achieve audio class accuracy, the I<sup>2</sup>S peripherals
  can be clocked via a dedicated internal audio PLL or via an external clock to allow
  synchronization;
- Four USARTs plus two UARTs;
- An USB OTG full-speed and an USB OTG high-speed with full-speed capability (with the ULPI), both with dedicated power rails allowing to use them throughout the entire power range;
- Two CANs;
- Two SAIs serial audio interfaces. To achieve audio class accuracy, the SAIs can be clocked via a dedicated internal audio PLL;
- An SDIO/MMC interface;
- · Camera interface;
- HDMI-CEC;
- SPDIF Receiver (SPDIFRx);
- QuadSPI.

Advanced peripherals include an SDIO, a flexible memory control (FMC) interface, a camera interface for CMOS sensors. Refer to *Table 2: STM32F446xx features and peripheral counts* for the list of peripherals available on each part number.

The STM32F446xx devices operates in the -40 to +105 °C temperature range from a 1.7 to 3.6 V power supply.

The supply voltage can drop to 1.7 V with the use of an external power supply supervisor (refer to *Section 3.16.2: Internal reset OFF*). A comprehensive set of power-saving mode allows the design of low-power applications.

The STM32F446xx devices offer devices in 6 packages ranging from 64 pins to 144 pins. The set of included peripherals changes with the device chosen.



STM32F446xx Description

These features make the STM32F446xx microcontrollers suitable for a wide range of applications:

- Motor drive and application control
- Medical equipment
- Industrial applications: PLC, inverters, circuit breakers
- Printers, and scanners
- Alarm systems, video intercom, and HVAC
- Home audio appliances

Table 2. STM32F446xx features and peripheral counts

| Peripherals                   |                         | STM32F44<br>6MC                       | STM32F44<br>6ME                                     | STM32F44<br>6RC | STM32F44<br>6RE | STM32F44<br>6VC       | STM32F44<br>6VE | STM32F44<br>6ZC  | STM32F44<br>6ZE |  |
|-------------------------------|-------------------------|---------------------------------------|---|-----------------|-----------------|-----------------------|-----------------|------------------|-----------------|--|
| Flash memory in Kbytes        |                         | 256                                   | 512   | 256             | 512             | 256                   | 512             | 256              | 512             |  |
| SRAM in                       | SRAM in System          |                                       | 128 (112+16)  |                 |                 |                       |                 |                  |                 |  |
| Kbytes                        | Backup                  |                                       |   |                 | 4               | 4                     |                 |                  |                 |  |
| FMC memory co                 | ntroller                |                                       | N   | lo              |                 |                       | Ye              | s <sup>(1)</sup> |                 |  |
|                               | General-<br>purpose     |                                       | 10  |                 |                 |                       |                 |                  |                 |  |
| Timers                        | Advanced-<br>control    |                                       | 2   |                 |                 |                       |                 |                  |                 |  |
|                               | Basic                   |                                       |   |                 | 2               | 2                     |                 |                  |                 |  |
|                               | SPI / I <sup>2</sup> S  |                                       |   |                 | 4/2 (sim        | nplex) <sup>(2)</sup> |                 |                  |                 |  |
|                               | I <sup>2</sup> C        |                                       |   |                 | 4/1 F           | MP +                  |                 |                  |                 |  |
|                               | USART/UART              |                                       |   |                 | 4.              | /2                    |                 |                  |                 |  |
|                               | USB OTG FS              |                                       |   |                 | Yes (6-E        | ndpoints)             |                 |                  |                 |  |
|                               | USB OTG HS              |                                       |   |                 | Yes (8-E        | ndpoints)             |                 |                  |                 |  |
| Communication interfaces      | CAN                     |                                       | 2   |                 |                 |                       |                 |                  |                 |  |
|                               | SAI                     | 2                                     |   |                 |                 |                       |                 |                  |                 |  |
|                               | SDIO                    | Yes                                   |   |                 |                 |                       |                 |                  |                 |  |
|                               | SPDIF-Rx                | 1                                     |   |                 |                 |                       |                 |                  |                 |  |
|                               | HDMI-CEC                | 1                                     |   |                 |                 |                       |                 |                  |                 |  |
|                               | Quad SPI <sup>(3)</sup> | 1                                     |   |                 |                 |                       |                 |                  |                 |  |
| Camera interface              | •                       | Yes                                   |   |                 |                 |                       |                 |                  |                 |  |
| GPIOs                         |                         | 6                                     | 3   | 5               | 0               | 8                     | 1               | 11               | 14              |  |
| 12-bit ADC                    |                         | 3                                     |   |                 |                 |                       |                 |                  |                 |  |
| Number of chann               | nels                    | 1                                     | 4   | 1               | 6               | 1                     | 6               | 2                | 4               |  |
| 12-bit DAC<br>Number of chann | nels                    | Yes<br>2                              |   |                 |                 |                       |                 |                  |                 |  |
| Maximum CPU frequency         |                         | 180 MHz                               |   |                 |                 |                       |                 |                  |                 |  |
| Operating voltage             |                         | 1.8 to 3.6 V <sup>(4)</sup>           |   |                 |                 |                       |                 |                  |                 |  |
| On a nation of the control    | -                       |                                       | Ambient temperatures: -40 to +85 °C /-40 to +105 °C |                 |                 |                       |                 |                  |                 |  |
| Operating tempe               | ratures                 | Junction temperature: –40 to + 125 °C |   |                 |                 |                       |                 |                  |                 |  |
| Packages                      |                         | WLC                                   | SP81  | LQF             | P64             | LQF                   | P100            | LQF<br>UFB0      |                 |  |

Description STM32F446xx

 For the LQFP100 package, only FMC Bank1 or Bank2 are available. Bank1 can only support a multiplexed NOR/PSRAM memory using the NE1 Chip Select. Bank2 can only support a 16- or 8-bit NAND Flash memory using the NCE2 Chip Select. The interrupt line cannot be used since Port G is not available in this package.

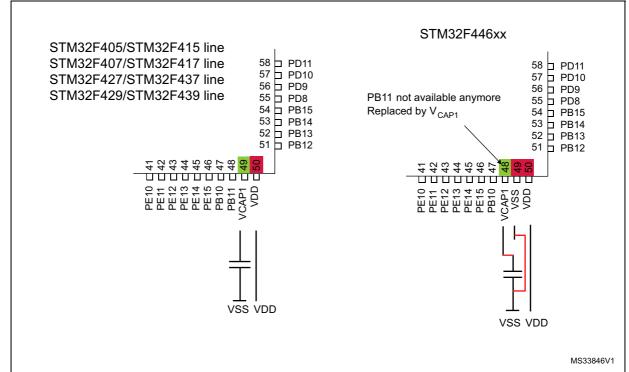
- 2. The SPI1, SPI2 and SPI3 interfaces give the flexibility to work in an exclusive way in either the SPI mode or the I2S audio mode.
- 3. For the LQFP64 package, the Quad SPI is available with limited features.
- V<sub>DD</sub>/V<sub>DDA</sub> minimum value of 1.7 V is obtained when the device operates in reduced temperature range, and with the use of an external power supply supervisor (refer to Section 3.16.2: Internal reset OFF).

## 2.1 Compatibility with STM32F4 family

The STM32F446xC/xV is software and feature compatible with the STM32F4 family.

The STM32F446xC/xV can be used as drop-in replacement of the other STM32F4 products but some slight changes have to be done on the PCB board.

Figure 1. Compatible board design for LQFP100 package



577

STM32F446xx Description

STM32F405/STM32F415 line STM32F446xx 22 52 51 50 49 53 52 51 50 49 54 45 PC12 PC11 PC10 PA15 53 52 51 50 49 49 48 VDD 47 VCAP2 46 PA13 45 PA12 44 PA11 43 PA10 - VDD VDD 42 PA9 41 PA8 40 PC9 VSS VSS 39 PC8 38 PC7 37 PC6 36 PB15 PB11 not available anymore 35 PB14 34 PB13 33 PB12 Replaced by  $V_{\text{CAP1}}$ VCAP 1 VDD 08 62 87 VDD 08 62 87 VDD 08 62 87  $V_{\text{CAP}}$  increased to 4.7  $\mu f$ ESR 1  $\Omega$  or below 1 VSS VDD VSS VDD MS33845V2

Figure 2. Compatible board for LQFP64 package

Figure 3 shows the STM32F446xx block diagram.

Description STM32F446xx

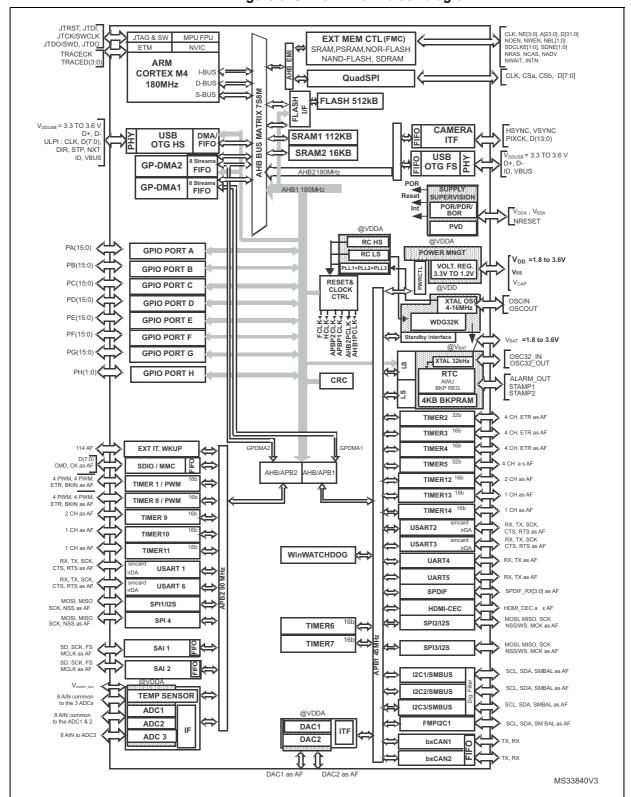


Figure 3. STM32F446xx block diagram



### 3 Functional overview

# 3.1 ARM® Cortex®-M4 with FPU and embedded Flash and SRAM

The ARM® Cortex®-M4 with FPU processor is the latest generation of ARM processors for embedded systems. It was developed to provide a low-cost platform that meets the needs of MCU implementation, with a reduced pin count and low-power consumption, while delivering outstanding computational performance and an advanced response to interrupts.

The ARM® Cortex®-M4 with FPU core is a 32-bit RISC processor that features exceptional code-efficiency, delivering the high-performance expected from an ARM core in the memory size usually associated with 8- and 16-bit devices.

The processor supports a set of DSP instructions which allow efficient signal processing and complex algorithm execution.

Its single precision FPU (floating point unit) speeds up software development by using metalanguage development tools, while avoiding saturation.

The STM32F446xx family is compatible with all ARM tools and software.

Figure 3 shows the general block diagram of the STM32F446xx family.

Note: Cortex-M4 with FPU core is binary compatible with the Cortex-M3 core.

## 3.2 Adaptive real-time memory accelerator (ART Accelerator™)

The ART Accelerator™ is a memory accelerator which is optimized for STM32 industry-standard ARM® Cortex®-M4 with FPU processors. It balances the inherent performance advantage of the ARM® Cortex®-M4 with FPU over Flash memory technologies, which normally requires the processor to wait for the Flash memory at higher frequencies.

To release the processor full 225 DMIPS performance at this frequency, the accelerator implements an instruction prefetch queue and branch cache, which increases program execution speed from the 128-bit Flash memory. Based on CoreMark benchmark, the performance achieved thanks to the ART Accelerator is equivalent to 0 wait state program execution from Flash memory at a CPU frequency up to 180 MHz.

## 3.3 Memory protection unit

The memory protection unit (MPU) is used to manage the CPU accesses to memory to prevent one task to accidentally corrupt the memory or resources used by any other active task. This memory area is organized into up to 8 protected areas that can in turn be divided up into 8 subareas. The protection area sizes are between 32 bytes and the whole 4 gigabytes of addressable memory.

The MPU is especially helpful for applications where some critical or certified code has to be protected against the misbehavior of other tasks. It is usually managed by an RTOS (real-time operating system). If a program accesses a memory location that is prohibited by the MPU, the RTOS can detect it and take action. In an RTOS environment, the kernel can dynamically update the MPU area setting, based on the process to be executed.

The MPU is optional and can be bypassed for applications that do not need it.

## 3.4 Embedded Flash memory

The devices embed a Flash memory of 512KB available for storing programs and data.

## 3.5 CRC (cyclic redundancy check) calculation unit

The CRC (cyclic redundancy check) calculation unit is used to get a CRC code from a 32-bit data word and a fixed generator polynomial.

Among other applications, CRC-based techniques are used to verify data transmission or storage integrity. In the scope of the EN/IEC 60335-1 standard, they offer a means of verifying the Flash memory integrity. The CRC calculation unit helps compute a software signature during runtime, to be compared with a reference signature generated at link-time and stored at a given memory location.

### 3.6 Embedded SRAM

All devices embed:

- Up to 128Kbytes of system SRAM.
   RAM memory is accessed (read/write) at CPU clock speed with 0 wait states.
- 4 Kbytes of backup SRAM

This area is accessible only from the CPU. Its content is protected against possible unwanted write accesses, and is retained in Standby or VBAT mode.

### 3.7 Multi-AHB bus matrix

The 32-bit multi-AHB bus matrix interconnects all the masters (CPU, DMAs, USB HS) and the slaves Flash memory, RAM, QuadSPI, FMC, AHB and APB peripherals and ensures a seamless and efficient operation even when several high-speed peripherals work simultaneously.

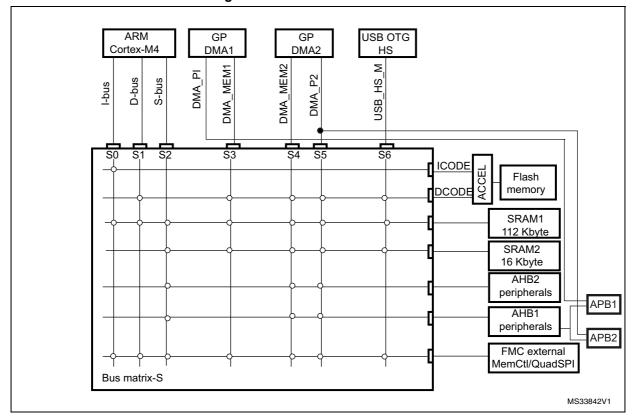


Figure 4. STM32F446xx and Multi-AHB matrix

## 3.8 DMA controller (DMA)

The devices feature two general-purpose dual-port DMAs (DMA1 and DMA2) with 8 streams each. They are able to manage memory-to-memory, peripheral-to-memory and memory-to-peripheral transfers. They feature dedicated FIFOs for APB/AHB peripherals, support burst transfer and are designed to provide the maximum peripheral bandwidth (AHB/APB).

The two DMA controllers support circular buffer management, so that no specific code is needed when the controller reaches the end of the buffer. The two DMA controllers also have a double buffering feature, which automates the use and switching of two memory buffers without requiring any special code.

Each stream is connected to dedicated hardware DMA requests, with support for software trigger on each stream. Configuration is made by software and transfer sizes between source and destination are independent.

The DMA can be used with the main peripherals:

- SPI and I<sup>2</sup>S
- I<sup>2</sup>C
- USART
- General-purpose, basic and advanced-control timers TIMx
- DAC
- SDIO
- Camera interface (DCMI)
- ADC
- SAI1/SAI2
- SPDIF Receiver (SPDIFRx)
- QuadSPI

## 3.9 Flexible memory controller (FMC)

All devices embed an FMC. It has seven Chip Select outputs supporting the following modes: SDRAM/LPSDR SDRAM, SRAM, PSRAM, NOR Flash and NAND Flash. With the possibility to remap FMC bank 1 (NOR/PSRAM 1 and 2) and FMC SDRAM bank 1/2 in the Cortex-M4 code area.

Functionality overview:

- 8-,16-bit data bus width
- Read FIFO for SDRAM controller
- Write FIFC
- Maximum FMC\_CLK/FMC\_SDCLK frequency for synchronous accesses is 90 MHz.

#### LCD parallel interface

The FMC can be configured to interface seamlessly with most graphic LCD controllers. It supports the Intel 8080 and Motorola 6800 modes, and is flexible enough to adapt to specific LCD interfaces. This LCD parallel interface capability makes it easy to build cost-effective graphic applications using LCD modules with embedded controllers or high performance solutions using external controllers with dedicated acceleration.

## 3.10 Quad SPI memory interface (QUADSPI)

All devices embed a Quad SPI memory interface, which is a specialized communication interface targeting Single, Dual or Quad SPI flash memories. It can work in direct mode through registers, external flash status register polling mode and memory mapped mode. Up to 256 Mbytes external flash are memory mapped, supporting 8, 16 and 32-bit access. Code execution is supported. The opcode and the frame format are fully programmable. Communication can be either in Single Data Rate or Dual Data Rate.



## 3.11 Nested vectored interrupt controller (NVIC)

The devices embed a nested vectored interrupt controller able to manage 16 priority levels, and handle up to 91 maskable interrupt channels plus the 16 interrupt lines of the Cortex<sup>®</sup>-M4 with FPU core.

- Closely coupled NVIC gives low-latency interrupt processing
- Interrupt entry vector table address passed directly to the core
- Allows early processing of interrupts
- Processing of late arriving, higher-priority interrupts
- Support tail chaining
- Processor state automatically saved
- Interrupt entry restored on interrupt exit with no instruction overhead

This hardware block provides flexible interrupt management features with minimum interrupt latency.

## 3.12 External interrupt/event controller (EXTI)

The external interrupt/event controller consists of 23 edge-detector lines used to generate interrupt/event requests. Each line can be independently configured to select the trigger event (rising edge, falling edge, both) and can be masked independently. A pending register maintains the status of the interrupt requests. The EXTI can detect an external line with a pulse width shorter than the Internal APB2 clock period. Up to 114 GPIOs can be connected to the 16 external interrupt lines.

## 3.13 Clocks and startup

On reset the 16 MHz internal RC oscillator is selected as the default CPU clock. The 16 MHz internal RC oscillator is factory-trimmed to offer 1% accuracy at 25 °C. The application can then select as system clock either the RC oscillator or an external 4-26 MHz clock source. This clock can be monitored for failure. If a failure is detected, the system automatically switches back to the internal RC oscillator and a software interrupt is generated (if enabled). This clock source is input to a PLL thus allowing to increase the frequency up to 180 MHz. Similarly, full interrupt management of the PLL clock entry is available when necessary (for example if an indirectly used external oscillator fails).

Several prescalers allow the configuration of the two AHB buses, the high-speed APB (APB2) and the low-speed APB (APB1) domains. The maximum frequency of the two AHB buses is 180 MHz while the maximum frequency of the high-speed APB domains is 90 MHz. The maximum allowed frequency of the low-speed APB domain is 45 MHz.

The devices embed a dedicated PLL (PLLI2S) and PLLSAI which allows to achieve audio class performance. In this case, the I<sup>2</sup>S master clock can generate all standard sampling frequencies from 8 kHz to 192 kHz.

#### 3.14 Boot modes

At startup, boot pins are used to select one out of three boot options:

- · Boot from user Flash
- Boot from system memory
- Boot from embedded SRAM

The boot loader is located in system memory. It is used to reprogram the Flash memory through a serial (UART, I<sup>2</sup>C, CAN, SPI and USB) communication interface. Refer to application note AN2606 for details.

## 3.15 Power supply schemes

- V<sub>DD</sub> = 1.7 to 3.6 V: external power supply for I/Os and the internal regulator (when enabled), provided externally through V<sub>DD</sub> pins.
- V<sub>SSA</sub>, V<sub>DDA</sub> = 1.7 to 3.6 V: external analog power supplies for ADC, DAC, Reset blocks, RCs and PLL. V<sub>DDA</sub> and V<sub>SSA</sub> must be connected to V<sub>DD</sub> and V<sub>SS</sub>, respectively.
- V<sub>BAT</sub> = 1.65 to 3.6 V: power supply for RTC, external clock 32 kHz oscillator and backup registers (through power switch) when V<sub>DD</sub> is not present.

Note:

 $V_{DD}/V_{DDA}$  minimum value of 1.7 V is obtained with the use of an external power supply supervisor (refer to Section 3.16.2: Internal reset OFF). Refer to Table 3: Voltage regulator configuration mode versus device operating mode to identify the packages supporting this option.

## 3.16 Power supply supervisor

#### 3.16.1 Internal reset ON

On packages embedding the PDR\_ON pin, the power supply supervisor is enabled by holding PDR\_ON high. On the other package, the power supply supervisor is always enabled.

The device has an integrated power-on reset (POR)/ power-down reset (PDR) circuitry coupled with a Brownout reset (BOR) circuitry. At power-on, POR/PDR is always active and ensures proper operation starting from 1.8 V. After the 1.8 V POR threshold level is reached, the option byte loading process starts, either to confirm or modify default BOR thresholds, or to disable BOR permanently. Three BOR thresholds are available through option bytes. The device remains in reset mode when  $V_{DD}$  is below a specified threshold,  $V_{POR/PDR}$  or  $V_{BOR}$ , without the need for an external reset circuit.

The device also features an embedded programmable voltage detector (PVD) that monitors the  $V_{DD}/V_{DDA}$  power supply and compares it to the  $V_{PVD}$  threshold. An interrupt can be generated when  $V_{DD}/V_{DDA}$  drops below the  $V_{PVD}$  threshold and/or when  $V_{DD}/V_{DDA}$  is higher than the  $V_{PVD}$  threshold. The interrupt service routine can then generate a warning message and/or put the MCU into a safe state. The PVD is enabled by software.

#### 3.16.2 Internal reset OFF

This feature is available only on packages featuring the PDR\_ON pin. The internal power-on reset (POR) / power-down reset (PDR) circuitry is disabled through the PDR\_ON pin.



> An external power supply supervisor should monitor  $V_{\mbox{\scriptsize DD}}$  and should maintain the device in reset mode as long as V<sub>DD</sub> is below a specified threshold. PDR\_ON should be connected to VSS, to allows device to operate down to 1.7v. Refer to Figure 5: Power supply supervisor interconnection with internal reset OFF.

**VDD** STM32F446x Application reset signal (optional) ☐ VBAT □ PDR ON **VSS** PDR not active: 1.7v< VDD<3.6v MS33844V1

Figure 5. Power supply supervisor interconnection with internal reset OFF

The V<sub>DD</sub> specified threshold, below which the device must be maintained under reset, is 1.7 V.

A comprehensive set of power-saving mode allows to design low-power applications.

When the internal reset is OFF, the following integrated features are no more supported:

- The integrated power-on reset (POR) / power-down reset (PDR) circuitry is disabled
- The brownout reset (BOR) circuitry must be disabled
- The embedded programmable voltage detector (PVD) is disabled
- V<sub>BAT</sub> functionality is no more available and V<sub>BAT</sub> pin should be connected to V<sub>DD</sub>.

All packages, except for the LQFP100/LQFP64, allow to disable the internal reset through the PDR\_ON signal.

#### 3.17 Voltage regulator

The regulator has four operating modes:

- Regulator ON
  - Main regulator mode (MR)
  - Low power regulator (LPR)
  - Power-down
- Regulator OFF

#### 3.17.1 Regulator ON

On packages embedding the BYPASS\_REG pin, the regulator is enabled by holding BYPASS\_REG low. On all other packages, the regulator is always enabled.

There are three power modes configured by software when the regulator is ON:

- MR mode used in Run/sleep modes or in Stop modes
  - In Run/Sleep mode

The MR mode is used either in the normal mode (default mode) or the over-drive mode (enabled by software). Different voltages scaling are provided to reach the best compromise between maximum frequency and dynamic power consumption. The over-drive mode allows operating at a higher frequency than the normal mode for a given voltage scaling.

In Stop modes

The MR can be configured in two ways during stop mode:

MR operates in normal mode (default mode of MR in stop mode)

MR operates in under-drive mode (reduced leakage mode).

LPR is used in the Stop modes:

The LP regulator mode is configured by software when entering Stop mode.

Like the MR mode, the LPR can be configured in two ways during stop mode:

- LPR operates in normal mode (default mode when LPR is ON)
- LPR operates in under-drive mode (reduced leakage mode).
- Power-down is used in Standby mode.

The Power-down mode is activated only when entering in Standby mode. The regulator output is in high impedance and the kernel circuitry is powered down, inducing zero consumption. The contents of the registers and SRAM are lost.

Refer to *Table 3* for a summary of voltage regulator modes versus device operating modes.

Two external ceramic capacitors should be connected on  $V_{CAP\ 1}$  and  $V_{CAP\ 2}$  pin.

All packages have the regulator ON feature.

Table 3. Voltage regulator configuration mode versus device operating mode<sup>(1)</sup>

| Voltage regulator configuration   |    |    | Stop mode | Standby mode |
|-----------------------------------|----|----|-----------|--------------|
| Normal mode                       | MR | MR | MR or LPR | -            |
| Over-drive<br>mode <sup>(2)</sup> | MR | MR | -         | -            |
| Under-drive mode                  | -  | -  | MR or LPR | -            |
| Power-down mode                   | -  | -  | -         | Yes          |

<sup>1. &#</sup>x27;-' means that the corresponding configuration is not available.

<sup>2.</sup> The over-drive mode is not available when  $V_{DD}$  = 1.7 to 2.1 V.

#### 3.17.2 Regulator OFF

This feature is available only on packages featuring the BYPASS\_REG pin. The regulator is disabled by holding BYPASS\_REG high. The regulator OFF mode allows to supply externally a  $V_{12}$  voltage source through  $V_{CAP}$  and  $V_{CAP}$  pins.

Since the internal voltage scaling is not managed internally, the external voltage value must be aligned with the targeted maximum frequency. The two 2.2  $\mu$ F ceramic capacitors should be replaced by two 100 nF decoupling capacitors.

When the regulator is OFF, there is no more internal monitoring on  $V_{12}$ . An external power supply supervisor should be used to monitor the  $V_{12}$  of the logic power domain. PA0 pin should be used for this purpose, and act as power-on reset on  $V_{12}$  power domain.

In regulator OFF mode, the following features are no more supported:

- PA0 cannot be used as a GPIO pin since it allows to reset a part of the V<sub>12</sub> logic power domain which is not reset by the NRST pin.
- As long as PA0 is kept low, the debug mode cannot be used under power-on reset. As a consequence, PA0 and NRST pins must be managed separately if the debug connection under reset or pre-reset is required.
- The over-drive and under-drive modes are not available.

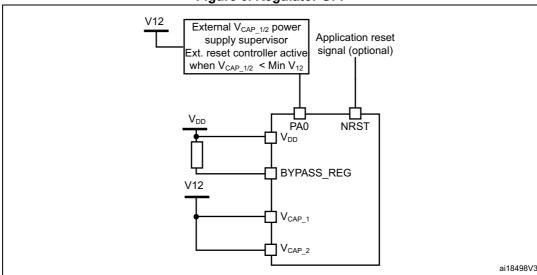


Figure 6. Regulator OFF

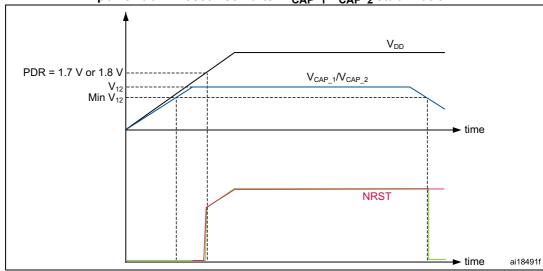
The following conditions must be respected:

- V<sub>DD</sub> should always be higher than V<sub>CAP\_1</sub> and V<sub>CAP\_2</sub> to avoid current injection between power domains.
- If the time for V<sub>CAP\_1</sub> and V<sub>CAP\_2</sub> to reach V<sub>12</sub> minimum value is faster than the time for V<sub>DD</sub> to reach 1.7 V, then PA0 should be kept low to cover both conditions: until V<sub>CAP\_1</sub> and V<sub>CAP\_2</sub> reach V<sub>12</sub> minimum value and until V<sub>DD</sub> reaches 1.7 V (see *Figure* 7).
- Otherwise, if the time for V<sub>CAP\_1</sub> and V<sub>CAP\_2</sub> to reach V<sub>12</sub> minimum value is slower than the time for V<sub>DD</sub> to reach 1.7 V, then PA0 could be asserted low externally (see Figure 8).
- If V<sub>CAP\_1</sub> and V<sub>CAP\_2</sub> go below V<sub>12</sub> minimum value and V<sub>DD</sub> is higher than 1.7 V, then a
  reset must be asserted on PA0 pin.



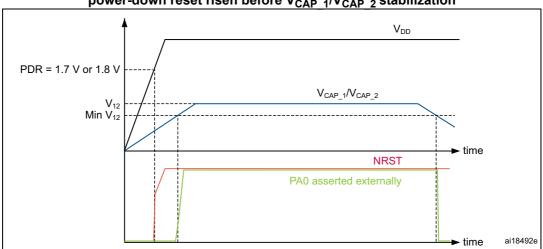
Note: The minimum value of  $V_{12}$  depends on the maximum frequency targeted in the application.

Figure 7. Startup in regulator OFF: slow  $\rm V_{DD}$  slope power-down reset risen after  $\rm V_{CAP-1}/V_{CAP-2}$  stabilization



1. This figure is valid whatever the internal reset mode (ON or OFF).

Figure 8. Startup in regulator OFF mode: fast  $V_{DD}$  slope power-down reset risen before  $V_{CAP\ 1}/V_{CAP\ 2}$  stabilization



1. This figure is valid whatever the internal reset mode (ON or OFF).

#### 3.17.3 Regulator ON/OFF and internal reset ON/OFF availability

Table 4. Regulator ON/OFF and internal reset ON/OFF availability

| Package           | Regulator ON             | Regulator OFF            | Internal reset ON                 | Internal reset OFF    |  |
|-------------------|--------------------------|--------------------------|-----------------------------------|-----------------------|--|
| LQFP64<br>LQFP100 | Yes                      | No                       | Yes                               | No                    |  |
| LQFP144           | Yes                      | No                       |                                   |                       |  |
| UFBGA144          | Yes                      | Yes                      | Yes PDR_ON set to V <sub>DD</sub> | Yes PDR_ON set to VSS |  |
| WLCSP81           | BYPASS_REG<br>set to Vss | BYPASS_REG<br>set to VDD |                                   |                       |  |

## 3.18 Real-time clock (RTC), backup SRAM and backup registers

The backup domain includes:

- The real-time clock (RTC)
- 4 Kbytes of backup SRAM
- 20 backup registers

The real-time clock (RTC) is an independent BCD timer/counter. Dedicated registers contain the second, minute, hour (in 12/24 hour), week day, date, month, year, in BCD (binary-coded decimal) format. Correction for 28, 29 (leap year), 30, and 31 day of the month are performed automatically. The RTC provides a programmable alarm and programmable periodic interrupts with wakeup from Stop and Standby modes. The sub-seconds value is also available in binary format.

It is clocked by a 32.768 kHz external crystal, resonator or oscillator, the internal low-power RC oscillator or the high-speed external clock divided by 128. The internal low-speed RC has a typical frequency of 32 kHz. The RTC can be calibrated using an external 512 Hz output to compensate for any natural quartz deviation.

Two alarm registers are used to generate an alarm at a specific time and calendar fields can be independently masked for alarm comparison. To generate a periodic interrupt, a 16-bit programmable binary auto-reload downcounter with programmable resolution is available and allows automatic wakeup and periodic alarms from every 120 µs to every 36 hours.

A 20-bit prescaler is used for the time base clock. It is by default configured to generate a time base of 1 second from a clock at 32.768 kHz.

The 4-Kbyte backup SRAM is an EEPROM-like memory area. It can be used to store data which need to be retained in VBAT and standby mode. This memory area is disabled by default to minimize power consumption (see Section 3.19: Low-power modes). It can be enabled by software.

The backup registers are 32-bit registers used to store 80 bytes of user application data when  $V_{DD}$  power is not present. Backup registers are not reset by a system, a power reset, or when the device wakes up from the Standby mode (see Section 3.19: Low-power modes).

Additional 32-bit registers contain the programmable alarm subseconds, seconds, minutes, hours, day, and date.

Like backup SRAM, the RTC and backup registers are supplied through a switch that is powered either from the  $V_{DD}$  supply when present or from the  $V_{BAT}$  pin.

## 3.19 Low-power modes

The devices support three low-power modes to achieve the best compromise between low power consumption, short startup time and available wakeup sources:

#### Sleep mode

In Sleep mode, only the CPU is stopped. All peripherals continue to operate and can wake up the CPU when an interrupt/event occurs.

#### Stop mode

The Stop mode achieves the lowest power consumption while retaining the contents of SRAM and registers. All clocks in the 1.2 V domain are stopped, the PLL, the HSI RC and the HSE crystal oscillators are disabled.

The voltage regulator can be put either in main regulator mode (MR) or in low-power mode (LPR). Both modes can be configured as follows (see *Table 5: Voltage regulator modes in stop mode*):

- Normal mode (default mode when MR or LPR is enabled)
- Under-drive mode.

The device can be woken up from the Stop mode by any of the EXTI line (the EXTI line source can be one of the 16 external lines, the PVD output, the RTC alarm / wakeup / tamper / time stamp events, the USB OTG FS/HS wakeup).

| Voltage regulator configuration | Main regulator (MR)    | Low-power regulator (LPR) |  |  |
|---------------------------------|------------------------|---------------------------|--|--|
| Normal mode                     | MR ON                  | LPR ON                    |  |  |
| Under-drive mode                | MR in under-drive mode | LPR in under-drive mode   |  |  |

Table 5. Voltage regulator modes in stop mode

#### • Standby mode

The Standby mode is used to achieve the lowest power consumption. The internal voltage regulator is switched off so that the entire 1.2 V domain is powered off. The PLL, the HSI RC and the HSE crystal oscillators are also switched off. After entering Standby mode, the SRAM and register contents are lost except for registers in the backup domain and the backup SRAM when selected.

The device exits the Standby mode when an external reset (NRST pin), an IWDG reset, a rising edge on the WKUP pin, or an RTC alarm / wakeup / tamper /time stamp event occurs.

The standby mode is not supported when the embedded voltage regulator is bypassed and the 1.2 V domain is controlled by an external power.

## 3.20 V<sub>BAT</sub> operation

The  $V_{BAT}$  pin allows to power the device  $V_{BAT}$  domain from an external battery, an external supercapacitor, or from  $V_{DD}$  when no external battery and an external supercapacitor are present.

 $V_{\text{BAT}}$  operation is activated when  $V_{\text{DD}}$  is not present.

The V<sub>BAT</sub> pin supplies the RTC, the backup registers and the backup SRAM.

Note: When the microcontroller is supplied from  $V_{BAT}$ , external interrupts and RTC alarm/events do not exit it from  $V_{BAT}$  operation.

When PDR\_ON pin is not connected to  $V_{DD}$  (Internal Reset OFF), the  $V_{BAT}$  functionality is no more available and  $V_{BAT}$  pin should be connected to  $V_{DD}$ .



## 3.21 Timers and watchdogs

The devices include two advanced-control timers, eight general-purpose timers, two basic timers and two watchdog timers.

All timer counters can be frozen in debug mode.

*Table 6* compares the features of the advanced-control, general-purpose and basic timers.

Table 6. Timer feature comparison

| Timer<br>type        | Timer           | Counter resolution | Counter<br>type         | Prescaler<br>factor                   | DMA<br>request<br>generation | Capture/<br>compare<br>channels | Complementary output | Max<br>interface<br>clock<br>(MHz) | Max<br>timer<br>clock<br>(MHz) <sup>(1)</sup> |
|----------------------|-----------------|--------------------|-------------------------|---------------------------------------|------------------------------|---------------------------------|----------------------|------------------------------------|---|
| Advanced-<br>control | TIM1,<br>TIM8   | 16-bit             | Up,<br>Down,<br>Up/down | Any integer<br>between 1<br>and 65536 | Yes                          | 4                               | Yes                  | 90                                 | 180   |
| General<br>purpose   | TIM2,<br>TIM5   | 32-bit             | Up,<br>Down,<br>Up/down | Any integer<br>between 1<br>and 65536 | Yes                          | 4                               | No                   | 45                                 | 90/180  |
|                      | TIM3,<br>TIM4   | 16-bit             | Up,<br>Down,<br>Up/down | Any integer<br>between 1<br>and 65536 | Yes                          | 4                               | No                   | 45                                 | 90/180  |
|                      | TIM9            | 16-bit             | Up                      | Any integer<br>between 1<br>and 65536 | No                           | 2                               | No                   | 90                                 | 180   |
|                      | TIM10,<br>TIM11 | 16-bit             | Up                      | Any integer<br>between 1<br>and 65536 | No                           | 1                               | No                   | 90                                 | 180   |
|                      | TIM12           | 16-bit             | Up                      | Any integer<br>between 1<br>and 65536 | No                           | 2                               | No                   | 45                                 | 90/180  |
|                      | TIM13,<br>TIM14 | 16-bit             | Up                      | Any integer<br>between 1<br>and 65536 | No                           | 1                               | No                   | 45                                 | 90/180  |
| Basic                | TIM6,<br>TIM7   | 16-bit             | Up                      | Any integer<br>between 1<br>and 65536 | Yes                          | 0                               | No                   | 45                                 | 90/180  |

<sup>1.</sup> The maximum timer clock is either 90 or 180 MHz depending on TIMPRE bit configuration in the RCC\_DCKCFGR register.

477

#### 3.21.1 Advanced-control timers (TIM1, TIM8)

The advanced-control timers (TIM1, TIM8) can be seen as three-phase PWM generators multiplexed on 6 channels. They have complementary PWM outputs with programmable inserted dead times. They can also be considered as complete general-purpose timers. Their 4 independent channels can be used for:

- Input capture
- Output compare
- PWM generation (edge- or center-aligned modes)
- One-pulse mode output

If configured as standard 16-bit timers, they have the same features as the general-purpose TIMx timers. If configured as 16-bit PWM generators, they have full modulation capability (0-100%).

The advanced-control timer can work together with the TIMx timers via the Timer Link feature for synchronization or event chaining.

TIM1 and TIM8 support independent DMA request generation.

#### 3.21.2 General-purpose timers (TIMx)

There are ten synchronized general-purpose timers embedded in the STM32F446xx devices (see *Table 6* for differences).

#### TIM2, TIM3, TIM4, TIM5

The STM32F446xx include 4 full-featured general-purpose timers: TIM2, TIM5, TIM3, and TIM4. The TIM2 and TIM5 timers are based on a 32-bit auto-reload up/downcounter and a 16-bit prescaler. The TIM3 and TIM4 timers are based on a 16-bit auto-reload up/downcounter and a 16-bit prescaler. They all feature 4 independent channels for input capture/output compare, PWM or one-pulse mode output. This gives up to 16 input capture/output compare/PWMs on the largest packages.

The TIM2, TIM3, TIM4, TIM5 general-purpose timers can work together, or with the other general-purpose timers and the advanced-control timers TIM1 and TIM8 via the Timer Link feature for synchronization or event chaining.

Any of these general-purpose timers can be used to generate PWM outputs.

TIM2, TIM3, TIM4, TIM5 all have independent DMA request generation. They are capable of handling quadrature (incremental) encoder signals and the digital outputs from 1 to 4 hall-effect sensors.

#### TIM9, TIM10, TIM11, TIM12, TIM13, and TIM14

These timers are based on a 16-bit auto-reload upcounter and a 16-bit prescaler. TIM10, TIM11, TIM13, and TIM14 feature one independent channel, whereas TIM9 and TIM12 have two independent channels for input capture/output compare, PWM or one-pulse mode output. They can be synchronized with the TIM2, TIM3, TIM4, TIM5 full-featured general-purpose timers. They can also be used as simple time bases.

#### 3.21.3 Basic timers TIM6 and TIM7

These timers are mainly used for DAC trigger and waveform generation. They can also be used as a generic 16-bit time base.

TIM6 and TIM7 support independent DMA request generation.



#### 3.21.4 Independent watchdog

The independent watchdog is based on a 12-bit downcounter and 8-bit prescaler. It is clocked from an independent 32 kHz internal RC and as it operates independently from the main clock, it can operate in Stop and Standby modes. It can be used either as a watchdog to reset the device when a problem occurs, or as a free-running timer for application timeout management. It is hardware- or software-configurable through the option bytes.

#### 3.21.5 Window watchdog

The window watchdog is based on a 7-bit downcounter that can be set as free-running. It can be used as a watchdog to reset the device when a problem occurs. It is clocked from the main clock. It has an early warning interrupt capability and the counter can be frozen in debug mode.

#### 3.21.6 SysTick timer

This timer is dedicated to real-time operating systems, but could also be used as a standard downcounter. It features:

- A 24-bit downcounter
- Autoreload capability
- Maskable system interrupt generation when the counter reaches 0
- Programmable clock source.

# 3.22 Inter-integrated circuit interface (I<sup>2</sup>C)

Four I<sup>2</sup>C bus interfaces can operate in multimaster and slave modes. Three I<sup>2</sup>C can support the standard (up to 100 KHz) and fast (up to 400 KHz) modes.

One I<sup>2</sup>C can support the standard (up to 100 KHz), fast (up to 400 KHz) and fast mode plus (up to 1MHz) modes.

They (all I<sup>2</sup>C) support the 7/10-bit addressing mode and the 7-bit dual addressing mode (as slave).

A hardware CRC generation/verification is embedded.

They can be served by DMA and they support SMBus 2.0/PMBus.

The devices also include programmable analog and digital noise filters (see Table 7).

Table 7. Comparison of I2C analog and digital filters

| -                                | Analog filter | Digital filter   |  |  |
|----------------------------------|---------------|--|--|--|
| Pulse width of suppressed spikes | ≥ 50 ns       | Programmable length from 1 to 15 I2C peripheral clocks |  |  |

# 3.23 Universal synchronous/asynchronous receiver transmitters (USART)

The devices embed four universal synchronous/asynchronous receiver transmitters (USART1, USART2, USART3 and USART6) and four universal asynchronous receiver transmitters (UART4, and UART5).

These six interfaces provide asynchronous communication, IrDA SIR ENDEC support, multiprocessor communication mode, single-wire half-duplex communication mode and have LIN Master/Slave capability. The USART1 and USART6 interfaces are able to communicate at speeds of up to 11.25 Mbit/s. The other available interfaces communicate at up to 5.62 bit/s.

USART1, USART2, USART3 and USART6 also provide hardware management of the CTS and RTS signals, Smart Card mode (ISO 7816 compliant) and SPI-like communication capability. All interfaces can be served by the DMA controller.

| Table 8. USART feature comparison(1) |                   |                    |     |                   |          |                         |   |  |                          |
|--------------------------------------|-------------------|--------------------|-----|-------------------|----------|-------------------------|---|--|--------------------------|
| USART<br>name                        | Standard features | Modem<br>(RTS/CTS) | LIN | SPI<br>maste<br>r | irD<br>A | Smartcard<br>(ISO 7816) | Max. baud<br>rate in Mbit/s<br>(oversamplin<br>g by 16) | Max. baud<br>rate in Mbit/s<br>(oversamplin<br>g by 8) | APB<br>mapping           |
| USART1                               | х                 | Х                  | Х   | Х                 | Х        | Х                       | 5.62  | 11.25  | APB2<br>(max.<br>90 MHz) |
| USART2                               | х                 | Х                  | Х   | Х                 | Х        | Х                       | 2.81  | 5.62   | APB1<br>(max.<br>45 MHz) |
| USART3                               | х                 | Х                  | Х   | х                 | х        | Х                       | 2.81  | 5.62   | APB1<br>(max.<br>45 MHz) |
| UART4                                | х                 | Х                  | Х   | -                 | х        | -                       | 2.81  | 5.62   | APB1<br>(max.<br>45 MHz) |
| UART5                                | х                 | х                  | Х   | -                 | х        | -                       | 2.81  | 5.62   | APB1<br>(max.<br>45 MHz) |
| USART6                               | Х                 | х                  | Х   | х                 | Х        | х                       | 5.62  | 11.25  | APB2<br>(max.<br>90 MHz) |

Table 8. USART feature comparison<sup>(1)</sup>

## 3.24 Serial peripheral interface (SPI)

The devices feature up to four SPIs in slave and master modes in full-duplex and simplex communication modes. SPI1, and SPI4 can communicate at up to 45 Mbits/s, SPI2 and SPI3 can communicate at up to 22.5 Mbit/s. The 3-bit prescaler gives 8 master mode frequencies and the frame is configurable to 8 bits or 16 bits. The hardware CRC generation/verification supports basic SD Card/MMC modes. All SPIs can be served by the DMA controller.

<sup>1.</sup> X = feature supported.

The SPI interface can be configured to operate in TI mode for communications in master mode and slave mode.

# 3.25 HDMI (high-definition multimedia interface) consumer electronics control (CEC)

The devices embeds a HDMI-CEC controller that provides hardware support of consumer electronics control (CEC) (Appendix supplement 1 to the HDMI standard).

This protocol provides high-level control functions between all audiovisual products in an environment. It is specified to operate at low speeds with minimum processing and memory overhead.

## 3.26 Inter-integrated sound (I<sup>2</sup>S)

Three standard I<sup>2</sup>S interfaces (multiplexed with SPI1, SPI2 and SPI3) are available. They can be operated in master or slave mode, in simplex communication modes, and can be configured to operate with a 16-/32-bit resolution as an input or output channel. Audio sampling frequencies from 8 kHz up to 192 kHz are supported. When either or both of the I<sup>2</sup>S interfaces is/are configured in master mode, the master clock can be output to the external DAC/CODEC at 256 times the sampling frequency.

All I2Sx can be served by the DMA controller.

## 3.27 SPDIF-RX Receiver Interface (SPDIFRX)

The SPDIF-RX peripheral, is designed to receive an S/PDIF flow compliant with IEC-60958 and IEC-61937. These standards support simple stereo streams up to high sample rate, and compressed multi-channel surround sound, such as those defined by Dolby or DTS (up to 5.1).

The main features of the SPDIF-RX are the following:

- Up to 4 inputs available
- Automatic symbol rate detection
- Maximum symbol rate: 12.288 MHz
- Stereo stream from 32 to 192 kHz supported
- Supports Audio IEC-60958 and IEC-61937, consumer applications
- Parity bit management
- · Communication using DMA for audio samples
- Communication using DMA for control and user channel information
- Interrupt capabilities

The SPDIF-RX receiver provides all the necessary features to detect the symbol rate, and decode the incoming data stream.

The user can select the wanted SPDIF input, and when a valid signal will be available, the SPDIF-RX will re-sample the incoming signal, decode the Manchester stream, recognize frames, sub-frames and blocks elements. It delivers to the CPU decoded data, and associated status flags.



The SPDIF-RX also offers a signal named spdifrx\_frame\_sync, which toggles at the S/PDIF sub-frame rate that will be used to compute the exact sample rate for clock drift algorithms.

## 3.28 Serial Audio interface (SAI)

The devices feature two serial audio interfaces (SAI1 and SAI2). Each serial audio interfaces based on two independent audio sub blocks which can operate as transmitter or receiver with their FIFO. Many audio protocols are supported by each block: I2S standards, LSB or MSB-justified, PCM/DSP, TDM, AC'97 and SPDIF output, supporting audio sampling frequencies from 8 kHz up to 192 kHz. Both sub blocks can be configured in master or in slave mode. The SAIs use a PLL to achieve audio class accuracy.

In master mode, the master clock can be output to the external DAC/CODEC at 256 times of the sampling frequency.

The two sub blocks can be configured in synchronous mode when full-duplex mode is required.

SAI1 and SA2 can be served by the DMA controller.

## 3.29 Audio PLL (PLLI<sup>2</sup>S)

The devices feature an additional dedicated PLL for audio I<sup>2</sup>S and SAI applications. It allows to achieve error-free I<sup>2</sup>S sampling clock accuracy without compromising on the CPU performance, while using USB peripherals.

The PLLI2S configuration can be modified to manage an I<sup>2</sup>S/SAI sample rate change without disabling the main PLL (PLL) used for CPU, USB and Ethernet interfaces.

The audio PLL can be programmed with very low error to obtain sampling rates ranging from 8 KHz to 192 KHz.

In addition to the audio PLL, a master clock input pin can be used to synchronize the I<sup>2</sup>S/SAI flow with an external PLL (or Codec output).

## 3.30 Serial Audio Interface PLL(PLLSAI)

An additional PLL dedicated to audio and USB is used for SAI1 and SAI2 peripheral in case the PLLI2S is programmed to achieve another audio sampling frequency (49.152 MHz or 11.2896 MHz) and the audio application requires both sampling frequencies simultaneously.

The PLLSAI is also used to generate the 48MHz clock for USB FS and SDIO in case the system PLL is programmed with factors not multiple of 48MHz.

## 3.31 Secure digital input/output interface (SDIO)

An SD/SDIO/MMC host interface is available, that supports MultiMediaCard System Specification Version 4.2 in three different databus modes: 1-bit (default), 4-bit and 8-bit.

The interface allows data transfer at up to 48 MHz, and is compliant with the SD Memory Card Specification Version 2.0.

> The SDIO Card Specification Version 2.0 is also supported with two different databus modes: 1-bit (default) and 4-bit.

The current version supports only one SD/SDIO/MMC4.2 card at any one time and a stack of MMC4.1 or previous.

#### 3.32 Controller area network (bxCAN)

The two CANs are compliant with the 2.0A and B (active) specifications with a bitrate up to 1 Mbit/s. They can receive and transmit standard frames with 11-bit identifiers as well as extended frames with 29-bit identifiers. Each CAN has three transmit mailboxes, two receive FIFOS with 3 stages and 28 shared scalable filter banks (all of them can be used even if one CAN is used). 256 bytes of SRAM are allocated for each CAN.

#### 3.33 Universal serial bus on-the-go full-speed (OTG FS)

The devices embed an USB OTG full-speed device/host/OTG peripheral with integrated transceivers. The USB OTG FS peripheral is compliant with the USB 2.0 specification and with the OTG 1.0 specification. It has software-configurable endpoint setting and supports suspend/resume. The USB OTG full-speed controller requires a dedicated 48 MHz clock that is generated by a PLL connected to the HSE oscillator. The USB has dedicated power rails allowing its use throughout the entire power range. The major features are:

- Combined Rx and Tx FIFO size of 320 × 35 bits with dynamic FIFO sizing
- Supports the session request protocol (SRP) and host negotiation protocol (HNP)
- 6 bidirectional endpoints
- 12 host channels with periodic OUT support
- HNP/SNP/IP inside (no need for any external resistor)
- For OTG/Host modes, a power switch is needed in case bus-powered devices are connected

#### 3.34 Universal serial bus on-the-go high-speed (OTG HS)

The devices embed a USB OTG high-speed (up to 480 Mb/s) device/host/OTG peripheral. The USB OTG HS supports both full-speed and high-speed operations. It integrates the transceivers for full-speed operation (12 MB/s) and features a UTMI low-pin interface (ULPI) for high-speed operation (480 MB/s). When using the USB OTG HS in HS mode, an external PHY device connected to the ULPI is required.

The USB OTG HS peripheral is compliant with the USB 2.0 specification and with the OTG 1.0 specification. It has software-configurable endpoint setting and supports suspend/resume. The USB OTG full-speed controller requires a dedicated 48 MHz clock that is generated by a PLL connected to the HSE oscillator. The USB has dedicated power rails allowing its use throughout the entire power range.



STM32F446xx Functional overview

The major features are:

- Combined Rx and Tx FIFO size of 1 Kbit × 35 with dynamic FIFO sizing
- Supports the session request protocol (SRP) and host negotiation protocol (HNP)
- 8 bidirectional endpoints
- 16 host channels with periodic OUT support
- Internal FS OTG PHY support
- External HS or HS OTG operation supporting ULPI in SDR mode. The OTG PHY is connected to the microcontroller ULPI port through 12 signals. It can be clocked using the 60 MHz output.
- Internal USB DMA
- HNP/SNP/IP inside (no need for any external resistor)
- for OTG/Host modes, a power switch is needed in case bus-powered devices are connected

### 3.35 Digital camera interface (DCMI)

The devices embed a camera interface that can connect with camera modules and CMOS sensors through an 8-bit to 14-bit parallel interface, to receive video data. The camera interface can sustain a data transfer rate up to 94.5 Mbyte/s (in 14-bit mode) at 54 MHz.

#### Its features:

- Programmable polarity for the input pixel clock and synchronization signals
- Parallel data communication can be 8-, 10-, 12- or 14-bit
- Supports 8-bit progressive video monochrome or raw bayer format, YCbCr 4:2:2 progressive video, RGB 565 progressive video or compressed data (like JPEG)
- Supports continuous mode or snapshot (a single frame) mode
- Capability to automatically crop the image black & white.

# 3.36 General-purpose input/outputs (GPIOs)

Each of the GPIO pins can be configured by software as output (push-pull or open-drain, with or without pull-up or pull-down), as input (floating, with or without pull-up or pull-down) or as peripheral alternate function. Most of the GPIO pins are shared with digital or analog alternate functions. All GPIOs are high-current-capable and have speed selection to better manage internal noise, power consumption and electromagnetic emission.

The I/O configuration can be locked if needed by following a specific sequence in order to avoid spurious writing to the I/Os registers.

Fast I/O handling allowing maximum I/O toggling up to 90 MHz.

# 3.37 Analog-to-digital converters (ADCs)

Three 12-bit analog-to-digital converters are embedded and each ADC shares up to 16 external channels, performing conversions in the single-shot or scan mode. In scan mode, automatic conversion is performed on a selected group of analog inputs.

Functional overview STM32F446xx

Additional logic functions embedded in the ADC interface allow:

- Simultaneous sample and hold
- Interleaved sample and hold

The ADC can be served by the DMA controller. An analog watchdog feature allows very precise monitoring of the converted voltage of one, some or all selected channels. An interrupt is generated when the converted voltage is outside the programmed thresholds.

To synchronize A/D conversion and timers, the ADCs could be triggered by any of TIM1, TIM2, TIM3, TIM4, TIM5, or TIM8 timer.

### 3.38 Temperature sensor

The temperature sensor has to generate a voltage that varies linearly with temperature. The conversion range is between 1.7 V and 3.6 V. The temperature sensor is internally connected to the same input channel as  $V_{BAT}$ , ADC1\_IN18, which is used to convert the sensor output voltage into a digital value. When the temperature sensor and  $V_{BAT}$  conversion are enabled at the same time, only  $V_{BAT}$  conversion is performed.

As the offset of the temperature sensor varies from chip to chip due to process variation, the internal temperature sensor is mainly suitable for applications that detect temperature changes instead of absolute temperatures. If an accurate temperature reading is needed, then an external temperature sensor part should be used.

# 3.39 Digital-to-analog converter (DAC)

The two 12-bit buffered DAC channels can be used to convert two digital signals into two analog voltage signal outputs.

This dual digital Interface supports the following features:

- two DAC converters: one for each output channel
- 8-bit or 10-bit monotonic output
- left or right data alignment in 12-bit mode
- synchronized update capability
- noise-wave generation
- triangular-wave generation
- dual DAC channel independent or simultaneous conversions
- DMA capability for each channel
- external triggers for conversion
- input voltage reference V<sub>RFF+</sub>

Eight DAC trigger inputs are used in the device. The DAC channels are triggered through the timer update outputs that are also connected to different DMA streams.

# 3.40 Serial wire JTAG debug port (SWJ-DP)

The ARM SWJ-DP interface is embedded, and is a combined JTAG and serial wire debug port that enables either a serial wire debug or a JTAG probe to be connected to the target.



STM32F446xx Functional overview

Debug is performed using 2 pins only instead of 5 required by the JTAG (JTAG pins could be re-use as GPIO with alternate function): the JTAG TMS and TCK pins are shared with SWDIO and SWCLK, respectively, and a specific sequence on the TMS pin is used to switch between JTAG-DP and SW-DP.

### 3.41 Embedded Trace Macrocell™

The ARM Embedded Trace Macrocell provides a greater visibility of the instruction and data flow inside the CPU core by streaming compressed data at a very high rate from the STM32F446xx through a small number of ETM pins to an external hardware trace port analyser (TPA) device. The TPA is connected to a host computer using USB, Ethernet, or any other high-speed channel. Real-time instruction and data flow activity can be recorded and then formatted for display on the host computer that runs the debugger software. TPA hardware is commercially available from common development tool vendors.

The Embedded Trace Macrocell operates with third party debugger software tools.



# 4 Pinout and pin description

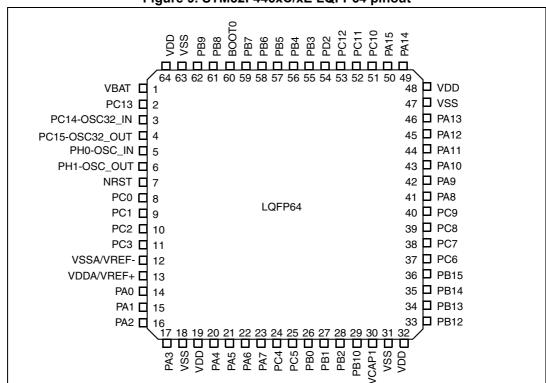


Figure 9. STM32F446xC/xE LQFP64 pinout

1. The above figure shows the package top view.



MS31149V2

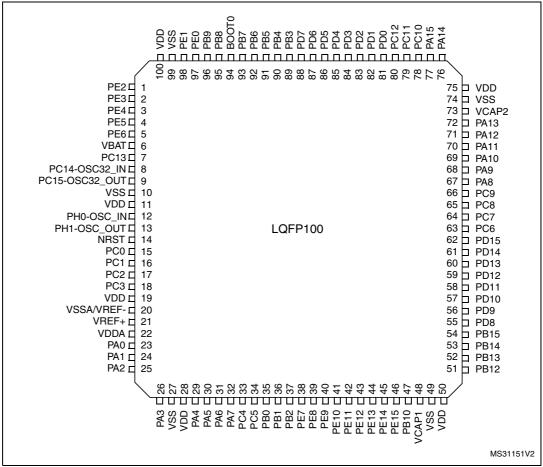
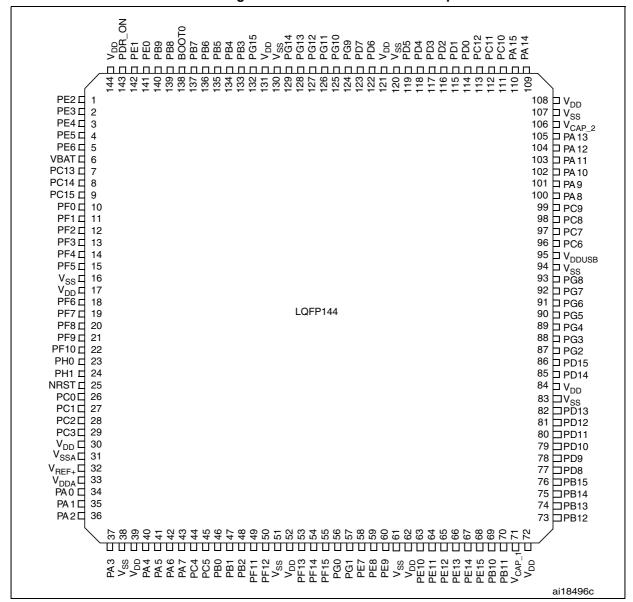


Figure 10. STM32F446xC/xE LQFP100 pinout

1. The above figure shows the package top view.

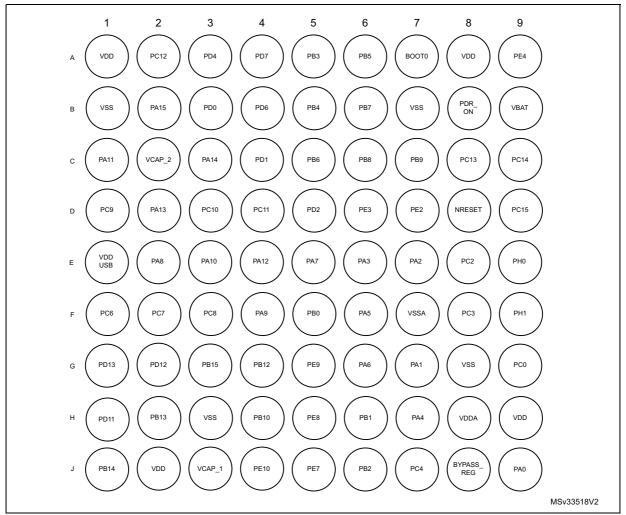


Figure 11. STM32F446xC LQFP144 pinout



1. The above figure shows the package top view.

Figure 12. STM32F446xC/xE WLCSP81 ballout



1. The above figure shows the package top view.

**57**/

### Figure 13. STM32F446xC/xE UFBGA144 ballout

| rigate is emissi 4-toxe/A2 of Be/Cit+4 builder                       |       |
|--|-------|
| 1 2 3 4 5 6 7 8 9 10 11 12   |       |
| A PC13 PE3 PE1 PE0 PB4 PB3 PD6 PD7 PA15 PA14 PA13                    | l     |
| B PC14 PE4 PE5 PB9 PB5 PG15 PG12 PD5 PC11 PC10 PA12                  | )     |
| C PC15 VBAT PF0 PF1 PB8 PB6 PG14 PG11 PD4 PC12 VDD USB PA11          | l     |
| D PHO VSS VDD PF2 BOOTO PB7 PG13 PG10 PD3 PD1 PA10 PA9               | )     |
| E PH1 PF3 PF4 PF5 PDR VSS PG9 PD2 PD0 PC9 PA8                        |       |
| F NRST PF9 PF8 VSS VDD VDD VDD VDD VDD VDD PC8 PC7                   | )     |
| G PF10 PF8 VSS VDD VDD VDD VCAP_2 VSS PG8 PC6                        | l     |
| H PC0 PC1 PC2 PC3 BYPASS VSS VCAP_1 PE11 PD11 PG7 PG6 PG6            | 1     |
| J VSSA PA0 PA4 PC4 PB2 PG1 PE10 PE12 PD10 PG4 PG3 PG2                | l     |
| K (VREF-) (PA1) (PD1) (PD13) (PD14) (PD15)                           |       |
| L (VREF+) (PA2) (PB0) (PF12) (PD8) (PD12) (PD8) (PD12) (PB14) (PB15) | l     |
| M VDDA PA3 PA7 PB1 PF11 PF14 PE7 PE15 PB10 PB11 PB12 PB13            | ı     |
| MSv365   | 519V1 |

1. The above picture shows the package top view.

Table 9. Legend/abbreviations used in the pinout table

| Name  | Abbreviation       | Definition   |  |  |  |  |  |
|---|--------------------|--|--|--|--|--|--|
| Pin name  |                    | specified in brackets below the pin name, the pin function during and after as the actual pin name |  |  |  |  |  |
|   | S                  | Supply pin   |  |  |  |  |  |
| Pin type  | 1                  | Input only pin   |  |  |  |  |  |
|   | I/O                | Input / output pin   |  |  |  |  |  |
|   | FT                 | 5 V tolerant I/O   |  |  |  |  |  |
|   | FTf                | 5V tolerant IO, I2C FM+ option   |  |  |  |  |  |
| I/O structure   | TTa                | 3.3 V tolerant I/O directly connected to ADC   |  |  |  |  |  |
|   | В                  | Dedicated BOOT0 pin  |  |  |  |  |  |
|   | RST                | Bidirectional reset pin with weak pull-up resistor   |  |  |  |  |  |
| Notes   | Unless otherwise   | specified by a note, all I/Os are set as floating inputs during and after reset                    |  |  |  |  |  |
| Alternate functions   | Functions selected | d through GPIOx_AFR registers  |  |  |  |  |  |
| Additional functions Functions directly selected/enabled through peripheral registers |                    |  |  |  |  |  |  |

Table 10. STM32F446xx pin and ball descriptions

|        | Piı     | n Nun    | nber     |         |                                    |          |               |       |   |                         |
|--------|---------|----------|----------|---------|------------------------------------|----------|---------------|-------|---|-------------------------|
| LQFP64 | LQFP100 | WLCSP 81 | UFBGA144 | LQFP144 | Pin name (function<br>after reset) | Pin type | I/O structure | Notes | Alternate functions   | Additional<br>functions |
| -      | 1       | D7       | A3       | 1       | PE2                                | I/O      | FT            | -     | TRACECLK, SPI4_SCK,<br>SAI1_MCLK_A,<br>QUADSPI_BK1_IO2,<br>FMC_A23, EVENTOUT  | -                       |
| -      | 2       | D6       | A2       | 2       | PE3                                | I/O      | FT            | -     | TRACED0, SAI1_SD_B,<br>FMC_A19, EVENTOUT                                      | -                       |
| -      | 3       | A9       | B2       | 3       | PE4                                | I/O      | FT            | -     | TRACED1, SPI4_NSS,<br>SAI1_FS_A, FMC_A20,<br>DCMI_D4, EVENTOUT                | -                       |
| -      | 4       | -        | В3       | 4       | PE5                                | I/O      | FT            | -     | TRACED2, TIM9_CH1,<br>SPI4_MISO, SAI1_SCK_A,<br>FMC_A21, DCMI_D6,<br>EVENTOUT | -                       |



Table 10. STM32F446xx pin and ball descriptions (continued)

|        | Piı     | n Nun    |          |         |                                    |          |               |       | escriptions (continued)  |                         |
|--------|---------|----------|----------|---------|------------------------------------|----------|---------------|-------|--|-------------------------|
| LQFP64 | LQFP100 | WLCSP 81 | UFBGA144 | LQFP144 | Pin name (function<br>after reset) | Pin type | I/O structure | Notes | Alternate functions  | Additional<br>functions |
| -      | 5       | 1        | B4       | 5       | PE6                                | I/O      | FT            | -     | TRACED3, TIM9_CH2,<br>SPI4_MOSI, SAI1_SD_A,<br>FMC_A22, DCMI_D7,<br>EVENTOUT | -                       |
| 1      | 6       | В9       | C2       | 6       | VBAT                               | S        | -             | -     | -  | -                       |
| 2      | 7       | C8       | A1       | 7       | PC13                               | I/O      | FT            | -     | EVENTOUT   | TAMP_1/WKUP1            |
| 3      | 8       | C9       | B1       | 8       | PC14-<br>OSC32_IN(PC14)            | I/O      | FT            | ı     | EVENTOUT   | OSC32_IN                |
| 4      | 9       | D9       | C1       | 9       | PC15-<br>OSC32_OUT(PC15)           | I/O      | FT            | ı     | EVENTOUT   | OSC32_OUT               |
| -      | -       | ı        | C3       | 10      | PF0                                | I/O      | FT            | 1     | I2C2_SDA, FMC_A0,<br>EVENTOUT  | -                       |
| -      | -       | -        | C4       | 11      | PF1                                | I/O      | FT            | -     | I2C2_SCL, FMC_A1,<br>EVENTOUT  | -                       |
| -      | -       | -        | D4       | 12      | PF2                                | I/O      | FT            | -     | I2C2_SMBA, FMC_A2,<br>EVENTOUT   | -                       |
| -      | -       | -        | E2       | 13      | PF3                                | I/O      | FT            | •     | FMC_A3, EVENTOUT   | ADC3_IN9                |
| -      | -       | 1        | E3       | 14      | PF4                                | I/O      | FT            | -     | FMC_A4, EVENTOUT   | ADC3_IN14               |
| -      | -       | -        | E4       | 15      | PF5                                | I/O      | FT            | -     | FMC_A5, EVENTOUT   | ADC3_IN15               |
| -      | 10      | -        | D2       | 16      | VSS                                | S        | -             | -     | -  | -                       |
| -      | 11      | -        | D3       | 17      | VDD                                | S        | -             | -     | -  | -                       |
| 1      | 1       | 1        | F3       | 18      | PF6                                | I/O      | FT            |       | TIM10_CH1, SAI1_SD_B,<br>QUADSPI_BK1_IO3,<br>EVENTOUT                        | ADC3_IN4                |
| -      | -       | -        | F2       | 19      | PF7                                | I/O      | FT            | -     | TIM11_CH1,<br>SAI1_MCLK_B,<br>QUADSPI_BK1_IO2,<br>EVENTOUT                   | ADC3_IN5                |
| -      | -       | -        | G3       | 20      | PF8                                | I/O      | FT            | 1     | SAI1_SCK_B, TIM13_CH1,<br>QUADSPI_BK1_IO0,<br>EVENTOUT                       | ADC3_IN6                |
| -      | -       | -        | G2       | 21      | PF9                                | I/O      | FT            | -     | SAI1_FS_B, TIM14_CH1,<br>QUADSPI_BK1_IO1,<br>EVENTOUT                        | ADC3_IN7                |
| -      | -       | -        | G1       | 22      | PF10                               | I/O      | FT            | -     | DCMI_D11, EVENTOUT   | ADC3_IN8                |
| 5      | 12      | E9       | D1       | 23      | PH0-OSC_IN(PH0)                    | I/O      | FT            | -     | EVENTOUT   | OSC_IN                  |

Table 10. STM32F446xx pin and ball descriptions (continued)

|        | Piı     | n Nun    | nber     |         |                                 |          |               |       |   |                             |
|--------|---------|----------|----------|---------|---------------------------------|----------|---------------|-------|---|-----------------------------|
| LQFP64 | LQFP100 | WLCSP 81 | UFBGA144 | LQFP144 | Pin name (function after reset) | Pin type | I/O structure | Notes | Alternate functions   | Additional<br>functions     |
| 6      | 13      | F9       | E1       | 24      | PH1-<br>OSC_OUT(PH1)            | I/O      | FT            | -     | EVENTOUT  | OSC_OUT                     |
| 7      | 14      | D8       | F1       | 25      | NRST                            | I/O      | RS<br>T       | -     | -   | -                           |
| 8      | 15      | G9       | H1       | 26      | PC0                             | I/O      | FT            | ı     | SAI1_MCLK_B, OTG_HS_ULPI_STP, FMC_SDNWE, EVENTOUT   | ADC123_IN10                 |
| 9      | 16      | 1        | H2       | 27      | PC1                             | I/O      | FT            | 1     | SPI3_MOSI/I2S3_SD,<br>SAI1_SD_A,<br>SPI2_MOSI/I2S2_SD,<br>EVENTOUT                              | ADC123_IN11                 |
| 10     | 17      | E8       | НЗ       | 28      | PC2                             | I/O      | FT            | 1     | SPI2_MISO,<br>OTG_HS_ULPI_DIR,<br>FMC_SDNE0, EVENTOUT   | ADC123_IN12                 |
| 11     | 18      | F8       | H4       | 29      | PC3                             | I/O      | FT            | 1     | SPI2_MOSI/I2S2_SD,<br>OTG_HS_ULPI_NXT,<br>FMC_SDCKE0,<br>EVENTOUT                               | ADC123_IN13                 |
| -      | 19      | Н9       | -        | 30      | VDD                             | S        | -             | 1     | -   | -                           |
| -      | -       | G8       | -        | -       | VSS                             | S        | -             | -     | -   | -                           |
| 12     | 20      | F7       | J1       | 31      | VSSA                            | S        | -             | -     | -   | -                           |
| -      | -       | 1        | K1       | -       | VREF-                           | S        | -             | 1     | -   | -                           |
| -      | 21      | Н8       | L1       | 32      | VREF+                           | S        | -             | -     | -   | -                           |
| 13     | 22      | -        | M1       | 33      | VDDA                            | S        | -             | 1     | -   | -                           |
| 14     | 23      | J9       | J2       | 34      | PA0-WKUP(PA0)                   | I/O      | FT            | 1     | TIM2_CH1/TIM2_ETR,<br>TIM5_CH1, TIM8_ETR,<br>USART2_CTS,<br>UART4_TX, EVENTOUT                  | ADC123_IN0,<br>WKUP0/TAMP_2 |
| 15     | 24      | G7       | K2       | 35      | PA1                             | I/O      | FT            | 1     | TIM2_CH2, TIM5_CH2,<br>USART2_RTS,<br>UART4_RX,<br>QUADSPI_BK1_IO3,<br>SAI2_MCLK_B,<br>EVENTOUT | ADC123_IN1                  |
| 16     | 25      | E7       | L2       | 36      | PA2                             | I/O      | FT            | -     | TIM2_CH3, TIM5_CH3,<br>TIM9_CH1, USART2_TX,<br>SAI2_SCK_B, EVENTOUT                             | ADC123_IN2                  |



Table 10. STM32F446xx pin and ball descriptions (continued)

|        | Piı     | n Nun    | nber     |         |                                 |          |               |       | escriptions (continued)   |                         |
|--------|---------|----------|----------|---------|---------------------------------|----------|---------------|-------|---|-------------------------|
| LQFP64 | LQFP100 | WLCSP 81 | UFBGA144 | LQFP144 | Pin name (function after reset) | Pin type | I/O structure | Notes | Alternate functions   | Additional<br>functions |
| 17     | 26      | E6       | M2       | 37      | PA3                             | I/O      | FT            | 1     | TIM2_CH4, TIM5_CH4,<br>TIM9_CH2, SAI1_FS_A,<br>USART2_RX,<br>OTG_HS_ULPI_D0,<br>EVENTOUT          | ADC123_IN3              |
| 18     | 27      | -        | G4       | 38      | VSS                             | S        | -             | -     | -   | -                       |
| -      | ı       | J8       | H5       | 1       | BYPASS_REG                      | I        | FT            | -     | -   | -                       |
| 19     | 28      | -        | F4       | 39      | VDD                             | S        | -             | -     | -   | -                       |
| 20     | 29      | H7       | J3       | 40      | PA4                             | I/O      | тс            | 1     | SPI1_NSS/I2S1_WS,<br>SPI3_NSS/I2S3_WS,<br>USART2_CK,<br>OTG_HS_SOF,<br>DCMI_HSYNC,<br>EVENTOUT    | ADC12_IN4,<br>DAC_OUT1  |
| 21     | 30      | F6       | K3       | 41      | PA5                             | I/O      | тс            | -     | TIM2_CH1/TIM2_ETR, TIM8_CH1N, SPI1_SCK/I2S1_CK, OTG_HS_ULPI_CK, EVENTOUT                          | ADC12_IN5,<br>DAC_OUT2  |
| 22     | 31      | G6       | L3       | 42      | PA6                             | I/O      | FT            | -     | TIM1_BKIN, TIM3_CH1,<br>TIM8_BKIN, SPI1_MISO,<br>I2S2_MCK, TIM13_CH1,<br>DCMI_PIXCLK,<br>EVENTOUT | ADC12_IN6               |
| 23     | 32      | E5       | М3       | 43      | PA7                             | I/O      | FT            | -     | TIM1_CH1N, TIM3_CH2,<br>TIM8_CH1N,<br>SPI1_MOSI/I2S1_SD,<br>TIM14_CH1,<br>FMC_SDNWE,<br>EVENTOUT  | ADC12_IN7               |
| 24     | 33      | J7       | J4       | 44      | PC4                             | I/O      | FT            | -     | I2S1_MCK, SPDIFRX_IN2,<br>FMC_SDNE0, EVENTOUT   | ADC12_IN14              |
| 25     | 34      | -        | K4       | 45      | PC5                             | I/O      | FT            | -     | USART3_RX,<br>SPDIFRX_IN3,<br>FMC_SDCKE0,<br>EVENTOUT   | ADC12_IN15              |

Table 10. STM32F446xx pin and ball descriptions (continued)

|        | Pin Number |          |          |         |                                 |          |               |       |  |                         |
|--------|------------|----------|----------|---------|---------------------------------|----------|---------------|-------|--|-------------------------|
| LQFP64 | LQFP100    | WLCSP 81 | UFBGA144 | LQFP144 | Pin name (function after reset) | Pin type | I/O structure | Notes | Alternate functions  | Additional<br>functions |
| 26     | 35         | F5       | L4       | 46      | PB0                             | I/O      | FT            | -     | TIM1_CH2N, TIM3_CH3,<br>TIM8_CH2N,<br>SPI3_MOSI/I2S3_SD,<br>UART4_CTS,<br>OTG_HS_ULPI_D1,<br>SDIO_D1, EVENTOUT | ADC12_IN8               |
| 27     | 36         | Н6       | M4       | 47      | PB1                             | I/O      | FT            | -     | TIM1_CH3N, TIM3_CH4,<br>TIM8_CH3N,<br>OTG_HS_ULPI_D2,<br>SDIO_D2, EVENTOUT                                     | ADC12_IN9               |
| 28     | 37         | J6       | J5       | 48      | PB2-BOOT1<br>(PB2)              | I/O      | FT            | 1     | TIM2_CH4, SAI1_SD_A,<br>SPI3_MOSI/I2S3_SD,<br>QUADSPI_CLK,<br>OTG_HS_ULPI_D4,<br>SDIO_CK, EVENTOUT             | -                       |
| -      | -          | 1        | M5       | 49      | PF11                            | I/O      | FT            | 1     | SAI2_SD_B,<br>FMC_SDNRAS,<br>DCMI_D12, EVENTOUT  | -                       |
| -      | ı          | -        | L5       | 50      | PF12                            | I/O      | FT            | -     | FMC_A6, EVENTOUT   | -                       |
| -      | ı          | -        | -        | 51      | VSS                             | S        | -             | -     | -  | -                       |
| -      | -          | -        | G5       | 52      | VDD                             | S        | -             | -     | -  | -                       |
| -      | -          | -        | K5       | 53      | PF13                            | I/O      | FT            | -     | FMPI2C1_SMBA,<br>FMC_A7, EVENTOUT  | -                       |
| -      | -          | -        | M6       | 54      | PF14                            | I/O      | FTf           | -     | FMPI2C1_SCL, FMC_A8,<br>EVENTOUT   | -                       |
| -      | -          | -        | L6       | 55      | PF15                            | I/O      | FTf           | -     | FMPI2C1_SDA, FMC_A9,<br>EVENTOUT   | -                       |
| -      | -          | -        | K6       | 56      | PG0                             | I/O      | FT            | -     | FMC_A10, EVENTOUT  | -                       |
| -      | -          | -        | J6       | 57      | PG1                             | I/O      | FT            | -     | FMC_A11, EVENTOUT  | -                       |
| -      | 38         | J5       | M7       | 58      | PE7                             | I/O      | FT            | -     | TIM1_ETR, UART5_RX,<br>QUADSPI_BK2_IO0,<br>FMC_D4, EVENTOUT  | -                       |
| -      | 39         | H5       | L7       | 59      | PE8                             | I/O      | FT            | 1     | TIM1_CH1N, UART5_TX,<br>QUADSPI_BK2_IO1,<br>FMC_D5, EVENTOUT   | -                       |
| -      | 40         | G5       | K7       | 60      | PE9                             | I/O      | FT            | -     | TIM1_CH1,<br>QUADSPI_BK2_IO2,<br>FMC_D6, EVENTOUT  | -                       |



Table 10. STM32F446xx pin and ball descriptions (continued)

|        | Pir     | n Nun    | nber     |         |                                 |          |               |       | escriptions (continued)  |                         |
|--------|---------|----------|----------|---------|---------------------------------|----------|---------------|-------|--|-------------------------|
| LQFP64 | LQFP100 | WLCSP 81 | UFBGA144 | LQFP144 | Pin name (function after reset) | Pin type | I/O structure | Notes | Alternate functions  | Additional<br>functions |
| -      | -       | -        | H6       | 61      | VSS                             | S        | -             | -     | -  | -                       |
| -      | -       | -        | G6       | 62      | VDD                             | S        | -             | -     | -  | -                       |
| -      | 41      | J4       | J7       | 63      | PE10                            | I/O      | FT            | 1     | TIM1_CH2N,<br>QUADSPI_BK2_IO3,<br>FMC_D7, EVENTOUT   | -                       |
| -      | 42      | ı        | Н8       | 64      | PE11                            | I/O      | FT            | 1     | TIM1_CH2, SPI4_NSS,<br>SAI2_SD_B, FMC_D8,<br>EVENTOUT  | -                       |
| -      | 43      | -        | J8       | 65      | PE12                            | I/O      | FT            | 1     | TIM1_CH3N, SPI4_SCK,<br>SAI2_SCK_B, FMC_D9,<br>EVENTOUT  | -                       |
| -      | 44      | -        | K8       | 66      | PE13                            | I/O      | FT            | 1     | TIM1_CH3, SPI4_MISO,<br>SAI2_FS_B, FMC_D10,<br>EVENTOUT  | -                       |
| -      | 45      | -        | L8       | 67      | PE14                            | I/O      | FT            | 1     | TIM1_CH4, SPI4_MOSI,<br>SAI2_MCLK_B, FMC_D11,<br>EVENTOUT  | -                       |
| -      | 46      | -        | M8       | 68      | PE15                            | I/O      | FT            | 1     | TIM1_BKIN, FMC_D12,<br>EVENTOUT  | -                       |
| 29     | 47      | H4       | M9       | 69      | PB10                            | I/O      | FT            | 1     | TIM2_CH3, I2C2_SCL, SPI2_SCK/I2S2_CK, SAI1_SCK_A, USART3_TX, OTG_HS_ULPI_D3, EVENTOUT                                      | -                       |
| -      | 1       | -        | M10      | 70      | PB11                            | I/O      | FT            | 1     | TIM2_CH4, I2C2_SDA,<br>USART3_RX, SAI2_SD_A,<br>EVENTOUT   | -                       |
| 30     | 48      | J3       | H7       | 71      | VCAP_1                          | S        | -             | -     | -  | -                       |
| 31     | 49      | НЗ       | -        | -       | VSS                             | S        | -             | 1     | -  | _                       |
| 32     | 50      | J2       | G7       | 72      | VDD                             | S        | -             | -     | -  | -                       |
| 33     | 51      | G4       | M11      | 73      | PB12                            | I/O      | FT            | -     | TIM1_BKIN, I2C2_SMBA,<br>SPI2_NSS/I2S2_WS,<br>SAI1_SCK_B,<br>USART3_CK, CAN2_RX,<br>OTG_HS_ULPI_D5,<br>OTG_HS_ID, EVENTOUT | -                       |

Table 10. STM32F446xx pin and ball descriptions (continued)

|        | Piı     | n Nun    | nber     |         |                                    |          |               |       |  |                         |
|--------|---------|----------|----------|---------|------------------------------------|----------|---------------|-------|--|-------------------------|
| LQFP64 | LQFP100 | WLCSP 81 | UFBGA144 | LQFP144 | Pin name (function<br>after reset) | Pin type | I/O structure | Notes | Alternate functions  | Additional<br>functions |
| 34     | 52      | H2       | M12      | 74      | PB13                               | I/O      | FT            | 1     | TIM1_CH1N,<br>SPI2_SCK/I2S2_CK,<br>USART3_CTS, CAN2_TX,<br>OTG_HS_ULPI_D6,<br>EVENTOUT         | OTG_HS_VBUS             |
| 35     | 53      | J1       | L11      | 75      | PB14 <sup>(1)</sup>                | I/O      | FT            | ı     | TIM1_CH2N, TIM8_CH2N,<br>SPI2_MISO,<br>USART3_RTS,<br>TIM12_CH1,<br>OTG_HS_DM, EVENTOUT        | -                       |
| 36     | 54      | G3       | L12      | 76      | PB15 <sup>(1)</sup>                | I/O      | FT            | 1     | RTC_REFIN, TIM1_CH3N,<br>TIM8_CH3N,<br>SPI2_MOSI/I2S2_SD,<br>TIM12_CH2, OTG_HS_DP,<br>EVENTOUT | -                       |
| -      | 55      | -        | L9       | 77      | PD8                                | I/O      | FT            | 1     | USART3_TX,<br>SPDIFRX_IN1, FMC_D13,<br>EVENTOUT  | -                       |
| -      | 56      | -        | K9       | 78      | PD9                                | I/O      | FT            | 1     | USART3_RX, FMC_D14,<br>EVENTOUT  | -                       |
| -      | 57      | -        | J9       | 79      | PD10                               | I/O      | FT            | 1     | USART3_CK, FMC_D15,<br>EVENTOUT  | -                       |
| -      | 58      | H1       | H9       | 80      | PD11                               | I/O      | FT            | 1     | FMPI2C1_SMBA, USART3_CTS, QUADSPI_BK1_IO0, SAI2_SD_A, FMC_A16, EVENTOUT                        | -                       |
| -      | 59      | G2       | L10      | 81      | PD12                               | I/O      | FTf           | 1     | TIM4_CH1, FMPI2C1_SCL, USART3_RTS, QUADSPI_BK1_IO1, SAI2_FS_A, FMC_A17, EVENTOUT               | -                       |
| -      | 60      | G1       | K10      | 82      | PD13                               | I/O      | FTf           | -     | TIM4_CH2,<br>FMPI2C1_SDA,<br>QUADSPI_BK1_IO3,<br>SAI2_SCK_A, FMC_A18,<br>EVENTOUT              | -                       |
| _      | ı       | -        | G8       | 83      | VSS                                | S        | -             | 1     | -  | -                       |
| -      | -       | -        | F8       | 84      | VDD                                | S        | -             | -     | -  | -                       |



Table 10. STM32F446xx pin and ball descriptions (continued)

|        | Piı     | n Nun    |          |         |                                    |          |               |       | escriptions (continued)   |                         |
|--------|---------|----------|----------|---------|------------------------------------|----------|---------------|-------|---|-------------------------|
| LQFP64 | LQFP100 | WLCSP 81 | UFBGA144 | LQFP144 | Pin name (function<br>after reset) | Pin type | I/O structure | Notes | Alternate functions   | Additional<br>functions |
| -      | 61      | -        | K11      | 85      | PD14                               | I/O      | FTf           | -     | TIM4_CH3,<br>FMPI2C1_SCL,<br>SAI2_SCK_A, FMC_D0,<br>EVENTOUT  | -                       |
| -      | 62      | ı        | K12      | 86      | PD15                               | I/O      | FTf           | ı     | TIM4_CH4,<br>FMPI2C1_SDA, FMC_D1,<br>EVENTOUT   | -                       |
| -      | -       | -        | J12      | 87      | PG2                                | I/O      | FT            | ı     | FMC_A12, EVENTOUT   | -                       |
| -      | -       | -        | J11      | 88      | PG3                                | I/O      | FT            | -     | FMC_A13, EVENTOUT   | -                       |
| -      | ı       | 1        | J10      | 89      | PG4                                | I/O      | FT            | ı     | FMC_A14/FMC_BA0,<br>EVENTOUT  | -                       |
| -      | ı       | -        | H12      | 90      | PG5                                | I/O      | FT            | 1     | FMC_A15/FMC_BA1,<br>EVENTOUT  | -                       |
| -      | -       | -        | H11      | 91      | PG6                                | I/O      | FT            | -     | QUADSPI_BK1_NCS,<br>DCMI_D12, EVENTOUT  | -                       |
| -      | -       | -        | H10      | 92      | PG7                                | I/O      | FT            | -     | USART6_CK, FMC_INT,<br>DCMI_D13, EVENTOUT   | -                       |
| -      | ı       | ı        | G11      | 93      | PG8                                | I/O      | FT            | ı     | SPDIFRX_IN2,<br>USART6_RTS,<br>FMC_SDCLK, EVENTOUT  | -                       |
| -      | ı       | ı        | -        | 94      | VSS                                | S        | -             | 1     | -   | -                       |
| -      | -       | -        | F10      | -       | VDD                                | S        | -             | -     | -   | -                       |
| -      | -       | E1       | C11      | 95      | VDDUSB                             | S        | -             | -     | -   | -                       |
| 37     | 63      | F1       | G12      | 96      | PC6                                | I/O      | FTf           | -     | TIM3_CH1, TIM8_CH1,<br>FMPI2C1_SCL,<br>I2S2_MCK, USART6_TX,<br>SDIO_D6, DCMI_D0,<br>EVENTOUT                    | -                       |
| 38     | 64      | F2       | F12      | 97      | PC7                                | I/O      | FTf           | -     | TIM3_CH2, TIM8_CH2, FMPI2C1_SDA, SPI2_SCK/I2S2_CK, I2S3_MCK, SPDIFRX_IN1, USART6_RX, SDIO_D7, DCMI_D1, EVENTOUT | -                       |
| 39     | 65      | F3       | F11      | 98      | PC8                                | I/O      | FT            | -     | TRACED0, TIM3_CH3,<br>TIM8_CH3, UART5_RTS,<br>USART6_CK, SDIO_D0,<br>DCMI_D2, EVENTOUT                          | -                       |

Table 10. STM32F446xx pin and ball descriptions (continued)

|        | Piı     | n Nun    |          |         |                                    |          |               |       | escriptions (continued)   |                         |
|--------|---------|----------|----------|---------|------------------------------------|----------|---------------|-------|---|-------------------------|
| LQFP64 | LQFP100 | WLCSP 81 | UFBGA144 | LQFP144 | Pin name (function<br>after reset) | Pin type | I/O structure | Notes | Alternate functions   | Additional<br>functions |
| 40     | 66      | D1       | E11      | 99      | PC9                                | I/O      | FT            | ı     | MCO2, TIM3_CH4,<br>TIM8_CH4, I2C3_SDA,<br>I2S_CKIN, UART5_CTS,<br>QUADSPI_BK1_IO0,<br>SDIO_D1, DCMI_D3,<br>EVENTOUT | -                       |
| 41     | 67      | E2       | E12      | 100     | PA8                                | I/O      | FT            | 1     | MCO1, TIM1_CH1,<br>I2C3_SCL, USART1_CK,<br>OTG_FS_SOF,<br>EVENTOUT  | -                       |
| 42     | 68      | F4       | D12      | 101     | PA9                                | I/O      | FT            | 1     | TIM1_CH2, I2C3_SMBA,<br>SPI2_SCK/I2S2_CK,<br>SAI1_SD_B, USART1_TX,<br>DCMI_D0, EVENTOUT                             | OTG_FS_VBUS             |
| 43     | 69      | E3       | D11      | 102     | PA10                               | I/O      | FT            | 1     | TIM1_CH3, USART1_RX,<br>OTG_FS_ID, DCMI_D1,<br>EVENTOUT   | -                       |
| 44     | 70      | C1       | C12      | 103     | PA11 <sup>(1)</sup>                | I/O      | FT            | 1     | TIM1_CH4, USART1_CTS,<br>CAN1_RX, OTG_FS_DM,<br>EVENTOUT  | -                       |
| 45     | 71      | E4       | B12      | 104     | PA12 <sup>(1)</sup>                | I/O      | FT            | 1     | TIM1_ETR, USART1_RTS,<br>SAI2_FS_B, CAN1_TX,<br>OTG_FS_DP, EVENTOUT   | -                       |
| 46     | 72      | D2       | A12      | 105     | PA13(JTMS-SWDIO)                   | I/O      | FT            | ı     | JTMS-SWDIO,<br>EVENTOUT   | -                       |
| -      | 73      | C2       | G9       | 106     | VCAP_2                             | S        | -             | 1     | -   | -                       |
| 47     | 74      | B1       | G10      | 107     | VSS                                | S        | -             | -     | -   | -                       |
| 48     | 75      | A1       | F9       | 108     | VDD                                | S        | -             | -     | -   | -                       |
| 49     | 76      | C3       | A11      | 109     | PA14(JTCK-SWCLK)                   | I/O      | FT            | -     | JTCK-SWCLK,<br>EVENTOUT   | -                       |
| 50     | 77      | B2       | A10      | 110     | PA15(JTDI)                         | I/O      | FT            | -     | JTDI, TIM2_CH1/TIM2_ETR, HDMI_CEC, SPI1_NSS/I2S1_WS, SPI3_NSS/I2S3_WS, UART4_RTS, EVENTOUT                          | -                       |



Table 10. STM32F446xx pin and ball descriptions (continued)

|        | Pir     | n Nun    |          |         | ·                                  |          |               |       | escriptions (continueu)  |                         |
|--------|---------|----------|----------|---------|------------------------------------|----------|---------------|-------|--|-------------------------|
| LQFP64 | LQFP100 | WLCSP 81 | UFBGA144 | LQFP144 | Pin name (function<br>after reset) | Pin type | I/O structure | Notes | Alternate functions  | Additional<br>functions |
| 51     | 78      | D3       | B11      | 111     | PC10                               | I/O      | FT            | 1     | SPI3_SCK/I2S3_CK,<br>USART3_TX, UART4_TX,<br>QUADSPI_BK1_IO1,<br>SDIO_D2, DCMI_D8,<br>EVENTOUT | -                       |
| 52     | 79      | D4       | B10      | 112     | PC11                               | I/O      | FT            | 1     | SPI3_MISO, USART3_RX,<br>UART4_RX,<br>QUADSPI_BK2_NCS,<br>SDIO_D3, DCMI_D4,<br>EVENTOUT        | -                       |
| 53     | 80      | A2       | C10      | 113     | PC12                               | I/O      | FT            | ı     | I2C2_SDA, SPI3_MOSI/I2S3_SD, USART3_CK, UART5_TX, SDIO_CK, DCMI_D9, EVENTOUT                   | -                       |
| -      | 81      | В3       | E10      | 114     | PD0                                | I/O      | FT            | 1     | SPI4_MISO,<br>SPI3_MOSI/I2S3_SD,<br>CAN1_RX, FMC_D2,<br>EVENTOUT                               | -                       |
| -      | 82      | C4       | D10      | 115     | PD1                                | I/O      | FT            | 1     | SPI2_NSS/I2S2_WS,<br>CAN1_TX, FMC_D3,<br>EVENTOUT  | -                       |
| 54     | 83      | D5       | E9       | 116     | PD2                                | I/O      | FT            | ı     | TIM3_ETR, UART5_RX,<br>SDIO_CMD, DCMI_D11,<br>EVENTOUT   | -                       |
| -      | 84      | -        | D9       | 117     | PD3                                | I/O      | FT            | -     | TRACED1, SPI2_SCK/I2S2_CK, USART2_CTS, QUADSPI_CLK, FMC_CLK, DCMI_D5, EVENTOUT                 | -                       |
| -      | 85      | A3       | С9       | 118     | PD4                                | I/O      | FT            | -     | USART2_RTS, FMC_NOE,<br>EVENTOUT   | -                       |
| -      | 86      | -        | В9       | 119     | PD5                                | I/O      | FT            | -     | USART2_TX, FMC_NWE,<br>EVENTOUT  | -                       |
| -      | -       | -        | E7       | 120     | VSS                                | S        | -             | -     | -  | -                       |
| -      | -       | -        | F7       | 121     | VDD                                | S        | -             | -     | -  | -                       |

Table 10. STM32F446xx pin and ball descriptions (continued)

|        | Piı     | n Nun    | nber     |         |                                    |          |               |       |   |                         |
|--------|---------|----------|----------|---------|------------------------------------|----------|---------------|-------|---|-------------------------|
| LQFP64 | LQFP100 | WLCSP 81 | UFBGA144 | LQFP144 | Pin name (function<br>after reset) | Pin type | I/O structure | Notes | Alternate functions   | Additional<br>functions |
| -      | 87      | B4       | A8       | 122     | PD6                                | I/O      | FT            | -     | SPI3_MOSI/I2S3_SD,<br>SAI1_SD_A, USART2_RX,<br>FMC_NWAIT, DCMI_D10,<br>EVENTOUT             | -                       |
| -      | 88      | A4       | A9       | 123     | PD7                                | I/O      | FT            | 1     | USART2_CK,<br>SPDIFRX_IN0, FMC_NE1,<br>EVENTOUT   | -                       |
| -      | -       | -        | E8       | 124     | PG9                                | I/O      | FT            | -     | SPDIFRX_IN3, USART6_RX, QUADSPI_BK2_IO2, SAI2_FS_B, FMC_NE2/FMC_NCE3, DCMI_VSYNC, EVENTOUT  | -                       |
| -      | -       | -        | D8       | 125     | PG10                               | I/O      | FT            | -     | SAI2_SD_B, FMC_NE3,<br>DCMI_D2, EVENTOUT  | -                       |
| -      | -       | -        | C8       | 126     | PG11                               | I/O      | FT            | -     | SPI4_SCK, SPDIFRX_IN0,<br>DCMI_D3, EVENTOUT   | -                       |
| -      | -       | -        | B8       | 127     | PG12                               | I/O      | FT            | -     | SPI4_MISO,<br>SPDIFRX_IN1,<br>USART6_RTS, FMC_NE4,<br>EVENTOUT                              | -                       |
| -      | -       | -        | D7       | 128     | PG13                               | I/O      | FT            | -     | TRACED2, SPI4_MOSI,<br>USART6_CTS, FMC_A24,<br>EVENTOUT                                     | -                       |
| -      | -       | -        | C7       | 129     | PG14                               | I/O      | FT            | -     | TRACED3, SPI4_NSS,<br>USART6_TX,<br>QUADSPI_BK2_IO3,<br>FMC_A25, EVENTOUT                   | -                       |
| -      | -       | -        | -        | 130     | VSS                                | S        | -             | -     | -   | -                       |
| -      | -       | -        | F6       | 131     | VDD                                | S        | -             | -     | -   | -                       |
| -      | -       | -        | В7       | 132     | PG15                               | I/O      | FT            | -     | USART6_CTS,<br>FMC_SDNCAS,<br>DCMI_D13, EVENTOUT  | -                       |
| 55     | 89      | A5       | A7       | 133     | PB3(JTDO/TRACES<br>WO)             | I/O      | FT            | -     | JTDO/TRACESWO,<br>TIM2_CH2, I2C2_SDA,<br>SPI1_SCK/I2S1_CK,<br>SPI3_SCK/I2S3_CK,<br>EVENTOUT | -                       |



Table 10. STM32F446xx pin and ball descriptions (continued)

|        | Pir     | n Nun    | nber     |         |                                 |          |               |       |  |                         |
|--------|---------|----------|----------|---------|---------------------------------|----------|---------------|-------|--|-------------------------|
| LQFP64 | LQFP100 | WLCSP 81 | UFBGA144 | LQFP144 | Pin name (function after reset) | Pin type | I/O structure | Notes | Alternate functions  | Additional<br>functions |
| 56     | 90      | B5       | A6       | 134     | PB4(NJTRST)                     | I/O      | FT            | 1     | NJTRST, TIM3_CH1,<br>I2C3_SDA, SPI1_MISO,<br>SPI3_MISO,<br>SPI2_NSS/I2S2_WS,<br>EVENTOUT   | -                       |
| 57     | 91      | A6       | В6       | 135     | PB5                             | I/O      | FT            | ı     | TIM3_CH2, I2C1_SMBA,<br>SPI1_MOSI/I2S1_SD,<br>SPI3_MOSI/I2S3_SD,<br>CAN2_RX,<br>OTG_HS_ULPI_D7,<br>FMC_SDCKE1,<br>DCMI_D10, EVENTOUT | -                       |
| 58     | 92      | C5       | C6       | 136     | PB6                             | I/O      | FT            | 1     | TIM4_CH1, HDMI_CEC,<br>I2C1_SCL, USART1_TX,<br>CAN2_TX,<br>QUADSPI_BK1_NCS,<br>FMC_SDNE1, DCMI_D5,<br>EVENTOUT                       | -                       |
| 59     | 93      | В6       | D6       | 137     | PB7                             | I/O      | FT            | 1     | TIM4_CH2, I2C1_SDA, USART1_RX, SPDIFRX_IN0, FMC_NL, DCMI_VSYNC, EVENTOUT   | -                       |
| 60     | 94      | A7       | D5       | 138     | BOOT0                           | I        | В             | -     | -  | VPP                     |
| 61     | 95      | C6       | C5       | 139     | PB8                             | I/O      | FT            | 1     | TIM2_CH1/TIM2_ETR,<br>TIM4_CH3, TIM10_CH1,<br>I2C1_SCL, CAN1_RX,<br>SDIO_D4, DCMI_D6,<br>EVENTOUT                                    | -                       |
| 62     | 96      | C7       | B5       | 140     | PB9                             | I/O      | FT            | 1     | TIM2_CH2, TIM4_CH4,<br>TIM11_CH1, I2C1_SDA,<br>SPI2_NSS/I2S2_WS,<br>SAI1_FS_B, CAN1_TX,<br>SDIO_D5, DCMI_D7,<br>EVENTOUT             | -                       |
| -      | 97      | -        | A5       | 141     | PE0                             | I/O      | FT            | -     | TIM4_ETR,<br>SAI2_MCLK_A,<br>FMC_NBL0, DCMI_D2,<br>EVENTOUT  | -                       |
| -      | 98      | -        | A4       | 142     | PE1                             | I/O      | FT            | -     | FMC_NBL1, DCMI_D3,<br>EVENTOUT   | -                       |

Table 10. STM32F446xx pin and ball descriptions (continued)

|        | Piı     | n Nun    | nber     |         |                                    |          |               |       |                     |                         |
|--------|---------|----------|----------|---------|------------------------------------|----------|---------------|-------|---------------------|-------------------------|
| LQFP64 | LQFP100 | WLCSP 81 | UFBGA144 | LQFP144 | Pin name (function<br>after reset) | Pin type | I/O structure | Notes | Alternate functions | Additional<br>functions |
| 63     | 99      | В7       | E6       | -       | VSS                                | S        | -             | -     | -                   | -                       |
| -      | -       | B8       | E5       | 143     | PDR_ON                             | S        | -             | -     | -                   | -                       |
| 64     | 100     | A8       | F5       | 144     | VDD                                | S        | -             | -     | -                   | -                       |

<sup>1.</sup> PA11, PA12, PB14 and PB15 I/Os are supplied by VDDUSB





### Table 11. Alternate function

|        |      |                |                       |          |                          |                    |                           |                          | liternate                                       |  |                                       |  |         |                          |                 |      |              |
|--------|------|----------------|-----------------------|----------|--------------------------|--------------------|---------------------------|--------------------------|---|--|---------------------------------------|--|---------|--------------------------|-----------------|------|--------------|
|        |      | AF0            | AF1                   | AF2      | AF3                      | AF4                | AF5                       | AF6                      | AF7   | AF8                                    | AF9                                   | AF10                                     | AF11    | AF12                     | AF13            | AF14 | AF15         |
| Po     | ort  | sys            | TIM1/2                | TIM3/4/5 | TIM8/9/<br>10/11/<br>CEC | I2C1/2/3<br>/4/CEC | SPI1/2/3/<br>4            | SPI2/3/4/<br>SAI1        | SPI2/3/<br>USART1/<br>2/3/UART<br>5/SPDIFR<br>X | SAI/<br>USART6/<br>UART4/5/<br>SPDIFRX | CAN1/2<br>TIM12/13/<br>14/<br>QUADSPI | SAI2/<br>QUADSPI/<br>OTG2_HS/<br>OTG1_FS | OTG1_FS | FMC/<br>SDIO/<br>OTG2_FS | DCMI            | -    | sys          |
|        | PA0  | -              | TIM2_CH1/<br>TIM2_ETR | TIM5_CH1 | TIM8_ETR                 | -                  | -                         | -                        | USART2_<br>CTS                                  | UART4_<br>TX                           | -                                     | -  | -       | -                        | -               | -    | EVENT<br>OUT |
|        | PA1  | -              | TIM2_CH2              | TIM5_CH2 | -                        | -                  | -                         | -                        | USART2_<br>RTS                                  | UART4_<br>RX                           | QUADSPI_<br>BK1_IO3                   | SAI2_<br>MCLK_B                          | -       | -                        | -               | -    | EVENT<br>OUT |
|        | PA2  | -              | TIM2_CH3              | TIM5_CH3 | TIM9_CH1                 | -                  | -                         | -                        | USART2_<br>TX                                   | SAI2_<br>SCK_B                         | -                                     | -  | -       | -                        | -               | -    | EVENT<br>OUT |
|        | PA3  | -              | TIM2_CH4              | TIM5_CH4 | TIM9_CH2                 | -                  | -                         | SAI1_<br>FS_A            | USART2_<br>RX                                   | -                                      | -                                     | OTG_HS_<br>ULPI_D0                       | -       | -                        | -               | -    | EVENT<br>OUT |
|        | PA4  | -              | -                     | -        | -                        | -                  | SPI1_NSS/I<br>2S1_WS      | SPI3_NSS<br>/<br>I2S3_WS | USART2_<br>CK                                   | -                                      | -                                     | -  | -       | OTG_HS_<br>SOF           | DCMI_<br>HSYNC  | -    | EVENT<br>OUT |
|        | PA5  | -              | TIM2_CH1/<br>TIM2_ETR | -        | TIM8_<br>CH1N            | -                  | SPI1_SCK/I<br>2S1_CK      | -                        | -   | -                                      | -                                     | OTG_HS_<br>ULPI_CK                       | -       | -                        | -               | -    | EVENT<br>OUT |
|        | PA6  | -              | TIM1_<br>BKIN         | TIM3_CH1 | TIM8_<br>BKIN            | -                  | SPI1_MISO                 | 12S2_<br>MCK             | -   | -                                      | TIM13_CH1                             | -  | -       | -                        | DCMI_<br>PIXCLK | -    | EVENT<br>OUT |
| Port A | PA7  | -              | TIM1_<br>CH1N         | TIM3_CH2 | TIM8_<br>CH1N            | -                  | SPI1_MOSI<br>/<br>I2S1_SD | -                        | -   | -                                      | TIM14_CH1                             | -  | -       | FMC_<br>SDNWE            | -               | -    | EVENT<br>OUT |
|        | PA8  | MCO1           | TIM1_CH1              | -        | -                        | I2C3_<br>SCL       | -                         | -                        | USART1_<br>CK                                   | -                                      | -                                     | OTG_FS_<br>SOF                           | -       | -                        | -               | -    | EVENT<br>OUT |
|        | PA9  | -              | TIM1_CH2              | -        | -                        | I2C3_<br>SMBA      | SPI2_SCK<br>/I2S2_CK      | SAI1_<br>SD_B            | USART1_<br>TX                                   | -                                      | -                                     | -  | -       | -                        | DCMI_D0         | -    | EVENT<br>OUT |
|        | PA10 | -              | TIM1_CH3              | -        | -                        | -                  | -                         | -                        | USART1_<br>RX                                   | -                                      | -                                     | OTG_FS_<br>ID                            | -       | -                        | DCMI_D1         | -    | EVENT<br>OUT |
|        | PA11 | -              | TIM1_CH4              | -        | -                        | -                  | -                         | -                        | USART1_<br>CTS                                  | -                                      | CAN1_RX                               | OTG_FS_<br>DM                            | -       | -                        | -               | -    | EVENT<br>OUT |
|        | PA12 | -              | TIM1_ETR              | -        | -                        | -                  | -                         | -                        | USART1_<br>RTS                                  | SAI2_<br>FS_B                          | CAN1_TX                               | OTG_FS_<br>DP                            | -       | -                        | -               | -    | EVENT<br>OUT |
|        | PA13 | JTMS-<br>SWDIO | -                     | -        | -                        | -                  | -                         | -                        | -   | -                                      | -                                     | ı  | -       | -                        | -               | -    | EVENT<br>OUT |
|        | PA14 | JTCK-<br>SWCLK | -                     | -        | -                        | -                  | -                         | -                        | -   | -                                      | -                                     | -  | -       | -                        | -               | -    | EVENT<br>OUT |
|        | PA15 | JTDI           | TIM2_CH1/<br>TIM2_ETR | -        | -                        | HDMI_<br>CEC       | SPI1_NSS/<br>I2S1_WS      | SPI3_<br>NSS/<br>I2S3_WS | -   | UART4_RT<br>S                          | -                                     | -  | -       | -                        | -               | -    | EVENT<br>OUT |

59/198

|        |      |                       |                       |          |                          |                    | Table 11.             |                           |   | <u> </u>                               | <u> </u>                              |  |         |                          |                |      | <del></del>  |
|--------|------|-----------------------|-----------------------|----------|--------------------------|--------------------|-----------------------|---------------------------|---|--|---------------------------------------|--|---------|--------------------------|----------------|------|--------------|
|        |      | AF0                   | AF1                   | AF2      | AF3                      | AF4                | AF5                   | AF6                       | AF7   | AF8                                    | AF9                                   | AF10                                     | AF11    | AF12                     | AF13           | AF14 | AF15         |
| Po     | ort  | sys                   | TIM1/2                | TIM3/4/5 | TIM8/9/<br>10/11/<br>CEC | I2C1/2/3<br>/4/CEC | SPI1/2/3/<br>4        | SPI2/3/4/<br>SAI1         | SPI2/3/<br>USART1/<br>2/3/UART<br>5/SPDIFR<br>X | SAI/<br>USART6/<br>UART4/5/<br>SPDIFRX | CAN1/2<br>TIM12/13/<br>14/<br>QUADSPI | SAI2/<br>QUADSPI/<br>OTG2_HS/<br>OTG1_FS | OTG1_FS | FMC/<br>SDIO/<br>OTG2_FS | DCMI           | -    | SYS          |
|        | PB0  | -                     | TIM1_CH2N             | TIM3_CH3 | TIM8_<br>CH2N            | -                  | -                     | -                         | SPI3_MOS<br>I/<br>I2S3_SD                       | UART4_<br>CTS                          | -                                     | OTG_HS_<br>ULPI_D1                       | -       | SDIO_D1                  | -              | -    | EVENT<br>OUT |
|        | PB1  | -                     | TIM1_CH3N             | TIM3_CH4 | TIM8_<br>CH3N            | -                  | -                     | -                         | -   | -                                      | -                                     | OTG_HS_<br>ULPI_D2                       | -       | SDIO_D2                  | -              | -    | EVENT<br>OUT |
|        | PB2  | -                     | TIM2_CH4              | -        | -                        | -                  | -                     | SAI1_<br>SD_A             | SPI3_MOS<br>I/<br>I2S3_SD                       | -                                      | QUADSPI_<br>CLK                       | OTG_HS_<br>ULPI_D4                       | -       | SDIO_CK                  | -              | -    | EVENT<br>OUT |
|        | PB3  | JTDO/<br>TRACES<br>WO | TIM2_CH2              | -        | -                        | I2C2_<br>SDA       | SPI1_SCK<br>/I2S1_CK  | SPI3_SCK<br>/<br>I2S3_CK  | -   | -                                      | -                                     | -  | -       | -                        | -              | -    | EVENT<br>OUT |
|        | PB4  | NJTRST                | -                     | TIM3_CH1 | -                        | I2C3_<br>SDA       | SPI1_MISO             | SPI3_<br>MISO             | SPI2_NSS/<br>I2S2_WS                            | -                                      | -                                     | -  | -       | -                        | -              | -    | EVENT<br>OUT |
|        | PB5  | -                     | -                     | TIM3_CH2 | -                        | I2C1_<br>SMBA      | SPI1_MOSI<br>/I2S1_SD | SPI3_<br>MOSI/<br>I2S3_SD | -   | -                                      | CAN2_RX                               | OTG_HS_<br>ULPI_D7                       | -       | FMC_<br>SDCKE1           | DCMI_<br>D10   | -    | EVENT<br>OUT |
|        | PB6  | -                     | -                     | TIM4_CH1 | HDMI_<br>CEC             | I2C1_<br>SCL       | -                     | -                         | USART1_<br>TX                                   | -                                      | CAN2_TX                               | Q <mark>UADSPI_</mark><br>BK1_NC\$       | -       | FMC_<br>SDNE1            | DCMI_D5        | -    | EVENT<br>OUT |
| Port B | PB7  | -                     | -                     | TIM4_CH2 | -                        | I2C1_<br>SDA       | -                     | -                         | USART1_<br>RX                                   | SPDIF_<br>RX0                          | -                                     | -  | -       | FMC_NL                   | DCMI_<br>VSYNC | -    | EVENT<br>OUT |
|        | PB8  | -                     | TIM2_CH1/<br>TIM2_ETR | TIM4_CH3 | TIM10_<br>CH1            | I2C1_<br>SCL       | -                     | -                         | -   | -                                      | CAN1_RX                               | -  | -       | SDIO_D4                  | DCMI_D6        | -    | EVENT<br>OUT |
|        | PB9  | -                     | TIM2_<br>CH2          | TIM4_CH4 | TIM11_<br>CH1            | I2C1_<br>SDA       | SPI2_NSS/<br>I2S2_WS  | SAI1_<br>FS_B             | -   | -                                      | CAN1_TX                               | -  | -       | SDIO_D5                  | DCMI_D7        | -    | EVENT<br>OUT |
|        | PB10 | -                     | TIM2_CH3              | -        | -                        | I2C2_<br>SCL       | SPI2_SCK/<br>I2S2_CK  | SAI1_<br>SCK_A            | USART3_<br>TX                                   | -                                      | -                                     | OTG_HS_<br>ULPI_D3                       | -       | -                        | -              | -    | EVENT<br>OUT |
|        | PB11 | -                     | TIM2_CH4              | -        | -                        | I2C2_<br>SDA       | -                     | -                         | USART3_<br>RX                                   | SAI2_<br>SD_A                          | -                                     | -  | -       | -                        | -              | -    | EVENT<br>OUT |
|        | PB12 | -                     | TIM1_BKIN             | -        | -                        | I2C2_<br>SMBA      | SPI2_NSS/<br>I2S2_WS  | SAI1_<br>SCK_B            | USART3_<br>CK                                   | -                                      | CAN2_RX                               | OTG_HS_<br>ULPI_D5                       | -       | OTG_<br>HS_ID            | -              | -    | EVENT<br>OUT |
|        | PB13 | -                     | TIM1_CH1N             | -        | -                        | -                  | SPI2_SCK/<br>I2S2_CK  | -                         | USART3_<br>CTS                                  | -                                      | CAN2_TX                               | OTG_HS_<br>ULPI_D6                       | -       | -                        | -              | -    | EVENT<br>OUT |
|        | PB14 | -                     | TIM1_CH2N             | -        | TIM8_<br>CH2N            | -                  | SPI2_MISO             | -                         | USART3_<br>RTS                                  | -                                      | TIM12_CH1                             | -  | -       | OTG_<br>HS_DM            | -              | -    | EVENT<br>OUT |
|        | PB15 | RTC_<br>REFIN         | TIM1_CH3N             | -        | TIM8_<br>CH3N            | -                  | SPI2_MOSI<br>/I2S2_SD | -                         | -   | -                                      | TIM12_CH2                             | -  | -       | OTG_<br>HS_DP            | -              | -    | EVENT<br>OUT |





## Table 11. Alternate function (continued)

|        |      | AF0         | AF1    | AF2      | AF3                      | AF4                | AF5                       | AF6                       | AF7   | AF8                                    | AF9                                   | AF10                                     | AF11    | AF12                     | AF13    | AF14 | AF15         |
|--------|------|-------------|--------|----------|--------------------------|--------------------|---------------------------|---------------------------|---|--|---------------------------------------|--|---------|--------------------------|---------|------|--------------|
| Po     | ort  | sys         | TIM1/2 | TIM3/4/5 | TIM8/9/<br>10/11/<br>CEC | I2C1/2/3<br>/4/CEC | SPI1/2/3/<br>4            | SPI2/3/4/<br>SAI1         | SPI2/3/<br>USART1/<br>2/3/UART<br>5/SPDIFR<br>X | SAI/<br>USART6/<br>UART4/5/<br>SPDIFRX | CAN1/2<br>TIM12/13/<br>14/<br>QUADSPI | SAI2/<br>QUADSPI/<br>OTG2_HS/<br>OTG1_FS | OTG1_FS | FMC/<br>SDIO/<br>OTG2_FS | DCMI    | -    | sys          |
|        | PC0  | -           | -      | -        | -                        | -                  | -                         | SAI1_<br>MCLK_B           | -   | -                                      | -                                     | OTG_HS_<br>ULPI_STP                      | ī       | FMC_<br>SDNWE            | -       | -    | EVENT<br>OUT |
|        | PC1  | -           | -      | -        | -                        | -                  | SPI3_MOSI<br>/I2S3_SD     | SAI1_<br>SD_A             | SPI2_MOS<br>I<br>/I2S2_SD                       | -                                      | -                                     | -  | -       | -                        | -       | -    | EVENT<br>OUT |
|        | PC2  | -           | -      | -        | -                        | -                  | SPI2_MISO                 | -                         | -   | -                                      | -                                     | OTG_HS_<br>ULPI_DIR                      | 1       | FMC_<br>SDNE0            | -       | -    | EVENT<br>OUT |
|        | PC3  | -           | -      | -        | -                        | -                  | SPI2_MOSI<br>/<br>I2S2_SD | -                         | -   | -                                      | -                                     | OTG_HS_<br>ULPI_NXT                      | -       | FMC_<br>SDCKE0           | -       | -    | EVENT<br>OUT |
|        | PC4  | -           | -      | -        | -                        | -                  | I2S1_MCK                  | -                         | -   | SPDIF_<br>RX2                          | -                                     | -  | -       | FMC_<br>SDNE0            | -       | -    | EVENT<br>OUT |
|        | PC5  | -           | -      | -        | -                        | -                  | -                         | -                         | USART3_<br>RX                                   | SPDIF_<br>RX3                          | -                                     | -  | -       | FMC_<br>SDCKE0           | -       | -    | EVENT<br>OUT |
|        | PC6  | -           | -      | TIM3_CH1 | TIM8_CH1                 | FMPI2C1<br>_SCL    | I2S2_MCK                  | -                         | -   | USART6_T<br>X                          | -                                     | -  | -       | SDIO_D6                  | DCMI_D0 | -    | EVENT<br>OUT |
| Port C | PC7  | -           | -      | TIM3_CH2 | TIM8_CH2                 | FMPI2C1<br>_SDA    | SPI2_SCK/<br>I2S2_CK      | I2S3_MCK                  | SPDIF_<br>RX1                                   | USART6_R<br>X                          | -                                     | -  | -       | SDIO_D7                  | DCMI_D1 | -    | EVENT<br>OUT |
|        | PC8  | TRACE<br>D0 | -      | TIM3_CH3 | TIM8_CH3                 | -                  | -                         | -                         | UART5_<br>RTS                                   | USART6_C<br>K                          | -                                     | -  | -       | SDIO_D0                  | DCMI_D2 | -    | EVENT<br>OUT |
|        | PC9  | MCO2        | -      | TIM3_CH4 | TIM8_CH4                 | I2C3_<br>SDA       | I2S_CKIN                  | -                         | UART5_<br>CTS                                   | -                                      | QUADSPI_<br>BK1_IO0                   | -  | -       | SDIO_D1                  | DCMI_D3 | -    | EVENT<br>OUT |
|        | PC10 | -           | -      | -        | -                        | -                  | -                         | SPI3_SCK<br>/<br>I2S3_CK  | USART3_<br>TX                                   | UART4_TX                               | QUADSPI_<br>BK1_IO1                   | -  | -       | SDIO_D2                  | DCMI_D8 | -    | EVENT<br>OUT |
|        | PC11 | -           | -      | -        | -                        | -                  | -                         | SPI3_<br>MISO             | USART3_<br>RX                                   | UART4_RX                               | QUADSPI_<br>BK2_NCS                   | -  | -       | SDIO_D3                  | DCMI_D4 | -    | EVENT<br>OUT |
|        | PC12 | -           | -      | -        | -                        | I2C2_<br>SDA       | -                         | SPI3_<br>MOSI/<br>I2S3_SD | USART3_<br>CK                                   | UART5_TX                               | -                                     | -  | -       | SDIO_CK                  | DCMI_D9 | -    | EVENT<br>OUT |
|        | PC13 | -           | -      | -        | -                        | -                  | -                         | -                         | -   | -                                      | -                                     | -  | -       | -                        | -       | -    | EVENT<br>OUT |
|        | PC14 | -           | -      | -        | -                        | -                  | -                         | -                         | -   | -                                      | -                                     | -  | -       | -                        | -       | -    | EVENT<br>OUT |
|        | PC15 | -           | -      | -        | -                        | -                  | -                         | -                         | -   | -                                      | -                                     | -  | -       | -                        | -       | -    | EVENT<br>OUT |

DocID027107 Rev 3

|        |      |             |        |          |                          | 7                  | able 11.                  | Alterna                   | te funct  | ion (con                               | tinued)                               |  |         |                          |              |      |              |
|--------|------|-------------|--------|----------|--------------------------|--------------------|---------------------------|---------------------------|---|--|---------------------------------------|--|---------|--------------------------|--------------|------|--------------|
|        |      | AF0         | AF1    | AF2      | AF3                      | AF4                | AF5                       | AF6                       | AF7   | AF8                                    | AF9                                   | AF10                                     | AF11    | AF12                     | AF13         | AF14 | AF15         |
| Po     | ort  | sys         | TIM1/2 | TIM3/4/5 | TIM8/9/<br>10/11/<br>CEC | I2C1/2/3<br>/4/CEC | SPI1/2/3/<br>4            | SPI2/3/4/<br>SAI1         | SPI2/3/<br>USART1/<br>2/3/UART<br>5/SPDIFR<br>X | SAI/<br>USART6/<br>UART4/5/<br>SPDIFRX | CAN1/2<br>TIM12/13/<br>14/<br>QUADSPI | SAI2/<br>QUADSPI/<br>OTG2_HS/<br>OTG1_FS | OTG1_FS | FMC/<br>SDIO/<br>OTG2_FS | DCMI         | -    | sys          |
|        | PD0  | -           | -      | -        | -                        | -                  | SPI4_MISO                 | SPI3_<br>MOSI/<br>I2S3_SD | -   | -                                      | CAN1_RX                               | -  | -       | FMC_D2                   | -            | -    | EVENT<br>OUT |
|        | PD1  | -           | -      | -        | -                        | -                  | -                         | -                         | SPI2_NSS/<br>I2S2_WS                            | -                                      | CAN1_TX                               | -  | -       | FMC_D3                   | -            | -    | EVENT<br>OUT |
|        | PD2  | -           | -      | TIM3_ETR | -                        | -                  | -                         | -                         | -   | UART5_RX                               | -                                     | -  | -       | SDIO_CMD                 | DCMI_<br>D11 | -    | EVENT<br>OUT |
|        | PD3  | TRACE<br>D1 | -      | -        | -                        | -                  | SPI2_SCK/<br>I2S2_CK      | -                         | USART2_<br>CTS                                  | -                                      | QUADSPI_<br>CLK                       | -  | ı       | FMC_CLK                  | DCMI_<br>D5  | -    | EVENT<br>OUT |
|        | PD4  | -           | -      | -        | -                        | -                  | -                         | -                         | USART2_<br>RTS                                  | -                                      | -                                     | -  | 1       | FMC_NOE                  | ı            | -    | EVENT<br>OUT |
|        | PD5  | -           | -      | -        | -                        | -                  | -                         | -                         | USART2_<br>TX                                   | -                                      | -                                     | -  | -       | FMC_NWE                  | -            | -    | EVENT<br>OUT |
|        | PD6  | -           | -      | -        | -                        | -                  | SPI3_<br>MOSI/<br>I2S3_SD | SAI1_<br>SD_A             | USART2_<br>RX                                   | -                                      | -                                     | -  | -       | FMC_<br>NWAIT            | DCMI_<br>D10 | -    | EVENT<br>OUT |
| Port D | PD7  | -           | -      | -        | -                        | -                  | -                         | -                         | USART2_<br>CK                                   | SPDIF_<br>RX0                          | -                                     | -  | -       | FMC_NE1                  | -            | -    | EVENT<br>OUT |
|        | PD8  | -           | -      | -        | -                        | -                  | -                         | -                         | USART3_<br>TX                                   | SPDIF_<br>RX1                          | -                                     | -  | -       | FMC_D13                  | -            | -    | EVENT<br>OUT |
|        | PD9  | -           | -      | -        | -                        | -                  | -                         | -                         | USART3_<br>RX                                   | -                                      | -                                     | -  | -       | FMC_D14                  | -            | -    | EVENT<br>OUT |
|        | PD10 | -           | -      | -        | -                        | -                  | -                         | -                         | USART3_<br>CK                                   | -                                      | -                                     | -  | -       | FMC_D15                  | -            | -    | EVENT<br>OUT |
|        | PD11 | -           | -      | -        | -                        | FMPI2C1<br>_SMBA   | -                         | -                         | USART3_<br>CTS                                  | -                                      | QUADSPI_<br>BK1_IO0                   | SAI2_SD_A                                | -       | FMC_A16                  | -            | -    | EVENT<br>OUT |
|        | PD12 | -           | -      | TIM4_CH1 | -                        | FMPI2C1<br>_SCL    | -                         | -                         | USART3_<br>RTS                                  | -                                      | QUADSPI_<br>BK1_IO1                   | SAI2_FS_A                                | -       | FMC_A17                  | -            | -    | EVENT<br>OUT |
|        | PD13 | -           | -      | TIM4_CH2 | -                        | FMPI2C1<br>_SDA    | -                         | -                         | -   | -                                      | QUADSPI_<br>BK1_IO3                   | SAI2_SCK_A                               | -       | FMC_A18                  | -            | -    | EVENT<br>OUT |
|        | PD14 | -           | -      | TIM4_CH3 | -                        | FMPI2C1<br>_SCL    | -                         | -                         | -   | SAI2_<br>SCK_A                         | -                                     | -  | -       | FMC_D0                   | -            | -    | EVENT<br>OUT |
|        | PD15 | -           | -      | TIM4_CH4 | -                        | FMPI2C1<br>_SDA    | -                         | -                         | -   | -                                      | -                                     | -  | -       | FMC_D1                   | -            | -    | EVENT<br>OUT |





## Table 11. Alternate function (continued)

|        |      | AF0          | AF1       | AF2      | AF3                      | AF4                | AF5            | AF6               | AF7   | AF8                                    | AF9                                   | AF10                                     | AF11    | AF12                     | AF13    | AF14 | AF15         |
|--------|------|--------------|-----------|----------|--------------------------|--------------------|----------------|-------------------|---|--|---------------------------------------|--|---------|--------------------------|---------|------|--------------|
| Po     | ort  | sys          | TIM1/2    | TIM3/4/5 | TIM8/9/<br>10/11/<br>CEC | I2C1/2/3<br>/4/CEC | SPI1/2/3/<br>4 | SPI2/3/4/<br>SAI1 | SPI2/3/<br>USART1/<br>2/3/UART<br>5/SPDIFR<br>X | SAI/<br>USART6/<br>UART4/5/<br>SPDIFRX | CAN1/2<br>TIM12/13/<br>14/<br>QUADSPI | SAI2/<br>QUADSPI/<br>OTG2_HS/<br>OTG1_FS | OTG1_FS | FMC/<br>SDIO/<br>OTG2_FS | DCMI    | -    | sys          |
|        | PE0  | -            | -         | TIM4_ETR | -                        | -                  | -              | -                 | -   | -                                      | -                                     | SAI2_<br>MCLK_A                          | -       | FMC_<br>NBL0             | DCMI_D2 | -    | EVENT<br>OUT |
|        | PE1  | -            | -         | -        | -                        | -                  | -              | -                 | -   | -                                      | -                                     | -  |         | FMC_<br>NBL1             | DCMI_D3 | -    | EVENT<br>OUT |
|        | PE2  | TRACE<br>CLK | -         | -        | -                        | -                  | SPI4_SCK       | SAI1_<br>MCLK_A   | -   | -                                      | QUADSPI_<br>BK1_IO2                   | -  | -       | FMC_A23                  | -       | -    | EVENT<br>OUT |
|        | PE3  | TRACE<br>D0  | -         | -        | -                        | -                  | -              | SAI1_<br>SD_B     | -   | -                                      | -                                     | -  | -       | FMC_A19                  | -       | -    | EVENT<br>OUT |
|        | PE4  | TRACE<br>D1  | -         | -        | -                        | -                  | SPI4_NSS       | SAI1_<br>FS_A     | -   | -                                      | -                                     | -  | -       | FMC_A20                  | DCMI_D4 | -    | EVENT<br>OUT |
|        | PE5  | TRACE<br>D2  | -         | -        | TIM9_CH1                 | -                  | SPI4_MISO      | SAI1_<br>SCK_A    | -   | -                                      | -                                     | -  | -       | FMC_A21                  | DCMI_D6 | -    | EVENT<br>OUT |
|        | PE6  | TRACE<br>D3  | -         | -        | TIM9_CH2                 | -                  | SPI4_MOSI      | SAI1_<br>SD_A     | -   | -                                      | -                                     | -  | -       | FMC_A22                  | DCMI_D7 | -    | EVENT<br>OUT |
|        | PE7  | -            | TIM1_ETR  | -        | -                        | -                  | -              | -                 | -   | UART5_RX                               | -                                     | QUADSPI_<br>BK2_IO0                      | -       | FMC_D4                   | -       | -    | EVENT<br>OUT |
| Port E | PE8  | -            | TIM1_CH1N | -        | -                        | -                  | -              | -                 | -   | UART5_TX                               | -                                     | QUADSPI_<br>BK2_IO1                      | -       | FMC_D5                   | -       | -    | EVENT<br>OUT |
|        | PE9  | -            | TIM1_CH1  | -        | -                        | -                  | -              | -                 | -   | -                                      | -                                     | QUADSPI_<br>BK2_IO2                      | -       | FMC_D6                   | -       | -    | EVENT<br>OUT |
|        | PE10 | -            | TIM1_CH2N | -        | -                        | -                  | -              | -                 | -   | -                                      | -                                     | QUADSPI_<br>BK2_IO3                      | -       | FMC_D7                   | -       | -    | EVENT<br>OUT |
|        | PE11 | -            | TIM1_CH2  | -        | -                        | -                  | SPI4_NSS       | -                 | -   | -                                      | -                                     | SAI2_<br>SD_B                            | -       | FMC_D8                   | -       | -    | EVENT<br>OUT |
|        | PE12 | -            | TIM1_CH3N | -        | -                        | -                  | SPI4_SCK       | -                 | -   | -                                      | -                                     | SAI2_<br>SCK_B                           | -       | FMC_D9                   | -       | -    | EVENT<br>OUT |
|        | PE13 | -            | TIM1_CH3  | -        | -                        | -                  | SPI4_MISO      | -                 | -   | -                                      | -                                     | SAI2_<br>FS_B                            | -       | FMC_D10                  | -       | -    | EVENT<br>OUT |
|        | PE14 | -            | TIM1_CH4  | -        | -                        | -                  | SPI4_MOSI      | -                 | -   | -                                      | -                                     | SAI2_<br>MCLK_B                          | -       | FMC_D11                  | -       | -    | EVENT<br>OUT |
|        | PE15 | -            | TIM1_BKIN | -        | -                        | -                  | -              | -                 | -   | -                                      | -                                     | -  | -       | FMC_D12                  | -       | -    | EVENT<br>OUT |

DocID027107 Rev 3

Pinout and pin description

Table 11. Alternate function (continued)

|        |      | AF0 | AF1    | AF2      | AF3                      | AF4                | AF5            | AF6               | AF7   | AF8                                    | AF9                                   | AF10                                     | AF11    | AF12                     | AF13         | AF14 | AF15         |
|--------|------|-----|--------|----------|--------------------------|--------------------|----------------|-------------------|---|--|---------------------------------------|--|---------|--------------------------|--------------|------|--------------|
| Po     | ort  | sys | TIM1/2 | TIM3/4/5 | TIM8/9/<br>10/11/<br>CEC | I2C1/2/3<br>/4/CEC | SPI1/2/3/<br>4 | SPI2/3/4/<br>SAI1 | SPI2/3/<br>USART1/<br>2/3/UART<br>5/SPDIFR<br>X | SAI/<br>USART6/<br>UART4/5/<br>SPDIFRX | CAN1/2<br>TIM12/13/<br>14/<br>QUADSPI | SAI2/<br>QUADSPI/<br>OTG2_HS/<br>OTG1_FS | OTG1_FS | FMC/<br>SDIO/<br>OTG2_FS | DCMI         | -    | sys          |
|        | PF0  | -   | -      | -        | -                        | I2C2_<br>SDA       | -              | -                 | -   | -                                      | -                                     | -  | -       | FMC_A0                   | -            | -    | EVENT<br>OUT |
|        | PF1  | -   | -      | -        | -                        | I2C2_<br>SCL       | -              | -                 | -   | -                                      | -                                     | -  | -       | FMC_A1                   | -            | -    | EVENT<br>OUT |
|        | PF2  | -   | -      | -        | -                        | I2C2_<br>SMBA      | -              | -                 | -   | -                                      | -                                     | -  | -       | FMC_A2                   | -            | -    | EVENT<br>OUT |
|        | PF3  | -   | -      | -        | -                        | -                  | -              | -                 | -   | -                                      | -                                     | -  | -       | FMC_A3                   | -            | -    | EVENT<br>OUT |
|        | PF4  | -   | -      | -        | -                        | -                  | -              | -                 | -   | -                                      | -                                     | -  | -       | FMC_A4                   | -            | -    | EVENT<br>OUT |
|        | PF5  | -   | -      | -        | -                        | -                  | -              | -                 | -   | -                                      | -                                     | -  | -       | FMC_A5                   | -            | -    | EVENT<br>OUT |
|        | PF6  | -   | -      | -        | TIM10_<br>CH1            | -                  | -              | SAI1_<br>SD_B     | -   | -                                      | QUADSPI_<br>BK1_IO3                   | -  | -       | -                        | -            | -    | EVENT<br>OUT |
|        | PF7  | -   | -      | -        | TIM11_<br>CH1            | -                  | -              | SAI1_<br>MCLK_B   | -   | -                                      | QUADSPI_<br>BK1_IO2                   | -  | -       | -                        | -            | -    | EVENT<br>OUT |
| Port F | PF8  | -   | -      | -        | -                        | -                  | -              | SAI1_<br>SCK_B    | -   | -                                      | TIM13_CH1                             | QUADSPI_<br>BK1_IO0                      | -       | -                        | -            | -    | EVENT<br>OUT |
|        | PF9  | -   | -      | -        | -                        | -                  | -              | SAI1_<br>FS_B     | -   | -                                      | TIM14_CH1                             | QUADSPI_<br>BK1_IO1                      | -       | -                        | -            | -    | EVENT<br>OUT |
|        | PF10 | -   | -      | -        | -                        | -                  | -              | -                 | -   | -                                      | -                                     | -  | -       | -                        | DCMI_<br>D11 | -    | EVENT<br>OUT |
|        | PF11 | -   | -      | -        | -                        | -                  | -              | -                 | -   | -                                      | -                                     | SAI2_SD_B                                | -       | FMC_<br>SDNRAS           | DCMI_<br>D12 | -    | EVENT<br>OUT |
|        | PF12 | -   | -      | -        | -                        | -                  | -              | -                 | -   | -                                      | -                                     | -  | -       | FMC_A6                   | -            | -    | EVENT<br>OUT |
|        | PF13 | -   | -      | -        | -                        | FMPI2C1<br>_SMBA   | -              | -                 | -   | -                                      | -                                     | -  | -       | FMC_A7                   | -            | -    | EVENT<br>OUT |
|        | PF14 | -   | -      | -        | -                        | FMPI2C1<br>_SCL    | -              | -                 | -   | -                                      | -                                     | -  | -       | FMC_A8                   | -            | -    | EVENT<br>OUT |
|        | PF15 | -   | -      | -        | -                        | FMPI2C1<br>_SDA    | -              | -                 | -   | -                                      | -                                     | -  | -       | FMC_A9                   | -            | -    | EVENT<br>OUT |





**Table 11. Alternate function (continued)** 

|        |      | AF0         | AF1    | AF2      | AF3                      | AF4                | AF5            | AF6               | AF7   | AF8                                    | AF9                                   | AF10                                     | AF11    | AF12                     | AF13                          | AF14 | AF15         |
|--------|------|-------------|--------|----------|--------------------------|--------------------|----------------|-------------------|---|--|---------------------------------------|--|---------|--------------------------|-------------------------------|------|--------------|
| Po     | ort  | sys         | TIM1/2 | TIM3/4/5 | TIM8/9/<br>10/11/<br>CEC | I2C1/2/3<br>/4/CEC | SPI1/2/3/<br>4 | SPI2/3/4/<br>SAI1 | SPI2/3/<br>USART1/<br>2/3/UART<br>5/SPDIFR<br>X | SAI/<br>USART6/<br>UART4/5/<br>SPDIFRX | CAN1/2<br>TIM12/13/<br>14/<br>QUADSPI | SAI2/<br>QUADSPI/<br>OTG2_HS/<br>OTG1_FS | OTG1_FS | FMC/<br>SDIO/<br>OTG2_FS | DCMI                          | -    | sys          |
|        | PG0  | -           | -      | -        | -                        | -                  | -              | -                 | -   | -                                      | -                                     | -  | -       | FMC_A10                  | -                             | -    | EVENT<br>OUT |
|        | PG1  | -           | -      | -        | -                        | -                  | -              | -                 | -   | -                                      | -                                     | -  | -       | FMC_A11                  | -                             | -    | EVENT<br>OUT |
|        | PG2  | -           | -      | -        | -                        | -                  | -              | -                 | -   | -                                      | -                                     | -  | -       | FMC_A12                  | -                             | -    | EVENT<br>OUT |
|        | PG3  | -           | -      | -        | -                        | -                  | -              | -                 | -   | -                                      | -                                     | -  | -       | FMC_A13                  | -                             | -    | EVENT<br>OUT |
|        | PG4  | -           | -      | -        | -                        | -                  | -              | -                 | -   | -                                      | -                                     | -  | -       | FMC_A14/<br>FMC_BA0      | -                             | -    | EVENT<br>OUT |
|        | PG5  | -           | -      | -        | -                        | -                  | -              | -                 | -   | -                                      | -                                     | -  | -       | FMC_A15/<br>FMC_BA1      | -                             | -    | EVENT<br>OUT |
|        | PG6  | -           | -      | -        | -                        | -                  | -              | -                 | -   | -                                      | -                                     | QUADSPI_<br>BK1_NCS                      | -       | -                        | DCMI_<br>D12                  | -    | EVENT<br>OUT |
|        | PG7  | -           | -      | -        | -                        | -                  | -              | -                 | -   | USART6_C<br>K                          | -                                     | -  | -       | FMC_INT                  | DCMI_<br>D13                  | -    | EVENT<br>OUT |
| Port G | PG8  | -           | -      | -        | -                        | -                  | -              | -                 | SPDIFRX_<br>IN2                                 | USART6_R<br>TS                         | -                                     | -  | -       | FMC_<br>SDCLK            | -                             | -    | EVENT<br>OUT |
|        | PG9  | -           | -      | -        | -                        | -                  | -              | -                 | SPDIFRX_<br>IN3                                 | USART6_R<br>X                          | QUADSPI_<br>BK2_IO2                   | SAI2_FS_B                                | -       | FMC_NE2/<br>FMC_NCE3     | DCMI_<br>VSYNC <sup>(1)</sup> | -    | EVENT<br>OUT |
|        | PG10 | -           | -      | -        | -                        | -                  | -              | -                 | -   | -                                      | -                                     | SAI2_SD_B                                | -       | FMC_NE3                  | DCMI_D2                       | -    | EVENT<br>OUT |
|        | PG11 | -           | -      | -        | -                        | -                  | -              | SPI4_<br>SCK      | SPDIFRX_<br>IN0                                 | -                                      | -                                     | -  | -       | -                        | DCMI_D3                       | -    | EVENT<br>OUT |
|        | PG12 | -           | -      | -        | -                        | -                  | -              | SPI4_<br>MISO     | SPDIFRX_<br>IN1                                 | USART6_R<br>TS                         | -                                     | -  | -       | FMC_NE4                  | -                             | -    | EVENT<br>OUT |
|        | PG13 | TRACE<br>D2 | -      | -        | -                        | -                  | -              | SPI4_<br>MOSI     | -   | USART6_C<br>TS                         | -                                     | -  | -       | FMC_A24                  | -                             | -    | EVENT<br>OUT |
|        | PG14 | TRACE<br>D3 | -      | -        | -                        | -                  | -              | SPI4_<br>NSS      | -   | USART6_T                               | QUADSPI_<br>BK2_IO3                   | -  | -       | FMC_A25                  | -                             | -    | EVENT<br>OUT |
|        | PG15 | -           | -      | -        | -                        | -                  | -              | -                 | -   | USART6_C<br>TS                         | -                                     | -  | -       | FMC_<br>SDNCAS           | DCMI_<br>D13                  | -    | EVENT<br>OUT |

DocID027107 Rev 3

**Table 11. Alternate function (continued)** 

|        |     | AF0 | AF1    | AF2      | AF3                      | AF4                | AF5            | AF6               | AF7   | AF8                                    | AF9                                   | AF10                                     | AF11    | AF12                     | AF13 | AF14 | AF15         |
|--------|-----|-----|--------|----------|--------------------------|--------------------|----------------|-------------------|---|--|---------------------------------------|--|---------|--------------------------|------|------|--------------|
| Po     | ort | sys | TIM1/2 | TIM3/4/5 | TIM8/9/<br>10/11/<br>CEC | I2C1/2/3<br>/4/CEC | SPI1/2/3/<br>4 | SPI2/3/4/<br>SAI1 | SPI2/3/<br>USART1/<br>2/3/UART<br>5/SPDIFR<br>X | SAI/<br>USART6/<br>UART4/5/<br>SPDIFRX | CAN1/2<br>TIM12/13/<br>14/<br>QUADSPI | SAI2/<br>QUADSPI/<br>OTG2_HS/<br>OTG1_FS | OTG1_FS | FMC/<br>SDIO/<br>OTG2_FS | DCMI | -    | sys          |
| D-#II  | PH0 | -   | -      | -        | -                        | -                  | -              | -                 | -   | -                                      | -                                     | -  | -       | -                        | -    | -    | EVENT<br>OUT |
| Port H | PH1 | -   | -      | -        | -                        | -                  | -              | -                 | -   | -                                      | -                                     | -  | -       | -                        | -    | -    | EVENT<br>OUT |

<sup>1.</sup> The DCMI\_VSYNC alternate function on PG9 is only available on silicon revision 3.

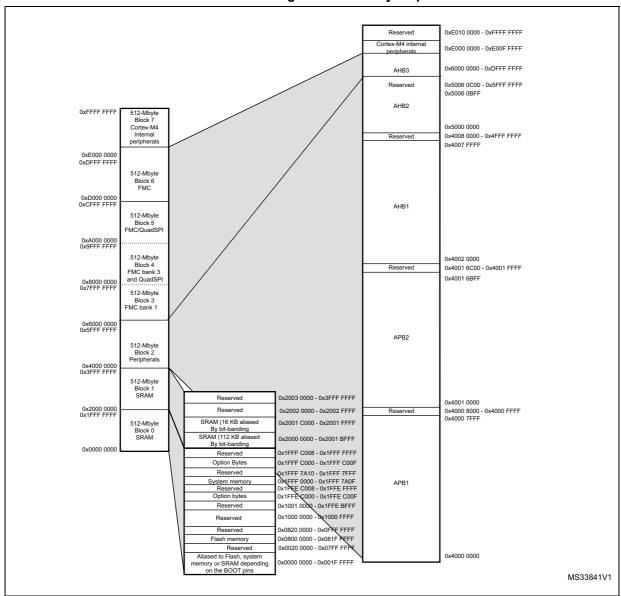


Memory mapping STM32F446xx

# 5 Memory mapping

The memory map is shown in Figure 14

Figure 14. Memory map



STM32F446xx Memory mapping

Table 12. STM32F446xx register boundary addresses<sup>(1)</sup>

| Bus       | Boundary address            | Peripheral                     |
|-----------|-----------------------------|--------------------------------|
| -         | 0xE00F FFFF - 0xFFFF FFFF   | Reserved                       |
| Cortex-M4 | 0xE000 0000 - 0xE00F FFFF   | Cortex-M4 internal peripherals |
|           | 0xD000 0000 - 0xDFFF FFFF   | FMC bank 6                     |
|           | 0xC000 0000 - 0xCFFF FFFF   | FMC bank 5                     |
|           | 0xA000 2000 - 0x0xBFFF FFFF | Reserved                       |
|           | 0xA000 1000 - 0x0xA000 1FFF | QuadSPI control register       |
| AHB3      | 0xA000 0000 - 0xA000 0FFF   | FMC control register           |
|           | 0x9000 0000 - 0x9FFF FFFF   | QuadSPI                        |
|           | 0x8000 0000 - 0x8FFF FFFF   | FMC bank 3                     |
|           | 0x7000 0000 - 0x0x7FFF FFFF | Reserved                       |
|           | 0x6000 0000 - 0x6FFF FFFF   | FMC bank 1                     |
| -         | 0x5006 0C00- 0x5FFF FFFF    | Reserved                       |
|           | 0x5006 0800- 0x500F 07FF    | Reserved                       |
|           | 0x5005 0400 - 0x5006 07FF   | Reserved                       |
| AHB2      | 0x5005 0000 - 0x5005 03FF   | DCMI                           |
|           | 0x5004 0000- 0x5004 FFFF    | Reserved                       |
|           | 0x5000 0000 - 0X5003 FFFF   | USB OTG FS                     |

Memory mapping STM32F446xx

Table 12. STM32F446xx register boundary addresses<sup>(1)</sup> (continued)

| Bus  | Boundary address          | Peripheral               |
|------|---------------------------|--------------------------|
| -    | 0x4008 0000- 0x4FFF FFFF  | Reserved                 |
|      | 0x4004 0000 - 0x4007 FFFF | USB OTG HS               |
|      | 0x4002 BC00- 0x4003 FFFF  | Reserved                 |
|      | 0x4002 B000 - 0x4002 BBFF |                          |
|      | 0x4002 9400 - 0x4002 AFFF |                          |
|      | 0x4002 9000 - 0x4002 93FF |                          |
|      | 0x4002 8C00 - 0x4002 8FFF |                          |
|      | 0x4002 8800 - 0x4002 8BFF |                          |
|      | 0x4002 8400 - 0x4002 87FF |                          |
|      | 0x4002 8000 - 0x4002 83FF |                          |
|      | 0x4002 6800 - 0x4002 7FFF |                          |
|      | 0x4002 6400 - 0x4002 67FF | DMA2                     |
|      | 0x4002 6000 - 0x4002 63FF | DMA1                     |
|      | 0X4002 5000 - 0X4002 5FFF | Reserved                 |
|      | 0x4002 4000 - 0x4002 4FFF | BKPSRAM                  |
| AHB1 | 0x4002 3C00 - 0x4002 3FFF | Flash interface register |
| AHBJ | 0x4002 3800 - 0x4002 3BFF | RCC                      |
|      | 0X4002 3400 - 0X4002 37FF | Reserved                 |
|      | 0x4002 3000 - 0x4002 33FF | CRC                      |
|      | 0x4002 2C00 - 0x4002 2FFF | Reserved                 |
| ·    | 0x4002 2800 - 0x4002 2BFF |                          |
|      | 0x4002 2400 - 0x4002 27FF |                          |
|      | 0x4002 2000 - 0x4002 23FF |                          |
|      | 0x4002 1C00 - 0x4002 1FFF | GPIOH                    |
|      | 0x4002 1800 - 0x4002 1BFF | GPIOG                    |
|      | 0x4002 1400 - 0x4002 17FF | GPIOF                    |
|      | 0x4002 1000 - 0x4002 13FF | GPIOE                    |
|      | 0X4002 0C00 - 0x4002 0FFF | GPIOD                    |
|      | 0x4002 0800 - 0x4002 0BFF | GPIOC                    |
|      | 0x4002 0400 - 0x4002 07FF | GPIOB                    |
|      |                           |                          |

STM32F446xx Memory mapping

Table 12. STM32F446xx register boundary addresses<sup>(1)</sup> (continued)

| Bus  | Boundary address          | Peripheral         |
|------|---------------------------|--------------------|
| -    | 0x4001 6C00- 0x4001 FFFF  | Reserved           |
|      | 0x4001 6800 - 0x4001 6BFF | Reserved           |
|      | 0x4001 5C00 - 0x4001 5FFF | SAI2               |
|      | 0x4001 6000 - 0x4001 67FF | Reserved           |
|      | 0x4001 5800 - 0x4001 5BFF | SAI1               |
|      | 0x4001 5400 - 0x4001 57FF |                    |
|      | 0x4001 5000 - 0x4001 53FF | Reserved           |
|      | 0x4001 4C00 - 0x4001 4FFF |                    |
|      | 0x4001 4800 - 0x4001 4BFF | TIM11              |
|      | 0x4001 4400 - 0x4001 47FF | TIM10              |
| APB2 | 0x4001 4000 - 0x4001 43FF | TIM9               |
|      | 0x4001 3C00 - 0x4001 3FFF | EXTI               |
|      | 0x4001 3800 - 0x4001 3BFF | SYSCFG             |
|      | 0x4001 3400 - 0x4001 37FF | SPI4               |
|      | 0x4001 3000 - 0x4001 33FF | SPI1               |
|      | 0x4001 2C00 - 0x4001 2FFF | SDIO               |
|      | 0x4001 2400 - 0x4001 2BFF | Reserved           |
|      | 0x4001 2000 - 0x4001 23FF | ADC1 - ADC2 - ADC3 |
|      | 0x4001 1800 - 0x4001 1FFF | Reserved           |
|      | 0x4001 1400 - 0x4001 17FF | USART6             |
|      | 0x4001 1000 - 0x4001 13FF | USART1             |
|      | 0x4001 0800 - 0x4001 0FFF | Reserved           |
|      | 0x4001 0400 - 0x4001 07FF | TIM8               |
|      | 0x4001 0000 - 0x4001 03FF | TIM1               |

Memory mapping STM32F446xx

Table 12. STM32F446xx register boundary addresses<sup>(1)</sup> (continued)

| Bus  | Boundary address          | Peripheral          |
|------|---------------------------|---------------------|
| -    | 0x4000 8000- 0x4000 FFFF  |                     |
|      | 0x4000 7C00 - 0x4000 7FFF | Reserved            |
|      | 0x4000 7800 - 0x4000 7BFF |                     |
|      | 0x4000 7400 - 0x4000 77FF | DAC                 |
|      | 0x4000 7000 - 0x4000 73FF | PWR                 |
|      | 0x4000 6C00 - 0x4000 6FFF | HDMI-CEC            |
|      | 0x4000 6800 - 0x4000 6BFF | CAN2                |
|      | 0x4000 6400 - 0x4000 67FF | CAN1                |
|      | 0x4000 6000 - 0x4000 63FF | FMPI2C1             |
|      | 0x4000 5C00 - 0x4000 5FFF | I2C3                |
|      | 0x4000 5800 - 0x4000 5BFF | I2C2                |
|      | 0x4000 5400 - 0x4000 57FF | I2C1                |
|      | 0x4000 5000 - 0x4000 53FF | UART5               |
|      | 0x4000 4C00 - 0x4000 4FFF | UART4               |
|      | 0x4000 4800 - 0x4000 4BFF | USART3              |
|      | 0x4000 4400 - 0x4000 47FF | USART2              |
| ADD4 | 0x4000 4000 - 0x4000 43FF | SPDIFRX             |
| APB1 | 0x4000 3C00 - 0x4000 3FFF | SPI3 / I2S3         |
|      | 0x4000 3800 - 0x4000 3BFF | SPI2 / I2S2         |
|      | 0x4000 3400 - 0x4000 37FF | Reserved            |
|      | 0x4000 3000 - 0x4000 33FF | IWDG                |
|      | 0x4000 2C00 - 0x4000 2FFF | WWDG                |
|      | 0x4000 2800 - 0x4000 2BFF | RTC & BKP Registers |
|      | 0x4000 2400 - 0x4000 27FF | Reserved            |
|      | 0x4000 2000 - 0x4000 23FF | TIM14               |
|      | 0x4000 1C00 - 0x4000 1FFF | TIM13               |
|      | 0x4000 1800 - 0x4000 1BFF | TIM12               |
|      | 0x4000 1400 - 0x4000 17FF | TIM7                |
|      | 0x4000 1000 - 0x4000 13FF | TIM6                |
|      | 0x4000 0C00 - 0x4000 0FFF | TIM5                |
|      | 0x4000 0800 - 0x4000 0BFF | TIM4                |
|      | 0x4000 0400 - 0x4000 07FF | TIM3                |
|      | 0x4000 0000 - 0x4000 03FF | TIM2                |

<sup>1.</sup> The grey color is used for reserved boundary addresses.

### 6 Electrical characteristics

#### 6.1 Parameter conditions

Unless otherwise specified, all voltages are referenced to V<sub>SS</sub>.

#### 6.1.1 Minimum and maximum values

Unless otherwise specified the minimum and maximum values are guaranteed in the worst conditions of ambient temperature, supply voltage and frequencies by tests in production on 100% of the devices with an ambient temperature at  $T_A = 25$  °C and  $T_A = T_A$ max (given by the selected temperature range).

Data based on characterization results, design simulation and/or technology characteristics are indicated in the table footnotes and are not tested in production. Based on characterization, the minimum and maximum values refer to sample tests and represent the mean value plus or minus three times the standard deviation (mean±3 $\sigma$ ).

#### 6.1.2 Typical values

Unless otherwise specified, typical data are based on  $T_A$  = 25 °C,  $V_{DD}$  = 3.3 V (for the 1.7 V  $\leq$  V<sub>DD</sub>  $\leq$  3.6 V voltage range). They are given only as design guidelines and are not tested.

Typical ADC accuracy values are determined by characterization of a batch of samples from a standard diffusion lot over the full temperature range, where 95% of the devices have an error less than or equal to the value indicated (mean±2σ).

#### 6.1.3 Typical curves

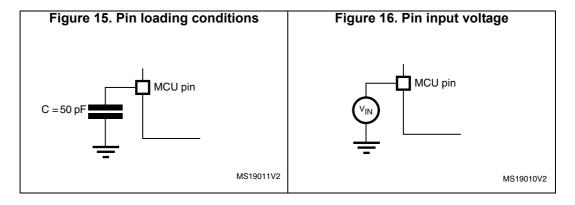
Unless otherwise specified, all typical curves are given only as design guidelines and are not tested.

### 6.1.4 Loading capacitor

The loading conditions used for pin parameter measurement are shown in Figure 15.

#### 6.1.5 Pin input voltage

The input voltage measurement on a pin of the device is described in *Figure 16*.



Electrical characteristics STM32F446xx

#### 6.1.6 Power supply scheme

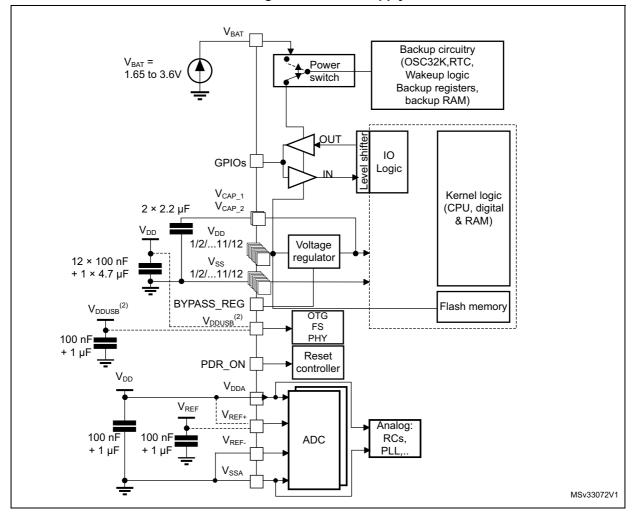


Figure 17. Power supply scheme

- V<sub>DDA</sub> and V<sub>SSA</sub> must be connected to V<sub>DD</sub> and V<sub>SS</sub>, respectively.
- 2. V<sub>DDUSB</sub> is a dedicated independent USB power supply for the on-chip full-speed OTG PHY module and associated DP/DM GPIOs. Its value is independent from the V<sub>DD</sub> and V<sub>DDA</sub> values, but must be the last supply to be provided and the first to disappear. If VDD is different from V<sub>DDUSB</sub> and only one on-chip OTG PHY is used, the second OTG PHY GPIOs (DP/DM) are still supplied at <sub>VDDUSB</sub> (3.3V).

#### Caution:

Each power supply pair ( $V_{DD}/V_{SS}$ ,  $V_{DDA}/V_{SSA}$ ...) must be decoupled with filtering ceramic capacitors as shown above. These capacitors must be placed as close as possible to, or below, the appropriate pins on the underside of the PCB to ensure good operation of the device. It is not recommended to remove filtering capacitors to reduce PCB size or cost. This might cause incorrect operation of the device.

#### 6.1.7 Current consumption measurement

IDD\_VBAT
VBAT

IDD
VDD

VDD

VDD

VDDUSB

MSv36557V1

Figure 18. Current consumption measurement scheme

# 6.2 Absolute maximum ratings

Stresses above the absolute maximum ratings listed in *Table 13: Voltage characteristics*, *Table 14: Current characteristics*, and *Table 15: Thermal characteristics* may cause permanent damage to the device. These are stress ratings only and functional operation of the device at these conditions is not implied. Exposure to maximum rating conditions for extended periods may affect device reliability.

| Symbol                            | Ratings   | Min  | Max                  | Unit |
|-----------------------------------|---|--|----------------------|------|
| V <sub>DD</sub> -V <sub>SS</sub>  | External main supply voltage (including $V_{DDA}, V_{DD}$ and $VBAT)^{(1)}$ | -0.3   | 4.0                  |      |
|                                   | Input voltage on FT & FTf pins <sup>(2)</sup>                               | V <sub>SS</sub> -0.3   | V <sub>DD</sub> +4.0 | l    |
| V                                 | Input voltage on TTa pins   | V <sub>SS</sub> -0.3   | 4.0                  | V    |
| V <sub>IN</sub>                   | Input voltage on any other pin  | V <sub>SS</sub> -0.3   | 4.0                  |      |
|                                   | Input voltage on BOOT0 pin  | V <sub>SS</sub>  | 9.0                  |      |
| $ \Delta V_{DDx} $                | Variations between different V <sub>DD</sub> power pins                     | -  | 50                   | mV   |
| V <sub>SSX</sub> -V <sub>SS</sub> | Variations between all the different ground pins                            | -  | 50                   | IIIV |
| V <sub>ESD(HBM)</sub>             | Electrostatic discharge voltage (human body model)                          | see Section 6.3.15:<br>Absolute maximum<br>ratings (electrical<br>sensitivity) |                      | -    |

Table 13. Voltage characteristics

All main power (V<sub>DD</sub>, V<sub>DDA</sub>) and ground (V<sub>SS</sub>, V<sub>SSA</sub>) pins must always be connected to the external power supply, in the permitted range.

<sup>2.</sup> V<sub>IN</sub> maximum value must always be respected. Refer to *Table 14* for the values of the maximum allowed injected current.

**Table 14. Current characteristics** 

| Symbol                 | Ratings  | Max.                 | Unit |
|------------------------|--|----------------------|------|
| $\Sigma I_{VDD}$       | Total current into sum of all V <sub>DD</sub> power lines (source) <sup>(1)</sup>  | 240                  |      |
| Σ I <sub>VSS</sub>     | Total current out of sum of all V <sub>SS</sub> ground lines (sink) <sup>(1)</sup> | 240                  |      |
| Σ IV <sub>DDUSB</sub>  | Total current into V <sub>DDUSB</sub> power line (source)                          | 25                   |      |
| I <sub>VDD</sub>       | Maximum current into each V <sub>DD</sub> power pin (source) <sup>(1)</sup>        | 100                  |      |
| I <sub>VSS</sub>       | Maximum current out of each V <sub>SS</sub> ground pin (sink) <sup>(1)</sup>       | 100                  |      |
| -                      | Output current sunk by any I/O and control pin                                     | 25                   |      |
| I <sub>IO</sub>        | Output current sourced by any I/Os and control pin                                 | -25                  | mA   |
|                        | Total output current sunk by sum of all I/Os and control pins (2)                  | 120                  |      |
| $\Sigma I_{IO}$        | Total output current sunk by sum of all USB I/Os                                   | 25                   |      |
|                        | Total output current sourced by sum of all I/Os and control pins <sup>(2)</sup>    | -120                 |      |
|                        | Injected current on FT, FTf, RST and B pins  | -5/+0 <sup>(3)</sup> |      |
| I <sub>INJ(PIN)</sub>  | Injected current on TTa pins   | ±5 <sup>(4)</sup>    |      |
| ΣΙ <sub>ΙΝJ(PIN)</sub> | Total injected current (sum of all I/O and control pins) <sup>(5)</sup>            | ±25                  |      |

<sup>1.</sup> All main power  $(V_{DD}, V_{DDA})$  and ground  $(V_{SS}, V_{SSA})$  pins must always be connected to the external power supply, in the permitted range.

**Table 15. Thermal characteristics** 

| Symbol           | Ratings                      | Value       | Unit |
|------------------|------------------------------|-------------|------|
| T <sub>STG</sub> | Storage temperature range    | -65 to +150 | °C   |
| T <sub>J</sub>   | Maximum junction temperature | 125         | °C   |

<sup>2.</sup> This current consumption must be correctly distributed over all I/Os and control pins. The total output current must not be sunk/sourced between two consecutive power supply pins referring to high pin count LQFP packages.

<sup>3.</sup> Positive injection is not possible on these I/Os and does not occur for input voltages lower than the specified maximum value.

A positive injection is induced by V<sub>IN</sub>>V<sub>DDA</sub> while a negative injection is induced by V<sub>IN</sub><V<sub>SS</sub>. I<sub>INJ(PIN)</sub> must never be exceeded. Refer to *Table 13* for the maximum allowed input voltage value.

When several inputs are submitted to a current injection, the maximum ΣI<sub>INJ(PIN)</sub> is the absolute sum of the positive and negative injected currents (instantaneous values).

# 6.3 Operating conditions

# 6.3.1 General operating conditions

Table 16. General operating conditions

| Symbol             | Parameter                      | Conditions <sup>(1)</sup>  | Min  | Тур | Max | Unit |     |
|--------------------|--------------------------------|--|--|-----|-----|------|-----|
| f <sub>HCLK</sub>  |                                |  | Power Scale 3 (VOS[1:0] bits<br>PWR_CR register = 0x01),<br>Regulator ON, over-drive OFF | 0   | -   | 120  |     |
|                    |                                | Power Scale 2 (VOS[1:0] bits   | Over-<br>drive<br>OFF  | 0   | -   | 144  |     |
|                    | Internal AHB clock frequency   | in PWR_CR register = 0x10), Regulator ON   | Over-<br>drive<br>ON   | U   | -   | 168  |     |
|                    |                                | Power Scale 1 (VOS[1:0] bits in PWR_CR register= 0x11), Regulator ON  Overdrive ON |  | 0   | -   | 168  | MHz |
|                    |                                |  |  |     | -   | 180  |     |
| f                  | Internal ADR1 clock frequency  | Over-drive OFF   |  | 0   | -   | 42   |     |
| f <sub>PCLK1</sub> | Internal APB1 clock frequency  | Over-drive ON  |  | 0   | _   | 45   |     |
| fnours             | Internal APB2 clock frequency  | Over-drive OFF   | 0  |     | -   | 84   |     |
| f <sub>PCLK2</sub> | Internal At B2 Clock frequency | Over-drive ON  | 0  | -   | 90  |      |     |

Table 16. General operating conditions (continued)

| Symbol                             | Parameter   | Conditions <sup>(1)</sup>  | Min                | Тур  | Max                   | Unit |
|------------------------------------|---|--|--------------------|------|-----------------------|------|
| $V_{DD}$                           | Standard operating voltage  | -  | 1.7 <sup>(2)</sup> | -    | 3.6                   |      |
| V <sub>DDA</sub> <sup>(3)(4)</sup> | Analog operating voltage (ADC limited to 1.2 M samples)                             | Must be the same potential as $V_{DD}^{(5)}$   | 1.7 <sup>(2)</sup> | -    | 2.4                   |      |
| VDDA' / /                          | Analog operating voltage (ADC limited to 2.4 M samples)                             | Must be the same potential as V <sub>DD</sub>  | 2.4                | -    | 3.6                   |      |
| $V_{BAT}$                          | Backup operating voltage  | -  | 1.65               | -    | 3.6                   |      |
|                                    | USB supply voltage (supply  | USB not used   | 1.7                | -    | 3.6                   |      |
| VDDUSB                             | voltage for PA11,PA12, PB14 and PB15 pins)  | USB used   | 3                  | -    | 3.6                   |      |
|                                    |   | Power Scale 3 ((VOS[1:0] bits in PWR_CR register = 0x01), 120 MHz HCLK max frequency   | 1.08               | 1.14 | 1.20                  | V    |
|                                    | Regulator ON: 1.2 V internal voltage on V <sub>CAP_1</sub> /V <sub>CAP_2</sub> pins | Power Scale 2 ((VOS[1:0] bits in PWR_CR register = 0x10), 144 MHz HCLK max frequency with over-drive OFF or 168 MHz with over-drive ON | 1.20               | 1.26 | 1.32                  |      |
| V <sub>12</sub>                    |   | Power Scale 1 ((VOS[1:0] bits in PWR_CR register = 0x11), 168 MHz HCLK max frequency with over-drive OFF or 180 MHz with over-drive ON | 1.26               | 1.32 | 1.40                  |      |
|                                    | Regulator OFF: 1.2 V external voltage must be supplied from external regulator on   | Max frequency 120 MHz  | 1.10               | 1.14 | 1.20                  |      |
|                                    |   | Max frequency 144 MHz  | 1.20               | 1.26 | 1.32                  |      |
|                                    | $V_{CAP_1}/V_{CAP_2}$ pins <sup>(6)</sup>   | Max frequency 168 MHz  | 1.26               | 1.32 | 1.38                  |      |
|                                    | Input voltage on RST, FTf and   | 2 V ≤V <sub>DD</sub> ≤3.6 V  | -0.3               | -    | 5.5                   |      |
| V                                  | FT pins <sup>(7)</sup>  | 1.7 V ≤ V <sub>DD</sub> ≤ 2 V  | -0.3               | -    | 5.2                   | V    |
| $V_{IN}$                           | Input voltage on TTa pins   | -  | -0.3               | -    | V <sub>DDA</sub> +0.3 | V    |
|                                    | Input voltage on BOOT0 pin  | -  | 0                  | -    | 9                     |      |
|                                    |   | LQFP64   | -                  | -    | 345                   |      |
|                                    |   | WLCSP81  | -                  | -    | 417                   |      |
| Б                                  | Power dissipation at T <sub>A</sub> = 85 °C   | LQFP100  | -                  | -    | 476                   | \^/  |
| $P_{D}$                            | for suffix 6 or $T_A = 105$ °C for suffix $7^{(8)}$                                 | LQFP 144   | -                  | -    | 606                   | mW   |
|                                    |   | UFBGA144 (7x7)   | -                  | -    | 392                   |      |
|                                    |   | UFBGA144(10x10)  | -                  | -    | 417                   |      |
|                                    | Ambient temperature for 6 suffix  | Maximum power dissipation  | <del>-4</del> 0    | -    | 85                    | °C   |
| т.                                 | version   | Low power dissipation <sup>(9)</sup>   | -40                | -    | 105                   |      |
| TA                                 | Ambient temperature for 7 suffix  | Maximum power dissipation  | -40                | -    | 105                   | °C   |
|                                    | version   | Low power dissipation <sup>(9)</sup>   | -40                | -    | 125                   | °C   |
| т.                                 | lunction tomporature range  | 6 suffix version   | <del>-4</del> 0    | -    | 105                   | °C   |
| TJ                                 | Junction temperature range  | 7 suffix version   | -40                | -    | 125                   |      |

- 1. The over-drive mode is not supported at the voltage ranges from 1.7 to 2.1 V.
- V<sub>DD</sub>/V<sub>DDA</sub> minimum value of 1.7 V is obtained with the use of an external power supply supervisor (refer to Section 3.16.2: Internal reset OFF).
- 3. When the ADC is used, refer to Table 74: ADC characteristics.
- 4. If  $V_{REF+}$  pin is present, it must respect the following condition:  $V_{DDA}-V_{REF+} < 1.2 \text{ V}$ .
- 5. It is recommended to power  $V_{DD}$  and  $V_{DDA}$  from the same source. A maximum difference of 300 mV between  $V_{DD}$  and  $V_{DDA}$  can be tolerated during power-up and power-down operation.
- 6. The over-drive mode is not supported when the internal regulator is OFF.
- 7. To sustain a voltage higher than VDD+0.3, the internal Pull-up and Pull-Down resistors must be disabled
- 8. If  $T_A$  is lower, higher  $P_D$  values are allowed as long as  $T_J$  does not exceed  $T_{Jmax}$ .
- 9. In low power dissipation state,  $T_A$  can be extended to this range as long as  $T_J$  does not exceed  $T_{Jmax}$ .

Table 17. Limitations depending on the operating power supply range

| Operating power supply range                 | ower supply ADC operation f    |                       | Maximum HCLK<br>frequency vs Flash<br>memory wait states<br>(1)(2) | I/O operation                            | Possible Flash<br>memory<br>operations  |
|--|--------------------------------|-----------------------|--|--|---|
| V <sub>DD</sub> =1.7 to 2.1 V <sup>(3)</sup> | Conversion time up to 1.2 Msps | 20 MHz <sup>(4)</sup> | 168 MHz with 8 wait states and over-drive OFF                      | - No I/O compensation                    | 8-bit erase and program operations only |
| V <sub>DD</sub> = 2.1 to 2.4 V               | Conversion time up to 1.2 Msps | 22 MHz                | 180 MHz with 8 wait states and over-drive ON                       | - No I/O compensation                    | 16-bit erase and program operations     |
| V <sub>DD</sub> = 2.4 to 2.7 V               | Conversion time up to 2.4 Msps | 24 MHz                | 180 MHz with 7 wait states and over-drive ON                       | <ul><li>I/O compensation works</li></ul> | 16-bit erase and program operations     |
| $V_{DD} = 2.7 \text{ to}$<br>3.6 $V^{(5)}$   | Conversion time up to 2.4 Msps | 30 MHz                | 180 MHz with 5 wait states and over-drive ON                       | <ul><li>I/O compensation works</li></ul> | 32-bit erase and program operations     |

Applicable only when the code is executed from Flash memory. When the code is executed from RAM, no wait state is required.

- 4. Prefetch is not available.
- The voltage range for USB full speed PHYs can drop down to 2.7 V. However the electrical characteristics of D- and D+ pins will be degraded between 2.7 and 3 V.

#### 6.3.2 VCAP1/VCAP2 external capacitor

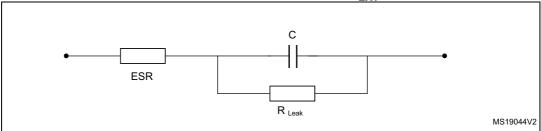
Stabilization for the main regulator is achieved by connecting an external capacitor  $C_{\text{EXT}}$  to the VCAP1/VCAP2 pins.  $C_{\text{EXT}}$  is specified in *Table 18*.



Thanks to the ART accelerator and the 128-bit Flash memory, the number of wait states given here does not impact the execution speed from Flash memory since the ART accelerator allows to achieve a performance equivalent to 0 wait state program execution.

V<sub>DD</sub>/V<sub>DDA</sub> minimum value of 1.7 V is obtained with the use of an external power supply supervisor (refer to Section 3.16.2: Internal reset OFF).

Figure 19. External capacitor C<sub>EXT</sub>



1. Legend: ESR is the equivalent series resistance.

Table 18. VCAP1/VCAP2 operating conditions<sup>(1)</sup>

| Symbol | Parameter                         | Conditions |
|--------|-----------------------------------|------------|
| CEXT   | Capacitance of external capacitor | 2.2 μF     |
| ESR    | ESR of external capacitor         | < 2 Ω      |

<sup>1.</sup> When bypassing the voltage regulator, the two 2.2  $\mu$ F V<sub>CAP</sub> capacitors are not required and should be replaced by two 100 nF decoupling capacitors.

#### 6.3.3 Operating conditions at power-up / power-down (regulator ON)

Subject to general operating conditions for T<sub>A</sub>.

Table 19. Operating conditions at power-up/power-down (regulator ON)

| Symbol           | Parameter                      | Min | Max |
|------------------|--------------------------------|-----|-----|
| 1                | V <sub>DD</sub> rise time rate | 20  | ∞   |
| t <sub>∨DD</sub> | V <sub>DD</sub> fall time rate | 20  | ∞   |

## 6.3.4 Operating conditions at power-up / power-down (regulator OFF)

Subject to general operating conditions for  $T_A$ .

Table 20. Operating conditions at power-up / power-down (regulator OFF)<sup>(1)</sup>

| Symbol            | Parameter  | Conditions | Min | Max | Unit  |
|-------------------|--|------------|-----|-----|-------|
| +                 | V <sub>DD</sub> rise time rate                           | Power-up   | 20  | ∞   |       |
| t∨DD              | V <sub>DD</sub> fall time rate                           | Power-down | 20  | 8   | μs/V  |
| + .               | V <sub>CAP_1</sub> and V <sub>CAP_2</sub> rise time rate | Power-up   | 20  | 8   | μ5/ ν |
| <sup>₹</sup> VCAP | V <sub>CAP_1</sub> and V <sub>CAP_2</sub> fall time rate | Power-down | 20  | 8   |       |

<sup>1.</sup> To reset the internal logic at power-down, a reset must be applied on pin PA0 when V<sub>DD</sub> reach below 1.08 V.

#### 6.3.5 Reset and power control block characteristics

The parameters given in *Table 21* are derived from tests performed under ambient temperature and V<sub>DD</sub> supply voltage conditions summarized in *Table 16*.



Table 21. reset and power control block characteristics

| Symbol  | Parameter   | Conditions  | Min  | Тур  | Max  | Unit     |
|---|---|---|------|------|------|----------|
|   |   | PLS[2:0]=000 (rising edge)  | 2.09 | 2.14 | 2.19 | V        |
|   |   | PLS[2:0]=000 (falling edge)   | 1.98 | 2.04 | 2.08 | V        |
|   |   | PLS[2:0]=001 (rising edge)  | 2.23 | 2.30 | 2.37 | V        |
|   |   | PLS[2:0]=001 (falling edge)   | 2.13 | 2.19 | 2.25 | V        |
|   |   | PLS[2:0]=010 (rising edge)  | 2.39 | 2.45 | 2.51 | V        |
|   |   | PLS[2:0]=010 (falling edge)   | 2.29 | 2.35 | 2.39 | V        |
|   |   | PLS[2:0]=011 (rising edge)  | 2.54 | 2.60 | 2.65 | V        |
| W   | Programmable voltage  | PLS[2:0]=011 (falling edge)   | 2.44 | 2.51 | 2.56 | V        |
| $V_{PVD}$   | detector level selection  | PLS[2:0]=100 (rising edge)  | 2.70 | 2.76 | 2.82 | V        |
|   |   | PLS[2:0]=100 (falling edge)   | 2.59 | 2.66 | 2.71 | ٧        |
|   |   | PLS[2:0]=101 (rising edge)  | 2.86 | 2.93 | 2.99 | V        |
|   |   | PLS[2:0]=101 (falling edge)   | 2.65 | 2.84 | 3.02 | V        |
|   |   | PLS[2:0]=110 (rising edge)  | 2.96 | 3.03 | 3.10 | V        |
|   |   | PLS[2:0]=110 (falling edge)   | 2.85 | 2.93 | 2.99 | V        |
|   |   | PLS[2:0]=111 (rising edge)  | 3.07 | 3.14 | 3.21 | V        |
|   |   | PLS[2:0]=111 (falling edge)   | 2.95 | 3.03 | 3.09 | V        |
| V <sub>PVDhyst</sub> <sup>(1)</sup>                   | PVD hysteresis  | -   | -    | 100  | -    | mV       |
| V   | Power-on/power-down   | Falling edge  | 1.60 | 1.68 | 1.76 | ٧        |
| V <sub>POR/PDR</sub>                                  | reset threshold   | Rising edge   | 1.64 | 1.72 | 1.80 | V        |
| V <sub>PDRhyst</sub> <sup>(1)</sup>                   | PDR hysteresis  | -   | ı    | 40   | -    | mV       |
| V   | Brownout level 1  | Falling edge  | 2.13 | 2.19 | 2.24 | ٧        |
| VBOR1   | threshold   | Rising edge   | 2.23 | 2.29 | 2.33 | V        |
| V   | Brownout level 2  | Falling edge  | 2.44 | 2.50 | 2.56 | <b>V</b> |
| V <sub>PDRhyst</sub> <sup>(1)</sup> V <sub>BOR1</sub> | threshold   | Rising edge   | 2.53 | 2.59 | 2.63 | >        |
| V   | Brownout level 3  | Falling edge  | 2.75 | 2.83 | 2.88 | >        |
| V <sub>BOR3</sub>                                     | threshold   | Rising edge   | 2.85 | 2.92 | 2.97 | >        |
| V <sub>BORhyst</sub> <sup>(1)</sup>                   | BOR hysteresis  | -   | ı    | 100  | -    | mV       |
| T <sub>RSTTEMPO</sub>                                 | POR reset temporization   | -   | 0.5  | 1.5  | 3.0  | ms       |
| I <sub>RUSH</sub> <sup>(1)</sup>                      | InRush current on<br>voltage regulator power-<br>on (POR or wakeup<br>from Standby) | -   | -    | 160  | 200  | mA       |
| E <sub>RUSH</sub> <sup>(1)</sup>                      | InRush energy on<br>voltage regulator power-<br>on (POR or wakeup<br>from Standby)  | V <sub>DD</sub> = 1.7 V, T <sub>A</sub> = 105 °C,<br>I <sub>RUSH</sub> = 171 mA for 31 μs | -    | -    | 5.4  | μC       |



- 1. Guaranteed by design, not tested in production.
- 2. The reset temporization is measured from the power-on (POR reset or wakeup from  $V_{BAT}$ ) to the instant when first instruction is read by the user application code.

#### 6.3.6 Over-drive switching characteristics

When the over-drive mode switches from enabled to disabled or disabled to enabled, the system clock is stalled during the internal voltage set-up.

The over-drive switching characteristics are given in *Table 22*. They are sbject to general operating conditions for  $T_A$ .

|           |                                | _                                       |     |     |     |      |
|-----------|--------------------------------|---|-----|-----|-----|------|
| Symbol    | Parameter                      | Conditions                              | Min | Тур | Max | Unit |
| Tod_swen  |                                | HSI                                     | -   | 45  | -   |      |
|           | Over_drive switch enable time  | HSE max for 4 MHz<br>and min for 26 MHz | 45  | -   | 100 |      |
|           |                                | External HSE<br>50 MHz                  | -   | 40  | -   | 0    |
|           | Over_drive switch disable time | HSI                                     | -   | 20  | -   | μs   |
| Tod_swdis |                                | HSE max for 4 MHz and min for 26 MHz.   | 20  | -   | 80  |      |
|           |                                | External HSE<br>50 MHz                  | -   | 15  | -   |      |

Table 22. Over-drive switching characteristics<sup>(1)</sup>

#### 6.3.7 Supply current characteristics

The current consumption is a function of several parameters and factors such as the operating voltage, ambient temperature, I/O pin loading, device software configuration, operating frequencies, I/O pin switching rate, program location in memory and executed binary code.

The current consumption is measured as described in *Figure 18: Current consumption measurement scheme*.

All the run-mode current consumption measurements given in this section are performed with a reduced code that gives a consumption equivalent to CoreMark code.

<sup>1.</sup> Guaranteed by design, not tested in production.

#### Typical and maximum current consumption

The MCU is placed under the following conditions:

- All I/O pins are in input mode with a static value at V<sub>DD</sub> or V<sub>SS</sub> (no load).
- All peripherals are disabled except if it is explicitly mentioned.
- The Flash memory access time is adjusted both to f<sub>HCLK</sub> frequency and V<sub>DD</sub> range (see *Table 17: Limitations depending on the operating power supply range*).
- Regulator ON
- The voltage scaling and over-drive mode are adjusted to f<sub>HCLK</sub> frequency as follows:
  - Scale 3 for f<sub>HCLK</sub> ≤120 MHz
  - Scale 2 for 120 MHz < f<sub>HCLK</sub> ≤144 MHz
  - Scale 1 for 144 MHz <  $f_{HCLK}$  ≤180 MHz. The over-drive is only ON at 180 MHz.
- The system clock is HCLK, f<sub>PCLK1</sub> = f<sub>HCLK</sub>/4, and f<sub>PCLK2</sub> = f<sub>HCLK</sub>/2.
- External clock frequency is 8 MHz and PLL is ON when f<sub>HCLK</sub> is higher than 16 MHz.
- Flash is enabled except if explicitly mentioned as disable.
- The maximum values are obtained for V<sub>DD</sub> = 3.6 V and a maximum ambient temperature (T<sub>A</sub>), and the typical values for T<sub>A</sub>= 25 °C and V<sub>DD</sub> = 3.3 V unless otherwise specified.



Table 23. Typical and maximum current consumption in Run mode, code with data processing running from Flash memory (ART accelerator enabled except prefetch) or RAM<sup>(1)</sup>

|                 |                                  |   |                         |                         |                        | Max <sup>(2)</sup>        |                         |      |      |      |    |
|-----------------|----------------------------------|---|-------------------------|-------------------------|------------------------|---------------------------|-------------------------|------|------|------|----|
| Symbol          | Parameter                        | Conditions                                  | f <sub>HCLK</sub> (MHz) | Тур                     | T <sub>A</sub> = 25 °C | T <sub>A</sub> =<br>85 °C | T <sub>A</sub> = 105 °C | Unit |      |      |    |
|                 |                                  |   | 180                     | 72                      | 83.0 <sup>(5)</sup>    | 100.0                     | 110.0 <sup>(5)</sup>    |      |      |      |    |
|                 |                                  |   | 168                     | 65                      | 71.0                   | 95.3                      | 101.0                   |      |      |      |    |
|                 |                                  |   | 150                     | 59                      | 63.6                   | 85.4                      | 100.8                   |      |      |      |    |
|                 |                                  | External clock,                             | 144 <sup>(6)</sup>      | 54                      | 58.4                   | 78.8                      | 91.2                    |      |      |      |    |
|                 |                                  | PLL ON, all peripherals                     | 120                     | 40                      | 44.9                   | 62.1                      | 73.2                    |      |      |      |    |
|                 |                                  | enabled <sup>(3)(4)</sup>                   | 90                      | 30                      | 35.3                   | 50.7                      | 60.0                    |      |      |      |    |
|                 |                                  |   | 60                      | 21                      | 25.5                   | 39.2                      | 46.8                    |      |      |      |    |
|                 |                                  |   | 30                      | 12                      | 16.2                   | 28.1                      | 36.0                    |      |      |      |    |
|                 |                                  |   | 25                      | 10                      | 14.41                  | 26.17                     | 32.4                    |      |      |      |    |
|                 | Supply<br>current in<br>RUN mode | HSI, PLL OFF,<br>all peripherals<br>enabled | all peripherals         | 16                      | 6                      | 11.4                      | 23.1                    | 25.2 |      |      |    |
|                 |                                  |   |                         | all peripherals enabled |                        | 8                         | 3                       | 9.5  | 20.3 | 22.5 |    |
|                 |                                  |   |                         |                         | 4                      | 2.3                       | 8.3                     | 18.9 | 21.1 |      |    |
| I               |                                  |   |                         |                         |                        | 2                         | 1.8                     | 7.7  | 18.1 | 20.5 | mA |
| I <sub>DD</sub> |                                  |   | 180                     | 32                      | 42.0 <sup>(5)</sup>    | 59.0                      | 75.0 <sup>(5)</sup>     | IIIA |      |      |    |
|                 |                                  |   | 168                     | 29                      | 35.5                   | 51.4                      | 55.7                    |      |      |      |    |
|                 |                                  |   | 150                     | 26                      | 31.5                   | 47.8                      | 51.9                    |      |      |      |    |
|                 |                                  | External clock,                             | 144 <sup>(6)</sup>      | 24                      | 29.2                   | 44.7                      | 48.6                    |      |      |      |    |
|                 |                                  | PLL ON, all Peripherals                     | 120                     | 18                      | 23.3                   | 36.8                      | 40.4                    |      |      |      |    |
|                 |                                  | disabled <sup>(3)</sup>                     | 90                      | 14                      | 19.0                   | 31.8                      | 35.1                    |      |      |      |    |
|                 |                                  |   | 60                      | 10                      | 14.7                   | 26.9                      | 29.9                    |      |      |      |    |
|                 |                                  |   | 30                      | 6                       | 10.7                   | 22.1                      | 24.9                    |      |      |      |    |
|                 |                                  |   | 25                      | 5                       | 9.96                   | 21.24                     | 24.02                   |      |      |      |    |
|                 |                                  |   | 16                      | 3                       | 8.7                    | 18.9                      | 21.9                    |      |      |      |    |
| l               |                                  | HSI, PLL OFF, all peripherals               | 8                       | 2                       | 8.1                    | 17.8                      | 20.9                    |      |      |      |    |
|                 |                                  | disabled <sup>(3)</sup>                     | 4                       | 1.7                     | 7.64                   | 17.23                     | 20.32                   |      |      |      |    |
|                 |                                  |   | 2                       | 1.4                     | 7.4                    | 16.94                     | 20.03                   |      |      |      |    |

<sup>1.</sup> Code and data processing running from SRAM1 using boot pins.

6. Overdrive OFF

<sup>2.</sup> Guaranteed by characterization, not tested in production.

When analog peripheral blocks such as ADCs, DACs, HSE, LSE, HSI, or LSI are ON, an additional power consumption should be considered.

When the ADC is ON (ADON bit set in the ADC\_CR2 register), add an additional power consumption of 1.6 mA per ADC for the analog part.

<sup>5.</sup> Tested in production.

Table 24. Typical and maximum current consumption in Run mode, code with data processing running from Flash memory (ART accelerator enabled with prefetch) or RAM<sup>(1)</sup>

|                 |                   | r Conditions f  | AIXT ACCEIETA           |   |   | Max <sup>(2)</sup>        |                         |      |       |       |      |                 |     |    |      |      |      |  |
|-----------------|-------------------|---|-------------------------|---|---|---------------------------|-------------------------|------|-------|-------|------|-----------------|-----|----|------|------|------|--|
| Symbol          | Parameter         | Conditions  | f <sub>HCLK</sub> (MHz) | Тур                                     | T <sub>A</sub> = 25 °C                    | T <sub>A</sub> =<br>85 °C | T <sub>A</sub> = 105 °C | Unit |       |       |      |                 |     |    |      |      |      |  |
|                 |                   |   | 180                     | 86                                      | 93.0                                      | 115.0                     | 125.0                   |      |       |       |      |                 |     |    |      |      |      |  |
|                 |                   |   | 168 <sup>(5)</sup>      | 79                                      | 85.1                                      | 111.2                     | 117.7                   |      |       |       |      |                 |     |    |      |      |      |  |
|                 |                   |   | 150                     | 73                                      | 79.6                                      | 104.8                     | 111.2                   |      |       |       |      |                 |     |    |      |      |      |  |
|                 |                   | External clock,   | 144 <sup>(5)</sup>      | 68                                      | 73.5                                      | 97.3                      | 103.3                   |      |       |       |      |                 |     |    |      |      |      |  |
|                 |                   | PLL ON,<br>all peripherals<br>enabled <sup>(3)(4)</sup>       | 120                     | 54                                      | 59.3                                      | 79.7                      | 84.7                    |      |       |       |      |                 |     |    |      |      |      |  |
|                 |                   |   | 90                      | 42                                      | 47.23                                     | 65.50                     | 70.10                   |      |       |       |      |                 |     |    |      |      |      |  |
|                 |                   |   | 60                      | 29                                      | 33.7                                      | 49.5                      | 53.4                    |      |       |       |      |                 |     |    |      |      |      |  |
|                 |                   |   | 30                      | 16                                      | 20.8                                      | 34.0                      | 37.4                    |      |       |       |      |                 |     |    |      |      |      |  |
|                 |                   |   | 25                      | 13                                      | 18.4                                      | 31.2                      | 34.5                    |      |       |       |      |                 |     |    |      |      |      |  |
|                 |                   | HSI, PLL OFF,<br>all peripherals<br>enabled <sup>(3)(4)</sup> | 16                      | 8                                       | 13.8                                      | 25.0                      | 28.3                    |      |       |       |      |                 |     |    |      |      |      |  |
|                 |                   |   | 8                       | 5                                       | 10.8                                      | 21.1                      | 24.2                    |      |       |       |      |                 |     |    |      |      |      |  |
|                 |                   |   | 4                       | 3.0                                     | 9.1                                       | 18.9                      | 22.0                    |      |       |       |      |                 |     |    |      |      |      |  |
| ,               | Supply current in |   | 2                       | 2.1                                     | 8.1                                       | 17.8                      | 20.9                    | mA   |       |       |      |                 |     |    |      |      |      |  |
| I <sub>DD</sub> | RUN mode          |   | 180                     | 46                                      | 55.0                                      | 75.0                      | 86.0                    | IIIA |       |       |      |                 |     |    |      |      |      |  |
|                 |                   |   | 168                     | 43                                      | 49.6                                      | 67.5                      | 72.6                    |      |       |       |      |                 |     |    |      |      |      |  |
|                 |                   |   | 150                     | 41                                      | 48.2                                      | 65.8                      | 70.8                    |      |       |       |      |                 |     |    |      |      |      |  |
|                 |                   | External clock,   | 144 <sup>(5)</sup>      | 38                                      | 43.6                                      | 61.9                      | 66.8                    |      |       |       |      |                 |     |    |      |      |      |  |
|                 |                   |   | PLL ON,                 |   | · ·                                       |                           |                         |      |       |       | · ·  | all Peripherals | 120 | 32 | 37.3 | 53.7 | 58.0 |  |
|                 |                   | disabled <sup>(3)</sup>                                       | 90                      | 26                                      | 30.7                                      | 46.0                      | 50.0                    |      |       |       |      |                 |     |    |      |      |      |  |
|                 |                   |   | -                       |   |   |                           | 60                      | 18   | 22.8  | 36.4  | 40.1 |                 |     |    |      |      |      |  |
|                 | all p             |   | 30                      | 10                                      | 14.9                                      | 27.1                      | 30.2                    |      |       |       |      |                 |     |    |      |      |      |  |
|                 |                   |   | 25                      | 9                                       | 13.55                                     | 25.40                     | 28.54                   |      |       |       |      |                 |     |    |      |      |      |  |
|                 |                   |   | 16                      | 5                                       | 11.1                                      | 21.8                      | 25.0                    |      |       |       |      |                 |     |    |      |      |      |  |
|                 |                   | HSI, PLL OFF,   | 8                       | 3                                       | 9.5                                       | 19.4                      | 22.5                    |      |       |       |      |                 |     |    |      |      |      |  |
|                 |                   | all peripherals - disabled <sup>(3)</sup>                     | all peripherals         | all peripherals disabled <sup>(3)</sup> | all peripherals — disabled <sup>(3)</sup> | 4                         | 2.4                     | 8.34 | 18.10 | 21.17 |      |                 |     |    |      |      |      |  |
|                 |                   |   | 2                       | 1.8                                     | 7.77                                      | 17.39                     | 20.50                   |      |       |       |      |                 |     |    |      |      |      |  |

<sup>1.</sup> Code and data processing running from SRAM1 using boot pins.

<sup>5.</sup> Overdrive OFF



<sup>2.</sup> Guaranteed by characterization, not tested in production.

<sup>3.</sup> When analog peripheral blocks such as ADCs, DACs, HSE, LSE, HSI, or LSI are ON, an additional power consumption should be considered.

When the ADC is ON (ADON bit set in the ADC\_CR2 register), add an additional power consumption of 1.6 mA per ADC for the analog part.

Table 25. Typical and maximum current consumption in Run mode, code with data processing running from Flash memory (ART accelerator disabled)

|                 |                   |   |                         |   |   | Max <sup>(1)</sup>                        |   |   |      |      |      |       |       |  |
|-----------------|-------------------|---|-------------------------|---|---|---|---|---|------|------|------|-------|-------|--|
| Symbol          | Parameter         | Conditions  | f <sub>HCLK</sub> (MHz) | Тур                                     | TA=<br>25 °C                            | TA=85 °C                                  | TA=105 °C                               | Unit                                    |      |      |      |       |       |  |
|                 |                   |   | 180                     | 81                                      | 89.0                                    | 110.0                                     | 120.0                                   |   |      |      |      |       |       |  |
|                 |                   |   | 168 <sup>(4)</sup>      | 74                                      | 80.2                                    | 105.7                                     | 112.0                                   |   |      |      |      |       |       |  |
|                 |                   |   | 150                     | 69                                      | 74.9                                    | 99.5                                      | 105.6                                   |   |      |      |      |       |       |  |
|                 |                   | External clock,   | 144 <sup>(4)</sup>      | 63                                      | 69.3                                    | 92.4                                      | 98.1                                    |   |      |      |      |       |       |  |
|                 |                   | PLL ON,<br>all peripherals<br>enabled <sup>(2)(3)</sup> | 120                     | 51                                      | 56.3                                    | 76.1                                      | 81.1                                    |   |      |      |      |       |       |  |
|                 |                   |   | 90                      | 40                                      | 45.32                                   | 63.19                                     | 67.63                                   |   |      |      |      |       |       |  |
|                 |                   |   | 60                      | 28                                      | 33.1                                    | 48.7                                      | 52.6                                    |   |      |      |      |       |       |  |
|                 |                   |   | 30                      | 16                                      | 20.8                                    | 34.0                                      | 37.4                                    |   |      |      |      |       |       |  |
|                 | Supply            |   | 25                      | 13                                      | 18.4                                    | 31.2                                      | 34.5                                    |   |      |      |      |       |       |  |
|                 |                   | External clock,<br>PLL ON,<br>all Peripherals           | 16                      | 8                                       | 13.8                                    | 25.0                                      | 28.2                                    |   |      |      |      |       |       |  |
|                 |                   |   |                         |   |   |   | 8                                       | 5                                       | 10.8 | 21.1 | 24.2 |       |       |  |
|                 |                   |   |                         |   |   |   |   | 4                                       | 3.0  | 9.1  | 19.0 | 22.0  |       |  |
|                 | Supply current in |   | 2                       | 2.1 8.1 17.9                            | 20.9                                    | m ^                                       |   |   |      |      |      |       |       |  |
| I <sub>DD</sub> | RUN mode          |   | 180                     | 41                                      | 47.0                                    | 69.0                                      | 79.0                                    | mA                                      |      |      |      |       |       |  |
|                 |                   | disabled <sup>(2)(3)</sup>                              | 168                     | 38                                      | 43.2                                    | 61.9                                      | 67.1                                    |   |      |      |      |       |       |  |
|                 |                   |   | 150                     | 37                                      | 41.8                                    | 60.3                                      | 65.4                                    |   |      |      |      |       |       |  |
|                 |                   |   | 144 <sup>(4)</sup>      | 34                                      | 39.3                                    | 56.9                                      | 61.6                                    |   |      |      |      |       |       |  |
|                 |                   |   | 120                     | 29                                      | 34.3                                    | 50.2                                      | 54.4                                    |   |      |      |      |       |       |  |
|                 |                   |   | 90                      | 24                                      | 28.8                                    | 43.6                                      | 47.5                                    |   |      |      |      |       |       |  |
|                 |                   | HSI, PLL OFF, all peripherals                           | 60                      | 17                                      | 22.0                                    | 35.6                                      | 39.2                                    |   |      |      |      |       |       |  |
|                 |                   | disabled <sup>(3)</sup>                                 | 30                      | 10                                      | 14.8                                    | 27.0                                      | 30.1                                    |   |      |      |      |       |       |  |
|                 |                   |   | 25                      | 8                                       | 13.51                                   | 25.36                                     | 28.47                                   |   |      |      |      |       |       |  |
|                 |                   |   | 16                      | 5                                       | 11.1                                    | 21.8                                      | 24.9                                    |   |      |      |      |       |       |  |
|                 |                   | HSI, PLL OFF,   | 8                       | 3                                       | 9.5                                     | 19.4                                      | 22.5                                    |   |      |      |      |       |       |  |
|                 |                   | á   | all Peripherals —       | all Peripherals disabled <sup>(3)</sup> | all Peripherals disabled <sup>(3)</sup> | all Peripherals — disabled <sup>(3)</sup> | all Peripherals disabled <sup>(3)</sup> | all Peripherals disabled <sup>(3)</sup> | 4    | 2.3  | 8.35 | 18.12 | 21.17 |  |
|                 |                   |   | 2                       | 1.8                                     | 7.78                                    | 17.42                                     | 20.51                                   |   |      |      |      |       |       |  |

<sup>1.</sup> Guaranteed by characterization, not tested in production unless otherwise specified.

<sup>2.</sup> When analog peripheral blocks such as ADCs, DACs, HSE, LSE, HSI, or LSI are ON, an additional power consumption should be considered.

<sup>3.</sup> When the ADC is ON (ADON bit set in the ADC\_CR2 register), add an additional power consumption of 1.6 mA per ADC for the analog part.

<sup>4.</sup> Overdrive OFF

Table 26. Typical and maximum current consumption in Sleep mode<sup>(1)</sup>

|        |                  |                  |                   | fHCLK              |       |                           | Max                       |                           |       |       |       |  |
|--------|------------------|------------------|-------------------|--------------------|-------|---------------------------|---------------------------|---------------------------|-------|-------|-------|--|
| Symbol | Parameter        | Conditions       |                   | (MHz)              | Тур   | T <sub>A</sub> = 25<br>°C | T <sub>A</sub> = 25<br>°C | T <sub>A</sub> = 25<br>°C | Unit  |       |       |  |
|        |                  |                  |                   | 180                | 51.2  | 59.00                     | 77.25                     | 102.00                    |       |       |       |  |
|        |                  |                  |                   | 168 <sup>(2)</sup> | 46.8  | 53.94                     | 66.48                     | 79.40                     |       |       |       |  |
|        |                  |                  |                   | 150                | 42.2  | 49.26                     | 60.84                     | 73.41                     |       |       |       |  |
|        |                  |                  |                   |                    |       | External                  | 144 <sup>(2)</sup>        | 38.6                      | 45.37 | 55.47 | 66.96 |  |
|        | Supply           |                  | clock,<br>PLL ON, | 120                | 29.3  | 35.70                     | 42.49                     | 51.46                     |       |       |       |  |
|        |                  | all              | Flash on          | 90                 | 22.8  | 29.17                     | 34.78                     | 43.12                     |       |       |       |  |
| IDD    | current in Sleep | peripherals      |                   | 60                 | 16.3  | 22.41                     | 27.12                     | 34.83                     | mA    |       |       |  |
|        | mode             | enabled          |                   | 30                 | 10.1  | 16.03                     | 19.72                     | 26.86                     |       |       |       |  |
|        |                  |                  |                   | 25                 | 9.0   | 14.92                     | 18.41                     | 25.38                     |       |       |       |  |
|        |                  |                  | 16                | 6.5                | 13.10 | 15.1                      | 22.3                      |                           |       |       |       |  |
|        |                  |                  | HSI, PLL          | 8                  | 5.2   | 12.31                     | 13.5                      | 20.4                      |       |       |       |  |
|        |                  | off, Flash<br>on | 4                 | 4.5                | 11.63 | 12.5                      | 19.3                      |                           |       |       |       |  |
|        |                  | Off              | 2                 | 4.1                | 11.23 | 12.0                      | 18.8                      |                           |       |       |       |  |

Table 26. Typical and maximum current consumption in Sleep mode<sup>(1)</sup> (continued)

|        |                  |                            |   | fHCLK              |       |                           | Max                       |                           |      |
|--------|------------------|----------------------------|---|--------------------|-------|---------------------------|---------------------------|---------------------------|------|
| Symbol | Parameter        | Condi                      | tions                                     | (MHz)              | Тур   | T <sub>A</sub> = 25<br>°C | T <sub>A</sub> = 25<br>°C | T <sub>A</sub> = 25<br>°C | Unit |
|        |                  |                            |   | 180                | 11.36 | 17.59                     | 28.2                      | 51.6                      |      |
|        |                  |                            |   | 168 <sup>(2)</sup> | 10.20 | 16.19                     | 22.0                      | 31.8                      |      |
|        |                  |                            |   | 150                | 9.53  | 15.59                     | 21.1                      | 30.9                      |      |
|        |                  |                            |   | 144 <sup>(2)</sup> | 8.90  | 14.87                     | 19.7                      | 28.4                      |      |
|        |                  |                            | Flash on                                  | 120                | 7.35  | 13.24                     | 16.5                      | 23.3                      |      |
|        |                  |                            |   | 90                 | 6.39  | 12.40                     | 15.3                      | 21.9                      |      |
|        |                  |                            |   | 60                 | 5.28  | 11.17                     | 14.1                      | 20.7                      |      |
|        |                  |                            |   | 30                 | 4.43  | 10.31                     | 13.1                      | 19.6                      |      |
|        |                  |                            |   | 25                 | 4.23  | 10.12                     | 12.85                     | 19.30                     |      |
|        |                  |                            | 180                                       | 8.3                | 13.44 | 30.72                     | 37.20                     |                           |      |
|        |                  |                            | 168 <sup>(2)</sup>                        | 7.3                | 12.25 | 25.16                     | 28.80                     | ı                         |      |
|        |                  | External clock, PLL on all | Flash in<br>Deep<br>Power<br>Down<br>mode | 150                | 6.7   | 11.60                     | 24.27                     | 27.84                     | mA   |
|        | Supply           |                            |   | 144 <sup>(2)</sup> | 6.1   | 11.08                     | 23.25                     | 26.28                     |      |
| IDD    | current in Sleep |                            |   | 120                | 4.7   | 9.64                      | 20.95                     | 23.72                     |      |
|        | mode             | peripherals disabled       |   | 90                 | 3.8   | 8.80                      | 19.77                     | 22.57                     |      |
|        |                  |                            |   | 60                 | 2.8   | 7.74                      | 18.69                     | 21.32                     | ]    |
|        |                  |                            |   | 30                 | 2.0   | 6.89                      | 17.66                     | 20.40                     |      |
|        |                  |                            |   | 25                 | 1.8   | 6.70                      | 17.43                     | 20.17                     |      |
|        |                  |                            |   | 180                | 8.3   | 13.44                     | 30.72                     | 37.20                     |      |
|        |                  |                            |   | 168 <sup>(2)</sup> | 7.3   | 12.25                     | 25.16                     | 28.80                     |      |
|        |                  |                            |   | 150                | 6.7   | 11.60                     | 24.27                     | 27.84                     |      |
|        |                  |                            | Flash in                                  | 144 <sup>(2)</sup> | 6.1   | 11.08                     | 23.25                     | 26.28                     |      |
|        |                  |                            | STOP                                      | 120                | 4.7   | 9.64                      | 20.95                     | 23.72                     |      |
|        |                  |                            | mode                                      | 90                 | 3.8   | 8.80                      | 19.77                     | 22.57                     |      |
|        |                  |                            |   | 60                 | 2.8   | 7.74                      | 18.69                     | 21.32                     |      |
|        |                  |                            |   | 30                 | 2.0   | 6.89                      | 17.66                     | 20.40                     |      |
|        |                  |                            |   | 25                 | 1.8   | 6.70                      | 17.43                     | 20.17                     |      |
|        | 1                | 1                          | 1   | 1                  | 1     | 1                         | 1                         |                           | ·    |

Table 26. Typical and maximum current consumption in Sleep mode<sup>(1)</sup> (continued)

|        |                   |                      |                  | fHCLK |      |                           | Max                       |                           |      |
|--------|-------------------|----------------------|------------------|-------|------|---------------------------|---------------------------|---------------------------|------|
| Symbol | Parameter         | Conditions           |                  | (MHz) | Тур  | T <sub>A</sub> = 25<br>°C | T <sub>A</sub> = 25<br>°C | T <sub>A</sub> = 25<br>°C | Unit |
|        |                   |                      |                  | 16    | 3.89 | 4.93                      | 11.72                     | 18.54                     |      |
|        |                   |                      | Flash on         | 8     | 2.45 | 3.29                      | 11.66                     | 18.46                     |      |
|        |                   |                      | riasii oii       | 4     | 1.69 | 2.56                      | 11.60                     | 18.40                     |      |
|        |                   |                      | 2                | 1.28  | 2.22 | 11.57                     | 18.37                     |                           |      |
|        |                   | LIOL DIL             | Flash in<br>Deep | 16    | 1.0  | 6.65                      | 16.54                     | 19.50                     |      |
| IDD    | Supply current in | HSI, PLL<br>off, all |                  | 8     | 0.9  | 6.93                      | 16.48                     | 19.45                     | A    |
| IDD    | Sleep             | peripherals          | Power<br>Down    | 4     | 0.9  | 6.90                      | 16.43                     | 19.39                     | mA   |
|        | mode              | disabled             | mode             | 2     | 0.9  | 6.88                      | 16.41                     | 19.37                     | 1    |
|        |                   |                      |                  | 16    | 1.0  | 6.7                       | 16.5                      | 19.5                      |      |
|        |                   |                      | Flash in         | 8     | 0.9  | 6.9                       | 16.5                      | 19.5                      |      |
|        |                   | STOP<br>mode         | 4                | 0.9   | 6.9  | 16.4                      | 19.4                      |                           |      |
|        |                   |                      |                  | 2     | 0.9  | 6.9                       | 16.4                      | 19.4                      |      |

<sup>1.</sup> Guaranteed by characterization, not tested in production unless otherwise specified.

<sup>2.</sup> Overdrive OFF

Table 27. Typical and maximum current consumptions in Stop mode

|                                     |   |   | Tvn                       |                                       | Max                       |  |      |
|-------------------------------------|---|---|---------------------------|---------------------------------------|---------------------------|--|------|
| Symbol                              | Parameter   | Conditions  | Тур                       | ٧                                     | v <sub>DD</sub> = 3.6     | V                                      | Unit |
|                                     |   |   | T <sub>A</sub> =<br>25 °C | T <sub>A</sub> = 25 °C <sup>(1)</sup> | T <sub>A</sub> =<br>85 °C | T <sub>A</sub> = 105 °C <sup>(1)</sup> |      |
|                                     | Supply current in Stop mode with  Flash memory in Stop mode, all oscillators OFF, no independent watchdog     |   | 0.234                     | 1.2                                   | 10                        | 16                                     |      |
| I <sub>DD_STOP_NM</sub>             | voltage regulator in main regulator mode  | Flash memory in Deep power down mode, all oscillators OFF, no independent watchdog  | 0.205                     | 1                                     | 9.5                       | 15                                     |      |
| (normal<br>mode)                    | Supply current in Stop mode with  | Flash memory in Stop mode, all oscillators OFF, no independent watchdog   | 0.15                      | 0.95                                  | 8.5                       | 14                                     |      |
|                                     | voltage regulator in<br>Low Power regulator<br>mode   | Flash memory in Deep power down mode, all oscillators OFF, no independent watchdog  | 0.121                     | 0.9                                   | 6                         | 12                                     | mA   |
| I <sub>DD</sub> STOP UD             | Supply current in<br>Stop mode with<br>voltage regulator in<br>main regulator and<br>under-drive mode         | Flash memory in Deep power<br>down mode, main regulator in<br>under-drive mode, all oscillators<br>OFF, no independent watchdog         | 0.119                     | 0.4                                   | 3                         | 5                                      |      |
| <sub>M</sub> (under-<br>drive mode) | Supply current in<br>Stop mode with<br>voltage regulator in<br>Low Power regulator<br>and under-drive<br>mode | Flash memory in Deep power<br>down mode, Low Power<br>regulator in under-drive mode,<br>all oscillators OFF, no<br>independent watchdog | 0.055                     | 0.35                                  | 3                         | 5                                      |      |

<sup>1.</sup> Data based on characterization, tested in production.

Table 28. Typical and maximum current consumptions in Standby mode

|                      |  |   |                         | Typ <sup>(1)</sup>         |                         |                        | Max <sup>(2)</sup>     |                         |      |
|----------------------|--|---|-------------------------|----------------------------|-------------------------|------------------------|------------------------|-------------------------|------|
| Symbol               | Parameter  | Conditions  | T <sub>A</sub> = 25 °C  |                            |                         | T <sub>A</sub> = 25 °C | T <sub>A</sub> = 85 °C | T <sub>A</sub> = 105 °C | Unit |
|                      |  |   | V <sub>DD</sub> = 1.7 V | V <sub>DD</sub> =<br>2.4 V | V <sub>DD</sub> = 3.3 V | ٧                      | <sub>DD</sub> = 3.3    | V                       |      |
|                      | Backup SRAM ON, and LSE oscillator in low power mode | 2.43  | 3.44                    | 4.12                       | 7                       | 20                     | 36                     |                         |      |
|                      |  | Backup SRAM OFF, RTC ON and LSE oscillator in low power mode  | 1.81                    | 2.81                       | 3.33                    | 6                      | 17                     | 31                      |      |
| I <sub>DD</sub> STBY | Supply current in                                    | Backup SRAM ON, RTC ON and LSE oscillator in high drive mode  | 3.32                    | 4.33                       | 4.95                    | 8                      | 21                     | 37                      | μA   |
| _                    | Standby mode   | Backup SRAM OFF, RTC ON and LSE oscillator in high drive mode | 2.57                    | 3.59                       | 4.16                    | 7                      | 18                     | 32                      |      |
|                      |  | Backup SRAM ON, RTC and LSE OFF                               | 2.03                    | 2.73                       | 3.5                     | 6 <sup>(3)</sup>       | 19                     | 35 <sup>(3)</sup>       |      |
|                      |  | Backup SRAM OFF, RTC and LSE OFF                              | 1.28                    | 1.97                       | 2.03                    | 5 <sup>(3)</sup>       | 16                     | 30 <sup>(3)</sup>       |      |

<sup>1.</sup> When the PDR is OFF (internal reset is OFF), the typical current consumption is reduced by 1.2  $\mu$ A.

<sup>2.</sup> Based on characterization, not tested in production unless otherwise specified.

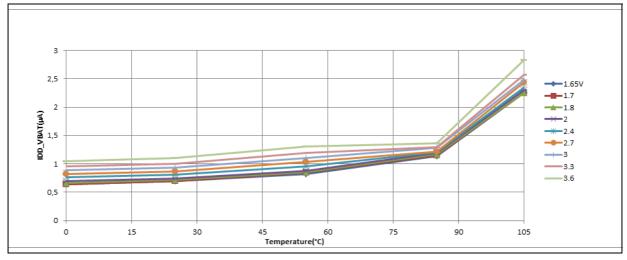
<sup>3.</sup> Tested in production.

Table 29. Typical and maximum current consumptions in V<sub>BAT</sub> mode

|                      |                            |   |                          | Тур                         |                          | Ма                                       | x <sup>(2)</sup> |      |
|----------------------|----------------------------|---|--------------------------|-----------------------------|--------------------------|--|------------------|------|
| Symbol               | Parameter                  | Conditions <sup>(1)</sup>                                     | 1                        | A = 25 °                    | C                        | T <sub>A</sub> = T <sub>A</sub> = 105 °C |                  | Unit |
|                      |                            |   | V <sub>BAT</sub> = 1.7 V | V <sub>BAT</sub> =<br>2.4 V | V <sub>BAT</sub> = 3.3 V | V <sub>BAT</sub> =                       | = 3.6 V          |      |
|                      |                            | Backup SRAM ON, RTC ON and LSE oscillator in low power mode   | 1.46                     | 1.62                        | 1.83                     | 6  | 11               |      |
|                      |                            | Backup SRAM OFF, RTC ON and LSE oscillator in low power mode  | 0.72                     | 0.85                        | 1.00                     | 3  | 5                |      |
| I <sub>DD_VBAT</sub> | Backup<br>domain<br>supply | Backup SRAM ON, RTC ON and LSE oscillator in high drive mode  | 2.24                     | 2.40                        | 2.64                     | -  | -                | μΑ   |
|                      | current                    | Backup SRAM OFF, RTC ON and LSE oscillator in high drive mode | 1.50                     | 1.64                        | 1.86                     | -  | 1                |      |
|                      |                            | Backup SRAM ON, RTC and LSE OFF                               | 0.74                     | 0.75                        | 0.78                     | 5  | 10               |      |
|                      |                            | Backup SRAM OFF, RTC and LSE OFF                              | 0.05                     | 0.05                        | 0.05                     | 2  | 4                |      |

<sup>1.</sup> Crystal used: Abracon ABS07-120-32.768 kHz-T with a  $\rm C_L$  of 6 pF for typical values.

Figure 20. Typical  $V_{BAT}$  current consumption (RTC ON/backup RAM OFF and LSE in low power mode)



<sup>2.</sup> Based on characterization, not tested in production.

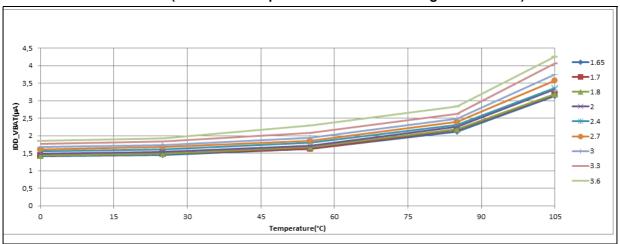


Figure 21. Typical V<sub>BAT</sub> current consumption (RTC ON/backup RAM OFF and LSE in high drive mode)

### Additional current consumption

The MCU is placed under the following conditions:

- All I/O pins are configured in analog mode.
- The Flash memory access time is adjusted to fHCLK frequency.
- The voltage scaling is adjusted to fHCLK frequency as follows:
  - Scale 3 for f<sub>HCLK</sub> ≤ 120 MHz,
  - Scale 2 for 120 MHz <  $f_{HCLK}$  ≤ 144 MHz
  - Scale 1 for 144 MHz <  $f_{HCLK}$  ≤ 180 MHz. The over-drive is only ON at 180 MHz.
- The system clock is HCLK, f<sub>PCLK1</sub> = f<sub>HCLK</sub>/4, and f<sub>PCLK2</sub> = f<sub>HCLK</sub>/2.
- HSE crystal clock frequency is 8 MHz.
- Flash is enabled except if explicitly mentioned as disable.
- When the regulator is OFF, V12 is provided externally as described in Table 16: General operating conditions
- T<sub>A</sub>= 25 °C.

Table 30. Typical current consumption in Run mode, code with data processing running from Flash memory or RAM, regulator ON (ART accelerator enabled except prefetch), VDD=1.7 V<sup>(1)</sup>

|                 |                                 |                            |                         |       |                        | Max                       |                            |      |
|-----------------|---------------------------------|----------------------------|-------------------------|-------|------------------------|---------------------------|----------------------------|------|
| Symbol          | Parameter                       | Conditions                 | f <sub>HCLK</sub> (MHz) | Тур   | T <sub>A</sub> = 25 °C | T <sub>A</sub> =<br>85 °C | T <sub>A</sub> =<br>105 °C | Unit |
|                 |                                 |                            | 168                     | 75.00 | 79.5                   | 101.6                     | 116.5                      |      |
|                 |                                 |                            | 150                     | 69.81 | 73.2                   | 93.4                      | 90.8                       |      |
|                 | Supply current in Run mode from |                            | 144                     | 64.43 | 68.1                   | 80.5                      | 83.4                       |      |
|                 |                                 | All Peripherals<br>enabled | 120                     | 52.00 | 59.2                   | 67.5                      | 70.5                       |      |
|                 |                                 |                            | 90                      | 40.59 | 45.95                  | 54.65                     | 58.01                      |      |
|                 |                                 |                            | 60                      | 28.42 | 33.2                   | 45.7                      | 52.4                       |      |
|                 |                                 |                            | 30                      | 15.94 | 19.1                   | 35.6                      | 44.5                       |      |
|                 |                                 |                            | 25                      | 13.54 | 14.8                   | 21.8                      | 28.4                       | mA   |
| I <sub>DD</sub> | V <sub>DD</sub> supply          |                            | 168                     | 38.67 | 42.25                  | 53.6                      | 61.4                       | IIIA |
|                 |                                 |                            | 150                     | 37.32 | 41.01                  | 52.9                      | 60.3                       |      |
|                 |                                 |                            | 144                     | 34.85 | 38.37                  | 50.4                      | 55.5                       |      |
|                 |                                 | All Peripherals            | 120                     | 29.87 | 36.08                  | 46.0                      | 48.6                       |      |
|                 |                                 | disabled                   | 90                      | 24.26 | 32.40                  | 43.8                      | 46.4                       |      |
|                 |                                 |                            | 60                      | 17.43 | 22.16                  | 32.7                      | 34.7                       |      |
|                 |                                 |                            | 30                      | 10.01 | 11.09                  | 24.7                      | 26.8                       |      |
|                 |                                 |                            | 25                      | 8.63  | 9.71                   | 16.57                     | 23.15                      |      |

When peripherals are enabled, the power consumption corresponding to the analog part of the peripherals (such as ADC, or DAC) is not included.

Table 31. Typical current consumption in Run mode, code with data processing running from Flash memory, regulator OFF (ART accelerator enabled except prefetch)<sup>(1)</sup>

| Symbol                              | Parameter   | Conditions              | f <sub>HCLK</sub> | VDD=              | =3.3 V          | VDD:              | =1.7 V          | Unit |  |
|-------------------------------------|---|-------------------------|-------------------|-------------------|-----------------|-------------------|-----------------|------|--|
| Symbol                              | Parameter   | Conditions              | (MHz)             | I <sub>DD12</sub> | I <sub>DD</sub> | I <sub>DD12</sub> | I <sub>DD</sub> | Oint |  |
|                                     |   |                         |                   | 168               | 61.72           | 1.6               | 60.15           | 1.5  |  |
|                                     |   |                         | 150               | 51.69             | 1.5             | 55.46             | 1.4             |      |  |
|                                     |   |                         | 144               | 51.45             | 1.5             | 50.94             | 1.3             |      |  |
|                                     | Supply current in Run mode from V <sub>12</sub> and V <sub>DD</sub> | All Peripherals enabled | 120               | 38.94             | 1.3             | 40.66             | 1.2             |      |  |
|                                     |   |                         | 90                | 29.48             | 1.1             | 28.18             | 1.0             |      |  |
|                                     |   |                         | 60                | 19.23             | 1.0             | 20.05             | 0.8             |      |  |
|                                     |   |                         | 30                | 10.41             | 0.9             | 11.26             | 0.7             |      |  |
|                                     |   |                         | 25                | 8.83              | 0.8             | 9.56              | 0.6             | mA   |  |
| I <sub>DD12</sub> / I <sub>DD</sub> |   |                         | 168               | 31.44             | 1.6             | 30.06             | 1.5             | IIIA |  |
|                                     | supply  |                         | 150               | 28.67             | 1.5             | 27.38             | 1.4             | -    |  |
|                                     |   |                         | 144               | 25.51             | 1.5             | 23.37             | 1.3             |      |  |
|                                     |   | All Peripherals         | 120               | 19.06             | 1.3             | 21.73             | 1.2             |      |  |
|                                     |   | disabled                | 90                | 14.83             | 1.2             | 14.74             | 1.0             |      |  |
|                                     |   |                         | 60                | 10.16             | 1.0             | 10.30             | 0.8             | -    |  |
|                                     |   |                         | 30                | 5.41              | 0.9             | 5.64              | 0.7             |      |  |
|                                     |   |                         | 25                | 4.599             | 0.8             | 4.80              | 0.6             |      |  |

<sup>1.</sup> When peripherals are enabled, the power consumption corresponding to the analog part of the peripherals (such as ADC, or DAC) is not included.

Table 32. Typical current consumption in Sleep mode, regulator ON,  $V_{DD}$ =1.7  $V^{(1)}$ 

|                 | <b>7,</b>                              |  |                         |      |                        | Max                       |                            |      |
|-----------------|--|--|-------------------------|------|------------------------|---------------------------|----------------------------|------|
| Symbol          | Parameter                              | Conditions                             | f <sub>HCLK</sub> (MHz) | Тур  | T <sub>A</sub> = 25 °C | T <sub>A</sub> =<br>85 °C | T <sub>A</sub> =<br>105 °C | Unit |
|                 |  |  | 168                     | 43.7 | 47.5                   | 66.5                      | 79.3                       |      |
|                 |  |  | 150                     | 39.2 | 42.7                   | 60.7                      | 73.3                       |      |
|                 | Supply current in                      | All Peripherals<br>enabled Flash<br>on | 144                     | 35.7 | 38.8                   | 55.3                      | 66.9                       |      |
|                 |  |  | 120                     | 26.5 | 28.6                   | 41.8                      | 51.6                       |      |
|                 |  |  | 90                      | 20.0 | 21.91                  | 33.85                     | 43.20                      |      |
|                 |  |  | 60                      | 13.6 | 15.2                   | 25.8                      | 34.9                       |      |
|                 |  |  | 30                      | 7.4  | 8.5                    | 18.4                      | 27.0                       |      |
| ı               |  |  | 25                      | 6.3  | 7.5                    | 16.9                      | 25.5                       | mA   |
| I <sub>DD</sub> | Sleep mode from V <sub>DD</sub> supply |  | 168                     | 7.3  | 8.6                    | 21.2                      | 31.9                       | ША   |
|                 |  |  | 150                     | 6.6  | 7.94                   | 20.4                      | 31.0                       |      |
|                 |  |  | 144                     | 6.0  | 7.3                    | 18.6                      | 28.5                       |      |
|                 |  | All Peripherals                        | 120                     | 4.6  | 5.5                    | 14.9                      | 23.4                       |      |
|                 |  | disabled, flash<br>on                  | 90                      | 3.6  | 4.6                    | 13.6                      | 22.1                       |      |
|                 |  |  | 60                      | 2.6  | 3.4                    | 12.5                      | 20.8                       |      |
|                 |  |  | 30                      | 1.8  | 2.7                    | 11.3                      | 19.7                       |      |
|                 |  |  | 25                      | 1.6  | 2.49                   | 11.09                     | 19.42                      |      |

When peripherals are enabled, the power consumption corresponding to the analog part of the peripherals (such as ADC, or DAC) is not included.

| Complete          | Davamatav                                       | Conditions               | £ (NALL=)               | VDD:              | =3.3 V          | VDD:              | =1.7 V          | Unit |
|-------------------|---|--------------------------|-------------------------|-------------------|-----------------|-------------------|-----------------|------|
| Symbol            | Parameter                                       | Conditions               | f <sub>HCLK</sub> (MHz) | I <sub>DD12</sub> | I <sub>DD</sub> | I <sub>DD12</sub> | I <sub>DD</sub> | -    |
|                   |   |                          | 180                     | 47.605            | 1.2             | NA                | NA              |      |
|                   |   |                          | 168                     | 44.35             | 1.0             | 41.53             | 0.8             |      |
|                   |   |                          | 150                     | 40.58             | 0.9             | 39.96             | 0.8             |      |
|                   |   | All Peripherals enabled  | 144                     | 35.68             | 0.9             | 34.60             | 0.7             |      |
|                   |   |                          | 120                     | 27.30             | 0.9             | 29.11             | 0.7             |      |
|                   |   |                          | 90                      | 20.69             | 0.8             | 19.78             | 0.6             |      |
|                   | Cumply average                                  |                          | 60                      | 13.88             | 0.7             | 13.36             | 0.6             |      |
|                   |   |                          | 30                      | 7.66              | 0.7             | 7.85              | 0.6             |      |
| 1 //              | Supply current in Sleep mode                    |                          | 25                      | 6.49              | 0.7             | 6.66              | 0.5             | mA   |
| $I_{DD12}/I_{DD}$ | from V <sub>12</sub> and V <sub>DD</sub> supply |                          | 180                     | 8.71              | 1.2             | NA                | NA              | IIIA |
|                   | VDD supply                                      |                          | 168                     | 7.00              | 0.9             | 8.42              | 0.8             |      |
|                   |   |                          | 150                     | 6.88              | 0.9             | 7.61              | 0.8             |      |
|                   |   |                          | 144                     | 6.29              | 0.9             | 6.99              | 0.7             |      |
|                   |   | All Peripherals disabled | 120                     | 4.87              | 0.9             | 5.95              | 0.7             |      |
|                   |   |                          | 90                      | 3.78              | 0.8             | 3.96              | 0.6             |      |
|                   |   |                          | 60                      | 2.66              | 0.7             | 2.80              | 0.6             |      |
|                   |   |                          | 30                      | 1.65              | 0.7             | 1.74              | 0.6             |      |
|                   |   |                          | 25                      | 1.45              | 0.7             | 1.52              | 0.5             |      |

Table 33. Typical current consumption in Sleep mode, regulator OFF<sup>(1)</sup>

#### I/O system current consumption

# The current consumption of the I/O system has two components: static and dynamic.

I/O static current consumption

All the I/Os used as inputs with pull-up generate current consumption when the pin is externally held low. The value of this current consumption can be simply computed by using the pull-up/pull-down resistors values given in *Table 56: I/O static characteristics*.

For the output pins, any external pull-down or external load must also be considered to estimate the current consumption.

Additional I/O current consumption is due to I/Os configured as inputs if an intermediate voltage level is externally applied. This current consumption is caused by the input Schmitt trigger circuits used to discriminate the input value. Unless this specific configuration is required by the application, this supply current consumption can be avoided by configuring these I/Os in analog mode. This is notably the case of ADC input pins which should be configured as analog inputs.



When peripherals are enabled, the power consumption corresponding to the analog part of the peripherals (such as ADC, or DAC) is not included.

#### Caution:

Any floating input pin can also settle to an intermediate voltage level or switch inadvertently, as a result of external electromagnetic noise. To avoid current consumption related to floating pins, they must either be configured in analog mode, or forced internally to a definite digital value. This can be done either by using pull-up/down resistors or by configuring the pins in output mode.

#### I/O dynamic current consumption

In addition to the internal peripheral current consumption (see *Table 35: Peripheral current consumption*), the I/Os used by an application also contribute to the current consumption. When an I/O pin switches, it uses the current from the MCU supply voltage to supply the I/O pin circuitry and to charge/discharge the capacitive load (internal or external) connected to the pin:

$$I_{SW} = V_{DD} \times f_{SW} \times C$$

#### where

 $I_{SW}$  is the current sunk by a switching I/O to charge/discharge the capacitive load  $V_{DD}$  is the MCU supply voltage

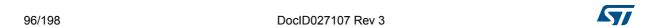
f<sub>SW</sub> is the I/O switching frequency

C is the total capacitance seen by the I/O pin:  $C = C_{INT} + C_{EXT}$ 

The test pin is configured in push-pull output mode and is toggled by software at a fixed frequency.

Table 34. Switching output I/O current consumption<sup>(1)</sup>

| Symbol            | Parameter     | Conditions                                   | I/O toggling<br>frequency<br>(fsw) | Тур  | Unit |
|-------------------|---------------|--|------------------------------------|------|------|
|                   |               |  | 2 MHz                              | 0.0  |      |
|                   |               |  | 8 MHz                              | 0.2  |      |
|                   |               |  | 25 MHz                             | 0.6  |      |
|                   |               | $V_{DD} = 3.3 \text{ V}$ $C = C_{INT}^{(2)}$ | 50 MHz                             | 1.1  |      |
|                   |               |  | 60 MHz                             | 1.3  |      |
|                   |               |  | 84 MHz                             | 1.8  |      |
|                   | I/O switching |  | 90 MHz                             | 1.9  |      |
| I <sub>DDIO</sub> | Current       |  | 2 MHz                              | 0.1  | mA   |
|                   |               |  | 8 MHz                              | 0.4  |      |
|                   |               | V <sub>DD</sub> = 3.3 V                      | 25 MHz                             | 1.23 | 1    |
|                   |               | $C_{EXT} = 0 pF$<br>$C = C_{INT} + C_{EXT}$  | 50 MHz                             | 2.43 |      |
|                   |               | + C <sub>S</sub>                             | 60 MHz                             | 2.93 |      |
|                   |               |  | 84 MHz                             | 3.86 |      |
|                   |               |  | 90 MHz                             | 4.07 |      |



| Symbol            | Parameter                        | Conditions   | I/O toggling<br>frequency<br>(fsw) | Тур   | Unit       |       |      |    |
|-------------------|----------------------------------|--|------------------------------------|-------|------------|-------|------|----|
|                   |                                  |  | 2 MHz                              | 0.18  |            |       |      |    |
|                   |                                  |  | 8 MHz                              | 0.67  | Unit<br>mA |       |      |    |
|                   |                                  | V <sub>DD</sub> = 3.3 V                              | 25 MHz                             | 2.09  |            |       |      |    |
|                   |                                  | $C_{EXT} = 10 \text{ pF}$<br>$C = C_{INT} + C_{EXT}$ | 50 MHz                             | 3.6   |            |       |      |    |
|                   |                                  | + C <sub>S</sub>                                     | 60 MHz                             | 4.5   | A          |       |      |    |
|                   |                                  |  | 84 MHz                             | 7.8   |            |       |      |    |
|                   |                                  |  | 90 MHz                             | 9.8   |            |       |      |    |
|                   | I/O switching                    |  | 2 MHz                              | 0.26  |            |       |      |    |
| I <sub>DDIO</sub> | Current $V_{DD} = 3.3 \text{ V}$ | Current  |                                    |       |            | 8 MHz | 1.01 | ША |
|                   |                                  | $C_{EXT} = 22 \text{ pF}$<br>$C = C_{INT} + C_{EXT}$ | 25 MHz                             | 3.14  |            |       |      |    |
|                   |                                  | + C <sub>S</sub>                                     | 50 MHz                             | 6.39  |            |       |      |    |
|                   |                                  |  | 60 MHz                             | 10.68 | 1          |       |      |    |
|                   |                                  | V <sub>DD</sub> = 3.3 V                              | 2 MHz                              | 0.33  |            |       |      |    |
|                   |                                  | $C_{EXT} = 33 \text{ pF}$                            | 8 MHz                              | 1.29  |            |       |      |    |
|                   | C =                              | C = C <sub>INT</sub> + Cext                          | 25 MHz                             | 4.23  |            |       |      |    |
|                   |                                  | + C <sub>S</sub>                                     | 50 MHz                             | 11.02 |            |       |      |    |

Table 34. Switching output I/O current consumption<sup>(1)</sup> (continued)

#### On-chip peripheral current consumption

The MCU is placed under the following conditions:

- At startup, all I/O pins are in analog input configuration.
- All peripherals are disabled unless otherwise mentioned.
- HCLK is the system clock. f<sub>PCLK1</sub> = f<sub>HCLK</sub>/4, and f<sub>PCLK2</sub> = f<sub>HCLK</sub>/2.
   The given value is calculated by measuring the difference of current consumption
  - with all peripherals clocked off
  - with only one peripheral clocked on
  - $f_{HCLK}$  = 180 MHz (Scale1 + over-drive ON),  $f_{HCLK}$  = 144 MHz (Scale 2),  $f_{HCLK}$  = 120 MHz (Scale 3)"
- Ambient operating temperature is 25 °C and V<sub>DD</sub>=3.3 V.

<sup>1.</sup>  $C_S$  is the PCB board capacitance including the pad pin.  $C_S$  = 7 pF (estimated value).

<sup>2.</sup> This test is performed by cutting the LQFP144 package pin (pad removal).

Table 35. Peripheral current consumption

|       |                     |                        | I <sub>DD</sub> (Typ Appli) |            |                     |
|-------|---------------------|------------------------|-----------------------------|------------|---------------------|
| F     | Peripheral          | Scale 1 +<br>OverDrive | Scale 2                     | Scale 3    | Unit                |
|       | GPIOA               | 2.29                   | 2.14                        | 1.89       |                     |
|       | GPIOB               | 2.29                   | 2.13                        | 1.89       |                     |
|       | GPIOC               | 2.33                   | 2.17                        | 1.93       |                     |
|       | GPIOD               | 2.34                   | 2.19                        | 1.94       |                     |
|       | GPIOE               | 2.39                   | 2.19                        | 1.93       |                     |
|       | GPIOF               | 2.31                   | 2.14                        | 1.91       |                     |
| AHB1  | GPIOG               | 2.36                   | 2.19                        | 1.94       | μΑ/MHz              |
|       | GPIOH               | 2.13                   | 1.98                        | 1.75       |                     |
|       | CRC                 | 0.53                   | 0.51                        | 0.46       |                     |
|       | BKPSRAM             | 0.76                   | 0.72                        | 0.65       |                     |
|       | DMA1 <sup>(1)</sup> | 2.39N + 4.13           | 2.23N+3.56                  | 1.97N+3.51 |                     |
|       | DMA2 <sup>(1)</sup> | 2.39N + 4.45           | 2.19N+3.72                  | 2.00N+3.66 |                     |
|       | OTG_HS+ULPI         | 45.45                  | 42.08                       | 37.28      |                     |
| AHB2  | DCMI                | 3.74                   | 3.42                        | 3.01       | μΑ/MHz              |
| ALIDZ | OTGFS               | 30.04                  | 27.88                       | 24.69      | μΑνίνιι ιΖ          |
| VHB3  | FMC                 | 16.15                  | 15.01                       | 13.33      | μΑ/MHz              |
| AHB3  | QSPI                | 16.78                  | 15.60                       | 13.84      | μ <i>Α</i> νινιι ιΖ |

Table 35. Peripheral current consumption (continued)

|      |                     |                        | I <sub>DD</sub> (Typ Appli) |         |        |
|------|---------------------|------------------------|-----------------------------|---------|--------|
| i    | Peripheral          | Scale 1 +<br>OverDrive | Scale 2                     | Scale 3 | Unit   |
|      | TIM2                | 18.18                  | 16.92                       | 15.07   |        |
|      | TIM3                | 14.49                  | 13.47                       | 12.00   |        |
|      | TIM4                | 15.18                  | 14.11                       | 12.50   |        |
|      | TIM5                | 16.91                  | 15.69                       | 14.07   |        |
|      | TIM6                | 2.69                   | 2.47                        | 2.20    |        |
|      | TIM7                | 2.56                   | 2.44                        | 2.17    |        |
|      | TIM12               | 7.07                   | 6.56                        | 5.83    |        |
|      | TIM13               | 4.96                   | 4.64                        | 4.07    |        |
|      | TIM14               | 5.09                   | 4.72                        | 4.27    |        |
|      | WWDG                | 1.07                   | 1.00                        | 0.93    |        |
|      | SPI2 <sup>(2)</sup> | 1.89                   | 1.78                        | 1.57    |        |
|      | SPI3 <sup>(2)</sup> | 1.93                   | 1.81                        | 1.67    |        |
| APB1 | SPDIFRX             | 6.91                   | 6.44                        | 5.80    | μΑ/MHz |
|      | USART2              | 4.20                   | 3.83                        | 3.40    |        |
|      | USART3              | 4.22                   | 3.94                        | 3.50    |        |
|      | UART4               | 4.13                   | 3.89                        | 3.40    |        |
|      | UART5               | 4.04                   | 3.78                        | 3.33    |        |
|      | I2C1                | 3.98                   | 3.69                        | 3.33    |        |
|      | I2C2                | 3.91                   | 3.61                        | 3.17    |        |
|      | I2C3                | 3.76                   | 3.53                        | 3.13    |        |
|      | FMPI2C1             | 5.51                   | 5.19                        | 4.57    |        |
|      | CAN1                | 6.58                   | 6.14                        | 5.43    |        |
|      | CAN2                | 5.91                   | 5.56                        | 4.90    |        |
|      | CEC                 | 0.71                   | 0.69                        | 0.60    |        |
|      | DAC                 | 2.96                   | 2.72                        | 2.40    |        |

Table 35. Peripheral current consumption (continued)

|      |            |                        | I <sub>DD</sub> (Typ Appli) |         |        |
|------|------------|------------------------|-----------------------------|---------|--------|
|      | Peripheral | Scale 1 +<br>OverDrive | Scale 2                     | Scale 3 | Unit   |
|      | TIM1       | 17.51                  | 16.28                       | 14.43   |        |
|      | TIM8       | 18.40                  | 17.10                       | 15.22   |        |
|      | USART1     | 4.53                   | 4.21                        | 3.72    |        |
|      | USART6     | 4.53                   | 4.21                        | 3.72    |        |
|      | ADC1       | 4.69                   | 4.35                        | 3.85    |        |
|      | ADC2       | 4.70                   | 4.35                        | 3.87    |        |
|      | ADC3       | 4.66                   | 4.31                        | 3.82    |        |
| ADDO | SDIO       | 9.06                   | 8.38                        | 7.47    |        |
| APB2 | SPI1       | 1.97                   | 1.89                        | 1.67    | µA/MHz |
|      | SPI4       | 1.88                   | 1.75                        | 1.57    |        |
|      | SYSCFG     | 1.51                   | 1.40                        | 1.23    |        |
|      | TIM9       | 8.17                   | 7.64                        | 6.77    |        |
|      | TIM10      | 5.07                   | 4.75                        | 4.22    |        |
|      | TIM11      | 5.37                   | 5.06                        | 4.50    |        |
|      | SAI1       | 3.89                   | 3.64                        | 3.17    |        |
|      | SAI2       | 3.74                   | 3.49                        | 3.10    |        |
| I    | Bus Matrix | 8.15                   | 8.10                        | 7.13    |        |

<sup>1.</sup> N = Number of strean enable (1..8)

#### 6.3.8 Wakeup time from low-power modes

The wakeup times given in *Table 36* are measured starting from the wakeup event trigger up to the first instruction executed by the CPU:

- For Stop or Sleep modes: the wakeup event is WFE.
- WKUP (PA0) pin is used to wakeup from Standby, Stop and Sleep modes.

All timings are derived from tests performed under ambient temperature and  $V_{DD}$ =3.3 V.

<sup>2.</sup> To enable an I2S peripheral, first set the I2SMOD bit and then the I2SE bit in the SPI\_I2SCFGR register.

Max<sup>(1)</sup> Typ<sup>(1)</sup> **Symbol Parameter Conditions** Unit CPU  $t_{\text{WUSLEEP}}^{(2)}$ Wakeup from Sleep 6 6 clock cycle Wakeup from Sleep with Flash memory in  $T_{WUSLEEPFDSM}^{(1)}$ 33.5 50 Deep power down mode Main regulator is ON 12.8 15 Main regulator is ON and Flash 104.9 115 memory in Deep power down mode Wakeup from Stop mode with MR/LP  $t_{\text{WUSTOP}}^{\phantom{(2)}(2)}$ regulator in normal Low power regulator is ON 20.6 28 mode Low power regulator is ON and us Flash memory in Deep power down 112.8 120 mode Main regulator in under-drive mode (Flash memory in Deep power-140 110 Wakeup from Stop down mode) mode with MR/LP t<sub>WUSTOP</sub><sup>(2)</sup> Low power regulator in under-drive regulator in Under-drive mode mode 114.4 128 (Flash memory in Deep powerdown mode)  $t_{\text{WUSTDBY}}^{(2)(3)}$ Wakeup from Standby 325 400 mode

Table 36. Low-power mode wakeup timings

#### 6.3.9 External clock source characteristics

#### High-speed external user clock generated from an external source

In bypass mode the HSE oscillator is switched off and the input pin is a standard I/O. The external clock signal has to respect the *Table 56: I/O static characteristics*. However, the recommended clock input waveform is shown in *Figure 22*.

The characteristics given in *Table 37* result from tests performed using an high-speed external clock source, and under ambient temperature and supply voltage conditions summarized in *Table 16*.

<sup>1.</sup> Based on characterization, not tested in production.

<sup>2.</sup> The wakeup times are measured from the wakeup event to the point in which the application code reads the first instruction

<sup>3.</sup>  $t_{WUSTDBY}$  maximum value is given at -40 °C.

| Symbol  | Parameter   | Conditions                     | Min                | Тур | Max                | Unit |
|---|---|--------------------------------|--------------------|-----|--------------------|------|
| f <sub>HSE_ext</sub>  | External user clock source frequency <sup>(1)</sup> |                                | 1                  | -   | 50                 | MHz  |
| V <sub>HSEH</sub>   | OSC_IN input pin high level voltage                 |                                | 0.7V <sub>DD</sub> | ı   | $V_{DD}$           | V    |
| $V_{HSEL}$  | OSC_IN input pin low level voltage                  | _                              | V <sub>SS</sub>    | ı   | 0.3V <sub>DD</sub> | V    |
| $\begin{array}{c} t_{\text{w(HSE)}} \\ t_{\text{w(HSE)}} \end{array}$ | OSC_IN high or low time <sup>(1)</sup>              |                                | 5                  | ı   | -                  | ns   |
| $t_{r(HSE)} \ t_{f(HSE)}$   | OSC_IN rise or fall time <sup>(1)</sup>             |                                | -                  | ı   | 10                 | 113  |
| C <sub>in(HSE)</sub>  | OSC_IN input capacitance <sup>(1)</sup>             | -                              | -                  | 5   | -                  | pF   |
| DuCy <sub>(HSE)</sub>   | Duty cycle  | -                              | 45                 | -   | 55                 | %    |
| ΙL  | OSC_IN Input leakage current                        | $V_{SS} \le V_{IN} \le V_{DD}$ | -                  | -   | ±1                 | μΑ   |

Table 37. High-speed external user clock characteristics

#### Low-speed external user clock generated from an external source

In bypass mode the LSE oscillator is switched off and the input pin is a standard I/O. The external clock signal has to respect the *Table 56: I/O static characteristics*. However, the recommended clock input waveform is shown in *Figure 23*.

The characteristics given in *Table 38* result from tests performed using an low-speed external clock source, and under ambient temperature and supply voltage conditions summarized in *Table 16*.

| Table 38. | Low-speed 6 | external | user ( | CIOCK C | naracteris | itics |
|-----------|-------------|----------|--------|---------|------------|-------|
|           |             |          |        |         |            |       |

| Symbol                    | Parameter   | Conditions                     | Min                | Тур    | Max                | Unit |
|---------------------------|---|--------------------------------|--------------------|--------|--------------------|------|
| f <sub>LSE_ext</sub>      | User External clock source frequency <sup>(1)</sup> |                                | -                  | 32.768 | 1000               | kHz  |
| V <sub>LSEH</sub>         | OSC32_IN input pin high level voltage               |                                | 0.7V <sub>DD</sub> | -      | V <sub>DD</sub>    | V    |
| V <sub>LSEL</sub>         | OSC32_IN input pin low level voltage                | -                              | V <sub>SS</sub>    | -      | 0.3V <sub>DD</sub> |      |
| $t_{w(LSE)} \ t_{f(LSE)}$ | OSC32_IN high or low time <sup>(1)</sup>            |                                | 450                | -      | -                  | ns   |
| t <sub>r(LSE)</sub>       | OSC32_IN rise or fall time <sup>(1)</sup>           |                                | -                  | -      | 200                | 115  |
| C <sub>in(LSE)</sub>      | OSC32_IN input capacitance <sup>(1)</sup>           | -                              | -                  | 5      | -                  | pF   |
| DuCy <sub>(LSE)</sub>     | Duty cycle  | -                              | 30                 | -      | 70                 | %    |
| ΙL                        | OSC32_IN Input leakage current                      | $V_{SS} \le V_{IN} \le V_{DD}$ | -                  | -      | ±1                 | μΑ   |

<sup>1.</sup> Guaranteed by design, not tested in production.

<sup>1.</sup> Guaranteed by design, not tested in production.

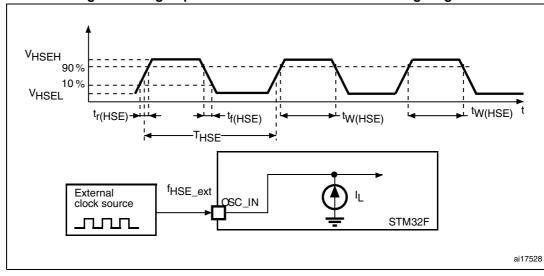
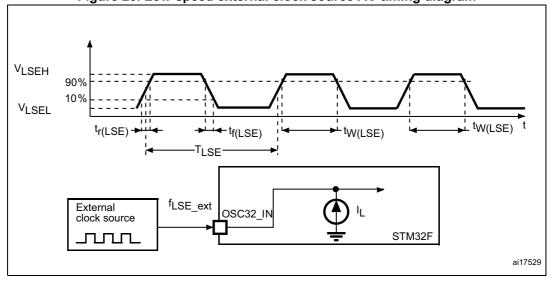


Figure 22. High-speed external clock source AC timing diagram





#### High-speed external clock generated from a crystal/ceramic resonator

The high-speed external (HSE) clock can be supplied with a 4 to 26 MHz crystal/ceramic resonator oscillator. All the information given in this paragraph are based on characterization results obtained with typical external components specified in *Table 39*. In the application, the resonator and the load capacitors have to be placed as close as possible to the oscillator pins in order to minimize output distortion and startup stabilization time. Refer to the crystal resonator manufacturer for more details on the resonator characteristics (frequency, package, accuracy).

**Symbol Conditions** Min Unit **Parameter** Тур Max Oscillator frequency 4 26 MHz fosc\_in  $R_{F}$ Feedback resistor 200  $k\Omega$ V<sub>DD</sub>=3.3 V, ESR= 30  $\Omega$ , 450  $C_1 = 5 pF@25 MHz$ HSE current consumption μΑ  $I_{DD}$  $V_{DD} = 3.3 V$ , ESR= 30  $\Omega$ . 530  $C_1 = 10 pF@25 MHz$ ACC<sub>HSE</sub>(2) 500 **HSE** accuracy -500 ppm Maximum critical crystal g<sub>m</sub> G<sub>m\_crit\_max</sub> Startup mA/V 1  $t_{\text{SU(HSE}}^{(3)}$ V<sub>DD</sub> is stabilized 2 Startup time

Table 39. HSE 4-26 MHz oscillator characteristics (1)

- 1. Guaranteed by design, not tested in production.
- This parameter depends on the crystal used in the application. The minimum and maximum values must be respected to comply with USB standard specifications.
- 3. t<sub>SU(HSE)</sub> is the startup time measured from the moment it is enabled (by software) to a stabilized 8 MHz oscillation is reached. This value is based on characterization and not tested in production. It is measured for a standard crystal resonator and it can vary significantly with the crystal manufacturer.

For  $C_{L1}$  and  $C_{L2}$ , it is recommended to use high-quality external ceramic capacitors in the 5 pF to 25 pF range (typ.), designed for high-frequency applications, and selected to match the requirements of the crystal or resonator (see *Figure 24*).  $C_{L1}$  and  $C_{L2}$  are usually the same size. The crystal manufacturer typically specifies a load capacitance which is the series combination of  $C_{L1}$  and  $C_{L2}$ . PCB and MCU pin capacitance must be included (10 pF can be used as a rough estimate of the combined pin and board capacitance) when sizing  $C_{L1}$  and  $C_{L2}$ .

Note: For information on selecting the crystal, refer to the application note AN2867 "Oscillator design guide for ST microcontrollers" available from the ST website www.st.com.

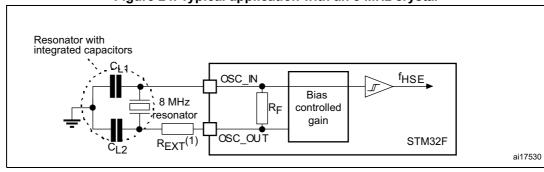


Figure 24. Typical application with an 8 MHz crystal

R<sub>EXT</sub> value depends on the crystal characteristics.

#### Low-speed external clock generated from a crystal/ceramic resonator

The low-speed external (LSE) clock can be supplied with a 32.768 kHz crystal/ceramic resonator oscillator. All the information given in this paragraph are based on characterization results obtained with typical external components specified in *Table 40*. In the application, the resonator and the load capacitors have to be placed as close as



possible to the oscillator pins in order to minimize output distortion and startup stabilization time. Refer to the crystal resonator manufacturer for more details on the resonator characteristics (frequency, package, accuracy).

|                                   | rable for the decimator of a factorious (FESE Tell 100 Mile) |                               |      |      |      |           |  |  |
|-----------------------------------|--|-------------------------------|------|------|------|-----------|--|--|
| Symbol                            | Parameter Conditions   |                               | Min  | Тур  | Max  | Unit      |  |  |
| R <sub>F</sub>                    | Feedback resistor  | -                             | -    | 18.4 | -    | $M\Omega$ |  |  |
| I <sub>DD</sub>                   | LSE current consumption                                      | -                             | -    | -    | 1    | μΑ        |  |  |
| ACC <sub>LSE</sub> <sup>(2)</sup> | LSE accuracy   | -                             | -500 | -    | 500  | ppm       |  |  |
| G <sub>m</sub> _crit_max          | Maximum critical crystal                                     | Startup low-power mode        | -    | -    | 0.56 | μΑ/V      |  |  |
| G <sub>m_</sub> CIII_IIIax        | 9 <sub>m</sub>   | Startup high-drive mode       | -    | -    | 1.5  | μΑνν      |  |  |
| t <sub>SU(LSE)</sub> (3)          | startup time   | V <sub>DD</sub> is stabilized | -    | 2    | -    | s         |  |  |

Table 40. LSE oscillator characteristics ( $f_{LSE} = 32.768 \text{ kHz}$ ) (1)

- 1. Guaranteed by design, not tested in production.
- 2. This parameter depends on the crystal used in the application. Refer to application note AN2867.
- 3. t<sub>SU(LSE)</sub> is the startup time measured from the moment it is enabled (by software) to a stabilized 32.768 kHz oscillation is reached. This value is based on characterization and not tested in production. It is measured for a standard crystal resonator and it can vary significantly with the crystal manufacturer.

Note: For information on selecting the crystal, refer to the application note AN2867 "Oscillator design guide for ST microcontrollers" available from the ST website www.st.com.

Resonator with integrated capacitors

CL1

OSC32

N

Bias controlled gain

STM32F

ai17531

Figure 25. Typical application with a 32.768 kHz crystal

#### 6.3.10 Internal clock source characteristics

The parameters given in *Table 41* and *Table 42* are derived from tests performed under ambient temperature and  $V_{DD}$  supply voltage conditions summarized in *Table 16*.

#### High-speed internal (HSI) RC oscillator

Table 41. HSI oscillator characteristics (1)

| Symbol           | Parameter | Conditions | Min | Тур | Max | Unit |
|------------------|-----------|------------|-----|-----|-----|------|
| f <sub>HSI</sub> | Frequency | -          | -   | 16  | -   | MHz  |

|   | Table 41. Her obtained distributed |  |  |     |     |      |    |  |
|---|------------------------------------|--|--|-----|-----|------|----|--|
| Symbol  | Parameter                          | С  | Min  | Тур | Max | Unit |    |  |
|   |                                    | User-trimmed with the RCC_CR register <sup>(2)</sup> |  | -   | -   | 1    | %  |  |
| ACC <sub>HSI</sub> Accuracy of the oscillator | Accuracy of the HSI                |  | $T_A = -40 \text{ to } 105 ^{\circ}\text{C}^{(3)}$ | -8  | -   | 4.5  | %  |  |
|   | Oscillator                         | Factory-<br>calibrated                               | $T_A = -10 \text{ to } 85  ^{\circ}\text{C}^{(3)}$ | -4  | -   | 4    | %  |  |
|   |                                    |  | T <sub>A</sub> = 25 °C                             | -1  | -   | 1    | %  |  |
| t <sub>su(HSI)</sub> <sup>(2)</sup>           | HSI oscillator startup time        | -  |  | -   | 2.2 | 4    | μs |  |
| I <sub>DD(HSI)</sub> <sup>(2)</sup>           | HSI oscillator power consumption   | -  |  | -   | 60  | 80   | μA |  |

Table 41. HSI oscillator characteristics (1)

- 1.  $V_{DD}$  = 3.3 V,  $T_A$  = -40 to 105 °C unless otherwise specified.
- 2. Guaranteed by design, not tested in production
- 3. Based on characterization, not tested in production.

0.06 0.04 0.02 0 -40 105 125 TA (°C) -0.02 -0.04 **—**Min Max -0.06 Typical -0.08 MS30492V1

Figure 26. LACC<sub>HSI</sub> versus temperature

1. Based on characterisation results, not tested in production.

#### Low-speed internal (LSI) RC oscillator

**Symbol Parameter** Min Unit Max Тур f<sub>I SI</sub><sup>(2)</sup> Frequency 17 32 47 kHz  $t_{su(LSI)}^{(3)}$ LSI oscillator startup time 15 40 μs I<sub>DD(LSI)</sub>(3) LSI oscillator power consumption 0.4 0.6 μΑ

Table 42. LSI oscillator characteristics (1)

- 1.  $V_{DD}$  = 3 V,  $T_A$  = -40 to 105 °C unless otherwise specified.
- 2. Based on characterization, not tested in production.
- 3. Guaranteed by design, not tested in production.

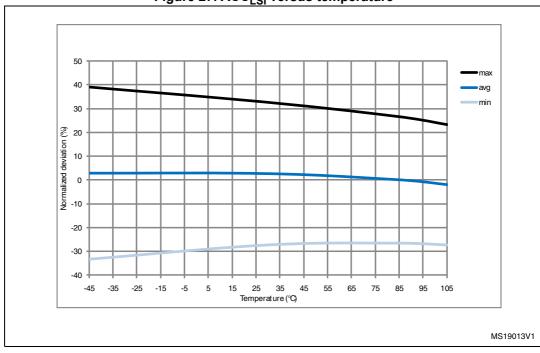


Figure 27. ACC<sub>LSI</sub> versus temperature

#### 6.3.11 PLL characteristics

The parameters given in *Table 43* and *Table 44* are derived from tests performed under temperature and  $V_{DD}$  supply voltage conditions summarized in *Table 16*.

| Symbol                                    | Parameter                          | Condition                         | ns                      | Min | Тур  | Max  | Unit |
|---|------------------------------------|-----------------------------------|-------------------------|-----|------|------|------|
| f <sub>PLL_IN</sub>                       | PLL input clock <sup>(1)</sup>     | -                                 | -                       |     | 1    | 2.10 | MHz  |
| f <sub>PLL_OUT</sub>                      | PLL multiplier output clock        | -                                 |                         | 24  | -    | 180  | MHz  |
| f <sub>PLL48_OUT</sub>                    | 48 MHz PLL multiplier output clock | -                                 |                         | -   | 48   | 75   | MHz  |
| f <sub>VCO_OUT</sub>                      | PLL VCO output                     | -                                 | -                       |     | -    | 432  | MHz  |
| t <sub>LOCK</sub>                         | PLL lock time                      | VCO freq = 100 MHz                |                         | 75  | -    | 200  |      |
|   | FLL IOCK (IIIIe                    | VCO freq = 432 MHz                |                         | 100 | -    | 300  | - µs |
|   |                                    |                                   | RMS                     | -   | 25   | -    |      |
|   | Cycle-to-cycle jitter              | System clock                      | peak<br>to<br>peak      | -   | ±150 | -    |      |
| Jitter <sup>(3)</sup>                     |                                    | 120 MHz                           | RMS                     | -   | 15   | -    | ps   |
| G. C. | Period Jitter                      |                                   | peak<br>to<br>peak      | -   | ±200 | -    | 1 5  |
|   | Bit Time CAN jitter                | Cycle to cycle at on 1000 sample: | Cycle to cycle at 1 MHz |     | 330  | -    |      |

**Table 43. Main PLL characteristics** 

| Symbol                               | Parameter                     | Conditions                               | Min          | Тур | Max          | Unit |
|--------------------------------------|-------------------------------|--|--------------|-----|--------------|------|
| I <sub>DD(PLL)</sub> <sup>(4)</sup>  | PLL power consumption on VDD  | VCO freq = 100 MHz<br>VCO freq = 432 MHz | 0.15<br>0.45 | -   | 0.40<br>0.75 | mA   |
| I <sub>DDA(PLL)</sub> <sup>(4)</sup> | PLL power consumption on VDDA | VCO freq = 100 MHz<br>VCO freq = 432 MHz | 0.30<br>0.55 | -   | 0.40<br>0.85 | mA   |

Take care of using the appropriate division factor M to obtain the specified PLL input clock values. The M factor is shared between PLL and PLLI2S.

Table 44. PLLI2S (audio PLL) characteristics

| Symbol                                  | Parameter                                    | Conditions  |                    | Min                 | Тур  | Max          | Unit |
|---|--|---|--------------------|---------------------|------|--------------|------|
| f <sub>PLLI2S_IN</sub>                  | PLLI2S input clock <sup>(1)</sup>            | -   |                    | 0.95 <sup>(2)</sup> | 1    | 2.10         | MHz  |
| f <sub>PLLI2S_OUT</sub>                 | PLLI2S multiplier output clock               | -   |                    | -                   | ī    | 216          | MHz  |
| f <sub>VCO_OUT</sub>                    | PLLI2S VCO output                            | -   |                    | 100                 | ī    | 432          | MHz  |
| t <sub>LOCK</sub>                       | PLLI2S lock time                             | VCO freq = 100 MHz  |                    | 75                  | -    | 200          | μs   |
|   |  | VCO freq = 432 MHz  |                    | 100                 | -    | 300          |      |
| Jitter <sup>(3)</sup>                   | Master I2S clock jitter                      | Cycle to cycle at<br>12.288 MHz on<br>48KHz period,<br>N=432, R=5       | RMS                | -                   | 90   | -            | -    |
|   |  |   | peak<br>to<br>peak | -                   | ±280 | -            | ps   |
|   |  | Average frequency of<br>12.288 MHz<br>N = 432, R = 5<br>on 1000 samples |                    | -                   | 90   | -            | ps   |
|   | WS I2S clock jitter                          | Cycle to cycle at 48 KHz on 1000 samples                                |                    | -                   | 400  | -            | ps   |
| I <sub>DD(PLLI2S)</sub> <sup>(4)</sup>  | PLLI2S power consumption on V <sub>DD</sub>  | VCO freq = 100 MHz<br>VCO freq = 432 MHz                                |                    | 0.15<br>0.45        | -    | 0.40<br>0.75 | mA   |
| I <sub>DDA(PLLI2S)</sub> <sup>(4)</sup> | PLLI2S power consumption on V <sub>DDA</sub> | VCO freq = 100 MHz<br>VCO freq = 432 MHz                                |                    | 0.30<br>0.55        | -    | 0.40<br>0.85 | mA   |

<sup>1.</sup> Take care of using the appropriate division factor M to have the specified PLL input clock values.

4. Based on characterization, not tested in production.

<sup>2.</sup> Guaranteed by design, not tested in production.

<sup>3.</sup> The use of 2 PLLs in parallel could degraded the Jitter up to +30%.

<sup>4.</sup> Based on characterization, not tested in production.

<sup>2.</sup> Guaranteed by design, not tested in production.

<sup>3.</sup> Value given with main PLL running.

| Symbol                                  | Parameter                                    | Conditions   |                    | Min                 | Тур  | Max          | Unit |
|---|--|--|--------------------|---------------------|------|--------------|------|
| f <sub>PLLSAI_IN</sub>                  | PLLSAI input clock <sup>(1)</sup>            | -  |                    | 0.95 <sup>(2)</sup> | 1    | 2.10         | MHz  |
| f <sub>PLLSAI_OUT</sub>                 | PLLSAI multiplier output clock               | -  |                    | -                   | -    | 216          | MHz  |
| f <sub>VCO_OUT</sub>                    | PLLSAI VCO output                            | -  |                    | 100                 | -    | 432          | MHz  |
| 4                                       | PLLSAI lock time                             | VCO freq = 100 MHz   | •                  | 75                  | -    | 200          |      |
| t <sub>LOCK</sub>                       | PLESALIOCK (IIIIe                            | VCO freq = 432 MHz   |                    | 100                 | -    | 300          | μs   |
|   |  | Cycle to cycle at  | RMS                | -                   | 90   | -            | -    |
|   | Main SAI clock jitter                        | 48KHz period,  | peak<br>to<br>peak | -                   | ±280 | -            | ps   |
| Jitter <sup>(3)</sup>                   |  | Average frequency o<br>12.288 MHz<br>N = 432, R = 5<br>on 1000 samples | f                  | -                   | 90   | -            | ps   |
|   | FS clock jitter                              | Cycle to cycle at 48 h<br>on 1000 samples                              | КНz                | -                   | 400  | -            | ps   |
| I <sub>DD(PLLSAI)</sub> <sup>(4)</sup>  | PLLSAI power consumption on $V_{DD}$         | VCO freq = 100 MHz<br>VCO freq = 432 MHz                               |                    | 0.15<br>0.45        | -    | 0.40<br>0.75 | mA   |
| I <sub>DDA(PLLSAI)</sub> <sup>(4)</sup> | PLLSAI power consumption on V <sub>DDA</sub> | VCO freq = 100 MHz<br>VCO freq = 432 MHz                               |                    | 0.30<br>0.55        | -    | 0.40<br>0.85 | mA   |

Table 45. PLLISAI (audio and LCD-TFT PLL) characteristics

# 6.3.12 PLL spread spectrum clock generation (SSCG) characteristics

The spread spectrum clock generation (SSCG) feature allows to reduce electromagnetic interferences (see *Table 52: EMI characteristics*). It is available only on the main PLL.

Table 46. SSCG parameters constraint

| Symbol            | Parameter             | Min  | Тур | Max <sup>(1)</sup> | Unit |
|-------------------|-----------------------|------|-----|--------------------|------|
| f <sub>Mod</sub>  | Modulation frequency  | -    | -   | 10                 | KHz  |
| md                | Peak modulation depth | 0.25 | -   | 2                  | %    |
| MODEPER * INCSTEP | -                     | -    | -   | 2 <sup>15</sup> –1 | -    |

<sup>1.</sup> Guaranteed by design, not tested in production.

#### Equation 1

The frequency modulation period (MODEPER) is given by the equation below:

$$\texttt{MODEPER} = \mathsf{round}[\mathsf{f}_{\mathsf{PLL\_IN}} / \ (4 \times \mathsf{f}_{\mathsf{Mod}})]$$



<sup>1.</sup> Take care of using the appropriate division factor M to have the specified PLL input clock values.

<sup>2.</sup> Guaranteed by design, not tested in production.

<sup>3.</sup> Value given with main PLL running.

<sup>4.</sup> Based on characterization, not tested in production.

 $f_{PLL\ IN}$  and  $f_{Mod}$  must be expressed in Hz.

As an example:

If  $f_{PLL\_IN}$  = 1 MHz, and  $f_{MOD}$  = 1 kHz, the modulation depth (MODEPER) is given by equation 1:

MODEPER = round[
$$10^6 / (4 \times 10^3)$$
] = 250

#### Equation 2

Equation 2 allows to calculate the increment step (INCSTEP):

INCSTEP = round[
$$((2^{15} - 1) \times md \times PLLN) / (100 \times 5 \times MODEPER)$$
]

 $f_{VCO\ OUT}$  must be expressed in MHz.

With a modulation depth (md) = ±2 % (4 % peak to peak), and PLLN = 240 (in MHz):

INCSTEP = round[
$$((2^{15}-1)\times 2\times 240)/(100\times 5\times 250)$$
] = 126md(quantitazed)%

An amplitude quantization error may be generated because the linear modulation profile is obtained by taking the quantized values (rounded to the nearest integer) of MODPER and INCSTEP. As a result, the achieved modulation depth is quantized. The percentage quantized modulation depth is given by the following formula:

$$md_{quantized}\% = (MODEPER \times INCSTEP \times 100 \times 5) / \ ((2^{15} - 1) \times PLLN)$$

As a result:

$$md_{quantized}\% = (250 \times 126 \times 100 \times 5) / ((2^{15} - 1) \times 240) = 2.002\%$$
(peak)

Figure 28 and Figure 29 show the main PLL output clock waveforms in center spread and down spread modes, where:

F0 is f<sub>PLL</sub> OUT nominal.

T<sub>mode</sub> is the modulation period.

md is the modulation depth.

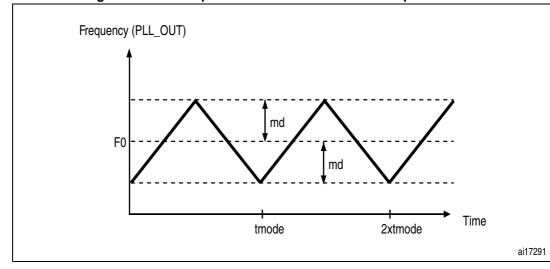
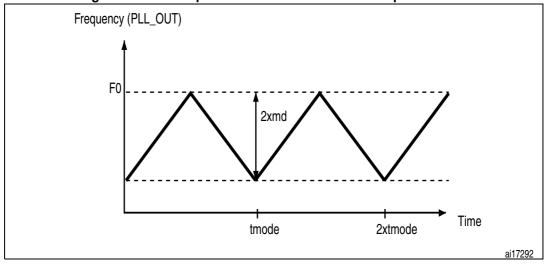


Figure 28. PLL output clock waveforms in center spread mode

Figure 29. PLL output clock waveforms in down spread mode



#### 6.3.13 **Memory characteristics**

### Flash memory

The characteristics are given at TA = - 40 to 105 °C unless otherwise specified.

The devices are shipped to customers with the Flash memory erased.

Table 47. Flash memory characteristics

| Symbol          | Parameter      | Conditions   | Min | Тур | Max | Unit |
|-----------------|----------------|--|-----|-----|-----|------|
|                 |                | Write / Erase 8-bit mode, V <sub>DD</sub> = 1.7 V  | 1   | 5   | i   |      |
| I <sub>DD</sub> | Supply current | Write / Erase 16-bit mode, V <sub>DD</sub> = 2.1 V | -   | 8   | -   | mA   |
|                 |                | Write / Erase 32-bit mode, V <sub>DD</sub> = 3.3 V | -   | 12  | -   |      |

Table 48. Flash memory programming

| Symbol                  | Parameter                  | Conditions                                    | Min <sup>(1)</sup> | Тур  | Max <sup>(1)</sup> | Unit |
|-------------------------|----------------------------|---|--------------------|------|--------------------|------|
| t <sub>prog</sub>       | Word programming time      | Program/erase parallelism (PSIZE) = x 8/16/32 | -                  | 16   | 100 <sup>(2)</sup> | μs   |
|                         |                            | Program/erase parallelism (PSIZE) = x 8       | -                  | 400  | 800                |      |
| t <sub>ERASE16KB</sub>  | Sector (16 KB) erase time  | Program/erase parallelism (PSIZE) = x 16      | -                  | 300  | 600                | ms   |
|                         |                            | Program/erase parallelism (PSIZE) = x 32      | -                  | 250  | 500                |      |
|                         |                            | Program/erase parallelism (PSIZE) = x 8       | -                  | 1200 | 2400               |      |
| t <sub>ERASE64KB</sub>  | Sector (64 KB) erase time  | Program/erase parallelism (PSIZE) = x 16      | -                  | 700  | 1400               | ms   |
|                         |                            | Program/erase parallelism (PSIZE) = x 32      | -                  | 550  | 1100               |      |
|                         | Sector (128 KB) erase time | Program/erase parallelism (PSIZE) = x 8       | -                  | 2    | 4                  |      |
| t <sub>ERASE128KB</sub> |                            | Program/erase parallelism (PSIZE) = x 16      | -                  | 1.3  | 2.6                | S    |
|                         |                            | Program/erase parallelism (PSIZE) = x 32      | -                  | 1    | 2                  |      |
|                         |                            | Program/erase parallelism (PSIZE) = x 8       | -                  | 8    | 16                 |      |
| t <sub>ME</sub>         | Mass erase time            | Program/erase parallelism (PSIZE) = x 16      | -                  | 5.5  | 11                 | S    |
|                         |                            | Program/erase parallelism (PSIZE) = x 32      | -                  | 8    | 16                 |      |
|                         |                            | 32-bit program operation                      | 2.7                | -    | 3.6                | V    |
| $V_{prog}$              | Programming voltage        | 16-bit program operation                      | 2.1                | -    | 3.6                | V    |
|                         |                            | 8-bit program operation                       | 1.7                | -    | 3.6                | V    |

<sup>1.</sup> Based on characterization, not tested in production.

Table 49. Flash memory programming with  $\mathrm{V}_{\mathrm{PP}}$ 

| Symbol                  | Parameter                       | Conditions                   | Min <sup>(1)</sup> | Тур | Max <sup>(1)</sup> | Unit |
|-------------------------|---------------------------------|------------------------------|--------------------|-----|--------------------|------|
| t <sub>prog</sub>       | Double word programming         |                              | -                  | 16  | 100 <sup>(2)</sup> | μs   |
| t <sub>ERASE16KB</sub>  | Sector (16 KB) erase time       | T <sub>A</sub> = 0 to +40 °C | -                  | 230 | -                  |      |
| t <sub>ERASE64KB</sub>  | Sector (64 KB) erase time       | V <sub>DD</sub> = 3.3 V      | -                  | 490 | -                  | ms   |
| t <sub>ERASE128KB</sub> | Sector (128 KB) erase time      | V <sub>PP</sub> = 8.5 V      | -                  | 875 | -                  |      |
| t <sub>ME</sub>         | t <sub>ME</sub> Mass erase time |                              | -                  | 3.5 | -                  | s    |
| V <sub>prog</sub>       | Programming voltage             | -                            | 2.7                | -   | 3.6                | V    |



<sup>2.</sup> The maximum programming time is measured after 100K erase operations.

|                      |   |            | (1)                | _   | (1)                |      |
|----------------------|---|------------|--------------------|-----|--------------------|------|
| Symbol               | Parameter   | Conditions | Min <sup>(1)</sup> | Тур | Max <sup>(1)</sup> | Unit |
| $V_{PP}$             | V <sub>PP</sub> voltage range                           | -          | 7                  | -   | 9                  | V    |
| I <sub>PP</sub>      | Minimum current sunk on the V <sub>PP</sub> pin         | -          | 10                 | -   | -                  | mA   |
| t <sub>VPP</sub> (3) | Cumulative time during which V <sub>PP</sub> is applied | -          | -                  | -   | 1                  | hour |

Table 49. Flash memory programming with V<sub>PP</sub> (continued)

- 1. Guaranteed by design, not tested in production.
- 2. The maximum programming time is measured after 100K erase operations.
- 3. V<sub>PP</sub> should only be connected during programming/erasing.

Table 50. Flash memory endurance and data retention

| Symbol           | Parameter      | Conditions  | Value              | Unit    |
|------------------|----------------|---|--------------------|---------|
| -                | -              | Conditions  | Min <sup>(1)</sup> | Ullit   |
| N <sub>END</sub> | Endurance      | $T_A = -40$ to +85 °C (6 suffix versions)<br>$T_A = -40$ to +105 °C (7 suffix versions) | 10                 | Kcycles |
|                  |                | 1 kcycle <sup>(2)</sup> at T <sub>A</sub> = 85 °C                                       | 30                 |         |
| t <sub>RET</sub> | Data retention | 1 kcycle <sup>(2)</sup> at T <sub>A</sub> = 105 °C                                      | 10                 | Years   |
|                  |                | 10 kcycles <sup>(2)</sup> at T <sub>A</sub> = 55 °C                                     | 20                 |         |

- 1. Based on characterization, not tested in production.
- 2. Cycling performed over the whole temperature range.

#### 6.3.14 EMC characteristics

Susceptibility tests are performed on a sample basis during device characterization.

#### Functional EMS (electromagnetic susceptibility)

While a simple application is executed on the device (toggling 2 LEDs through I/O ports). the device is stressed by two electromagnetic events until a failure occurs. The failure is indicated by the LEDs:

- Electrostatic discharge (ESD) (positive and negative) is applied to all device pins until a functional disturbance occurs. This test is compliant with the IEC 61000-4-2 standard.
- FTB: A burst of fast transient voltage (positive and negative) is applied to V<sub>DD</sub> and V<sub>SS</sub> through a 100 pF capacitor, until a functional disturbance occurs. This test is compliant with the IEC 61000-4-4 standard.

A device reset allows normal operations to be resumed.

The test results are given in *Table 51*. They are based on the EMS levels and classes defined in application note AN1709.



| 14510 011 21110 01141 40101101100 |   |  |                 |  |  |  |
|-----------------------------------|---|--|-----------------|--|--|--|
| Symbol                            | Parameter   | Conditions   | Level/<br>Class |  |  |  |
| V <sub>FESD</sub>                 | Voltage limits to be applied on any I/O pin to induce a functional disturbance  | $V_{\rm DD} = 3.3$ V, LQFP144, $T_{\rm A} =$ +25 °C, $f_{\rm HCLK} = 168$ MHz, conforms to IEC 61000-4-2                     | 2B              |  |  |  |
| V <sub>EFTB</sub>                 | Fast transient voltage burst limits to be applied through 100 pF on V <sub>DD</sub> and V <sub>SS</sub> pins to induce a functional disturbance | $V_{DD} = 3.3 \text{ V, LQFP144,}$<br>$T_A = +25 ^{\circ}\text{C, f}_{HCLK} = 168 \text{ MHz,}$<br>conforms to IEC 61000-4-2 | 4B              |  |  |  |

Table 51. EMS characteristics

#### Designing hardened software to avoid noise problems

EMC characterization and optimization are performed at component level with a typical application environment and simplified MCU software. It should be noted that good EMC performance is highly dependent on the user application and the software in particular.

Therefore it is recommended that the user applies EMC software optimization and prequalification tests in relation with the EMC level requested for his application.

Software recommendations

The software flowchart must include the management of runaway conditions such as:

- Corrupted program counter
- Unexpected reset
- Critical Data corruption (control registers...)

Prequalification trials

Most of the common failures (unexpected reset and program counter corruption) can be reproduced by manually forcing a low state on the NRST pin or the Oscillator pins for 1 second.

To complete these trials, ESD stress can be applied directly on the device, over the range of specification values. When unexpected behavior is detected, the software can be hardened to prevent unrecoverable errors occurring (see application note AN1015).

#### **Electromagnetic Interference (EMI)**

The electromagnetic field emitted by the device are monitored while a simple application, executing EEMBC code, is running. This emission test is compliant with SAE IEC61967-2 standard which specifies the test board and the pin loading.

| Symbol   | Parameter     | Conditions  | Monitored frequency band | Max vs.<br>[f <sub>HSE</sub> /f <sub>CPU</sub> ] | Unit |
|--|---------------|---|--------------------------|--|------|
|  |               |   | irequericy band          | 8/180 MHz  |      |
| V <sub>DD</sub> = 3.3 V, T <sub>A</sub> = 25 °C, LQFP144 | 0.1 to 30 MHz | 11  |                          |  |      |
|  |               | package, conforming to SAE J1752/3  | 30 to 130 MHz            | 10   | dΒμV |
|  |               | EEMBC, ART ON, all peripheral clocks enabled, clock dithering disabled.   | 130 MHz to 1GHz          | 11   |      |
| 9  | Peak level    | chabica, dock differing disabled.   | SAE EMI Level            | 3  | -    |
| S <sub>EMI</sub>   |               | V <sub>DD</sub> = 3.3 V, T <sub>A</sub> = 25 °C, LQFP144 package, conforming to SAE J1752/3 EEMBC, ART ON, all peripheral clocks enabled, clock dithering enabled | 0.1 to 30 MHz            | 24   |      |
|  |               |   | 30 to 130 MHz            | 25   | dΒμV |
|  |               |   | 130 MHz to 1GHz          | 20   |      |
|  |               | Chabled, clock difficility enabled  | SAE EMI level            | 4  | -    |

Table 52. EMI characteristics

## 6.3.15 Absolute maximum ratings (electrical sensitivity)

Based on three different tests (ESD, LU) using specific measurement methods, the device is stressed in order to determine its performance in terms of electrical sensitivity.

# Electrostatic discharge (ESD)

Electrostatic discharges (a positive then a negative pulse separated by 1 second) are applied to the pins of each sample according to each pin combination. The sample size depends on the number of supply pins in the device (3 parts × (n+1) supply pins). This test conforms to the ANSI/JEDEC standard.

| Symbol                | Ratings  | Conditions  | Class | Maximum<br>value <sup>(1)</sup> | Unit |
|-----------------------|--|---|-------|---------------------------------|------|
| V <sub>ESD(HBM)</sub> | Electrostatic<br>discharge voltage<br>(human body model) | T <sub>A</sub> = + 25 °C conforming to ANSI/JEDEC JS-001  | 2     | 2000                            |      |
|                       | Electrostatic  | T <sub>A</sub> = + 25 °C conforming to ANSI/ESD STM5.3.1,<br>LQFP64, LQFP100, WLCSP81 packages    | C4    | 500                             | ٧    |
| V <sub>ESD(CDM)</sub> | discharge voltage<br>(charge device model)               | $T_A$ = + 25 °C conforming to ANSI/ESD STM5.3.1,<br>LQFP144, UFBGA144 (7 x 7), UFBGA144 (10 x 10) | C3    | 250                             |      |

Table 53. ESD absolute maximum ratings

#### Static latchup

Two complementary static tests are required on six parts to assess the latchup performance:

A supply overvoltage is applied to each power supply pin

packages

• A current injection is applied to each input, output and configurable I/O pin



<sup>1.</sup> Guaranteed by characterization results, not tested in production.

These tests are compliant with EIA/JESD 78A IC latchup standard.

Table 54. Electrical sensitivities

| Symbol | Parameter             | Conditions                                     | Class      |
|--------|-----------------------|--|------------|
| LU     | Static latch-up class | T <sub>A</sub> = +105 °C conforming to JESD78A | II level A |

# 6.3.16 I/O current injection characteristics

As a general rule, current injection to the I/O pins, due to external voltage below  $V_{\rm SS}$  or above  $V_{\rm DD}$  (for standard, 3 V-capable I/O pins) should be avoided during normal product operation. However, in order to give an indication of the robustness of the microcontroller in cases when abnormal injection accidentally happens, susceptibility tests are performed on a sample basis during device characterization.

#### Functional susceptibility to I/O current injection

While a simple application is executed on the device, the device is stressed by injecting current into the I/O pins programmed in floating input mode. While current is injected into the I/O pin, one at a time, the device is checked for functional failures.

The failure is indicated by an out of range parameter: ADC error above a certain limit (>5 LSB TUE), out of conventional limits of induced leakage current on adjacent pins (out of - 5  $\mu$ A/+0  $\mu$ A range), or other functional failure (for example reset, oscillator frequency deviation).

Negative induced leakage current is caused by negative injection and positive induced leakage current by positive injection.

The test results are given in *Table 55*.

Table 55. I/O current injection susceptibility<sup>(1)</sup>

|                  |   | Functional s       |                    |      |
|------------------|---|--------------------|--------------------|------|
| Symbol           | Description   | Negative injection | Positive injection | Unit |
|                  | Injected current on BOOT0 pin   | -0                 | NA                 |      |
|                  | Injected current on NRST pin  | -0                 | NA                 |      |
| I <sub>INJ</sub> | Injected current on PE2, PE3,PE4, PE5, PE6, PC13, PC14, PF10, PH0, PH1, NRST, PC0, PC1, PC2, PC3, PG15, PB3, PB4, PB5, PB6, PB7, PB8, PB9, PE0, PE1 | -0                 | NA                 | mA   |
|                  | Injected current on any other FT and FTf pins   | -5                 | NA                 |      |
|                  | Injected current on any other pins  | -5                 | +5                 |      |

<sup>1.</sup> NA = not applicable.

Note:

It is recommended to add a Schottky diode (pin to ground) to analog pins which may potentially inject negative currents.



# 6.3.17 I/O port characteristics

# General input/output characteristics

Unless otherwise specified, the parameters given in *Table 56: I/O static characteristics* are derived from tests performed under the conditions summarized in *Table 16*. All I/Os are CMOS and TTL compliant.

Table 56. I/O static characteristics

| Symbol           | Parameter                                  | Conditions   | Min                                     | Тур                | Max                                      | Unit |  |
|------------------|--|--|---|--------------------|--|------|--|
|                  | FT, FTf, TTa and NRST I/O                  | 1.7 V≤V <sub>DD</sub> ≤3.6 V   | _                                       | _                  | 0.35V <sub>DD</sub> -0.04 <sup>(1)</sup> |      |  |
|                  | input low level voltage                    | 1.7 V \( \times \text{DD} \( \times \text{SO} \)   | _                                       | -                  | 0.3V <sub>DD</sub> <sup>(2)</sup>        |      |  |
| V <sub>IL</sub>  | BOOT0 I/O input low level voltage          | 1.75 V ≤ V <sub>DD</sub> ≤<br>3.6 V,<br>- 40 °C≤ T <sub>A</sub> ≤<br>105 °C                                | -                                       | -                  | 0.1V <sub>DD</sub> +0.1 <sup>(1)</sup>   | V    |  |
|                  |  | $1.7 \text{ V} \le \text{V}_{DD} \le 3.6 \text{ V},$<br>$0 \text{ °C} \le \text{T}_{A} \le 105 \text{ °C}$ | -                                       | -                  |  |      |  |
|                  | FT, FTf, TTa and NRST I/O                  | 171/4/ 2261/   | 0.45V <sub>DD</sub> +0.3 <sup>(1)</sup> |                    |  |      |  |
|                  | input high level voltage <sup>(4)</sup>    | 1.7 V≤V <sub>DD</sub> ≤3.6 V   | 0.7V <sub>DD</sub> <sup>(2)</sup>       | -                  | _  |      |  |
| V <sub>IH</sub>  | BOOT0 I/O input high level voltage         | 1.75 V≤V <sub>DD</sub> ≤3.6 V,<br>- 40 °C≤T <sub>A</sub> ≤105 °C   | 0.17V <sub>DD</sub> +0.7 <sup>(1)</sup> |                    |  | V    |  |
|                  |  | 1.7 V≤V <sub>DD</sub> ≤3.6 V,<br>0 °C≤T <sub>A</sub> ≤105 °C   | 0.17 V <sub>DD</sub> +0.7 × 7           | 1                  | -  |      |  |
|                  | FT, FTf, TTa and NRST I/O input hysteresis | 1.7 V≤V <sub>DD</sub> ≤3.6 V   | -                                       | 10%V <sub>DD</sub> | -  |      |  |
| V <sub>HYS</sub> | BOOT0 I/O input hysteresis                 | 1.75 V≤V <sub>DD</sub> ≤3.6 V,<br>-40 °C≤T <sub>A</sub> ≤105 °C  | -                                       | 100m               | -  | V    |  |
|                  | BOOTO I/O Input hysteresis                 | 1.7 V≤V <sub>DD</sub> ≤3.6 V,<br>0 °C≤T <sub>A</sub> ≤105 °C   | -                                       | 100111             | -  |      |  |
|                  | I/O input leakage current (3)              | $V_{SS} \leq V_{IN} \leq V_{DD}$   | -                                       | -                  | ±1                                       |      |  |
| l <sub>lkg</sub> | I/O FT input leakage current               | V <sub>IN</sub> = 5 V  | -                                       | -                  | 3  | μA   |  |

Table 56. I/O static characteristics (continued)

| Symbol                         | Para  | meter  | Conditions        | Min | Тур | Max | Unit  |
|--------------------------------|---|--|-------------------|-----|-----|-----|-------|
| R <sub>PU</sub>                | Weak pull-up<br>equivalent<br>resistor <sup>(5)</sup> | All pins<br>except for<br>PA10/PB12<br>(OTG_FS_ID,<br>OTG_HS_ID) | $V_{IN} = V_{SS}$ | 30  | 40  | 50  |       |
|                                |   | PA10/PB12<br>(OTG_FS_ID,<br>OTG_HS_ID)                           |                   | 7   | 10  | 14  | kΩ    |
| R <sub>PD</sub>                | Weak pull-<br>down<br>equivalent                      | All pins<br>except for<br>PA10/PB12<br>(OTG_FS_ID,<br>OTG_HS_ID) | $V_{IN} = V_{DD}$ | 30  | 40  | 50  | , K22 |
|                                | resistor <sup>(6)</sup>                               | PA10/PB12<br>(OTG_FS_ID,<br>OTG_HS_ID)                           |                   | 7   | 10  | 14  |       |
| C <sub>IO</sub> <sup>(7)</sup> | I/O pin capaci  | tance  | -                 | -   | 5   | -   | pF    |

- 1. Guaranteed by design, not tested in production.
- 2. Tested in production.
- Leakage could be higher than the maximum value, if negative current is injected on adjacent pins, Refer to Table 55: I/O current injection susceptibility
- To sustain a voltage higher than VDD +0.3 V, the internal pull-up/pull-down resistors must be disabled. Leakage could be higher than the maximum value, if negative current is injected on adjacent pins. Refer to Table 55: I/O current injection susceptibility
- 5. Pull-up resistors are designed with a true resistance in series with a switchable PMOS. This PMOS contribution to the series resistance is minimum (~10% order).
- Pull-down resistors are designed with a true resistance in series with a switchable NMOS. This NMOS contribution to the series resistance is minimum (~10% order).
- 7. Hysteresis voltage between Schmitt trigger switching levels. Based on characterization, not tested in production.

All I/Os are CMOS and TTL compliant (no software configuration required). Their characteristics cover more than the strict CMOS-technology or TTL parameters. The coverage of these requirements for FT I/Os is shown in *Figure 30*.

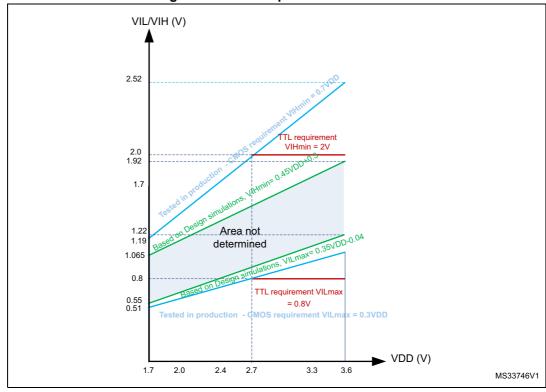


Figure 30. FT I/O input characteristics

#### **Output driving current**

The GPIOs (general purpose input/outputs) can sink or source up to  $\pm 20$  mA (with a relaxed  $V_{OL}/V_{OH}$ ) except PC13, PC14 and PC15 which can sink or source up to  $\pm 3$ mA. When using the PC13 to PC15 GPIOs in output mode, the speed should not exceed 2 MHz with a maximum load of 30 pF.

In the user application, the number of I/O pins which can drive current must be limited to respect the absolute maximum rating specified in *Section 6.2*. In particular:

- The sum of the currents sourced by all the I/Os on  $V_{DD}$ , plus the maximum Run consumption of the MCU sourced on  $V_{DD}$ , cannot exceed the absolute maximum rating  $\Sigma I_{VDD}$  (see *Table 14*).
- The sum of the currents sunk by all the I/Os on V<sub>SS</sub> plus the maximum Run consumption of the MCU sunk on V<sub>SS</sub> cannot exceed the absolute maximum rating ΣI<sub>VSS</sub> (see *Table 14*).

#### Output voltage levels

Unless otherwise specified, the parameters given in *Table 57* are derived from tests performed under ambient temperature and  $V_{DD}$  supply voltage conditions summarized in *Table 16*. All I/Os are CMOS and TTL compliant.

|                                | Table Cit Catput Total                   | 9   |                                     |                    |       |
|--------------------------------|--|---|-------------------------------------|--------------------|-------|
| Symbol                         | Parameter                                | Conditions  | Min                                 | Max                | Unit  |
| V <sub>OL</sub> <sup>(1)</sup> | Output low level voltage for an I/O pin  | CMOS port <sup>(2)</sup>                                      | -                                   | 0.4                |       |
| V <sub>OH</sub> <sup>(3)</sup> | Output high level voltage for an I/O pin | $I_{IO}$ = +8 mA<br>2.7 V $\leq$ V <sub>DD</sub> $\leq$ 3.6 V | V <sub>DD</sub> -0.4                | -                  | V     |
| V <sub>OL</sub> <sup>(1)</sup> | Output low level voltage for an I/O pin  | TTL port <sup>(2)</sup>                                       | -                                   | 0.4                |       |
| V <sub>OH</sub> <sup>(3)</sup> | Output high level voltage for an I/O pin | I <sub>IO</sub> =+ 8mA<br>2.7 V ≤V <sub>DD</sub> ≤3.6 V       | 2.4                                 | -                  | V     |
| V <sub>OL</sub> <sup>(1)</sup> | Output low level voltage for an I/O pin  | I <sub>IO</sub> = +20 mA                                      | -                                   | 1.3 <sup>(4)</sup> | V     |
| V <sub>OH</sub> <sup>(3)</sup> | Output high level voltage for an I/O pin | 2.7 V ≤V <sub>DD</sub> ≤3.6 V                                 | V <sub>DD</sub> -1.3 <sup>(4)</sup> | -                  | \ \ \ |
| V <sub>OL</sub> <sup>(1)</sup> | Output low level voltage for an I/O pin  | I <sub>IO</sub> = +6 mA                                       | -                                   | 0.4 <sup>(4)</sup> | V     |
| V <sub>OH</sub> <sup>(3)</sup> | Output high level voltage for an I/O pin | 1.8 V ≤V <sub>DD</sub> ≤3.6 V                                 | V <sub>DD</sub> -0.4 <sup>(4)</sup> | -                  | ľ     |
| V <sub>OL</sub> <sup>(1)</sup> | Output low level voltage for an I/O pin  | I <sub>IO</sub> = +4 mA                                       | -                                   | 0.4 <sup>(5)</sup> | V     |
| V <sub>OH</sub> <sup>(3)</sup> | Output high level voltage for an I/O pin | 1.7 V ≤V <sub>DD</sub> ≤3.6V                                  | V <sub>DD</sub> -0.4 <sup>(5)</sup> | -                  | ľ     |

Table 57. Output voltage characteristics

5. Guaranteed by design, not tested in production.

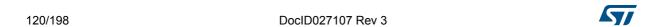
#### Input/output AC characteristics

The definition and values of input/output AC characteristics are given in *Figure 31* and *Table 58*, respectively.

Unless otherwise specified, the parameters given in *Table 58* are derived from tests performed under the ambient temperature and  $V_{DD}$  supply voltage conditions summarized in *Table 16*.

Table 58. I/O AC characteristics<sup>(1)(2)</sup>

| OSPEEDR<br>y[1:0] bit<br>value <sup>(1)</sup> | Symbol   | Parameter   | Conditions  | Min | Тур | Max | Unit |
|---|--|---|---|-----|-----|-----|------|
|   |  |   | $C_L = 50 \text{ pF}, V_{DD} \ge 2.7 \text{ V}$             | -   | -   | 4   |      |
|   | f <sub>max(IO)out</sub>                          | Maximum frequency <sup>(3)</sup>  | C <sub>L</sub> = 50 pF, V <sub>DD</sub> ≥ 1.7 V             | -   | -   | 2   | MHz  |
|   |  |   | C <sub>L</sub> = 10 pF, V <sub>DD</sub> ≥ 2.7 V             | -   | -   | 8   |      |
| 00  |  |   | C <sub>L</sub> = 10 pF, V <sub>DD</sub> ≥ 1.8 V             | -   | -   | 4   |      |
|   |  |   | C <sub>L</sub> = 10 pF, V <sub>DD</sub> ≥ 1.7 V             | -   | -   | 3   |      |
|   | t <sub>f(IO)out</sub> /<br>t <sub>r(IO)out</sub> | Output high to low level fall time and output low to high level rise time | C <sub>L</sub> = 50 pF, V <sub>DD</sub> = 1.7 V<br>to 3.6 V | ı   | 1   | 100 | ns   |



The I<sub>IO</sub> current sunk by the device must always respect the absolute maximum rating specified in *Table 14*.
 and the sum of I<sub>IO</sub> (I/O ports and control pins) must not exceed I<sub>VSS</sub>.

<sup>2.</sup> TTL and CMOS outputs are compatible with JEDEC standards JESD36 and JESD52.

<sup>3.</sup> The  $I_{IO}$  current sourced by the device must always respect the absolute maximum rating specified in *Table 14* and the sum of  $I_{IO}$  (I/O ports and control pins) must not exceed  $I_{VDD}$ .

<sup>4.</sup> Based on characterization data.

Table 58. I/O AC characteristics<sup>(1)(2)</sup> (continued)

| OSPEEDR<br>y[1:0] bit<br>value <sup>(1)</sup> | Symbol                  | Parameter   | Conditions                                      | Min | Тур | Max                | Unit  |  |
|---|-------------------------|---|---|-----|-----|--------------------|-------|--|
|   |                         |   | C <sub>L</sub> = 50 pF, V <sub>DD</sub> ≥ 2.7 V | -   | -   | 25                 |       |  |
|   |                         |   | C <sub>L</sub> = 50 pF, V <sub>DD</sub> ≥ 1.8 V | -   | -   | 12.5               |       |  |
|   | £                       | Maximum fraguanay(3)  | C <sub>L</sub> = 50 pF, V <sub>DD</sub> ≥ 1.7 V | -   | -   | 10                 | NALI- |  |
|   | f <sub>max(IO)out</sub> | Maximum frequency <sup>(3)</sup>  | C <sub>L</sub> = 10 pF, V <sub>DD</sub> ≥ 2.7 V | -   | -   | 50                 | MHz   |  |
| 04  |                         |   | C <sub>L</sub> = 10 pF, V <sub>DD</sub> ≥ 1.8 V | -   | -   | 20                 |       |  |
| 01  |                         |   | C <sub>L</sub> = 10 pF, V <sub>DD</sub> ≥ 1.7 V | -   | -   | 12.5               |       |  |
|   |                         |   | C <sub>L</sub> = 50 pF, V <sub>DD</sub> ≥ 2.7 V | -   | -   | 10                 |       |  |
|   | t <sub>f(IO)out</sub> / | Output high to low level fall   | C <sub>L</sub> = 10 pF, V <sub>DD</sub> ≥ 2.7 V | -   | -   | 6                  |       |  |
|   | t <sub>r(IO)</sub> out  | time and output low to high level rise time                               | C <sub>L</sub> = 50 pF, V <sub>DD</sub> ≥ 1.7 V | -   | -   | 20                 | ns    |  |
|   |                         |   | C <sub>L</sub> = 10 pF, V <sub>DD</sub> ≥ 1.7 V | -   | -   | 10                 |       |  |
|   |                         |   | C <sub>L</sub> = 40 pF, V <sub>DD</sub> ≥ 2.7 V | -   | -   | 50 <sup>(4)</sup>  |       |  |
|   |                         |   | C <sub>L</sub> = 10 pF, V <sub>DD</sub> ≥ 2.7 V | -   | -   | 100 <sup>(4)</sup> | MHz   |  |
|   | f <sub>max(IO)out</sub> | Maximum frequency <sup>(3)</sup>  | C <sub>L</sub> = 40 pF, V <sub>DD</sub> ≥ 1.7 V | -   | -   | 25                 |       |  |
|   |                         |   | C <sub>L</sub> = 10 pF, V <sub>DD</sub> ≥ 1.8 V | -   | -   | 50                 |       |  |
| 10  |                         |   | C <sub>L</sub> = 10 pF, V <sub>DD</sub> ≥ 1.7 V | -   | -   | 42.5               |       |  |
|   | _                       |   | C <sub>L</sub> = 40 pF, V <sub>DD</sub> ≥2.7 V  | -   | -   | 6                  |       |  |
|   | t <sub>f(IO)out</sub> / | Output high to low level fall time and output low to high level rise time | C <sub>L</sub> = 10 pF, V <sub>DD</sub> ≥ 2.7 V | -   | -   | 4                  |       |  |
|   | t <sub>r(IO)out</sub>   |   | C <sub>L</sub> = 40 pF, V <sub>DD</sub> ≥ 1.7 V | -   | -   | 10                 | ns    |  |
|   |                         |   | C <sub>L</sub> = 10 pF, V <sub>DD</sub> ≥ 1.7 V | -   | -   | 6                  |       |  |
|   |                         |   | $C_L = 30 \text{ pF}, V_{DD} \ge 2.7 \text{ V}$ | -   | -   | 100 <sup>(4)</sup> |       |  |
|   |                         |   | C <sub>L</sub> = 30 pF, V <sub>DD</sub> ≥ 1.8 V | -   | -   | 50                 | 1     |  |
|   |                         | Manipulation (3)  | C <sub>L</sub> = 30 pF, V <sub>DD</sub> ≥ 1.7 V | -   | -   | 42.5               |       |  |
|   | f <sub>max(IO)out</sub> | Maximum frequency <sup>(3)</sup>  | C <sub>L</sub> = 10 pF, V <sub>DD</sub> ≥ 2.7 V | -   | -   | 180 <sup>(4)</sup> | MHz   |  |
|   |                         |   | C <sub>L</sub> = 10 pF, V <sub>DD</sub> ≥ 1.8 V | -   | -   | 100                |       |  |
| 44  |                         |   | C <sub>L</sub> = 10 pF, V <sub>DD</sub> ≥ 1.7 V | -   | -   | 72.5               |       |  |
| 11  |                         |   | $C_L = 30 \text{ pF}, V_{DD} \ge 2.7 \text{ V}$ | -   | -   | 4                  |       |  |
|   |                         |   | C <sub>L</sub> = 30 pF, V <sub>DD</sub> ≥1.8 V  | -   | -   | 6                  |       |  |
|   | t <sub>f(IO)out</sub> / | Output high to low level fall   | C <sub>L</sub> = 30 pF, V <sub>DD</sub> ≥1.7 V  | -   | -   | 7                  | ns    |  |
|   | t <sub>r(IO)out</sub>   | time and output low to high level rise time                               | C <sub>L</sub> = 10 pF, V <sub>DD</sub> ≥ 2.7 V | -   | -   | 2.5                |       |  |
|   | •                       |   | C <sub>L</sub> = 10 pF, V <sub>DD</sub> ≥1.8 V  | -   | -   | 3.5                |       |  |
|   |                         |   | C <sub>L</sub> = 10 pF, V <sub>DD</sub> ≥1.7 V  | -   | -   | 4                  |       |  |
| -   | t <sub>EXTIpw</sub>     | Pulse width of external signals detected by the EXTI controller           | -   | 10  | -   | -                  | ns    |  |



- 1. Guaranteed by design, not tested in production.
- The I/O speed is configured using the OSPEEDRy[1:0] bits. Refer to the STM32F4xx reference manual for a description of the GPIOx\_SPEEDR GPIO port output speed register.
- 3. The maximum frequency is defined in *Figure 31*.
- 4. For maximum frequencies above 50 MHz and  $V_{DD}$  > 2.4 V, the compensation cell should be used.

EXTERNAL OUTPUT ON CL

Maximum frequency is achieved if  $(t_r + t_f) \le (2/3)T$  and if the duty cycle is (45-55%) when loaded by CL specified in the table " I/O AC characteristics".

Figure 31. I/O AC characteristics definition

# 6.3.18 NRST pin characteristics

The NRST pin input driver uses CMOS technology. It is connected to a permanent pull-up resistor, R<sub>PU</sub> (see *Table 56: I/O static characteristics*).

Unless otherwise specified, the parameters given in *Table 59* are derived from tests performed under the ambient temperature and  $V_{DD}$  supply voltage conditions summarized in *Table 16*.

| Symbol                               | Parameter                                       | Conditions              | Min | Тур | Max | Unit |
|--------------------------------------|---|-------------------------|-----|-----|-----|------|
| R <sub>PU</sub>                      | Weak pull-up equivalent resistor <sup>(1)</sup> | $V_{IN} = V_{SS}$       | 30  | 40  | 50  | kΩ   |
| V <sub>F(NRST)</sub> <sup>(2)</sup>  | NRST Input filtered pulse                       | -                       | -   | -   | 100 | ns   |
| V <sub>NF(NRST)</sub> <sup>(2)</sup> | NRST Input not filtered pulse                   | V <sub>DD</sub> > 2.7 V | 300 | -   | -   | ns   |
| T <sub>NRST_OUT</sub>                | Generated reset pulse duration                  | Internal Reset source   | 20  | -   | i   | μs   |

Table 59. NRST pin characteristics

2. Guaranteed by design, not tested in production.

The pull-up is designed with a true resistance in series with a switchable PMOS. This PMOS contribution to the series resistance must be minimum (~10% order).

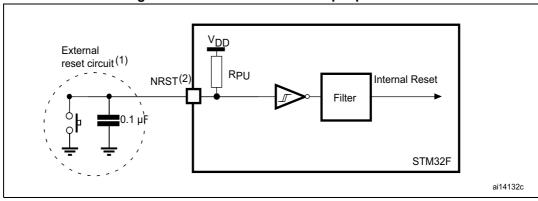


Figure 32. Recommended NRST pin protection

- 1. The reset network protects the device against parasitic resets.
- 2. The user must ensure that the level on the NRST pin can go below the V<sub>IL(NRST)</sub> max level specified in *Table 59*. Otherwise the reset is not taken into account by the device.

#### 6.3.19 TIM timer characteristics

The parameters given in Table 60 are guaranteed by design.

Refer to Section 6.3.17: I/O port characteristics for details on the input/output alternate function characteristics (output compare, input capture, external clock, PWM output).

| Symbol                 | Parameter  | Conditions <sup>(3)</sup>  | Min | Max                     | Unit                 |
|------------------------|--|--|-----|-------------------------|----------------------|
| t                      | Timer resolution time                              | AHB/APBx<br>prescaler=1 or 2 or 4,<br>f <sub>TIMxCLK</sub> = 180 MHz | 1   | -                       | t <sub>TIMxCLK</sub> |
| <sup>t</sup> res(TIM)  | Time resolution time                               | AHB/APBx<br>prescaler>4, f <sub>TIMxCLK</sub><br>= 90 MHz            | 1   | -                       | t <sub>TIMxCLK</sub> |
| f <sub>EXT</sub>       | Timer external clock<br>frequency on CH1 to<br>CH4 | f <sub>TIMxCLK</sub> = 180 MHz                                       | 0   | f <sub>TIMxCLK</sub> /2 | MHz                  |
| Res <sub>TIM</sub>     | Timer resolution                                   |  | -   | 16/32                   | bit                  |
| t <sub>MAX_COUNT</sub> | Maximum possible count with 32-bit counter         | -  | -   | 65536 ×<br>65536        | t <sub>TIMxCLK</sub> |

Table 60. TIMx characteristics<sup>(1)(2)</sup>

- 1. TIMx is used as a general term to refer to the TIM1 to TIM12 timers.
- 2. Guaranteed by design, not tested in production.
- 3. The maximum timer frequency on APB1 or APB2 is up to 180 MHz, by setting the TIMPRE bit in the RCC\_DCKCFGR register, if APBx prescaler is 1 or 2 or 4, then TIMxCLK = HCKL, otherwise TIMxCLK = 4x PCLKx.

### 6.3.20 Communications interfaces

# I<sup>2</sup>C interface characteristics

The I<sup>2</sup>C interface meets the requirements of the standard I<sup>2</sup>C communication protocol with the following restrictions: the I/O pins SDA and SCL too are mapped as not "true"



open-drain. When configured as open-drain, the PMOS connected between the I/O pin and  $V_{DD}$  is disabled, but is still present.

The I<sup>2</sup>C characteristics are described in *Table 61*. Refer also to *Section 6.3.17: I/O port characteristics* for more details on the input/output alternate function characteristics (SDA and SCL).

Table 61. I<sup>2</sup>C characteristics

| Symbol                                     | Parameter  | Standaı<br>I <sup>2</sup> C <sup>(</sup> | rd mode<br>1)(2)    | Fast mode | Unit                |    |  |
|--|--|--|---------------------|-----------|---------------------|----|--|
|  |  | Min                                      | Max                 | Min       | Max                 |    |  |
| t <sub>w(SCLL)</sub>                       | SCL clock low time   | 4.7                                      | -                   | 1.3       | -                   | ше |  |
| t <sub>w(SCLH)</sub>                       | SCL clock high time  | 4.0                                      | -                   | 0.6       | -                   | μs |  |
| t <sub>su(SDA)</sub>                       | SDA setup time   | 250                                      | -                   | 100       | -                   |    |  |
| t <sub>h(SDA)</sub>                        | SDA data hold time   | -  | 3450 <sup>(3)</sup> | -         | 900 <sup>(4)</sup>  |    |  |
| t <sub>v(SDA, ACK)</sub>                   | Data, ACK valid time   | -  | 3.45                | -         | 0.9                 |    |  |
| t <sub>r(SDA)</sub><br>t <sub>r(SCL)</sub> | SDA and SCL rise time  | -  | 1000                | -         | 300                 | ns |  |
| t <sub>f(SDA)</sub><br>t <sub>f(SCL)</sub> | SDA and SCL fall time  | -  | 300                 | -         | 300                 |    |  |
| t <sub>h(STA)</sub>                        | Start condition hold time  | 4.0                                      | -                   | 0.6       | -                   |    |  |
| t <sub>su(STA)</sub>                       | Repeated Start condition setup time  | 4.7                                      | -                   | 0.6       | -                   | μs |  |
| t <sub>su(STO)</sub>                       | Stop condition setup time  | 4.0                                      | -                   | 0.6       | -                   | μs |  |
| t <sub>w(STO:STA)</sub>                    | Stop to Start condition time (bus free)  | 4.7                                      | -                   | 1.3       | -                   | μs |  |
| t <sub>SP</sub>                            | Pulse width of the spikes<br>that are suppressed by the<br>analog filter for standard and<br>fast mode | -  | -                   | 0.05      | 0.09 <sup>(5)</sup> | μs |  |
| C <sub>b</sub>                             | Capacitive load for each bus line  | -  | 400                 | -         | 400                 | pF |  |

<sup>1.</sup> Based on characterization result, not tested in production.

f<sub>PCLK1</sub> must be at least 2 MHz to achieve standard mode I<sup>2</sup>C frequencies. It must be at least 4 MHz to achieve fast mode I<sup>2</sup>C frequencies, and a multiple of 10 MHz to reach the 400 kHz maximum I<sup>2</sup>C fast mode clock.

<sup>3.</sup> The device must internally provide a hold time of at least 300 ns for the SDA signal in order to bridge the undefined region of the falling edge of SCL.

The maximum data hold time has only to be met if the interface does not stretch the low period of SCL signal.

<sup>5.</sup> The minimum width of the spikes filtered by the analog filter is above  $t_{SP}(max)$ .

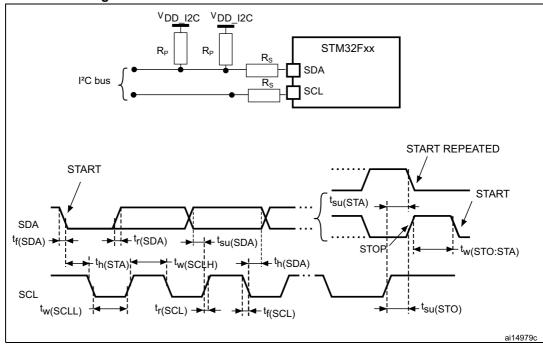


Figure 33. I<sup>2</sup>C bus AC waveforms and measurement circuit

- 1.  $R_S$  = series protection resistor.
- 2.  $R_P$  = external pull-up resistor.
- 3.  $V_{DD\_I2C}$  is the I2C bus power supply.

# FMPI<sup>2</sup>C characteristics

The FMPI2C characteristics are described in Table 62.

Refer also to Section 6.3.17: I/O port characteristics for more details on the input/output alternate function characteristics (SDA and SCL).

Table 62. FMPI<sup>2</sup>C characteristics<sup>(1)</sup>

|  | Damana dan   | Standa | rd mode | Fast | mode | Fast+                   | mode               | Unit |
|--|--|--------|---------|------|------|-------------------------|--------------------|------|
| -  | Parameter  | Min    | Max     | Min  | Max  | Min                     | Max                | Unit |
| f <sub>FMPI2CC</sub>                       | F <sub>MPI2CCLK</sub> frequency  | 2      | -       | 8    | -    | 17<br>16 <sup>(2)</sup> | -                  |      |
| t <sub>w(SCLL)</sub>                       | SCL clock low time   | 4.7    | -       | 1.3  | -    | 0.5                     | -                  |      |
| t <sub>w(SCLH)</sub>                       | SCL clock high time  | 4.0    | -       | 0.6  | -    | 0.26                    | -                  |      |
| t <sub>su(SDA)</sub>                       | SDA setup time   | 0.25   | -       | 0.10 | -    | 0.05                    | -                  |      |
| t <sub>H(SDA)</sub>                        | SDA data hold time   | 0      | -       | 0    | -    | 0                       | -                  |      |
| t <sub>v(SDA,ACK)</sub>                    | Data, ACK valid time   | -      | 3.45    | -    | 0.9  | -                       | 0.45               |      |
| t <sub>r(SDA)</sub><br>t <sub>r(SCL)</sub> | SDA and SCL rise time  | -      | 0.100   | -    | 0.30 | -                       | 0.12               |      |
| t <sub>f(SDA)</sub>                        | SDA and SCL fall time  | -      | 0.30    | -    | 0.30 | -                       | 0.12               | us   |
| t <sub>h(STA)</sub>                        | Start condition hold time  | 4      | -       | 0.6  | -    | 0.26                    | -                  |      |
| t <sub>su(STA)</sub>                       | Repeated Start condition setup time  | 4.7    | -       | 0.6  | -    | 0.26                    | -                  |      |
| t <sub>su(STO)</sub>                       | Stop condition setup time  | 4      | -       | 0.6  | -    | 0.26                    | -                  |      |
| t <sub>w(STO:STA)</sub>                    | Stop to Start condition time (bus free)  | 4.7    | -       | 1.3  | -    | 0.5                     | -                  |      |
| t <sub>SP</sub>                            | Pulse width of the spikes that<br>are suppressed by the<br>analog filter for standard and<br>fast mode | -      | -       | 0.05 | 0.09 | 0.05                    | 0.09               |      |
| C <sub>b</sub>                             | Capacitive load for each bus Line  | -      | 400     | -    | 400  | -                       | 550 <sup>(3)</sup> | pF   |

<sup>1.</sup> Based on characterization results, not tested in production.

<sup>2.</sup> When tr(SDA,SCL)<=110ns.

<sup>3.</sup> Can be limited. Maximum supported value can be retrieved by referring to the following formulas:  $t_{T(SDA/SCL)} = 0.8473 \times R_p \times C_{load} \\ R_{p(min)} = (V_{DD} - V_{OL(max)}) / I_{OL(max)}$ 

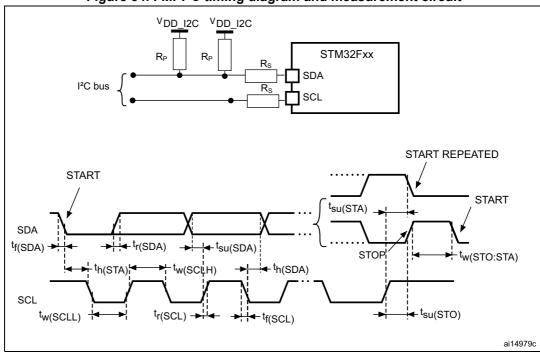


Figure 34. FMPI<sup>2</sup>C timing diagram and measurement circuit



#### **SPI** interface characteristics

Unless otherwise specified, the parameters given in *Table 63* for SPI are derived from tests performed under the ambient temperature, fPCLKx frequency and VDD supply voltage conditions summarized in *Table 16*, with the following configuration:

- Output speed is set to OSPEEDRy[1:0] = 10
- Capacitive load C=30pF
- Measurement points are done at CMOS levels: 0.5VDD

Refer to Section 6.3.17: I/O port characteristics for more details on the input/output alternate function characteristics (NSS, SCK, MOSI, MISO for SPI).

Table 63. SPI dynamic characteristics<sup>(1)</sup>

| Symbol                                    | Parameter                         | Conditions  | Min | Тур | Max                 | Unit |  |
|---|-----------------------------------|---|-----|-----|---------------------|------|--|
| f <sub>SCK</sub><br>1/t <sub>c(SCK)</sub> | SPI clock frequency               | Master full duplex/receiver mode,<br>2.7 V≤V <sub>DD</sub> ≤3.6 V<br>SPI1/4         |     |     |                     | 45   |  |
|   |                                   | Master transmitter<br>1.71V <v<sub>DD&lt; 3.6V<br/>SPI1/4</v<sub>                   |     |     | 45                  |      |  |
|   |                                   | Master<br>1.71V <v<sub>DD&lt; 3.6V<br/>SPI1/2/3/4</v<sub>                           |     |     | 22.5                |      |  |
|   |                                   | Slave transmitter/<br>full duplex mode<br>SPI1/4<br>2.7V <v<sub>DD&lt; 3.6V</v<sub> | -   | -   | 45                  | MHz  |  |
|   |                                   | Slave receiver mode<br>SPI1/4<br>1.71V <v<sub>DD&lt; 3.6V</v<sub>                   |     |     | 45                  |      |  |
|   |                                   | Slave mode<br>SPI1/2/3/4<br>1.71V <v<sub>DD&lt; 3.6V</v<sub>                        |     |     | 22.5 <sup>(2)</sup> |      |  |
| Duty(SCK)                                 | Duty cycle of SPI clock frequency | Slave mode  | 30  | 50  | 70                  | %    |  |

| Symbol               | Parameter                   | Conditions   | Min                     | Тур               | Max                     | Unit |
|----------------------|-----------------------------|--|-------------------------|-------------------|-------------------------|------|
| t <sub>w(SCKH)</sub> | SCK high and low time       | Master mode, SPI presc = 2   | T <sub>PCLK</sub> - 1.5 | T <sub>PCLK</sub> | T <sub>PCLK</sub> + 1.5 |      |
| t <sub>su(NSS)</sub> | NSS setup time              | Slave mode, SPI presc = 2  | 4T <sub>PCLK</sub>      |                   |                         |      |
| t <sub>h(NSS)</sub>  | NSS hold time               | Slave mode, SPI presc = 2  | 2T <sub>PCLK</sub>      | -                 | -                       |      |
| t <sub>su(MI)</sub>  | Data input setup time       | Master mode  | 4                       | -                 | -                       |      |
| t <sub>su(SI)</sub>  | Data input setup time       | Slave mode   | 3                       | -                 | -                       |      |
| t <sub>h(MI)</sub>   | Data input hold time        | Master mode  | 4                       | -                 | -                       |      |
| t <sub>h(SI)</sub>   | Data input noid time        | Slave mode   | 2                       | -                 | -                       | i    |
| t <sub>a(SO</sub> )  | Data output access time     | Slave mode   | 7                       | -                 | 21                      | ns   |
| t <sub>dis(SO)</sub> | Data output disable time    | Slave mode   | 5                       | -                 | 12                      | i    |
| +                    | Data output valid/hold      | Slave mode (after enable edge), $2.7V \le V_{DD} \le 3.6V$                                 | -                       | 7.5               | 22                      |      |
| t <sub>v(SO)</sub>   | time                        | Slave mode (after enable edge), $1.7 \text{ V} \le \text{V}_{\text{DD}} \le 3.6 \text{ V}$ | -                       | 7.5               | 10.5                    |      |
| t <sub>h(SO)</sub>   | Data output valid/hold time | Slave mode (after enable edge)   | 5                       | -                 | -                       |      |
| t <sub>v(MO)</sub>   | Data output valid time      | Master mode (after enable edge)  | -                       | 1.5               | 5                       |      |
| t <sub>h(MO)</sub>   | Data output hold time       | Master mode (after enable edge)  | 0                       | -                 | -                       |      |

Table 63. SPI dynamic characteristics<sup>(1)</sup> (continued)

<sup>2.</sup> Maximum frequency in Slave transmitter mode is determined by the sum of  $t_{v(SO)}$  and  $t_{su(MI)}$  which has to fit into SCK low or high phase preceding the SCK sampling edge. This value can be achieved when the SPI communicates with a master having  $t_{su(MI)} = 0$  while Duty(SCK) = 50%.

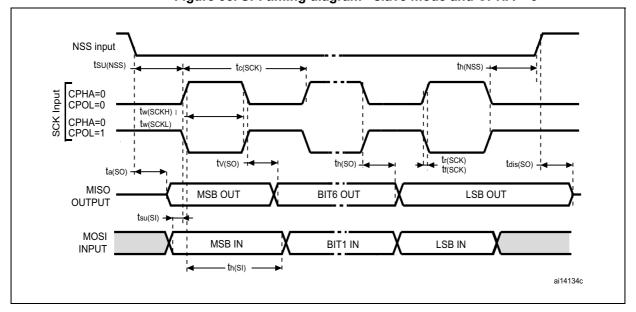
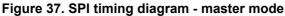


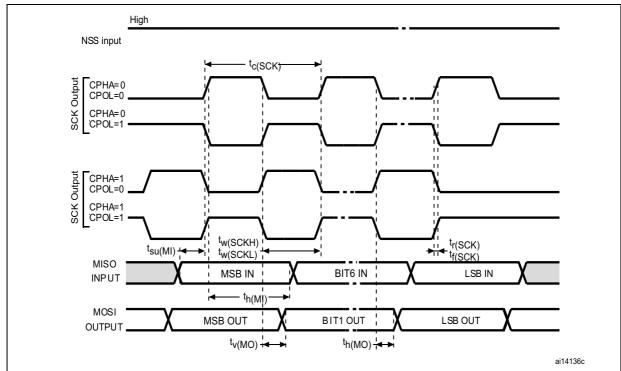
Figure 35. SPI timing diagram - slave mode and CPHA = 0

<sup>1.</sup> Guaranteed by characterization results, not tested in production.

NSS input tsu(NSS) tc(SCK) th(NSS)CPHA=1 CPOL=0 tw(SCKH) CPHA=1 tw(SCKL) CPOL=1 tr(SCK) th(SO) tdis(SO) tv(SO) → ta(SO) → tf(SCK) MISO MSB OUT **BIT6 OUT** LSB OUT OUTPUT th(SI) tsu(SI) MOSI MSB IN BIT 1 IN LSB IN **INPUT** ai14135b

Figure 36. SPI timing diagram - slave mode and CPHA = 1





#### **QSPI** interface characteristics

Unless otherwise specified, the parameters given in *Table 64* for QSPI are derived from tests performed under the ambient temperature,  $f_{AHB}$  frequency and  $V_{DD}$  supply voltage conditions summarized in *Table 16*, with the following configuration:

- Output speed is set to OSPEEDRy[1:0] = 11
- Capacitive load C=20pF
- Measurement points are done at CMOS levels: 0.5VDD

Refer to Section 6.3.17: I/O port characteristics for more details on the input/output alternate function characteristics.

Table 64. QSPI dynamic characteristics in SDR Mode<sup>(1)</sup>

| Symbol                                    | Parameter                | Conditions   | Min                         | Тур | Max                        | Unit |  |
|---|--------------------------|--|-----------------------------|-----|----------------------------|------|--|
|   |                          | Write mode 1.71 $V \le V_{DD} \le 3.6 \text{ V}$ Cload = 15 pF | -                           | -   | 90                         |      |  |
| f <sub>SCK</sub><br>1/t <sub>c(SCK)</sub> | QSPI clock frequency     | Read mode<br>2.7V <vdd< 3.6v<br="">Cload = 15 pF</vdd<>        | -                           | -   | 90                         | MHz  |  |
|   |                          | 1.71 V≤V <sub>DD</sub> ≤3.6 V                                  | -                           | -   | 48                         |      |  |
| t <sub>w(CKH)</sub>                       | QSPI clock high and low  | _  | (T <sub>(CK)</sub> / 2) - 2 | -   | T <sub>(CK)</sub> / 2      |      |  |
| t <sub>w(CKL)</sub>                       | QOI I CIOCK HIGH AND IOW | -  | T <sub>(CK)</sub> / 2       | -   | (T <sub>(CK)</sub> / 2) +2 |      |  |
| t <sub>s(IN)</sub>                        | Data input setup time    | -  | 2                           | -   | -                          | ns   |  |
| t <sub>h(IN)</sub>                        | Data input hold time     | -  | 4.5                         | -   | -                          | 113  |  |
| t <sub>v(OUT)</sub>                       | Data output valid time   | -  | -                           | 1.5 | 3                          |      |  |
| t <sub>h(OUT)</sub>                       | Data output hold time    | -  | 0                           | -   | -                          |      |  |

<sup>1.</sup> Guaranteed by characterization results, not tested in production.

Table 65. QSPI dynamic characteristics in DDR Mode<sup>(1)</sup>

| Symbol           | Parameter            | Conditions   | Min | Тур | Max | Unit |
|------------------|----------------------|--|-----|-----|-----|------|
| f <sub>SCK</sub> |                      | Write mode<br>1.71 V≤V <sub>DD</sub> ≤3.6 V<br>Cload = 15 pF | -   | -   | 60  |      |
|                  | QSPI clock frequency | Read mode<br>2.7V <vdd< 3.6v<br="">Cload = 15 pF</vdd<>      | -   | -   | 60  | MHz  |
|                  |                      | 1.71 V≤V <sub>DD</sub> ≤3.6 V                                | -   | -   | 48  |      |



|                     | rable of agriculture official official of the part mode (continuou) |  |                             |     |                            |      |  |  |
|---------------------|---|--|-----------------------------|-----|----------------------------|------|--|--|
| Symbol              | Parameter   | Conditions   | Min                         | Тур | Max                        | Unit |  |  |
| t <sub>w(CKH)</sub> | QSPI clock high and low   |  | (T <sub>(CK)</sub> / 2) - 2 | -   | T <sub>(CK)</sub> / 2      |      |  |  |
| t <sub>w(CKL)</sub> | QSFI Clock High and low   | -  | T <sub>(CK)</sub> / 2       | -   | (T <sub>(CK)</sub> / 2) +2 |      |  |  |
| t <sub>s(IN)</sub>  | Data input setup time   | -  | 0                           | -   | -                          |      |  |  |
| t <sub>h(IN)</sub>  | Data input hold time  | -  | 5.5                         | -   | -                          | ns   |  |  |
| +                   | Data output valid time  | 2.7V <vdd< 3.6v<="" td=""><td>-</td><td>5.5</td><td>6.5</td><td></td></vdd<> | -                           | 5.5 | 6.5                        |      |  |  |
| τ <sub>ν(OUT)</sub> | Data output valid time  | 1.71V <vdd< 3.6v<="" td=""><td>-</td><td>8</td><td>9.5</td><td></td></vdd<>  | -                           | 8   | 9.5                        |      |  |  |
|                     |   |  | 1                           |     | 1                          | 1    |  |  |

Table 65. QSPI dynamic characteristics in DDR Mode<sup>(1)</sup> (continued)

Data output hold time

# I<sup>2</sup>S interface characteristics

Unless otherwise specified, the parameters given in *Table 66* for the  $I^2S$  interface are derived from tests performed under the ambient temperature,  $f_{PCLKx}$  frequency and  $V_{DD}$  supply voltage conditions summarized in *Table 16*, with the following configuration:

3.5

- Output speed is set to OSPEEDRy[1:0] = 10
- Capacitive load C = 30 pF
- Measurement points are done at CMOS levels: 0.5V<sub>DD</sub>

Refer to Section 6.3.17: I/O port characteristics for more details on the input/output alternate function characteristics (CK, SD, WS).

Table 66. I<sup>2</sup>S dynamic characteristics<sup>(1)</sup>

| Symbol           | Parameter                           | Conditions     | Min      | Max                     | Unit    |
|------------------|-------------------------------------|----------------|----------|-------------------------|---------|
| f <sub>MCK</sub> | I2S Main clock output               | -              | 256 x 8K | 256 x Fs <sup>(2)</sup> | MHz     |
| f                | 129 clock frequency                 | Master data    | -        | 64 x Fs                 | MHz     |
| 'CK              | f <sub>CK</sub> I2S clock frequency | Slave data     | -        | 64 x Fs                 | IVII IZ |
| D <sub>CK</sub>  | I2S clock frequency duty cycle      | Slave receiver | 30       | 70                      | %       |

<sup>1.</sup> Guaranteed by characterization results, not tested in production.

 $t_{h(SD\_MT)}$ 

**Conditions Symbol Parameter** Min Max Unit WS valid time Master mode 5.5  $t_{v(WS)}$ WS hold time Master mode 1 t<sub>h(WS)</sub> Slave mode 1 t<sub>su(WS)</sub> WS setup time PCM short pulse Slave mode<sup>(3)</sup> 2 3 Slave mode t<sub>h(WS)</sub> WS hold time PCM short pulse Slave mode<sup>(3)</sup> 1.5 3 Master receiver t<sub>su(SD\_MR)</sub> Data input setup time ns Slave receiver 2.5 t<sub>su(SD\_SR)</sub> 4 Master receiver t<sub>h(SD MR)</sub> Data input hold time Slave receiver 1  $t_{h(SD\_SR)}$ Slave transmitter (after enable edge) 16  $t_{v(SD\_ST)}$ Data output valid time Master transmitter (after enable edge)  $t_{v(SD\_MT)}$ 4.5 Slave transmitter (after enable edge) 5 t<sub>h(SD\_ST)</sub> Data output hold time

Table 66. I<sup>2</sup>S dynamic characteristics<sup>(1)</sup> (continued)

- 1. Guaranteed by characterization results, not tested in production.
- 2. The maximum value of 256xFs is 45 MHz (APB1 maximum frequency).
- 3. Measurement done with respect to I2S\_CK rising edge.

Note: Refer to the I2S section of RM0390 reference manual for more details on the sampling frequency  $(F_S)$ .

 $f_{MCK}$ ,  $f_{CK}$ , and  $D_{CK}$  values reflect only the digital peripheral behavior. The values of these parameters might be slightly impacted by the source clock precision.  $D_{CK}$  depends mainly on the value of ODD bit. The digital contribution leads to a minimum value of (I2SDIV/(2\*I2SDIV+ODD) and a maximum value of (I2SDIV+ODD)/(2\*I2SDIV+ODD).  $F_{S}$  maximum value is supported for each mode/condition.

Master transmitter (after enable edge)

1



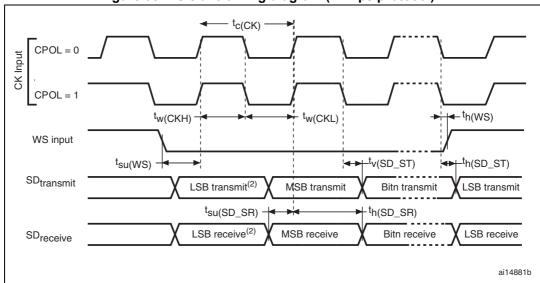


Figure 38. I<sup>2</sup>S slave timing diagram (Philips protocol)<sup>(1)</sup>

LSB transmit/receive of the previously transmitted byte. No LSB transmit/receive is sent before the first byte.

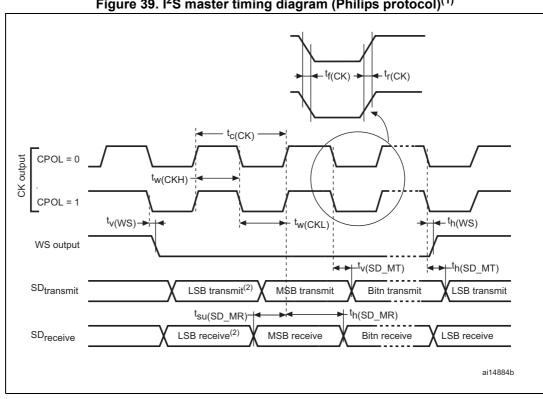


Figure 39. I<sup>2</sup>S master timing diagram (Philips protocol)<sup>(1)</sup>

LSB transmit/receive of the previously transmitted byte. No LSB transmit/receive is sent before the first 1. byte.

#### **SAI** characteristics

Unless otherwise specified, the parameters given in *Table 67* for SAI are derived from tests performed under the ambient temperature, f<sub>PCLKx</sub> frequency and VDD supply voltage conditions summarized in *Table 16*, with the following configuration:

- Output speed is set to OSPEEDRy[1:0] = 10
- Capacitive load C=30 pF
- Measurement points are performed at CMOS levels: 0.5V<sub>DD</sub>

Refer to Section 6.3.17: I/O port characteristics for more details on the input/output alternate function characteristics (SCK,SD,WS).

Table 67. SAI characteristics<sup>(1)</sup>

| Symbol                   | Parameter                          | Conditions  | Min      | Max                     | Unit  |
|--------------------------|------------------------------------|---|----------|-------------------------|-------|
| f <sub>MCK</sub>         | SAI Main clock output              | -   | 256 x 8K | 256 x Fs                | MHz   |
| f                        | SAI clock frequency <sup>(2)</sup> | Master data: 32 bits  | -        | 128 x Fs <sup>(3)</sup> | MHz   |
| f <sub>CK</sub>          | SAI Clock frequency.               | Slave data: 32 bits   | -        | 128 x Fs <sup>(3)</sup> | IVI□∠ |
| t                        | FS valid time                      | Master mode<br>2.7 V ≤ V <sub>DD</sub> ≤3.6 V                                   | -        | 14                      | %     |
| t <sub>v(FS)</sub>       | rs valid time                      | Master mode<br>1.71 V ≤ V <sub>DD</sub> ≤3.6 V                                  | -        | 17.5                    |       |
| t <sub>h(FS)</sub>       | FS hold time                       | Master mode   | 7        | -                       |       |
| t <sub>su(FS)</sub>      | FS setup time                      | Slave mode  | 1        | -                       |       |
| t <sub>h(FS)</sub>       | FS hold time                       | Slave mode  | 1        | -                       |       |
| t <sub>su(SD_A_MR)</sub> | Data input actus time              | Master receiver   | 1        | -                       |       |
| t <sub>su(SD_B_SR)</sub> | Data input setup time              | Slave receiver  | 1        | -                       |       |
| t <sub>h(SD_A_MR)</sub>  | Data input hold time               | Master receiver   | 5        | -                       |       |
| t <sub>h(SD_B_SR)</sub>  | Data input hold time               | Slave receiver  | 1        | -                       | no    |
| 4                        | Data output valid time             | Slave trasmitter (after enable edge 2.7 V $\leq$ V <sub>DD</sub> $\leq$ 3.6 V   | -        | 9.5                     | ns    |
| t <sub>v(SD_B_ST)</sub>  | Data output valid time             | Slave transmitter (after enable edge 1.71 V ≤ V <sub>DD</sub> ≤3.6 V            | -        | 16                      |       |
| t <sub>h(SD_B_ST)</sub>  | Data output hold time              | Slave transmitter (after enable edge  | 6        | -                       |       |
| t                        | Data output valid time             | Master transmitter (after enable edge 2.7 V $\leq$ V <sub>DD</sub> $\leq$ 3.6 V | -        | 15                      |       |
| t <sub>v(SD_B_ST)</sub>  | Data output valid time             | Master transmitter (after enable edge 1.71 V ≤ V <sub>DD</sub> ≤3.6 V           | -        | 18                      |       |
| t <sub>h(SD_B_ST)</sub>  | Data output hold time              | Master transmitter (after enable edge   | 7        | -                       |       |

<sup>1.</sup> Guaranteed by characterization results, not tested in production.



<sup>2. 256</sup>xFs maximum corresponds to 45 MHz (APB2 xaximum frequency)

<sup>3.</sup> With Fs = 192 KHz

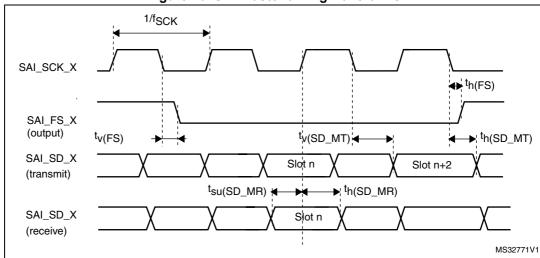
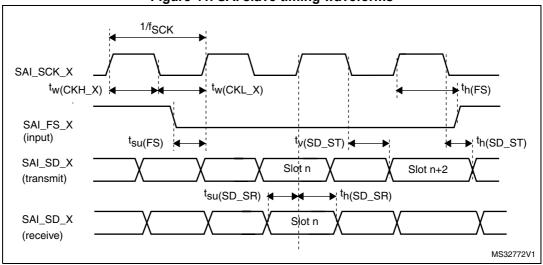


Figure 40. SAI master timing waveforms

Figure 41. SAI slave timing waveforms



# **USB OTG full speed (FS) characteristics**

This interface is present in both the USB OTG HS and USB OTG FS controllers.

Table 68. USB OTG full speed startup time

| Symbol                              | Parameter                                   | Max | Unit |
|-------------------------------------|---|-----|------|
| t <sub>STARTUP</sub> <sup>(1)</sup> | USB OTG full speed transceiver startup time | 1   | μs   |

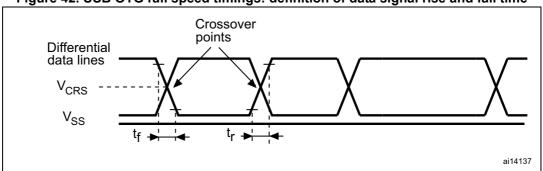
1. Guaranteed by design, not tested in production.

Max.<sup>(1)</sup> Min.<sup>(1)</sup> Typ. **Symbol Parameter Conditions** Unit USB OTG full speed 3.0<sup>(2)</sup>  $V_{DDUSB}$ transceiver operating 3.6 ٧ voltage Differential input I(USB FS DP/DM,  $V_{DI}^{(3)}$ 0.2 Input USB\_HS\_DP/DM) sensitivity levels Differential common mode  $V_{CM}^{(3)}$ V Includes V<sub>DI</sub> range 0.8 2.5 range Single ended receiver  $V_{SE}^{(3)}$ 1.3 2.0 threshold  $R_L$  of 1.5 k $\Omega$  to 3.6  $V^{(4)}$ Static output level low  $V_{OL}$ 0.3 Output V levels  $V_{\mathsf{OH}}$  $R_{\rm I}$  of 15 k $\Omega$  to  $V_{\rm SS}^{(4)}$ Static output level high 2.8 3.6 PA11, PA12, PB14, PB15 (USB FS DP/DM, 17 21 24 USB HS DP/DM)  $V_{IN} = V_{DDUSB}$  $R_{PD}$ PA9, PB13 (OTG\_FS\_VBUS, 0.65 1.1 2.0 OTG\_HS\_VBUS)  $k\Omega$ PA12, PB15 (USB FS DP, 1.5 1.8 2.1  $V_{IN} = V_{SS}$ USB\_HS\_DP)  $R_{PU}$ PA9, PB13  $V_{IN} = V_{SS}$ (OTG\_FS\_VBUS, 0.25 0.37 0.55 OTG\_HS\_VBUS)

Table 69. USB OTG full speed DC electrical characteristics

Note: When VBUS sensing feature is enabled, PA9 and PB13 should be left at their default state (floating input), not as alternate function. A typical 200 µA current consumption of the sensing block (current to voltage conversion to determine the different sessions) can be observed on PA9 and PB13 when the feature is enabled.

Figure 42. USB OTG full speed timings: definition of data signal rise and fall time





<sup>1.</sup> All the voltages are measured from the local ground potential.

The USB OTG full speed transceiver functionality is ensured down to 2.7 V but not the full USB full speed electrical characteristics which are degraded in the 2.7-to-3.0 V V<sub>DD</sub> voltage range.

<sup>3.</sup> Guaranteed by design, not tested in production.

<sup>4.</sup>  $R_L$  is the load connected on the USB OTG full speed drivers.

|                  | Driver characteristics                 |                                |     |     |      |  |  |
|------------------|--|--------------------------------|-----|-----|------|--|--|
| Symbol           | Parameter                              | Conditions                     | Min | Max | Unit |  |  |
| t <sub>r</sub>   | Rise time <sup>(2)</sup>               | C <sub>L</sub> = 50 pF         | 4   | 20  | ns   |  |  |
| t <sub>f</sub>   | Fall time <sup>(2)</sup>               | C <sub>L</sub> = 50 pF         | 4   | 20  | ns   |  |  |
| t <sub>rfm</sub> | Rise/ fall time matching               | t <sub>r</sub> /t <sub>f</sub> | 90  | 110 | %    |  |  |
| V <sub>CRS</sub> | Output signal crossover voltage        | -                              | 1.3 | 2.0 | V    |  |  |
| Z <sub>DRV</sub> | Output driver impedance <sup>(3)</sup> | Driving high or low            | 28  | 44  | Ω    |  |  |

Table 70. USB OTG full speed electrical characteristics<sup>(1)</sup>

### **USB** high speed (HS) characteristics

Unless otherwise specified, the parameters given in *Table 73* for ULPI are derived from tests performed under the ambient temperature,  $f_{HCLK}$  frequency summarized in *Table 72* and  $V_{DD}$  supply voltage conditions summarized in *Table 71*, with the following configuration:

- Output speed is set to OSPEEDRy[1:0] = 10, unless otherwise specified
- Capacitive load C = 30 pF, unless otherwise specified
- Measurement points are done at CMOS levels: 0.5V<sub>DD</sub>.

Refer to Section 6.3.17: I/O port characteristics for more details on the input/output characteristics.

Table 71. USB HS DC electrical characteristics

| Symbo       | ol       | Parameter                    | Min. <sup>(1)</sup> | Max. <sup>(1)</sup> | Unit |
|-------------|----------|------------------------------|---------------------|---------------------|------|
| Input level | $V_{DD}$ | USB OTG HS operating voltage | 1.7                 | 3.6                 | V    |

<sup>1.</sup> All the voltages are measured from the local ground potential.

Table 72. USB HS clock timing parameters<sup>(1)</sup>

| Symbol                  | Parameter  |                 | Min    | Тур | Max    | Unit |
|-------------------------|--|-----------------|--------|-----|--------|------|
| -                       | f <sub>HCLK</sub> value to guarantee prope<br>USB HS interface     | er operation of | 30     | -   | -      | MHz  |
| F <sub>START_8BIT</sub> | Frequency (first transition)                                       | 8-bit ±10%      | 54     | 60  | 66     | MHz  |
| F <sub>STEADY</sub>     | Frequency (steady state) ±500                                      | ppm             | 59.97  | 60  | 60.03  | MHz  |
| D <sub>START_8BIT</sub> | Duty cycle (first transition)                                      | 8-bit ±10%      | 40     | 50  | 60     | %    |
| D <sub>STEADY</sub>     | Duty cycle (steady state) ±500                                     | ppm             | 49.975 | 50  | 50.025 | %    |
| t <sub>STEADY</sub>     | Time to reach the steady state duty cycle after the first transiti |                 | ı      | -   | 1.4    | ms   |





<sup>1.</sup> Guaranteed by design, not tested in production.

Measured from 10% to 90% of the data signal. For more detailed informations, please refer to USB Specification - Chapter 7 (version 2.0).

No external termination series resistors are required on DP (D+) and DM (D-) pins since the matching impedance is included in the embedded driver.

|                         | Tuble 72. COD TIC Clock                           | tilling param      | 01010 (0 | ontinuca |     |      |
|-------------------------|---|--------------------|----------|----------|-----|------|
| Symbol                  | Parameter   |                    | Min      | Тур      | Max | Unit |
| t <sub>START_DEV</sub>  | Clock startup time after the                      | Peripheral         | -        | -        | 5.6 | ms   |
| t <sub>START_HOST</sub> | de-assertion of SuspendM                          | Host               | -        | -        | -   | 1115 |
| t <sub>PREP</sub>       | PHY preparation time after the of the input clock | e first transition | -        | -        | -   | μs   |

Table 72. USB HS clock timing parameters<sup>(1)</sup> (continued)

<sup>1.</sup> Guaranteed by design, not tested in production.

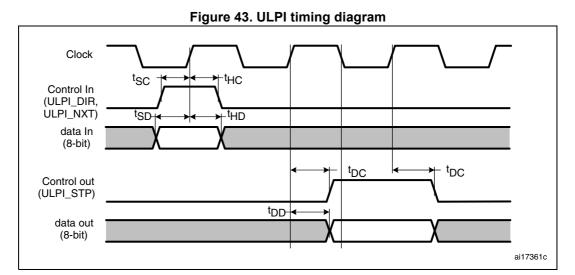


Table 73. Dynamic characteristics: USB ULPI<sup>(1)</sup>

| Symbol                           | Parameter                                  | Conditions  | Min. | Тур. | Max. | Unit |
|----------------------------------|--|---|------|------|------|------|
| t <sub>SC</sub>                  | Control in (ULPI_DIR, ULPI_NXT) setup time | -   | 1    | -    | -    |      |
| t <sub>HC</sub>                  | Control in (ULPI_DIR, ULPI_NXT) hold time  | -   | 1.5  | -    | -    |      |
| t <sub>SD</sub>                  | Data in setup time                         | -   | 1.5  | -    | -    |      |
| t <sub>HD</sub>                  | Data in hold time                          | -   | 1.5  | -    | -    | ns   |
|                                  |  | 2.7 V < V <sub>DD</sub> < 3.6 V,<br>C <sub>L</sub> = 20 pF  | -    | 6    | 8.5  |      |
| t <sub>DC</sub> /t <sub>DD</sub> | Data/control output delay                  | 1.71 V < V <sub>DD</sub> < 3.6 V,<br>C <sub>L</sub> = 15 pF | -    | 6    | 11.5 |      |

<sup>1.</sup> Guaranteed by characterization results, not tested in production.

### CAN (controller area network) interface

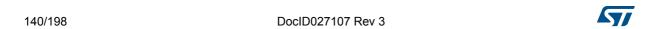
Refer to Section 6.3.17: I/O port characteristics for more details on the input/output alternate function characteristics (CANx\_TX and CANx\_RX).

### 6.3.21 12-bit ADC characteristics

Unless otherwise specified, the parameters given in *Table 74* are derived from tests performed under the ambient temperature,  $f_{PCLK2}$  frequency and  $V_{DDA}$  supply voltage conditions summarized in *Table 16*.

Table 74. ADC characteristics

| Symbol                             | Parameter                                       | Conditions  | Min  | Тур | Max               | Unit               |
|------------------------------------|---|---|--|-----|-------------------|--------------------|
| V <sub>DDA</sub>                   | Power supply                                    | V V (40)  | 1.7 <sup>(1)</sup>                                       | -   | 3.6               | V                  |
| V <sub>REF+</sub>                  | Positive reference voltage                      | V <sub>DDA</sub> –V <sub>REF+</sub> < 1.2 V   | 1.7 <sup>(1)</sup>                                       | -   | $V_{DDA}$         | V                  |
| £                                  | ADC clock fraguency                             | $V_{DDA} = 1.7^{(1)}$ to 2.4 V  | 0.6  | 15  | 18                | MHz                |
| f <sub>ADC</sub>                   | ADC clock frequency                             | V <sub>DDA</sub> = 2.4 to 3.6 V   | 0.6  | 30  | 36                | MHz                |
| f <sub>TRIG</sub> <sup>(2)</sup>   | External trigger frequency                      | f <sub>ADC</sub> = 30 MHz,<br>12-bit resolution                                       | -  | -   | 1764              | kHz                |
|                                    |   | -   | -  | -   | 17                | 1/f <sub>ADC</sub> |
| V <sub>AIN</sub>                   | Conversion voltage range <sup>(3)</sup>         | -   | 0 (V <sub>SSA</sub> or V <sub>REF-</sub> tied to ground) | -   | V <sub>REF+</sub> | V                  |
| R <sub>AIN</sub> <sup>(2)</sup>    | External input impedance                        | See Equation 1 for details  | -  | -   | 50                | κΩ                 |
| R <sub>ADC</sub> <sup>(2)(4)</sup> | Sampling switch resistance                      | -   | -  | -   | 6                 | κΩ                 |
| C <sub>ADC</sub> <sup>(2)</sup>    | Internal sample and hold capacitor              | -   | -  | 4   | 7                 | pF                 |
| t <sub>lat</sub> (2)               | Injection trigger conversion                    | f <sub>ADC</sub> = 30 MHz   | -  | -   | 0.100             | μs                 |
| lat` ′                             | latency   | -   | -  | -   | 3 <sup>(5)</sup>  | 1/f <sub>ADC</sub> |
| t <sub>latr</sub> (2)              | Regular trigger conversion                      | f <sub>ADC</sub> = 30 MHz   | -  | -   | 0.067             | μs                 |
| latr` ′                            | latency   | -   | -  | -   | 2 <sup>(5)</sup>  | 1/f <sub>ADC</sub> |
| t <sub>S</sub> <sup>(2)</sup>      | Sampling time                                   | f <sub>ADC</sub> = 30 MHz   | 0.100  | -   | 16                | μs                 |
| ıs` '                              | Sampling time                                   | -   | 3  | -   | 480               | 1/f <sub>ADC</sub> |
| t <sub>STAB</sub> <sup>(2)</sup>   | Power-up time                                   | -   | -  | 2   | 3                 | μs                 |
|                                    |   | f <sub>ADC</sub> = 30 MHz<br>12-bit resolution  | 0.50   | -   | 16.40             | μs                 |
|                                    |   | f <sub>ADC</sub> = 30 MHz<br>10-bit resolution  | 0.43   | -   | 16.34             | μs                 |
| t <sub>CONV</sub> <sup>(2)</sup>   | Total conversion time (including sampling time) | f <sub>ADC</sub> = 30 MHz<br>8-bit resolution   | 0.37   | -   | 16.27             | μs                 |
|                                    |   | f <sub>ADC</sub> = 30 MHz<br>6-bit resolution   | 0.30   | -   | 16.20             | μs                 |
|                                    |   | 9 to 492 (t <sub>S</sub> for sampling +n-bit resolution for successive approximation) |  |     |                   | 1/f <sub>ADC</sub> |



| Symbol                           | Parameter   | Conditions   | Min | Тур | Max  | Unit |
|----------------------------------|---|--|-----|-----|------|------|
|                                  |   | 12-bit resolution<br>Single ADC                    | -   | -   | 2    | Msps |
| f <sub>S</sub> <sup>(2)</sup>    | Sampling rate  (f <sub>ADC</sub> = 30 MHz, and t <sub>S</sub> = 3 ADC cycles) | 12-bit resolution<br>Interleave Dual ADC<br>mode   | -   | -   | 3.75 | Msps |
|                                  |   | 12-bit resolution<br>Interleave Triple ADC<br>mode | -   | -   | 6    | Msps |
| I <sub>VREF+</sub> (2)           | ADC V <sub>REF</sub> DC current consumption in conversion mode                | -  | -   | 300 | 500  | μΑ   |
| I <sub>VDDA</sub> <sup>(2)</sup> | ADC V <sub>DDA</sub> DC current consumption in conversion mode                | -  | -   | 1.6 | 1.8  | mA   |

Table 74. ADC characteristics (continued)

- 2. Based on characterization, not tested in production.
- 3.  $V_{REF+}$  is internally connected to  $V_{DDA}$  and  $V_{REF-}$  is internally connected to  $V_{SSA}$ .
- 4.  $R_{ADC}$  maximum value is given for  $V_{DD}$ =1.7 V, and minimum value for  $V_{DD}$ =3.3 V.
- 5. For external triggers, a delay of 1/f<sub>PCLK2</sub> must be added to the latency specified in *Table 74*.

#### Equation 1: R<sub>AIN</sub> max formula

$$R_{AIN} = \frac{(k-0.5)}{f_{ADC} \times C_{ADC} \times ln(2^{N+2})} - R_{ADC}$$

The formula above (*Equation 1*) is used to determine the maximum external impedance allowed for an error below 1/4 of LSB. N = 12 (from 12-bit resolution) and k is the number of sampling periods defined in the ADC\_SMPR1 register.

Table 75. ADC static accuracy at  $f_{ADC} = 18 \text{ MHz}^{(1)}$ 

|        | - 7.50                       |  |     |                    |      |
|--------|------------------------------|--|-----|--------------------|------|
| Symbol | Parameter                    | Test conditions  | Тур | Max <sup>(2)</sup> | Unit |
| ET     | Total unadjusted error       | f <sub>ADC</sub> =18 MHz<br>V <sub>DDA</sub> = 1.7 to 3.6 V<br>V <sub>REF</sub> = 1.7 to 3.6 V<br>V <sub>DDA</sub> -V <sub>REF</sub> < 1.2 V | ±3  | ±4                 |      |
| EO     | Offset error                 |  | ±2  | ±3                 |      |
| EG     | Gain error                   |  | ±1  | ±3                 | LSB  |
| ED     | Differential linearity error |  | ±1  | ±2                 | ·    |
| EL     | Integral linearity error     |  | ±2  | ±3                 | ·    |

- 1. Better performance could be achieved in restricted  $V_{DD}$ , frequency and temperature ranges.
- 2. Based on characterization, not tested in production.

V<sub>DDA</sub> minimum value of 1.7 V is obtained with the use of an external power supply supervisor (refer to Section 3.16.2: Internal reset OFF).

Table 76. ADC static accuracy at f<sub>ADC</sub> = 30 MHz<sup>(1)</sup>

|        | 7 750                        |   |      |                    |      |
|--------|------------------------------|---|------|--------------------|------|
| Symbol | Parameter                    | Test conditions   | Тур  | Max <sup>(2)</sup> | Unit |
| ET     | Total unadjusted error       | $f_{ADC}$ = 30 MHz,<br>$R_{AIN}$ < 10 k $\Omega$ ,<br>$V_{DDA}$ = 2.4 to 3.6 V,<br>$V_{REF}$ = 1.7 to 3.6 V,<br>$V_{DDA}$ - $V_{REF}$ < 1.2 V | ±2   | ±5                 |      |
| EO     | Offset error                 |   | ±1.5 | ±2.5               |      |
| EG     | Gain error                   |   | ±1.5 | ±3                 | LSB  |
| ED     | Differential linearity error |   | ±1   | ±2                 |      |
| EL     | Integral linearity error     |   | ±1.5 | ±3                 |      |

- 1. Better performance could be achieved in restricted  $V_{DD}$ , frequency and temperature ranges.
- 2. Based on characterization, not tested in production.

Table 77. ADC static accuracy at  $f_{ADC} = 36 \text{ MHz}^{(1)}$ 

| Symbol | Parameter                    | Test conditions  | Тур | Max <sup>(2)</sup> | Unit |
|--------|------------------------------|--|-----|--------------------|------|
| ET     | Total unadjusted error       | f <sub>ADC</sub> =36 MHz,<br>V <sub>DDA</sub> = 2.4 to 3.6 V,<br>V <sub>REF</sub> = 1.7 to 3.6 V<br>V <sub>DDA</sub> -V <sub>REF</sub> < 1.2 V | ±4  | ±7                 |      |
| EO     | Offset error                 |  | ±2  | ±3                 |      |
| EG     | Gain error                   |  | ±3  | ±6                 | LSB  |
| ED     | Differential linearity error |  | ±2  | ±3                 |      |
| EL     | Integral linearity error     |  | ±3  | ±6                 |      |

- 1. Better performance could be achieved in restricted  $V_{\text{DD}}$ , frequency and temperature ranges.
- 2. Based on characterization, not tested in production.

Table 78. ADC dynamic accuracy at  $f_{ADC}$  = 18 MHz - limited test conditions<sup>(1)</sup>

| Symbol | Parameter                            | Test conditions   | Min             | Тур         | Max | Unit |
|--------|--------------------------------------|---|-----------------|-------------|-----|------|
| ENOB   | Effective number of bits             | f <sub>ADC</sub> =18 MHz<br>V <sub>DDA</sub> = V <sub>REF+</sub> = 1.7 V<br>Input Frequency = 20 KHz<br>Temperature = 25 °C | 10.3            | 10.4        | -   | bits |
| SINAD  | Signal-to-noise and distortion ratio |   | 64              | 64.2        | -   |      |
| SNR    | Signal-to-noise ratio                |   | 64              | 65          | -   | dB   |
| THD    | Total harmonic distortion            |   | <del>-</del> 67 | <b>-</b> 72 | -   |      |

<sup>1.</sup> Guaranteed by characterization results, not tested in production.

Table 79. ADC dynamic accuracy at  $f_{ADC} = 36 \text{ MHz} - \text{limited test conditions}^{(1)}$ 

| Symbol | Parameter                            | Test conditions   | Min         | Тур         | Max | Unit |
|--------|--------------------------------------|---|-------------|-------------|-----|------|
| ENOB   | Effective number of bits             | f <sub>ADC</sub> =36 MHz<br>V <sub>DDA</sub> = V <sub>REF+</sub> = 3.3 V<br>Input Frequency = 20 KHz<br>Temperature = 25 °C | 10.6        | 10.8        | -   | bits |
| SINAD  | Signal-to noise and distortion ratio |   | 66          | 67          | -   |      |
| SNR    | Signal-to noise ratio                |   | 64          | 68          | -   | dB   |
| THD    | Total harmonic distortion            |   | <b>-</b> 70 | <b>-</b> 72 | -   |      |

<sup>1.</sup> Guaranteed by characterization results, not tested in production.

Note:

ADC accuracy vs. negative injection current: injecting a negative current on any analog input pins should be avoided as this significantly reduces the accuracy of the conversion



being performed on another analog input. It is recommended to add a Schottky diode (pin to ground) to analog pins which may potentially inject negative currents.

Any positive injection current within the limits specified for  $I_{\text{INJ}(\text{PIN})}$  and  $\Sigma I_{\text{INJ}(\text{PIN})}$  in Section 6.3.17 does not affect the ADC accuracy.

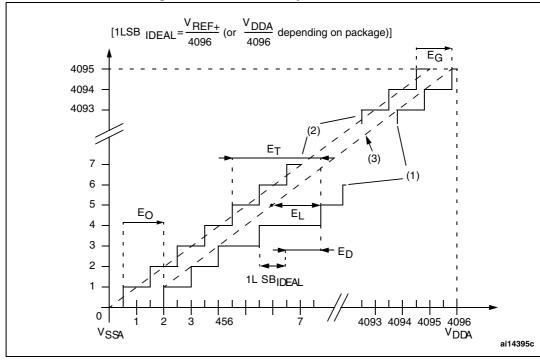


Figure 44. ADC accuracy characteristics

- 1. See also Table 76.
- Example of an actual transfer curve.
- 3. Ideal transfer curve.
- End point correlation line.
- E<sub>T</sub> = Total Unadjusted Error: maximum deviation between the actual and the ideal transfer curves. EO = Offset Error: deviation between the first actual transition and the first ideal one.

  - EG = Gain Error: deviation between the last ideal transition and the last actual one.

    ED = Differential Linearity Error: maximum deviation between actual steps and the ideal one.

    EL = Integral Linearity Error: maximum deviation between any actual transition and the end point correlation line.

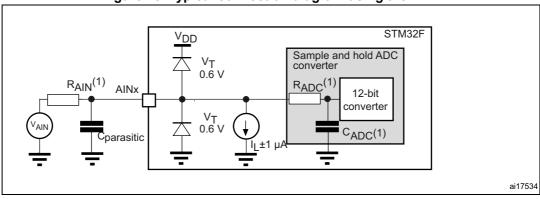


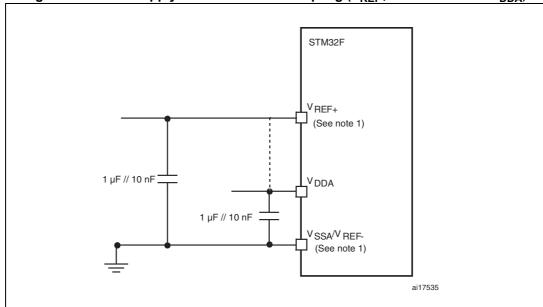
Figure 45. Typical connection diagram using the ADC

- 1. Refer to *Table 74* for the values of R<sub>AIN</sub>, R<sub>ADC</sub> and C<sub>ADC</sub>.
- $C_{parasitic}$  represents the capacitance of the PCB (dependent on soldering and PCB layout quality) plus the pad capacitance (roughly 5 pF). A high  $C_{parasitic}$  value downgrades conversion accuracy. To remedy this,  $f_{ADC}$  should be reduced.

## General PCB design guidelines

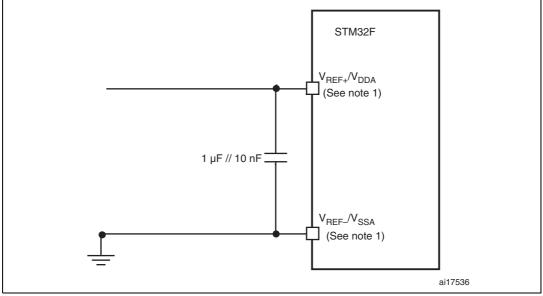
Power supply decoupling should be performed as shown in *Figure 46* or *Figure 47*, depending on whether  $V_{REF+}$  is connected to  $V_{DDA}$  or not. The 10 nF capacitors should be ceramic (good quality). They should be placed them as close as possible to the chip.

Figure 46. Power supply and reference decoupling ( $V_{REF+}$  not connected to  $V_{DDA}$ )



1.  $V_{REF+}$  and  $V_{REF-}$  inputs are both available on UFBGA144.  $V_{REF+}$  is also available on LQFP100, LQFP144, and WLCSP81. When  $V_{REF+}$  and  $V_{REF-}$  are not available, they are internally connected to  $V_{DDA}$  and  $V_{SSA}$ .

Figure 47. Power supply and reference decoupling (V<sub>REF+</sub> connected to V<sub>DDA</sub>)



V<sub>REF+</sub> and V<sub>REF</sub> inputs are both available on UFBGA144. V<sub>REF+</sub> is also available on LQFP100, LQFP144, and WLCSP81. When V<sub>REF+</sub> and V<sub>REF</sub> are not available, they are internally connected to V<sub>DDA</sub> and V<sub>SSA</sub>.

## 6.3.22 Temperature sensor characteristics

Table 80. Temperature sensor characteristics

| Symbol                             | Parameter  |    | Тур  | Max       | Unit  |
|------------------------------------|--|----|------|-----------|-------|
| T <sub>L</sub> <sup>(1)</sup>      | V <sub>SENSE</sub> linearity with temperature                  | -  | ±1   | <u>±2</u> | °C    |
| Avg_Slope <sup>(1)</sup>           | Average slope  | -  | 2.5  | -         | mV/°C |
| V <sub>25</sub> <sup>(1)</sup>     | Voltage at 25 °C   | -  | 0.76 | -         | V     |
| t <sub>START</sub> (2)             | Startup time   | -  | 6    | 10        | μs    |
| T <sub>S_temp</sub> <sup>(2)</sup> | ADC sampling time when reading the temperature (1 °C accuracy) | 10 | -    | -         | μs    |

<sup>1.</sup> Based on characterization, not tested in production.

**Table 81. Temperature sensor calibration values** 

| Symbol  | Parameter   | Memory address            |
|---------|---|---------------------------|
| TS_CAL1 | TS ADC raw data acquired at temperature of 30 °C, V <sub>DDA</sub> = 3.3 V  | 0x1FFF 7A2C - 0x1FFF 7A2D |
| TS_CAL2 | TS ADC raw data acquired at temperature of 110 °C, V <sub>DDA</sub> = 3.3 V | 0x1FFF 7A2E - 0x1FFF 7A2F |

# 6.3.23 V<sub>BAT</sub> monitoring characteristics

Table 82. V<sub>BAT</sub> monitoring characteristics

| Symbol                                | Parameter   | Min | Тур | Max | Unit |
|---------------------------------------|---|-----|-----|-----|------|
| R                                     | Resistor bridge for V <sub>BAT</sub>                              | -   | 50  | -   | ΚΩ   |
| Q                                     | Ratio on V <sub>BAT</sub> measurement                             | -   | 4   | -   | -    |
| Er <sup>(1)</sup>                     | Error on Q  | -1  | -   | +1  | %    |
| T <sub>S_vbat</sub> <sup>(2)(2)</sup> | ADC sampling time when reading the V <sub>BAT</sub> 1 mV accuracy | 5   | -   | -   | μs   |

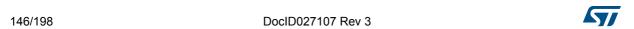
<sup>1.</sup> Guaranteed by design, not tested in production.

## 6.3.24 reference voltage

The parameters given in *Table 83* are derived from tests performed under ambient temperature and  $V_{DD}$  supply voltage conditions summarized in *Table 16*.

Table 83. internal reference voltage

| Symbol                               | Parameter   | Conditions                        | Min  | Тур  | Max  | Unit |
|--------------------------------------|---|-----------------------------------|------|------|------|------|
| V <sub>REFINT</sub>                  | Internal reference voltage                                    | -40 °C < T <sub>A</sub> < +105 °C | 1.18 | 1.21 | 1.24 | V    |
| T <sub>S_vrefint</sub> (1)           | ADC sampling time when reading the internal reference voltage | -                                 | 10   | -    | -    | μs   |
| V <sub>RERINT_s</sub> <sup>(2)</sup> | Internal reference voltage spread over the temperature range  | V <sub>DD</sub> = 3V ± 10mV       | -    | 3    | 5    | mV   |



<sup>2.</sup> Guaranteed by design, not tested in production.

<sup>2.</sup> Shortest sampling time can be determined in the application by multiple iterations.

Table 83. internal reference voltage (continued)

| Symbol                            | Parameter               | Conditions | Min | Тур | Max | Unit   |
|-----------------------------------|-------------------------|------------|-----|-----|-----|--------|
| T <sub>Coeff</sub> <sup>(2)</sup> | Temperature coefficient | -          | -   | 30  | 50  | ppm/°C |
| t <sub>START</sub> <sup>(2)</sup> | Startup time            | -          | -   | 6   | 10  | μs     |

<sup>1.</sup> Shortest sampling time can be determined in the application by multiple iterations.

Table 84. Internal reference voltage calibration values

| Symbol                 | Parameter   | Memory address            |
|------------------------|---|---------------------------|
| V <sub>REFIN_CAL</sub> | Raw data acquired at temperature of 30 °C <sub>VDDA</sub> = 3.3 V | 0x1FFF 7A2A - 0x1FFF 7A2B |

## 6.3.25 DAC electrical characteristics

**Table 85. DAC characteristics** 

| Symbol                           | Parameter  | Min                | Тур | Max                         | Unit | Comments  |
|----------------------------------|--|--------------------|-----|-----------------------------|------|---|
| V <sub>DDA</sub>                 | Analog supply voltage                                    | 1.7 <sup>(1)</sup> | -   | 3.6                         | V    | -   |
| V <sub>REF+</sub>                | Reference supply voltage                                 | 1.7 <sup>(1)</sup> | -   | 3.6                         | V    | V <sub>REF+</sub> ≤V <sub>DDA</sub>   |
| V <sub>SSA</sub>                 | Ground   | 0                  | -   | 0                           | V    | -   |
| R <sub>LOAD</sub> <sup>(2)</sup> | Resistive load with buffer ON                            | 5                  | -   | -                           | kΩ   | -   |
| R <sub>O</sub> <sup>(2)</sup>    | Impedance output with buffer OFF                         | -                  | -   | 15                          | kΩ   | When the buffer is OFF, the Minimum resistive load between DAC_OUT and $V_{SS}$ to have a 1% accuracy is 1.5 M $\Omega$ |
| C <sub>LOAD</sub> <sup>(2)</sup> | Capacitive load  | -                  | -   | 50                          | pF   | Maximum capacitive load at DAC_OUT pin (when the buffer is ON).   |
| DAC_OUT min <sup>(2)</sup>       | Lower DAC_OUT voltage with buffer ON                     | 0.2                | -   | -                           | ٧    | It gives the maximum output excursion of the DAC. It corresponds to 12-bit input code                                   |
| DAC_OUT max <sup>(2)</sup>       | Higher DAC_OUT voltage with buffer ON                    | -                  | -   | V <sub>DDA</sub> – 0.2      | ٧    | (0x0E0) to (0xF1C) at V <sub>REF+</sub> = 3.6 V<br>and (0x1C7) to (0xE38) at V <sub>REF+</sub> = 1.7 V                  |
| DAC_OUT min <sup>(2)</sup>       | Lower DAC_OUT voltage with buffer OFF                    | -                  | 0.5 | -                           | mV   | It gives the maximum output excursion   |
| DAC_OUT max <sup>(2)</sup>       | Higher DAC_OUT voltage with buffer OFF                   | -                  | ı   | V <sub>REF+</sub><br>– 1LSB | >    | of the DAC.   |
| I <sub>VREF+</sub> (4)           | DAC DC V <sub>REF</sub> current consumption in quiescent | -                  | 170 | 240                         | μA   | With no load, worst code (0x800) at V <sub>REF+</sub> = 3.6 V in terms of DC consumption on the inputs                  |
| 'VREF+'                          | mode (Standby mode)                                      | -                  | 50  | 75                          | μΛ   | With no load, worst code (0xF1C) at V <sub>REF+</sub> = 3.6 V in terms of DC consumption on the inputs                  |

<sup>2.</sup> Guaranteed by design, not tested in production

Table 85. DAC characteristics (continued)

| Symbol                               | Parameter  | Min | Тур | Max  | Unit | Comments   |
|--------------------------------------|--|-----|-----|------|------|--|
|                                      | DAC DC VDDA current  | -   | 280 | 380  | μA   | With no load, middle code (0x800) on the inputs  |
| I <sub>DDA</sub> <sup>(4)</sup>      | consumption in quiescent mode <sup>(3)</sup>   | -   | 475 | 625  | μA   | With no load, worst code (0xF1C) at V <sub>REF+</sub> = 3.6 V in terms of DC consumption on the inputs |
| DNL <sup>(4)</sup>                   | Differential non linearity Difference between two  | -   | -   | ±0.5 | LSB  | Given for the DAC in 10-bit configuration.   |
|                                      | consecutive code-1LSB)   | ı   | -   | ±2   | LSB  | Given for the DAC in 12-bit configuration.   |
|                                      | Integral non linearity<br>(difference between  | ı   | -   | ±1   | LSB  | Given for the DAC in 10-bit configuration.   |
| INL <sup>(4)</sup>                   | measured value at Code i<br>and the value at Code i on a<br>line drawn between Code 0<br>and last Code 1023) | -   | -   | ±4   | LSB  | Given for the DAC in 12-bit configuration.   |
|                                      | Offset error   | -   | -   | ±10  | mV   | Given for the DAC in 12-bit configuration  |
| Offset <sup>(4)</sup>                | (difference between measured value at Code   | -   | -   | ±3   | LSB  | Given for the DAC in 10-bit at V <sub>REF+</sub> = 3.6 V   |
|                                      | (0x800) and the ideal value<br>= V <sub>REF+</sub> /2)   | -   | -   | ±12  | LSB  | Given for the DAC in 12-bit at V <sub>REF+</sub> = 3.6 V   |
| Gain<br>error <sup>(4)</sup>         | Gain error   | -   | -   | ±0.5 | %    | Given for the DAC in 12-bit configuration  |
| t <sub>SETTLING</sub> <sup>(4)</sup> | Total Harmonic Distortion<br>Buffer ON   | -   | 3   | 6    | μs   | $C_{LOAD} \le 50 \text{ pF},$ $R_{LOAD} \ge 5 \text{ k}\Omega$   |
| THD <sup>(4)</sup>                   | -  | ı   | -   | ı    | dB   | $C_{LOAD} \le 50 \text{ pF},$ $R_{LOAD} \ge 5 \text{ k}\Omega$   |
| Update rate <sup>(2)</sup>           | Max frequency for a correct DAC_OUT change when small variation in the input code (from code i to i+1LSB)    | -   | -   | 1    | MS/s | $C_{LOAD} \le 50 \text{ pF},$ $R_{LOAD} \ge 5 \text{ k}\Omega$   |
| t <sub>WAKEUP</sub> (4)              | Wakeup time from off state<br>(Setting the ENx bit in the<br>DAC Control register)                           | -   | 6.5 | 10   | μs   | $C_{LOAD} \le 50$ pF, $R_{LOAD} \ge 5$ k $\Omega$ input code between lowest and highest possible ones. |
| PSRR+ (2)                            | Power supply rejection ratio (to V <sub>DDA</sub> ) (static DC measurement)                                  | -   | -67 | -40  | dB   | No R <sub>LOAD</sub> , C <sub>LOAD</sub> = 50 pF   |

V<sub>DDA</sub> minimum value of 1.7 V is obtained with the use of an external power supply supervisor (refer to Section 3.16.2: Internal reset OFF).

<sup>2.</sup> Guaranteed by design, not tested in production.

<sup>3.</sup> The quiescent mode corresponds to a state where the DAC maintains a stable output level to ensure that no dynamic consumption occurs.

<sup>4.</sup> Guaranteed by characterization, not tested in production.

Buffered/Non-buffered DAC

Buffer(1)

12-bit digital to analog converter

C L

ai17157d

Figure 48. 12-bit buffered/non-buffered DAC

 The DAC integrates an output buffer that can be used to reduce the output impedance and to drive external loads directly without the use of an external operational amplifier. The buffer can be bypassed by configuring the BOFFx bit in the DAC\_CR register.

### 6.3.26 FMC characteristics

Unless otherwise specified, the parameters given in *Table 86* to *Table 93* for the FMC interface are derived from tests performed under the ambient temperature,  $f_{HCLK}$  frequency and  $V_{DD}$  supply voltage conditions summarized in *Table 15*, with the following configuration:

- Output speed is set to OSPEEDRy[1:0] = 10
- Capacitance load C = 30 pF
- Measurement points are done at CMOS levels: 0.5V<sub>DD</sub>

Refer to Section 6.3.17: I/O port characteristics for more details on the input/output characteristics.

### Asynchronous waveforms and timings

Figure 49 through Figure 52 represent asynchronous waveforms and Table 86 through Table 93 provide the corresponding timings. The results shown in these tables are obtained with the following FMC configuration:

- AddressSetupTime = 0x1
- AddressHoldTime = 0x1
- DataSetupTime = 0x1 (except for asynchronous NWAIT mode, DataSetupTime = 0x5)
- BusTurnAroundDuration = 0x0

In all timing tables, the T<sub>HCLK</sub> is the HCLK clock period.

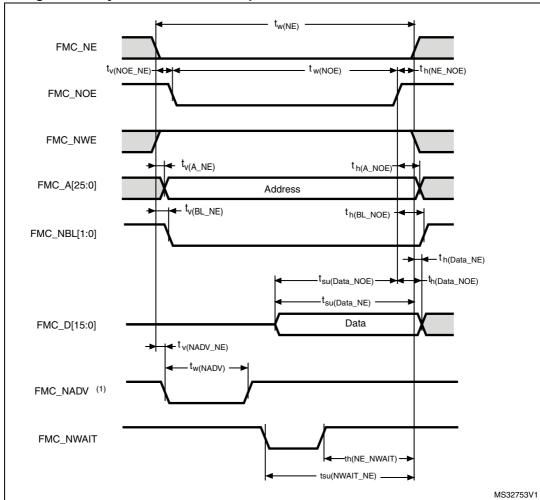


Figure 49. Asynchronous non-multiplexed SRAM/PSRAM/NOR read waveforms

1. Mode 2/B, C and D only. In Mode 1, FMC\_NADV is not used.



Table 86. Asynchronous non-multiplexed SRAM/PSRAM/NOR - read timings  $^{(1)(2)}$ 

| Symbol                    | Parameter                             | Min                    | Max                       | Unit |
|---------------------------|---------------------------------------|------------------------|---------------------------|------|
| t <sub>w(NE)</sub>        | FMC_NE low time                       | 2T <sub>HCLK</sub> – 2 | 2 T <sub>HCLK</sub> + 0.5 |      |
| t <sub>v(NOE_NE)</sub>    | FMC_NEx low to FMC_NOE low            | 0                      | 1                         |      |
| t <sub>w(NOE)</sub>       | FMC_NOE low time                      | 2T <sub>HCLK</sub> - 1 | 2T <sub>HCLK</sub> + 0.5  |      |
| t <sub>h(NE_NOE)</sub>    | FMC_NOE high to FMC_NE high hold time | 0                      | -                         |      |
| t <sub>v(A_NE)</sub>      | FMC_NEx low to FMC_A valid            | -                      | 0.5                       |      |
| t <sub>h(A_NOE)</sub>     | Address hold time after FMC_NOE high  | 0                      | -                         |      |
| t <sub>v(BL_NE)</sub>     | FMC_NEx low to FMC_BL valid           | -                      | 2                         | ns   |
| t <sub>h(BL_NOE)</sub>    | FMC_BL hold time after FMC_NOE high   | 0                      | -                         | 115  |
| t <sub>su(Data_NE)</sub>  | Data to FMC_NEx high setup time       | T <sub>HCLK</sub> - 2  | -                         |      |
| t <sub>su(Data_NOE)</sub> | Data to FMC_NOEx high setup time      | T <sub>HCLK</sub> - 2  | -                         |      |
| t <sub>h(Data_NOE)</sub>  | Data hold time after FMC_NOE high     | 0                      | -                         |      |
| t <sub>h(Data_NE)</sub>   | Data hold time after FMC_NEx high     | 0                      | -                         |      |
| t <sub>v(NADV_NE)</sub>   | FMC_NEx low to FMC_NADV low           | -                      | 0                         |      |
| t <sub>w(NADV)</sub>      | FMC_NADV low time                     | -                      | T <sub>HCLK</sub> +1      |      |

<sup>1.</sup>  $C_L = 30 pF$ .

Table 87. Asynchronous non-multiplexed SRAM/PSRAM/NOR read - NWAIT timings  $^{(1)(2)}$ 

| Symbol                    | Parameter                                 | Min                      | Max                    | Unit |
|---------------------------|---|--------------------------|------------------------|------|
| $t_{w(NE)}$               | FMC_NE low time                           | 7T <sub>HCLK</sub> + 1   | 7T <sub>HCLK</sub>     |      |
| t <sub>w(NOE)</sub>       | FMC_NWE low time                          | 5T <sub>HCLK</sub> – 1   | 5T <sub>HCLK</sub> + 1 |      |
| t <sub>w(NWAIT)</sub>     | FMC_NWAIT low time                        | T <sub>HCLK</sub> - 0.5  | -                      | ns   |
| t <sub>su(NWAIT_NE)</sub> | FMC_NWAIT valid before FMC_NEx high       | 5T <sub>HCLK</sub> + 1.5 | -                      |      |
| t <sub>h(NE_NWAIT)</sub>  | FMC_NEx hold time after FMC_NWAIT invalid | 4T <sub>HCLK</sub> + 1   | -                      |      |

<sup>1.</sup>  $C_L = 30 pF$ .

<sup>2.</sup> Based on characterization, not tested in production.

<sup>2.</sup> Based on characterization, not tested in production.

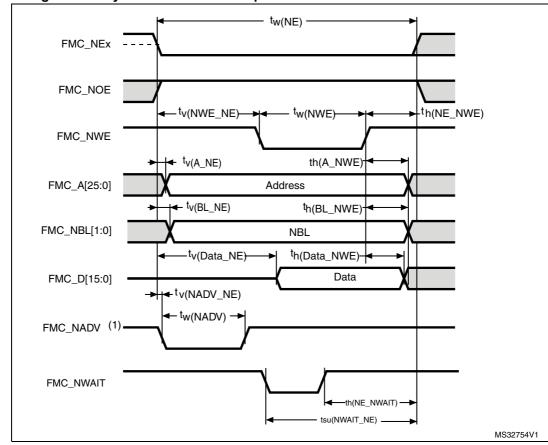


Figure 50. Asynchronous non-multiplexed SRAM/PSRAM/NOR write waveforms

1. Mode 2/B, C and D only. In Mode 1, FMC\_NADV is not used.

Table 88. Asynchronous non-multiplexed SRAM/PSRAM/NOR write timings<sup>(1)(2)</sup>

| Symbol                   | Parameter                             | Min                     | Max                      | Unit |
|--------------------------|---------------------------------------|-------------------------|--------------------------|------|
| t <sub>w(NE)</sub>       | FMC_NE low time                       | 3 T <sub>HCLK</sub> - 2 | 3 T <sub>HCLK</sub> +0.5 |      |
| t <sub>v(NWE_NE)</sub>   | FMC_NEx low to FMC_NWE low            | T <sub>HCLK</sub> - 0.5 | T <sub>HCLK</sub> + 0.5  |      |
| t <sub>w(NWE)</sub>      | FMC_NWE low time                      | T <sub>HCLK</sub>       | T <sub>HCLK</sub> + 0.5  |      |
| t <sub>h(NE_NWE)</sub>   | FMC_NWE high to FMC_NE high hold time | T <sub>HCLK</sub> + 0.5 | -                        |      |
| t <sub>v(A_NE)</sub>     | FMC_NEx low to FMC_A valid            | -                       | 0                        |      |
| t <sub>h(A_NWE)</sub>    | Address hold time after FMC_NWE high  | T <sub>HCLK</sub> - 0.5 | -                        | ns   |
| t <sub>v(BL_NE)</sub>    | FMC_NEx low to FMC_BL valid           | -                       | 1                        | 115  |
| t <sub>h(BL_NWE)</sub>   | FMC_BL hold time after FMC_NWE high   | T <sub>HCLK</sub> + 0.5 | -                        |      |
| t <sub>v(Data_NE)</sub>  | Data to FMC_NEx low to Data valid     | -                       | T <sub>HCLK</sub> + 2    |      |
| t <sub>h(Data_NWE)</sub> | Data hold time after FMC_NWE high     | T <sub>HCLK</sub> + 0.5 | -                        |      |
| t <sub>v(NADV_NE)</sub>  | FMC_NEx low to FMC_NADV low           | -                       | 0                        |      |
| t <sub>w(NADV)</sub>     | FMC_NADV low time                     | -                       | T <sub>HCLK</sub> + 0.5  |      |

<sup>1.</sup>  $C_L = 30 pF$ .

<sup>2.</sup> Based on characterization, not tested in production.

Table 89. Asynchronous non-multiplexed SRAM/PSRAM/NOR write - NWAIT timings  $^{(1)(2)}$ 

| Symbol                    | Parameter                                 | Min                      | Max                    | Unit |
|---------------------------|---|--------------------------|------------------------|------|
| t <sub>w(NE)</sub>        | FMC_NE low time                           | 8T <sub>HCLK</sub> - 0.5 | 8T <sub>HCLK</sub> + 1 |      |
| t <sub>w(NWE)</sub>       | FMC_NWE low time                          | 6T <sub>HCLK</sub> - 0.5 | 6T <sub>HCLK</sub> + 1 | ns   |
| t <sub>su(NWAIT_NE)</sub> | FMC_NWAIT valid before FMC_NEx high       | 6T <sub>HCLK</sub> - 0.5 | -                      | 113  |
| t <sub>h(NE_NWAIT)</sub>  | FMC_NEx hold time after FMC_NWAIT invalid | 4T <sub>HCLK</sub> + 2   | -                      |      |

- 1.  $C_L = 30 pF$ .
- 2. Based on characterization, not tested in production.

Figure 51. Asynchronous multiplexed PSRAM/NOR read waveforms

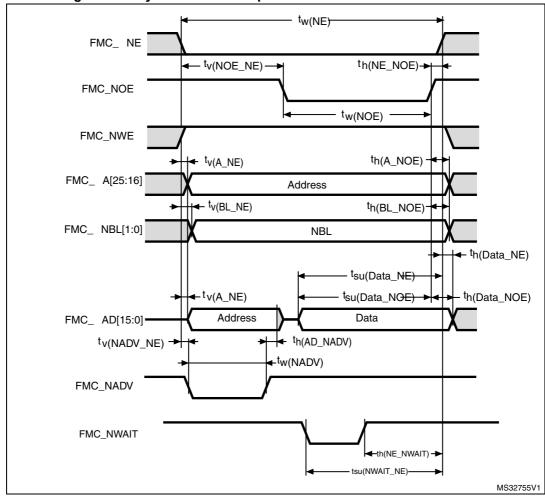


Table 90. Asynchronous multiplexed PSRAM/NOR read timings<sup>(1)(2)</sup>

| Symbol                    | Parameter  | Min                      | Max                     | Unit |
|---------------------------|--|--------------------------|-------------------------|------|
| t <sub>w(NE)</sub>        | FMC_NE low time                                      | 3T <sub>HCLK</sub> – 2   | 3T <sub>HCLK</sub> +0.5 |      |
| t <sub>v(NOE_NE)</sub>    | FMC_NEx low to FMC_NOE low                           | 2T <sub>HCLK</sub> - 0.5 | 2T <sub>HCLK</sub>      |      |
| t <sub>tw(NOE)</sub>      | FMC_NOE low time                                     | T <sub>HCLK</sub> – 1    | T <sub>HCLK</sub> + 0.5 |      |
| t <sub>h(NE_NOE)</sub>    | FMC_NOE high to FMC_NE high hold time                | 0                        | -                       |      |
| t <sub>v(A_NE)</sub>      | FMC_NEx low to FMC_A valid                           | -                        | 2                       |      |
| t <sub>v(NADV_NE)</sub>   | FMC_NEx low to FMC_NADV low                          | 0                        | 2                       |      |
| t <sub>w(NADV)</sub>      | FMC_NADV low time                                    | T <sub>HCLK</sub> - 0.5  | T <sub>HCLK</sub> + 0.5 |      |
| t <sub>h(AD_NADV)</sub>   | FMC_AD(address) valid hold time after FMC_NADV high) | 0                        | -                       | ns   |
| t <sub>h(A_NOE)</sub>     | Address hold time after FMC_NOE high                 | T <sub>HCLK</sub> - 0.5  | -                       |      |
| t <sub>h(BL_NOE)</sub>    | FMC_BL time after FMC_NOE high                       | 0                        | -                       |      |
| t <sub>v(BL_NE)</sub>     | FMC_NEx low to FMC_BL valid                          | -                        | 2                       |      |
| t <sub>su(Data_NE)</sub>  | Data to FMC_NEx high setup time                      | T <sub>HCLK</sub> + 1.5  | -                       |      |
| t <sub>su(Data_NOE)</sub> | Data to FMC_NOE high setup time                      | T <sub>HCLK</sub> + 1    | -                       |      |
| t <sub>h(Data_NE)</sub>   | Data hold time after FMC_NEx high                    | 0                        | -                       |      |
| t <sub>h(Data_NOE)</sub>  | Data hold time after FMC_NOE high                    | 0                        | -                       |      |

<sup>1.</sup>  $C_1 = 30 \text{ pF}.$ 

Table 91. Asynchronous multiplexed PSRAM/NOR read-NWAIT timings<sup>(1)(2)</sup>

| Symbol                    | Parameter                                 | Min                      | Max                    | Unit |
|---------------------------|---|--------------------------|------------------------|------|
| t <sub>w(NE)</sub>        | FMC_NE low time                           | 8T <sub>HCLK</sub> - 1   | 8T <sub>HCLK</sub> + 2 |      |
| t <sub>w(NOE)</sub>       | FMC_NWE low time                          | 5T <sub>HCLK</sub> – 1   | 5T <sub>HCLK</sub> + 1 | ns   |
| t <sub>su(NWAIT_NE)</sub> | FMC_NWAIT valid before FMC_NEx high       | 5T <sub>HCLK</sub> + 1.5 | -                      |      |
| t <sub>h(NE_NWAIT)</sub>  | FMC_NEx hold time after FMC_NWAIT invalid | 4T <sub>HCLK</sub> + 1   | -                      |      |

<sup>1.</sup>  $C_L = 30 pF$ .

<sup>2.</sup> Based on characterization, not tested in production.

<sup>2.</sup> Based on characterization, not tested in production.

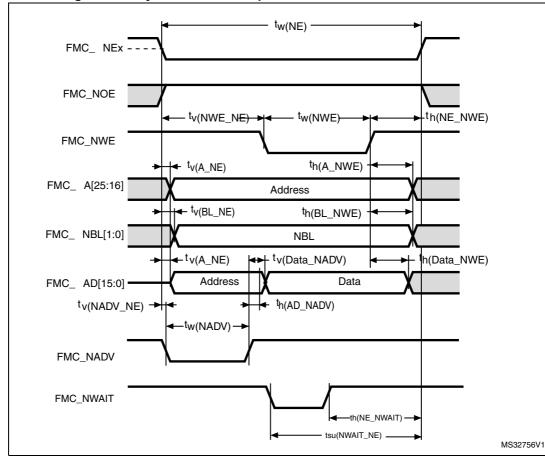


Figure 52. Asynchronous multiplexed PSRAM/NOR write waveforms

Table 92. Asynchronous multiplexed PSRAM/NOR write timings<sup>(1)(2)</sup>

| Symbol                    | Parameter   | Min                     | Max                      | Unit |
|---------------------------|---|-------------------------|--------------------------|------|
| Cymbol                    | 1 didiliotoi  |                         | Mux                      | 0    |
| t <sub>w(NE)</sub>        | FMC_NE low time                                     | 4T <sub>HCLK</sub> - 2  | 4T <sub>HCLK</sub> +0.5  |      |
| t <sub>v(NWE_NE)</sub>    | FMC_NEx low to FMC_NWE low                          | T <sub>HCLK</sub>       | T <sub>HCLK</sub> + 0.5  |      |
| t <sub>w(NWE)</sub>       | FMC_NWE low time                                    | 2T <sub>HCLK</sub>      | 2T <sub>HCLK</sub> + 0.5 |      |
| t <sub>h(NE_NWE)</sub>    | FMC_NWE high to FMC_NE high hold time               | T <sub>HCLK</sub>       | -                        |      |
| t <sub>v(A_NE)</sub>      | FMC_NEx low to FMC_A valid                          | -                       | 0                        |      |
| t <sub>v(NADV_NE)</sub>   | FMC_NEx low to FMC_NADV low                         | 0.5                     | 1                        |      |
| t <sub>w(NADV)</sub>      | FMC_NADV low time                                   | T <sub>HCLK</sub> - 0.5 | T <sub>HCLK</sub> + 0.5  | ns   |
| t <sub>h(AD_NADV)</sub>   | FMC_AD(adress) valid hold time after FMC_NADV high) | T <sub>HCLK</sub> – 2   | -                        |      |
| t <sub>h(A_NWE)</sub>     | Address hold time after FMC_NWE high                | T <sub>HCLK</sub>       | -                        |      |
| t <sub>h(BL_NWE)</sub>    | FMC_BL hold time after FMC_NWE high                 | T <sub>HCLK</sub> -2    | -                        |      |
| t <sub>v(BL_NE)</sub>     | FMC_NEx low to FMC_BL valid                         | -                       | 2                        |      |
| t <sub>v(Data_NADV)</sub> | FMC_NADV high to Data valid                         | -                       | T <sub>HCLK</sub> + 1.5  |      |
| t <sub>h(Data_NWE)</sub>  | Data hold time after FMC_NWE high                   | T <sub>HCLK</sub> + 0.5 | -                        |      |

<sup>1.</sup>  $C_L = 30 pF$ .

Table 93. Asynchronous multiplexed PSRAM/NOR write-NWAIT timings<sup>(1)(2)</sup>

| Symbol                    | Parameter                                 | Min                      | Max                      | Unit |
|---------------------------|---|--------------------------|--------------------------|------|
| t <sub>w(NE)</sub>        | FMC_NE low time                           | 9T <sub>HCLK</sub>       | 9T <sub>HCLK</sub> + 0.5 |      |
| t <sub>w(NWE)</sub>       | FMC_NWE low time                          | 7T <sub>HCLK</sub>       | 7T <sub>HCLK</sub> + 2   | ns   |
| t <sub>su(NWAIT_NE)</sub> | FMC_NWAIT valid before FMC_NEx high       | 6T <sub>HCLK</sub> + 1.5 | -                        |      |
| t <sub>h(NE_NWAIT)</sub>  | FMC_NEx hold time after FMC_NWAIT invalid | 4T <sub>HCLK</sub> – 1   | -                        |      |

<sup>1.</sup>  $C_L = 30 pF$ .

### Synchronous waveforms and timings

Figure 53 through Figure 56 represent synchronous waveforms and Table 94 through Table 97 provide the corresponding timings. The results shown in these tables are obtained with the following FMC configuration:

- BurstAccessMode = FMC\_BurstAccessMode\_Enable;
- MemoryType = FMC\_MemoryType\_CRAM;
- WriteBurst = FMC WriteBurst Enable;
- CLKDivision = 1; (0 is not supported, see the STM32F446 reference manual: RM0390)
- DataLatency = 1 for NOR Flash; DataLatency = 0 for PSRAM



<sup>2.</sup> Based on characterization, not tested in production.

<sup>2.</sup> Based on characterization, not tested in production.

In all timing tables, the  $T_{HCLK}$  is the HCLK clock period (with maximum FMC\_CLK = 90 MHz).

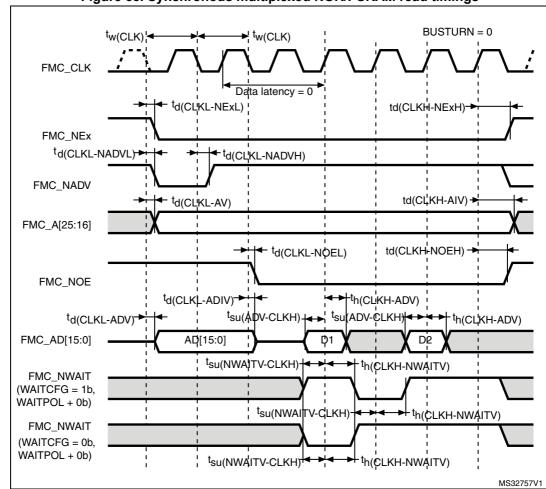


Figure 53. Synchronous multiplexed NOR/PSRAM read timings

Table 94. Synchronous multiplexed NOR/PSRAM read timings<sup>(1)(2)</sup>

| Symbol                      | Parameter                                    | Min                     | Max | Unit |
|-----------------------------|--|-------------------------|-----|------|
| t <sub>w(CLK)</sub>         | FMC_CLK period                               | 2T <sub>HCLK</sub>      | -   |      |
| t <sub>d(CLKL-NExL)</sub>   | FMC_CLK low to FMC_NEx low (x=02)            | -                       | 2.5 |      |
| t <sub>d(CLKH_NExH)</sub>   | FMC_CLK high to FMC_NEx high (x= 02)         | T <sub>HCLK</sub> - 0.5 | -   |      |
| t <sub>d(CLKL-NADVL)</sub>  | FMC_CLK low to FMC_NADV low                  | -                       | 0   |      |
| t <sub>d(CLKL-NADVH)</sub>  | FMC_CLK low to FMC_NADV high                 | 0                       | -   |      |
| t <sub>d(CLKL-AV)</sub>     | FMC_CLK low to FMC_Ax valid (x=1625)         | -                       | 2.5 |      |
| t <sub>d(CLKH-AIV)</sub>    | FMC_CLK high to FMC_Ax invalid (x=1625)      | T <sub>HCLK</sub>       | -   |      |
| t <sub>d(CLKL-NOEL)</sub>   | FMC_CLK low to FMC_NOE low                   | -                       | 2   | ns   |
| t <sub>d(CLKH-NOEH)</sub>   | FMC_CLK high to FMC_NOE high                 | T <sub>HCLK</sub> – 0.5 | -   |      |
| t <sub>d(CLKL-ADV)</sub>    | FMC_CLK low to FMC_AD[15:0] valid            | -                       | 0.5 |      |
| t <sub>d(CLKL-ADIV)</sub>   | FMC_CLK low to FMC_AD[15:0] invalid          | 0                       | -   |      |
| t <sub>su(ADV-CLKH)</sub>   | FMC_A/D[15:0] valid data before FMC_CLK high | 1                       | -   |      |
| t <sub>h(CLKH-ADV)</sub>    | FMC_A/D[15:0] valid data after FMC_CLK high  | 3.5                     | -   |      |
| t <sub>su(NWAIT-CLKH)</sub> | FMC_NWAIT valid before FMC_CLK high          | 1                       | -   |      |
| t <sub>h(CLKH-NWAIT)</sub>  | FMC_NWAIT valid after FMC_CLK high           | 3.5                     | -   |      |

<sup>1.</sup>  $C_L = 30 \text{ pF.}$ 

<sup>2.</sup> Based on characterization, not tested in production.

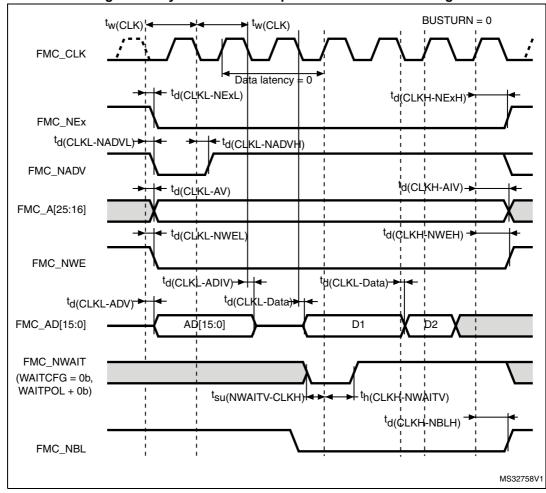


Figure 54. Synchronous multiplexed PSRAM write timings

Table 95. Synchronous multiplexed PSRAM write timings<sup>(1)(2)</sup>

| Symbol                      | Parameter                                  | Min                     | Max | Unit |
|-----------------------------|--|-------------------------|-----|------|
| t <sub>w(CLK)</sub>         | FMC_CLK period, VDD range= 2.7 to 3.6 V    | 2T <sub>HCLK</sub> - 1  | -   |      |
| t <sub>d(CLKL-NExL)</sub>   | FMC_CLK low to FMC_NEx low (x=02)          | -                       | 2.5 |      |
| t <sub>d(CLKH-NExH)</sub>   | FMC_CLK high to FMC_NEx high (x= 02)       | T <sub>HCLK</sub> + 0.5 | -   |      |
| t <sub>d(CLKL-NADVL)</sub>  | FMC_CLK low to FMC_NADV low                | -                       | 2   |      |
| t <sub>d(CLKL-NADVH)</sub>  | FMC_CLK low to FMC_NADV high               | 0                       | -   |      |
| t <sub>d(CLKL-AV)</sub>     | FMC_CLK low to FMC_Ax valid (x=1625)       | -                       | 2   |      |
| t <sub>d(CLKH-AIV)</sub>    | FMC_CLK high to FMC_Ax invalid (x=1625)    | T <sub>HCLK</sub>       | -   |      |
| t <sub>d(CLKL-NWEL)</sub>   | FMC_CLK low to FMC_NWE low                 | -                       | 0   | 200  |
| t <sub>(CLKH-NWEH)</sub>    | FMC_CLK high to FMC_NWE high               | T <sub>HCLK</sub> - 0.5 | -   | ns   |
| t <sub>d(CLKL-ADV)</sub>    | FMC_CLK low to FMC_AD[15:0] valid          | -                       | 3   |      |
| t <sub>d(CLKL-ADIV)</sub>   | FMC_CLK low to FMC_AD[15:0] invalid        | 0                       | -   |      |
| t <sub>d(CLKL-DATA)</sub>   | FMC_A/D[15:0] valid data after FMC_CLK low | -                       | 3   |      |
| t <sub>d(CLKL-NBLL)</sub>   | FMC_CLK low to FMC_NBL low                 | 0                       | -   |      |
| t <sub>d(CLKH-NBLH)</sub>   | FMC_CLK high to FMC_NBL high               | T <sub>HCLK</sub> - 0.5 | -   |      |
| t <sub>su(NWAIT-CLKH)</sub> | FMC_NWAIT valid before FMC_CLK high        | 4                       | -   |      |
| t <sub>h(CLKH-NWAIT)</sub>  | FMC_NWAIT valid after FMC_CLK high         | 0                       | -   |      |

<sup>1.</sup> C<sub>L</sub> = 30 pF.

<sup>2.</sup> Based on characterization, not tested in production.

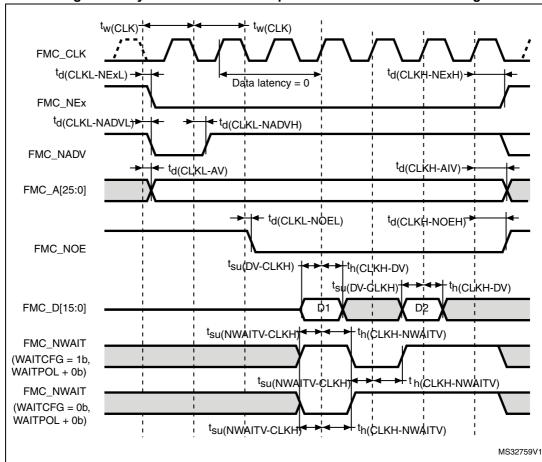
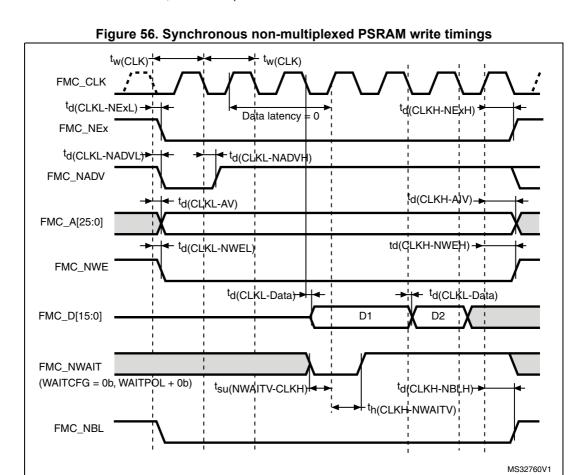


Figure 55. Synchronous non-multiplexed NOR/PSRAM read timings

Table 96. Synchronous non-multiplexed NOR/PSRAM read timings<sup>(1)(2)</sup>

| Symbol                      | Parameter                                  | Min                     | Max | Unit |
|-----------------------------|--|-------------------------|-----|------|
| t <sub>w(CLK)</sub>         | FMC_CLK period                             | 2T <sub>HCLK</sub>      | -   |      |
| t <sub>(CLKL-NExL)</sub>    | FMC_CLK low to FMC_NEx low (x=02)          | -                       | 2.5 |      |
| t <sub>d(CLKH-NExH)</sub>   | FMC_CLK high to FMC_NEx high (x= 02)       | T <sub>HCLK</sub> - 0.5 | -   |      |
| t <sub>d(CLKL-NADVL)</sub>  | FMC_CLK low to FMC_NADV low                | -                       | 0   |      |
| t <sub>d(CLKL-NADVH)</sub>  | FMC_CLK low to FMC_NADV high               | 0                       | -   |      |
| t <sub>d(CLKL-AV)</sub>     | FMC_CLK low to FMC_Ax valid (x=1625)       | -                       | 2.5 |      |
| t <sub>d(CLKH-AIV)</sub>    | FMC_CLK high to FMC_Ax invalid (x=1625)    | T <sub>HCLK</sub>       | -   | ns   |
| t <sub>d(CLKL-NOEL)</sub>   | FMC_CLK low to FMC_NOE low                 | -                       | 2   |      |
| t <sub>d(CLKH-NOEH)</sub>   | FMC_CLK high to FMC_NOE high               | T <sub>HCLK</sub> - 0.5 | -   |      |
| t <sub>su(DV-CLKH)</sub>    | FMC_D[15:0] valid data before FMC_CLK high | 1                       | -   |      |
| t <sub>h(CLKH-DV)</sub>     | FMC_D[15:0] valid data after FMC_CLK high  | 3.5                     | -   |      |
| t <sub>su(NWAIT-CLKH)</sub> | FMC_NWAIT valid before FMC_CLK high        | 1                       | -   |      |
| t <sub>h(CLKH-NWAIT)</sub>  | FMC_NWAIT valid after FMC_CLK high         | 3.5                     | -   | 1    |

- 1.  $C_L = 30 pF$ .
- 2. Based on characterization, not tested in production.



| Symbol                      | Parameter                                | Min                     | Max | Unit |
|-----------------------------|--|-------------------------|-----|------|
| t <sub>w(CLK)</sub>         | FMC_CLK period                           | 2T <sub>HCLK</sub> – 1  | -   |      |
| t <sub>d(CLKL-NExL)</sub>   | FMC_CLK low to FMC_NEx low (x=02)        | -                       | 2.5 |      |
| t <sub>d(CLKH-NExH)</sub>   | FMC_CLK high to FMC_NEx high (x= 02)     | T <sub>HCLK</sub> – 0.5 | -   |      |
| t <sub>d(CLKL-NADVL)</sub>  | FMC_CLK low to FMC_NADV low              | -                       | 2   |      |
| t <sub>d(CLKL-NADVH)</sub>  | FMC_CLK low to FMC_NADV high             | 0                       | -   |      |
| t <sub>d(CLKL-AV)</sub>     | FMC_CLK low to FMC_Ax valid (x=1625)     | -                       | 2   |      |
| t <sub>d(CLKH-AIV)</sub>    | FMC_CLK high to FMC_Ax invalid (x=1625)  | 0                       | -   | ns   |
| t <sub>d(CLKL-NWEL)</sub>   | FMC_CLK low to FMC_NWE low               | -                       | 3   | 113  |
| t <sub>d(CLKH-NWEH)</sub>   | FMC_CLK high to FMC_NWE high             | T <sub>HCLK</sub> + 1   | -   |      |
| t <sub>d(CLKL-Data)</sub>   | FMC_D[15:0] valid data after FMC_CLK low | -                       | 2.5 |      |
| t <sub>d(CLKL-NBLL)</sub>   | FMC_CLK low to FMC_NBL low               | 3                       | -   |      |
| t <sub>d(CLKH-NBLH)</sub>   | FMC_CLK high to FMC_NBL high             | T <sub>HCLK</sub> + 1.5 | -   |      |
| t <sub>su(NWAIT-CLKH)</sub> | FMC_NWAIT valid before FMC_CLK high      | 1.5                     | -   |      |
| t <sub>h(CLKH-NWAIT)</sub>  | FMC_NWAIT valid after FMC_CLK high       | 0                       | -   |      |

Table 97. Synchronous non-multiplexed PSRAM write timings<sup>(1)(2)</sup>

## NAND controller waveforms and timings

*Figure 57* through *Figure 60* represent synchronous waveforms, and *Table 98* and *Table 99* provide the corresponding timings. The results shown in this table are obtained with the following FMC configuration:

- COM.FSMC\_SetupTime = 0x01;
- COM.FMC\_WaitSetupTime = 0x03;
- COM.FMC\_HoldSetupTime = 0x02;
- COM.FMC\_HiZSetupTime = 0x01;
- ATT.FMC\_SetupTime = 0x01;
- ATT.FMC WaitSetupTime = 0x03;
- ATT.FMC\_HoldSetupTime = 0x02;
- ATT.FMC\_HiZSetupTime = 0x01;
- Bank = FMC\_Bank\_NAND;
- MemoryDataWidth = FMC\_MemoryDataWidth\_16b;
- ECC = FMC\_ECC\_Enable;
- ECCPageSize = FMC\_ECCPageSize\_512Bytes;
- TCLRSetupTime = 0;
- TARSetupTime = 0.

In all timing tables, the T<sub>HCLK</sub> is the HCLK clock period.



<sup>1.</sup>  $C_L = 30 pF$ .

<sup>2.</sup> Based on characterization, not tested in production.

FMC\_NCEX

ALE (FMC\_A17)
CLE (FMC\_A16)

FMC\_NWE

FMC\_NOE (NRE)

Th(NOE-ALE)

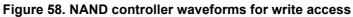
Th(NOE-D)

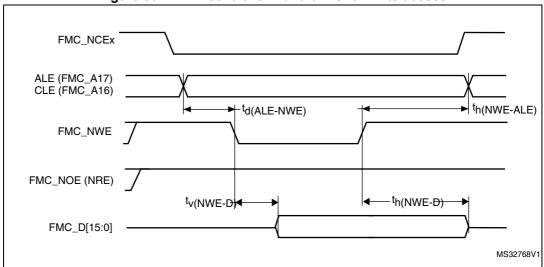
Th(NOE-D)

Th(NOE-D)

Th(NOE-D)

Figure 57. NAND controller waveforms for read access





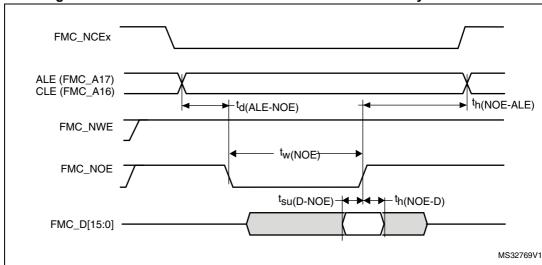


Figure 59. NAND controller waveforms for common memory read access



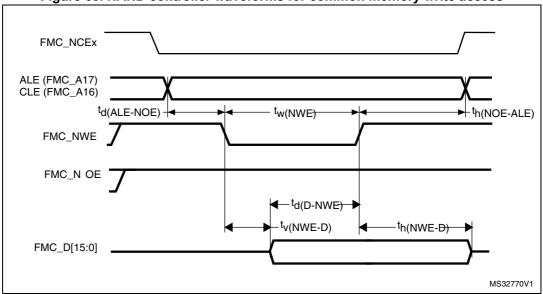


Table 98. Switching characteristics for NAND Flash read cycles<sup>(1)</sup>

| Symbol                  | Parameter                                  | Min                      | Max                      | Unit |
|-------------------------|--|--------------------------|--------------------------|------|
| t <sub>w(N0E)</sub>     | FMC_NOE low width                          | 4T <sub>HCLK</sub> - 0.5 | 4T <sub>HCLK</sub> + 0.5 |      |
| t <sub>su(D-NOE)</sub>  | FMC_D[15-0] valid data before FMC_NOE high | 9                        | -                        |      |
| t <sub>h(NOE-D)</sub>   | FMC_D[15-0] valid data after FMC_NOE high  | 2.5                      | -                        | ns   |
| t <sub>d(ALE-NOE)</sub> | FMC_ALE valid before FMC_NOE low           | -                        | 3T <sub>HCLK</sub> - 0.5 |      |
| t <sub>h(NOE-ALE)</sub> | FMC_NWE high to FMC_ALE invalid            | 3T <sub>HCLK</sub> – 2   | -                        |      |

<sup>1.</sup>  $C_L = 30 pF$ .

| Table 99. Switching characteristics for NAND Flash write cycles <sup>(1)</sup> | Table 99. Switching ch | naracteristics fo | or NAND Flas | h write cycles <sup>(1)</sup> |
|--|------------------------|-------------------|--------------|-------------------------------|
|--|------------------------|-------------------|--------------|-------------------------------|

| Symbol                  | Parameter                             | Min                    | Max                      | Unit |
|-------------------------|---------------------------------------|------------------------|--------------------------|------|
| t <sub>w(NWE)</sub>     | FMC_NWE low width                     | 4T <sub>HCLK</sub> - 2 | 4T <sub>HCLK</sub>       | ns   |
| t <sub>v(NWE-D)</sub>   | FMC_NWE low to FMC_D[15-0] valid      | 0                      | -                        | ns   |
| t <sub>h(NWE-D)</sub>   | FMC_NWE high to FMC_D[15-0] invalid   | 3T <sub>HCLK</sub> – 1 | -                        | ns   |
| t <sub>d(D-NWE)</sub>   | FMC_D[15-0] valid before FMC_NWE high | 5T <sub>HCLK</sub> – 3 | -                        | ns   |
| t <sub>d(ALE-NWE)</sub> | FMC_ALE valid before FMC_NWE low      | -                      | 3T <sub>HCLK</sub> - 0.5 | ns   |
| t <sub>h(NWE-ALE)</sub> | FMC_NWE high to FMC_ALE invalid       | 3T <sub>HCLK</sub> – 2 | -                        | ns   |

<sup>1.</sup> C<sub>L</sub> = 30 pF.

## **SDRAM** waveforms and timings

Figure 61. SDRAM read access waveforms (CL = 1)

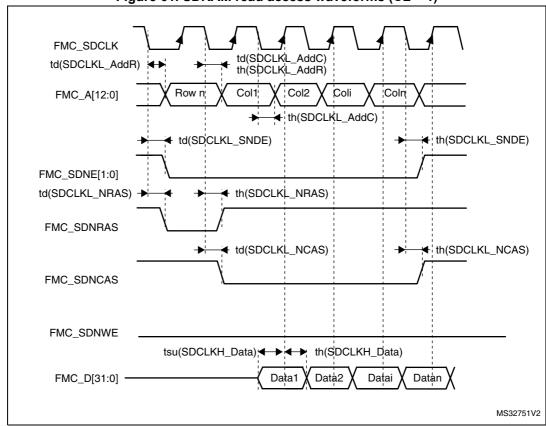


Table 100. SDRAM read timings<sup>(1)(2)</sup>

| Symbol                        | Parameter              | Min                     | Max                     | Unit |
|-------------------------------|------------------------|-------------------------|-------------------------|------|
| t <sub>w(SDCLK)</sub>         | FMC_SDCLK period       | 2T <sub>HCLK</sub> -0.5 | 2T <sub>HCLK</sub> +0.5 |      |
| t <sub>su(SDCLKH _Data)</sub> | Data input setup time  | 1                       | -                       |      |
| t <sub>h(SDCLKH_Data)</sub>   | Data input hold time   | 4                       | -                       |      |
| t <sub>d(SDCLKL_Add)</sub>    | Address valid time     | -                       | 3                       |      |
| t <sub>d(SDCLKL_SDNE)</sub>   | Chip select valid time | -                       | 1.5                     | ns   |
| t <sub>h(SDCLKL_SDNE)</sub>   | Chip select hold time  | 0                       | -                       | 113  |
| t <sub>d(SDCLKL_SDNRAS)</sub> | SDNRAS valid time      | -                       | 1.5                     |      |
| t <sub>h(SDCLKL_SDNRAS)</sub> | SDNRAS hold time       | 0                       | -                       |      |
| t <sub>d(SDCLKL_SDNCAS)</sub> | SDNCAS valid time      | -                       | 0.5                     |      |
| t <sub>h(SDCLKL_SDNCAS)</sub> | SDNCAS hold time       | 0                       | -                       |      |

- 1. CL = 30 pF on data and address lines. CL=15pF on FMC\_SDCLK.
- 2. Guaranteed by characterization results, not tested in production.

Table 101. LPSDR SDRAM read timings<sup>(1)(2)</sup>

| Symbol                         | Parameter              | Min                      | Max                      | Unit |
|--------------------------------|------------------------|--------------------------|--------------------------|------|
| t <sub>w(SDCLK)</sub>          | FMC_SDCLK period       | 2T <sub>HCLK</sub> - 0.5 | 2T <sub>HCLK</sub> + 0.5 |      |
| t <sub>su(SDCLKH _Data)</sub>  | Data input setup time  | 1                        | -                        |      |
| t <sub>h(SDCLKH_Data)</sub>    | Data input hold time   | 5                        | -                        |      |
| t <sub>d</sub> (SDCLKL_Add)    | Address valid time     | -                        | 3                        |      |
| t <sub>d(SDCLKL_SDNE)</sub>    | Chip select valid time | -                        | 3                        | ns   |
| t <sub>h(SDCLKL_SDNE)</sub>    | Chip select hold time  | 0                        | -                        | 115  |
| t <sub>d</sub> (SDCLKL_SDNRAS) | SDNRAS valid time      | -                        | 2                        |      |
| t <sub>h(SDCLKL_SDNRAS)</sub>  | SDNRAS hold time       | 0                        | -                        |      |
| t <sub>d(SDCLKL_SDNCAS)</sub>  | SDNCAS valid time      | -                        | 2                        |      |
| t <sub>h(SDCLKL_SDNCAS)</sub>  | SDNCAS hold time       | 0                        | -                        |      |

- 1. CL = 10 pF.
- 2. Guaranteed by characterization results, not tested in production.

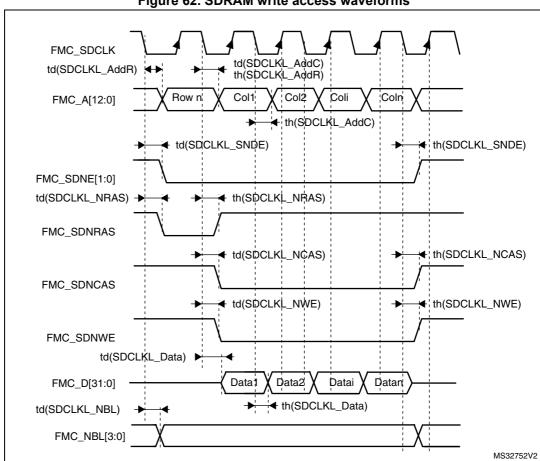


Figure 62. SDRAM write access waveforms

Table 102. SDRAM write timings<sup>(1)(2)</sup>

| Symbol                        | Parameter              | Min                      | Max                      | Unit |
|-------------------------------|------------------------|--------------------------|--------------------------|------|
| F <sub>(SDCLK)</sub>          | Frequency of operation | -                        | 90                       | MHz  |
| t <sub>w(SDCLK)</sub>         | FMC_SDCLK period       | 2T <sub>HCLK</sub> - 0.5 | 2T <sub>HCLK</sub> + 0.5 |      |
| t <sub>d(SDCLKL _Data)</sub>  | Data output valid time | -                        | 2                        |      |
| t <sub>h(SDCLKL _Data)</sub>  | Data output hold time  | 0.5                      | -                        |      |
| t <sub>d(SDCLK _Add)</sub>    | Address valid time     | -                        | 3                        |      |
| $t_{d(SDCLKL\_SDNWE))}$       | SDNWE valid time       | -                        | 1.5                      |      |
| t <sub>h(SDCLKL_SDNWE))</sub> | SDNWE hold time        | 0                        | -                        | ns   |
| t <sub>d(SDCLKL_SDNE))</sub>  | Chip select valid time | -                        | 1.5                      | 113  |
| t <sub>h(SDCLKL_SDNE)</sub>   | Chip select hold time  | 0                        | -                        |      |
| t <sub>d(SDCLKL_SDNRAS)</sub> | SDNRAS valie time      | -                        | 1                        |      |
| t <sub>h(SDCLKL_SDNRAS)</sub> | SDNRAS hold time       | 0                        | -                        |      |
| t <sub>d(SDCLKL_SDNCAS)</sub> | SDNCAS valid time      | -                        | 1                        |      |
| t <sub>h(SDCLKL_SDNCAS)</sub> | SDNCAS hold time       | 0                        | -                        |      |

<sup>1.</sup> CL = 10 pF on data and address line. CL=1.5pF on FMC\_SDCLK.

<sup>2.</sup> Guaranteed by characterization results, not tested in production.

| Symbol  | Parameter              | Min                      | Max                      | Unit |
|---|------------------------|--------------------------|--------------------------|------|
| F <sub>(SDCLK)</sub>                            | Frequency of operation | -                        | 84                       | MHz  |
| t <sub>w(SDCLK)</sub>                           | FMC_SDCLK period       | 2T <sub>HCLK</sub> - 0.5 | 2T <sub>HCLK</sub> + 0.5 |      |
| t <sub>d(SDCLKL _Data)</sub>                    | Data output valid time | -                        | 5                        |      |
| t <sub>h(SDCLKL _Data)</sub>                    | Data output hold time  | 0.5                      | -                        |      |
| t <sub>d(SDCLK _Add)</sub>                      | Address valid time     | -                        | 3                        |      |
| t <sub>d(SDCLKL _SDNWE))</sub>                  | SDNWE valid time       | -                        | 3                        |      |
| t <sub>h(SDCLKL_SDNWE))</sub>                   | SDNWE hold time        | 0                        | -                        | ns   |
| t <sub>d(SDCLKL_SDNE))</sub>                    | Chip select valid time | -                        | 2.5                      | 113  |
| t <sub>h(SDCLKL_SDNE)</sub>                     | Chip select hold time  | 0                        | -                        |      |
| t <sub>d(SDCLKL_SDNRAS)</sub>                   | SDNRAS valid time      | -                        | 2                        |      |
| t <sub>h(SDCLKL_SDNRAS)</sub>                   | SDNRAS hold time       | 0                        | -                        |      |
| t <sub>d(SDCLKL_SDNCAS)</sub> SDNCAS valid time |                        | -                        | 2                        |      |
| t <sub>d(SDCLKL_SDNCAS)</sub>                   | SDNCAS hold time       | 0                        | -                        |      |

Table 103. LPSDR SDRAM write timings<sup>(1)(2)</sup>

## 6.3.27 Camera interface (DCMI) timing specifications

Unless otherwise specified, the parameters given in *Table 104* for DCMI are derived from tests performed under the ambient temperature,  $f_{HCLK}$  frequency and  $V_{DD}$  supply voltage summarized in *Table 16*, with the following configuration:

- DCMI\_PIXCLK polarity: falling
- DCMI\_VSYNC and DCMI\_HSYNC polarity: high
- Data formats: 14 bits

**Table 104. DCMI characteristics** 

| Symbol   | Parameter                                     | Min | Max | Unit |
|--|---|-----|-----|------|
| -  | Frequency ratio DCMI_PIXCLK/f <sub>HCLK</sub> | -   | 0.4 | -    |
| DCMI_PIXCLK                                      | Pixel clock input                             | -   | 54  | MHz  |
| D <sub>Pixel</sub>                               | Pixel clock input duty cycle                  | 30  | 70  | %    |
| t <sub>su(DATA)</sub>                            | Data input setup time                         | 1   | -   |      |
| t <sub>h(DATA)</sub>                             | Data input hold time                          | 3.5 | -   |      |
| t <sub>su(HSYNC)</sub><br>t <sub>su(VSYNC)</sub> | DCMI_HSYNC/DCMI_VSYNC input setup time        | 2   | -   | ns   |
| t <sub>h(HSYNC)</sub><br>t <sub>h(VSYNC)</sub>   | DCMI_HSYNC/DCMI_VSYNC input hold time         | 0   | -   |      |

<sup>1.</sup> CL = 10 pF.

<sup>2.</sup> Guaranteed by characterization results, not tested in production.

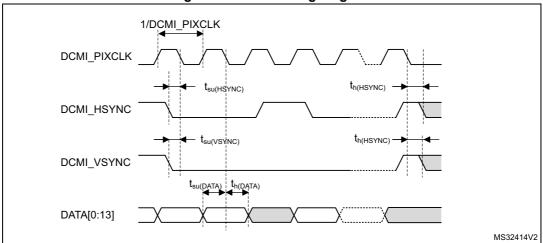


Figure 63. DCMI timing diagram

## 6.3.28 SD/SDIO MMC card host interface (SDIO) characteristics

Unless otherwise specified, the parameters given in *Table 105* for the SDIO are derived from tests performed under the ambient temperature,  $f_{PCLK2}$  frequency and  $V_{DD}$  supply voltage conditions summarized in *Table 16*, with the following configuration:

- Output speed is set to OSPEEDRy[1:0] = 10
- Capacitive load C = 30 pF
- Measurement points are done at CMOS levels: 0.5V<sub>DD</sub>

Refer to Section 6.3.17: I/O port characteristics for more details on the input/output characteristics.

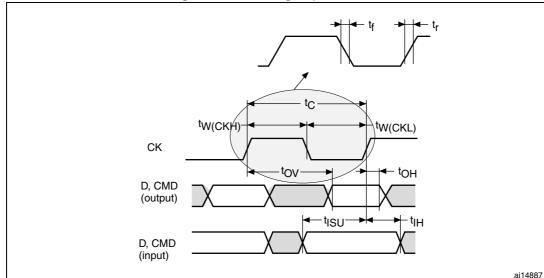


Figure 64. SDIO high-speed mode

57

Figure 65. SD default mode

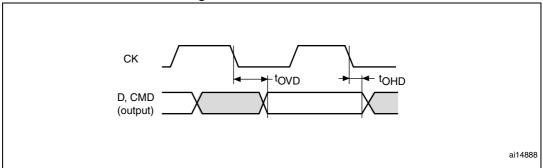


Table 105. Dynamic characteristics: SD / MMC characteristics $^{(1)(2)}$ 

| Symbol              | Parameter                               | Conditions | Min | Тур  | Max | Unit |
|---------------------|---|------------|-----|------|-----|------|
| $f_{PP}$            | Clock frequency in data transfer mode   | -          | 0   | -    | 50  | MHz  |
| -                   | SDIO_CK/fPCLK2 frequency ratio          | -          | -   | -    | 8/3 | -    |
| t <sub>W(CKL)</sub> | Clock low time                          | fpp =50MHz | 9.5 | 10.5 | -   | ns   |
| t <sub>W(CKH)</sub> | Clock high time                         | fpp =50MHz | 8.5 | 9.5  | -   | 115  |
| CMD, D inp          | outs (referenced to CK) in MMC and SE   | ) HS mode  |     |      |     |      |
| t <sub>ISU</sub>    | Input setup time HS                     | fpp =50MHz | 1   | -    | -   | no   |
| t <sub>IH</sub>     | Input hold time HS                      | fpp =50MHz | 4.5 | -    | -   | ns   |
| CMD, D out          | tputs (referenced to CK) in MMC and S   | SD HS mode |     |      |     |      |
| t <sub>OV</sub>     | Output valid time HS                    | fpp =50MHz | -   | 12.5 | 13  | ns   |
| t <sub>OH</sub>     | Output hold time HS                     | fpp =50MHz | 11  | -    | -   | 115  |
| CMD, D inp          | outs (referenced to CK) in SD default m | node       |     |      |     |      |
| t <sub>ISUD</sub>   | Input setup time SD                     | fpp =25MHz | 2.5 | -    | -   |      |
| t <sub>IHD</sub>    | Input hold time SD                      | fpp =25MHz | 5.5 | -    | -   | ns   |
| CMD, D out          | tputs (referenced to CK) in SD default  | mode       |     |      |     |      |
| t <sub>OVD</sub>    | Output valid default time SD            | fpp =24MHz | -   | 3.5  | 4   |      |
| t <sub>OHD</sub>    | Output hold default time SD             | fpp =24MHz | 2   | -    | -   | ns   |

<sup>1.</sup> Guaranteed by characterization results, not tested in production.

<sup>2.</sup>  $V_{DD} = 2.7 \text{ to } 3.6 \text{ V}.$ 

Table 106. Dynamic characteristics: eMMC characteristics  $V_{DD}$  = 1.7 V to 1.9  $V^{(1)(2)}$ 

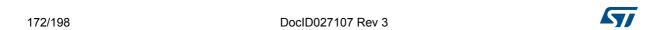
| Symbol              | Parameter                                      | Conditions | Min | Тур  | Max  | Unit |  |  |  |  |
|---------------------|--|------------|-----|------|------|------|--|--|--|--|
| f <sub>PP</sub>     | Clock frequency in data transfer mode          | -          | 0   | -    | 50   | MHz  |  |  |  |  |
| -                   | SDIO_CK/fPCLK2 frequency ratio                 | -          | -   | -    | 8/3  | -    |  |  |  |  |
| t <sub>W(CKL)</sub> | Clock low time                                 | fpp =50MHz | 9.5 | 10.5 | -    | no   |  |  |  |  |
| t <sub>W(CKH)</sub> | Clock high time                                | fpp =50MHz | 8.5 | 9.5  | -    | ns   |  |  |  |  |
| CMD, D inp          | uts (referenced to CK) in eMMC mode            | )          |     |      |      |      |  |  |  |  |
| t <sub>ISU</sub>    | Input setup time HS                            | fpp =50MHz | 0.5 | -    | -    | no   |  |  |  |  |
| t <sub>IH</sub>     | Input hold time HS                             | fpp =50MHz | 7.5 | -    | -    | ns   |  |  |  |  |
| CMD, D out          | CMD, D outputs (referenced to CK) in eMMC mode |            |     |      |      |      |  |  |  |  |
| t <sub>OV</sub>     | Output valid time HS                           | fpp =50MHz | -   | 13.5 | 14.5 | ne   |  |  |  |  |
| t <sub>OH</sub>     | Output hold time HS                            | fpp =50MHz | 12  | -    | -    | ns   |  |  |  |  |

<sup>1.</sup> Guaranteed by characterization results, not tested in production.

## 6.3.29 RTC characteristics

**Table 107. RTC characteristics** 

| Symbol | Parameter                                  | Conditions                                       | Min | Max |
|--------|--|--|-----|-----|
| -      | f <sub>PCLK1</sub> /RTCCLK frequency ratio | Any read/write operation from/to an RTC register | 4   | -   |



<sup>2.</sup>  $V_{DD} = 2.7 \text{ to } 3.6 \text{ V}.$ 

### **Package information** 7

In order to meet environmental requirements, ST offers these devices in different grades of ECOPACK® packages, depending on their level of environmental compliance. ECOPACK® specifications, grade definitions and product status are available at: www.st.com. ECOPACK® is an ST trademark.

#### LQFP64 package information 7.1

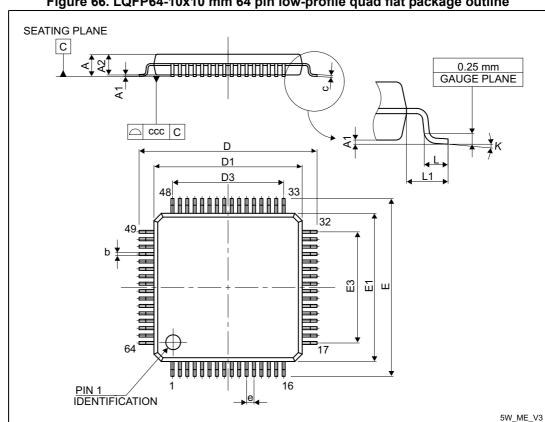


Figure 66. LQFP64-10x10 mm 64 pin low-profile quad flat package outline

1. Drawing is not to scale

Table 108. LQFP64 - 10 x 10 mm low-profile quad flat package mechanical data

| Symbol   | millimeters |       |       |        | inches <sup>(1)</sup> |        |
|----------|-------------|-------|-------|--------|-----------------------|--------|
| Symbol M | Min         | Тур   | Max   | Min    | Тур                   | Max    |
| А        | -           | -     | 1.600 | -      | -                     | 0.0630 |
| A1       | 0.050       | -     | 0.150 | 0.0020 | -                     | 0.0059 |
| A2       | 1.350       | 1.400 | 1.450 | 0.0531 | 0.0551                | 0.0571 |
| b        | 0.170       | 0.220 | 0.270 | 0.0067 | 0.0087                | 0.0106 |
| С        | 0.090       | -     | 0.200 | 0.0035 | -                     | 0.0079 |



**Package information** STM32F446xx

Table 108. LQFP64 – 10 x 10 mm low-profile quad flat package mechanical data (continued)

| Comple of | millimeters |        |        | inches <sup>(1)</sup> |        |        |
|-----------|-------------|--------|--------|-----------------------|--------|--------|
| Symbol    | Min         | Тур    | Max    | Min                   | Тур    | Max    |
| D         | 11.800      | 12.000 | 12.200 | 0.4646                | 0.4724 | 0.4803 |
| D1        | 9.800       | 10.000 | 10.200 | 0.3858                | 0.3937 | 0.4016 |
| D3        | -           | 7.500  | -      | -                     | 0.2953 | -      |
| E         | 11.800      | 12.000 | 12.200 | 0.4646                | 0.4724 | 0.4803 |
| E1        | 9.800       | 10.000 | 10.200 | 0.3858                | 0.3937 | 0.4016 |
| E3        | -           | 7.500  | -      | -                     | 0.2953 | -      |
| е         | -           | 0.500  | -      | -                     | 0.0197 | -      |
| L         | 0.450       | 0.600  | 0.750  | 0.0177                | 0.0236 | 0.0295 |
| L1        | -           | 1.000  | -      | -                     | 0.0394 | -      |
| K         | 0°          | 3.5°   | 7°     | 0°                    | 3.5°   | 7°     |
| ccc       | -           | -      | 0.080  | -                     | -      | 0.0031 |

<sup>1.</sup> Values in inches are converted from mm and rounded to 4 decimal digits.

0.3 12.7 10.3 10.3 12.7 ai14909c

Figure 67. LQFP64 Recommended footprint

- 1. Drawing is not to scale.
- Dimensions are in millimeters.

## Marking of engineering samples for LQFP64

The following figure gives an example of topside marking orientation versus pin 1 identifier location.

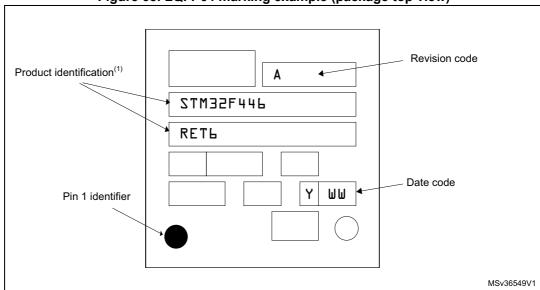
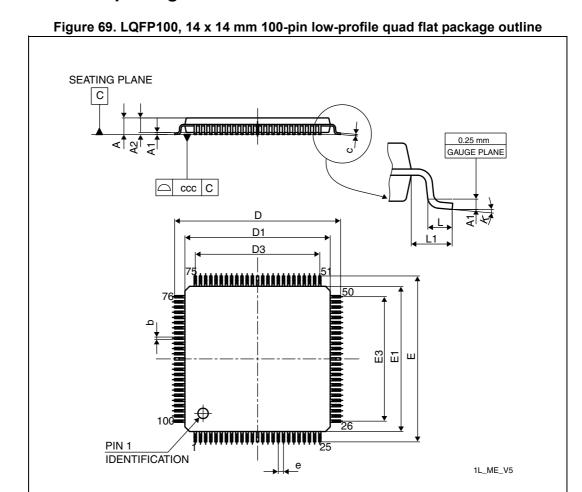


Figure 68. LQFP64 marking example (package top view)

1. Parts marked as "ES", "E" or accompanied by an Engineering Sample notification letter, are not yet qualified and therefore not yet ready to be used in production and any consequences deriving from such usage will not be at ST charge. In no event ST will be liable for any customer usage of these engineering samples in production. ST Quality has to be contacted prior to any decision to use these Engineering samples to run qualification activity.

Package information STM32F446xx

# 7.2 LQFP100 package information



1. Drawing is not to scale.

Table 109. LQPF100, 14 x 14 mm 100-pin low-profile quad flat package mechanical data

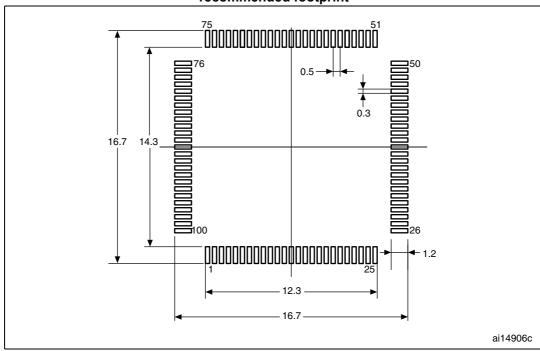
| Combal |        | millimeters |        |        | inches <sup>(1)</sup> |        |
|--------|--------|-------------|--------|--------|-----------------------|--------|
| Symbol | Min    | Тур         | Max    | Min    | Тур                   | Max    |
| Α      | -      | -           | 1.600  | -      | -                     | 0.0630 |
| A1     | 0.050  | -           | 0.150  | 0.0020 | -                     | 0.0059 |
| A2     | 1.350  | 1.400       | 1.450  | 0.0531 | 0.0551                | 0.0571 |
| b      | 0.170  | 0.220       | 0.270  | 0.0067 | 0.0087                | 0.0106 |
| С      | 0.090  | -           | 0.200  | 0.0035 | -                     | 0.0079 |
| D      | 15.800 | 16.000      | 16.200 | 0.6220 | 0.6299                | 0.6378 |
| D1     | 13.800 | 14.000      | 14.200 | 0.5433 | 0.5512                | 0.5591 |
| D3     | -      | 12.000      | -      | -      | 0.4724                | -      |
| E      | 15.800 | 16.000      | 16.200 | 0.6220 | 0.6299                | 0.6378 |

Table 109. LQPF100, 14 x 14 mm 100-pin low-profile quad flat package mechanical data

| Cumbal |        | millimeters |        | inches <sup>(1)</sup> |        |        |
|--------|--------|-------------|--------|-----------------------|--------|--------|
| Symbol | Min    | Тур         | Max    | Min                   | Тур    | Max    |
| E1     | 13.800 | 14.000      | 14.200 | 0.5433                | 0.5512 | 0.5591 |
| E3     | -      | 12.000      | -      | -                     | 0.4724 | -      |
| е      | -      | 0.500       | -      | -                     | 0.0197 | -      |
| L      | 0.450  | 0.600       | 0.750  | 0.0177                | 0.0236 | 0.0295 |
| L1     | -      | 1.000       | -      | -                     | 0.0394 | -      |
| k      | 0°     | 3.5°        | 7°     | 0°                    | 3.5°   | 7°     |
| ccc    | -      | -           | 0.080  | -                     | -      | 0.0031 |

<sup>1.</sup> Values in inches are converted from mm and rounded to 4 decimal digits.

Figure 70. LQFP100 - 100-pin, 14 x 14 mm low-profile quad flat recommended footprint



1. Dimensions are expressed in millimeters.

Package information STM32F446xx

## Device marking for LQFP100 package

The following figure gives an example of topside marking orientation versus pin 1 identifier location.

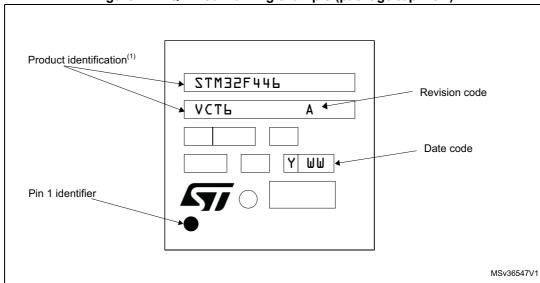


Figure 71. LQFP100 marking example (package top view)

1. Parts marked as "ES", "E" or accompanied by an Engineering Sample notification letter, are not yet qualified and therefore not yet ready to be used in production and any consequences deriving from such usage will not be at ST charge. In no event ST will be liable for any customer usage of these engineering samples in production. ST Quality has to be contacted prior to any decision to use these Engineering samples to run qualification activity.



### 7.3 LQFP144 package information.

0.25 mm □ ccc C GAUGE PLANE D D1 D3 109 72 E3 E1 37 PIN 1 **IDENTIFICATION** е 1A\_ME\_V4

Figure 72. LQFP144, 20 x 20 mm, 144-pin low-profile quad flat package outline

1. Drawing is not to scale.

Package information STM32F446xx

Table 110. LQFP144, 20 x 20 mm, 144-pin low-profile quad flat package mechanical data

| 0      |        | millimeters |        |        | inches <sup>(1)</sup> |        |
|--------|--------|-------------|--------|--------|-----------------------|--------|
| Symbol | Min    | Тур         | Max    | Min    | Тур                   | Max    |
| Α      | -      | -           | 1.600  | -      | -                     | 0.0630 |
| A1     | 0.050  | -           | 0.150  | 0.0020 | -                     | 0.0059 |
| A2     | 1.350  | 1.400       | 1.450  | 0.0531 | 0.0551                | 0.0571 |
| b      | 0.170  | 0.220       | 0.270  | 0.0067 | 0.0087                | 0.0106 |
| С      | 0.090  | -           | 0.200  | 0.0035 | -                     | 0.0079 |
| D      | 21.800 | 22.000      | 22.200 | 0.8583 | 0.8661                | 0.874  |
| D1     | 19.800 | 20.000      | 20.200 | 0.7795 | 0.7874                | 0.7953 |
| D3     | -      | 17.500      | -      | -      | 0.689                 | -      |
| E      | 21.800 | 22.000      | 22.200 | 0.8583 | 0.8661                | 0.8740 |
| E1     | 19.800 | 20.000      | 20.200 | 0.7795 | 0.7874                | 0.7953 |
| E3     | -      | 17.500      | -      | -      | 0.6890                | -      |
| е      | -      | 0.500       | -      | -      | 0.0197                | -      |
| L      | 0.450  | 0.600       | 0.750  | 0.0177 | 0.0236                | 0.0295 |
| L1     | -      | 1.000       | -      | -      | 0.0394                | -      |
| k      | 0°     | 3.5°        | 7°     | 0°     | 3.5°                  | 7°     |
| ccc    | -      | -           | 0.080  | -      | -                     | 0.0031 |

<sup>1.</sup> Values in inches are converted from mm and rounded to 4 decimal digits.

180/198

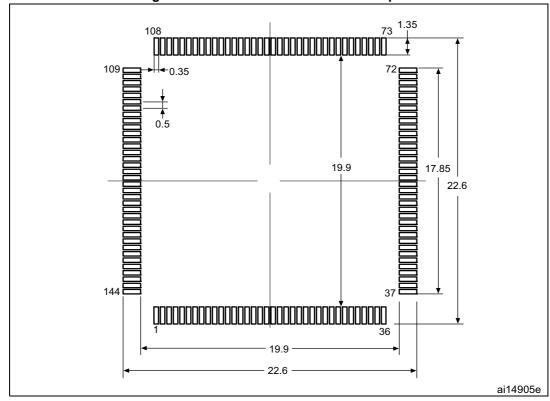


Figure 73. LQFP144 recommended footprint

1. Dimensions are expressed in millimeters.

### Device marking for LQFP144 package

The following figure gives an example of topside marking orientation versus pin 1 identifier location.

Product identification<sup>(1)</sup>

Revision code

A

STM32F446ZET6

Date code

Y W W

Pin 1 identifier

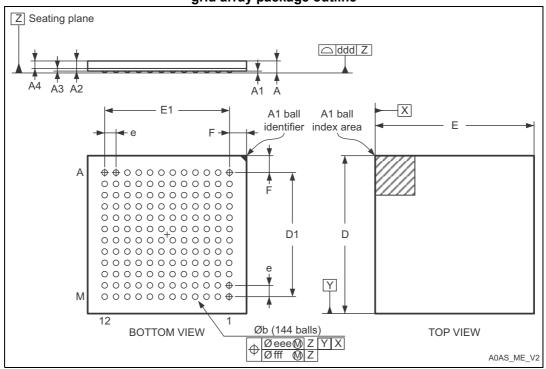
Figure 74. LQFP144 marking example (package top view)

1. Parts marked as "ES", "E" or accompanied by an Engineering Sample notification letter, are not yet qualified and therefore not yet ready to be used in production and any consequences deriving from such usage will not be at ST charge. In no event ST will be liable for any customer usage of these engineering samples in production. ST Quality has to be contacted prior to any decision to use these Engineering samples to run qualification activity.



## 7.4 UFBGA144 7 x 7 mm package information

Figure 75. UFBGA144 - 144-pin, 7 x 7 mm, 0.50 mm pitch, ultra fine pitch ball grid array package outline



1. Drawing is not in scale.

Table 111. UFBGA144 - 144-pin, 7 x 7 mm, 0.50 mm pitch, ultra fine pitch ball grid array package mechanical data

| Symbol | millimeters |       |       | inches <sup>(1)</sup> |        |        |
|--------|-------------|-------|-------|-----------------------|--------|--------|
| Symbol | Min.        | Тур.  | Max.  | Min.                  | Тур.   | Max.   |
| Α      | 0.460       | 0.530 | 0.600 | 0.0181                | 0.0209 | 0.0236 |
| A1     | 0.050       | 0.080 | 0.110 | 0.0020                | 0.0031 | 0.0043 |
| A2     | 0.400       | 0.450 | 0.500 | 0.0157                | 0.0177 | 0.0197 |
| A3     | -           | 0.130 | -     | -                     | 0.0051 | -      |
| A4     | 0.270       | 0.320 | 0.370 | 0.0106                | 0.0126 | 0.0146 |
| b      | 0.230       | 0.280 | 0.320 | 0.0091                | 0.0110 | 0.0126 |
| D      | 6.950       | 7.000 | 7.050 | 0.2736                | 0.2756 | 0.2776 |
| D1     | 5.450       | 5.500 | 5.550 | 0.2146                | 0.2165 | 0.2185 |
| Е      | 6.950       | 7.000 | 7.050 | 0.2736                | 0.2756 | 0.2776 |
| E1     | 5.450       | 5.500 | 5.550 | 0.2146                | 0.2165 | 0.2185 |
| е      | -           | 0.500 | -     | -                     | 0.0197 | -      |
| F      | 0.700       | 0.750 | 0.800 | 0.0276                | 0.0295 | 0.0315 |

Table 111. UFBGA144 - 144-pin, 7 x 7 mm, 0.50 mm pitch, ultra fine pitch ball grid array package mechanical data (continued)

| Sumbol | millimeters |      |       | inches <sup>(1)</sup> |      |        |
|--------|-------------|------|-------|-----------------------|------|--------|
| Symbol | Min.        | Тур. | Max.  | Min.                  | Тур. | Max.   |
| ddd    | -           | -    | 0.100 | -                     | -    | 0.0039 |
| eee    | -           | -    | 0.150 | -                     | -    | 0.0059 |
| fff    | -           | -    | 0.050 | -                     | -    | 0.0020 |

<sup>1.</sup> Values in inches are converted from mm and rounded to 4 decimal digits.

### Device marking for UFBGA144 7 x 7 mm package

The following figure gives an example of topside marking orientation versus pin 1 identifier location.

Product identification(1) STM32F **446ZEH6** Date code Ball A1 indentifier Additional information MSv37953V1

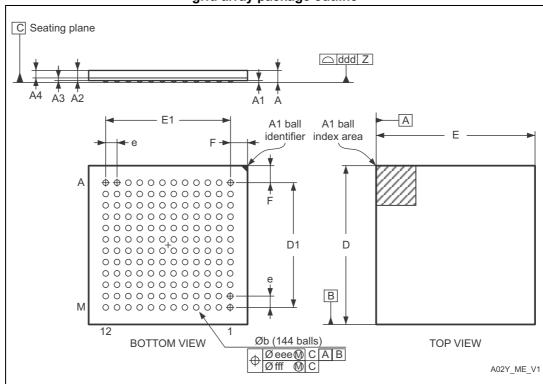
Figure 76. UQFP144 7 x 7 mm marking example (package top view)

Parts marked as "ES", "E" or accompanied by an Engineering Sample notification letter, are not yet qualified and therefore not yet ready to be used in production and any consequences deriving from such usage will not be at ST charge. In no event ST will be liable for any customer usage of these engineering samples in production. ST Quality has to be contacted prior to any decision to use these Engineering samples to run qualification activity.

DocID027107 Rev 3 184/198

## 7.5 UFBGA144 10 x 10 mm package information

Figure 77. UFBGA144 - 144-pin, 10 x 10 mm, 0.80 mm pitch, ultra fine pitch ball grid array package outline



1. Drawing is not to scale.

Table 112. UFBGA144 - 144-pin, 10 x 10 mm, 0.80 mm pitch, ultra fine pitch ball grid array package mechanical data

| Symbol | millimeters |        |        | inches <sup>(1)</sup> |        |        |
|--------|-------------|--------|--------|-----------------------|--------|--------|
| Symbol | Min.        | Тур.   | Max.   | Min.                  | Тур.   | Max.   |
| А      | 0.460       | 0.530  | 0.600  | 0.0181                | 0.0209 | 0.0236 |
| A1     | 0.050       | 0.080  | 0.110  | 0.0020                | 0.0031 | 0.0043 |
| A2     | 0.400       | 0.450  | 0.500  | 0.0157                | 0.0177 | 0.0197 |
| A3     | 0.050       | 0.080  | 0.110  | -                     | 0.0051 | -      |
| A4     | 0.270       | 0.320  | 0.370  | 0.0106                | 0.0126 | 0.0146 |
| b      | 0.360       | 0.400  | 0.440  | 0.0091                | 0.0110 | 0.0130 |
| D      | 9.950       | 10.000 | 10.050 | 0.2736                | 0.2756 | 0.2776 |
| D1     | 8.750       | 8.800  | 8.850  | 0.2343                | 0.2362 | 0.2382 |
| Е      | 9.950       | 10.000 | 10.050 | 0.2736                | 0.2756 | 0.2776 |
| E1     | 8.750       | 8.800  | 8.850  | 0.2343                | 0.2362 | 0.2382 |
| е      | 0.750       | 0.800  | 0.850  | -                     | 0.0197 | -      |

Table 112. UFBGA144 - 144-pin, 10 x 10 mm, 0.80 mm pitch, ultra fine pitch ball grid array package mechanical data (continued)

| Compleal |       | millimeters | nillimeters |        | inches <sup>(1)</sup> |        |  |
|----------|-------|-------------|-------------|--------|-----------------------|--------|--|
| Symbol   | Min.  | Тур.        | Max.        | Min.   | Тур.                  | Max.   |  |
| F        | 0.550 | 0.600       | 0.650       | 0.0177 | 0.0197                | 0.0217 |  |
| ddd      | -     | -           | 0.080       | -      | -                     | 0.0039 |  |
| eee      | -     | -           | 0.150       | -      | -                     | 0.0059 |  |
| fff      | -     | -           | 0.080       | -      | -                     | 0.0020 |  |

<sup>1.</sup> Values in inches are converted from mm and rounded to 4 decimal digits.

Figure 78. UFBGA144 - 144-pin, 10 x 10 mm, 0.80 mm pitch, ultra fine pitch ball grid array package recommended footprint

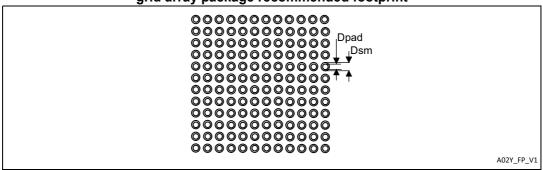


Table 113. UFBGA144 recommended PCB design rules (0.80 mm pitch BGA)

| Dimension         | Recommended values   |
|-------------------|--|
| Pitch             | 0.80 mm  |
| Dpad              | 0.400 mm   |
| Dsm               | 0.550 mm typ. (depends on the soldermask registration tolerance) |
| Stencil opening   | 0.400 mm   |
| Stencil thickness | Between 0.100 mm and 0.125 mm                                    |
| Pad trace width   | 0.120 mm   |

186/198 DocID027107 Rev 3

### Device marking for UFBGA144 10 x 10 mm package

The following figure gives an example of topside marking orientation versus pin 1 identifier location.

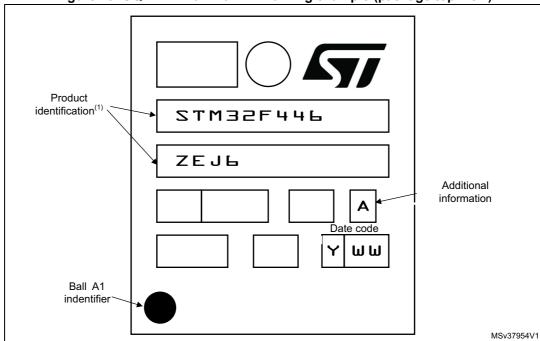
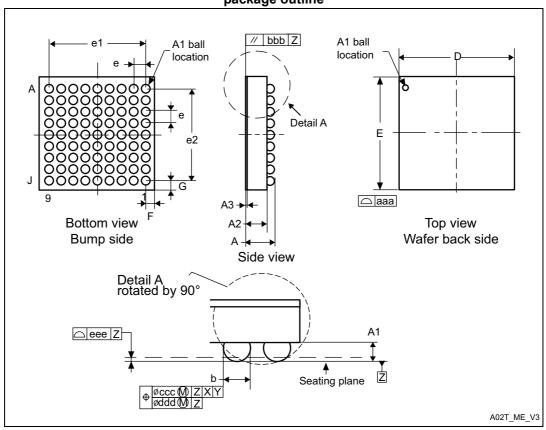


Figure 79. UQFP144 10 x 10 mm marking example (package top view)

Parts marked as "ES", "E" or accompanied by an Engineering Sample notification letter, are not yet qualified and therefore not yet ready to be used in production and any consequences deriving from such usage will not be at ST charge. In no event ST will be liable for any customer usage of these engineering samples in production. ST Quality has to be contacted prior to any decision to use these Engineering samples to run qualification activity.

## 7.6 WLCSP81 package information

Figure 80. WLCSP81 - 81-pin, 3.693 x 3.815 mm, 0.4 mm pitch wafer level chip scale package outline



1. Drawing is not to scale.

Table 114. WLCSP81- 81-pin, 3.693 x 3.815 mm, 0.4 mm pitch wafer level chip scale package mechanical data

|                   |             | pasta, | ,     |                       |        |        |
|-------------------|-------------|--------|-------|-----------------------|--------|--------|
| Symbol            | millimeters |        |       | inches <sup>(1)</sup> |        |        |
|                   | Min         | Тур    | Max   | Min                   | Тур    | Max    |
| Α                 | -           | -      | 0.600 | -                     | -      | 0.0236 |
| A1                | -           | 0.170  | -     | -                     | 0.0067 | -      |
| A2                | -           | 0.380  | -     | -                     | 0.0150 | -      |
| A3 <sup>(2)</sup> | -           | 0.025  | -     | -                     | 0.0010 | -      |
| b <sup>(3)</sup>  | 0.220       | 0.250  | 0.280 | 0.0087                | 0.0098 | 0.0110 |
| D                 | 3.658       | 3.693  | 3.728 | 0.1440                | 0.1454 | 0.1468 |
| E                 | 3.780       | 3.815  | 3.850 | 0.1488                | 0.1502 | 0.1516 |
| е                 | -           | 0.400  | -     | -                     | 0.0157 | -      |
| e1                | -           | 3.200  | -     | -                     | 0.1260 | -      |
| e2                | -           | 3.200  | -     | -                     | 0.1260 | -      |

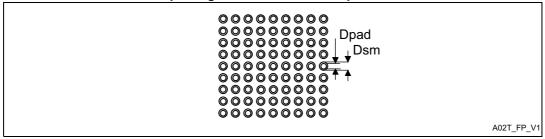
188/198 DocID027107 Rev 3

Table 114. WLCSP81- 81-pin, 3.693 x 3.815 mm, 0.4 mm pitch wafer level chip scale package mechanical data (continued)

| Symbol | millimeters |        |       | inches <sup>(1)</sup> |        |        |
|--------|-------------|--------|-------|-----------------------|--------|--------|
|        | Min         | Тур    | Max   | Min                   | Тур    | Max    |
| F      | -           | 0.2465 | -     | -                     | 0.0097 | -      |
| G      | -           | 0.3075 | -     | -                     | 0.0121 | -      |
| aaa    | -           | -      | 0.100 | -                     | -      | 0.0039 |
| bbb    | -           | -      | 0.100 | -                     | -      | 0.0039 |
| ccc    | -           | -      | 0.100 | -                     | -      | 0.0039 |
| ddd    | -           | -      | 0.050 | -                     | -      | 0.0020 |
| eee    | -           | -      | 0.050 | -                     | -      | 0.0020 |

- 1. Values in inches are converted from mm and rounded to 4 decimal digits.
- 2. Back side coating
- 3. Dimension is measured at the maximum bump diameter parallel to primary datum Z.

Figure 81. WLCSP81- 81-pin, 4.4084 x 3.7594 mm, 0.4 mm pitch wafer level chip scale package recommended footprint



### Device marking for WLCSP81 package

The following figure gives an example of topside marking orientation versus pin 1 identifier location.

Pin 1 identifier

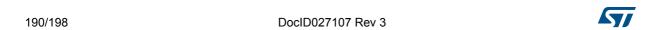
Product identification (1)

Product identification Additional information

Additional information

Figure 82. WLCSP81 10 x 10 mm marking example (package top view)

Parts marked as "ES", "E" or accompanied by an Engineering Sample notification letter, are not yet qualified and therefore not yet ready to be used in production and any consequences deriving from such usage will not be at ST charge. In no event ST will be liable for any customer usage of these engineering samples in production. ST Quality has to be contacted prior to any decision to use these Engineering samples to run qualification activity.



### 7.7 Thermal characteristics

Table 115. WLCSP81 recommended PCB design rules (0.4 mm pitch)

| Dimension         | Recommended values   |  |  |  |
|-------------------|--|--|--|--|
| Pitch             | 0.4 mm   |  |  |  |
| Dpad              | 0.225 mm   |  |  |  |
| Dsm               | 0.290 mm typ. (depends on the soldermask registration tolerance) |  |  |  |
| Stencil opening   | 0.250 mm   |  |  |  |
| Stencil thickness | 0.100 mm   |  |  |  |

The maximum chip-junction temperature,  $T_J$  max, in degrees Celsius, may be calculated using the following equation:

$$T_J \max = T_A \max + (P_D \max x \Theta_{JA})$$

#### Where:

- T<sub>A</sub> max is the maximum ambient temperature in °C,
- $\Theta_{JA}$  is the package junction-to-ambient thermal resistance, in ° C/W,
- $P_D$  max is the sum of  $P_{INT}$  max and  $P_{I/O}$  max ( $P_D$  max =  $P_{INT}$  max +  $P_{I/O}$ max),
- P<sub>INT</sub> max is the product of I<sub>DD</sub> and V<sub>DD</sub>, expressed in Watts. This is the maximum chip internal power.

P<sub>I/O</sub> max represents the maximum power dissipation on output pins where:

$$P_{I/O} \max = \sum (V_{OL} \times I_{OL}) + \sum ((V_{DD} - V_{OH}) \times I_{OH}),$$

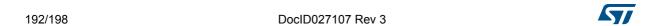
taking into account the actual  $V_{OL}$  /  $I_{OL}$  and  $V_{OH}$  /  $I_{OH}$  of the I/Os at low and high level in the application.

Table 116. Package thermal characteristics

| Symbol            | Parameter  | Value | Unit |
|-------------------|--|-------|------|
|                   | Thermal resistance junction-ambient LQFP64 - 10 × 10 mm                    | 46    |      |
|                   | Thermal resistance junction-ambient<br>LQFP100 - 14 × 14 mm / 0.5 mm pitch | 42    |      |
|                   | Thermal resistance junction-ambient<br>LQFP144 - 20 × 20 mm / 0.5 mm pitch | 33    | °C/W |
| $\Theta_{\sf JA}$ | Thermal resistance junction-ambient UFBGA144 - 7 × 7 mm / 0.5 mm pitch     | 51    | C/VV |
|                   | Thermal resistance junction-ambient UFBGA144 - 10 × 10 mm / 0.8 mm pitch   | 48    |      |
|                   | Thermal resistance junction-ambient WLCSP81                                | 48    |      |

### Reference document

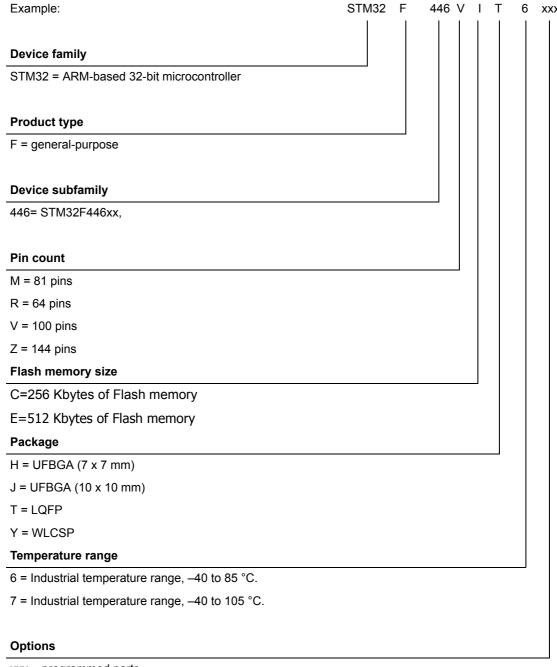
JESD51-2 Integrated Circuits Thermal Test Method Environment Conditions - Natural Convection (Still Air). Available from www.jedec.org.



STM32F446xx Part numbering

## 8 Part numbering

Table 117. Ordering information scheme



xxx = programmed parts

TR = tape and reel

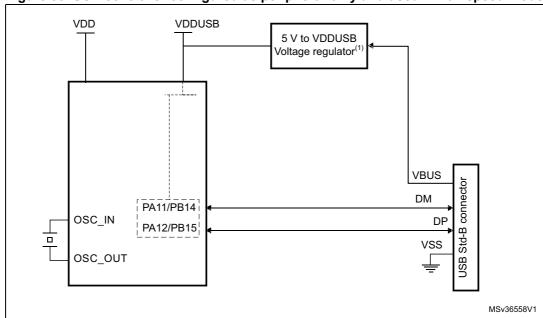
For a list of available options (speed, package, etc.) or for further information on any aspect of this device, please contact your nearest ST sales office.



## Appendix A Application block diagrams

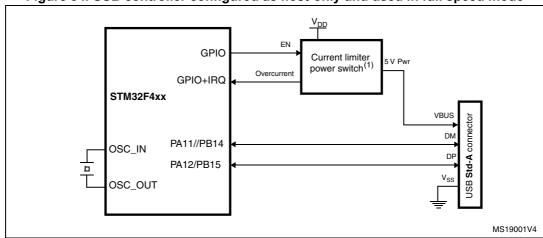
### A.1 USB OTG full speed (FS) interface solutions

Figure 83. USB controller configured as peripheral-only and used in Full speed mode



- 1. External voltage regulator only needed when building a  $V_{\mbox{\scriptsize BUS}}$  powered device.
- 2. The same application can be developed using the OTG HS in FS mode to achieve enhanced performance thanks to the large Rx/Tx FIFO and to a dedicated DMA controller.

Figure 84. USB controller configured as host-only and used in full speed mode



- The current limiter is required only if the application has to support a V<sub>BUS</sub> powered device. A basic power switch can be used if 5 V are available on the application board.
- The same application can be developed using the OTG HS in FS mode to achieve enhanced performance thanks to the large Rx/Tx FIFO and to a dedicated DMA controller.

194/198 DocID027107 Rev 3

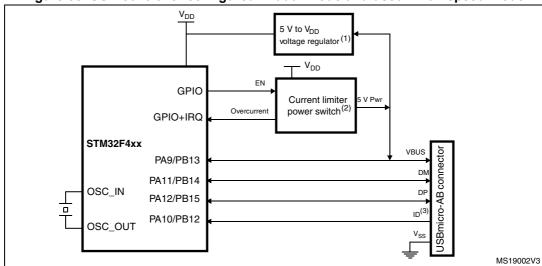


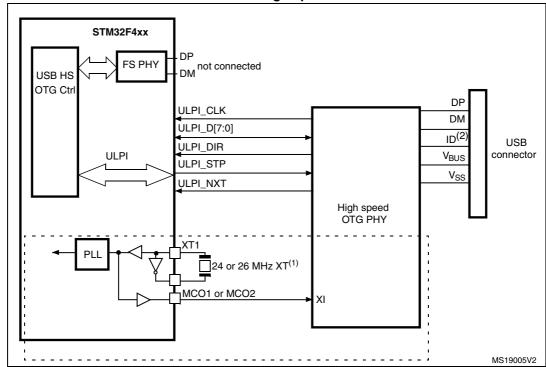
Figure 85. USB controller configured in dual mode and used in full speed mode

- 1. External voltage regulator only needed when building a  $\ensuremath{V_{BUS}}$  powered device.
- 2. The current limiter is required only if the application has to support a V<sub>BUS</sub> powered device. A basic power switch can be used if 5 V are available on the application board.
- 3. The ID pin is required in dual role only.
- 4. The same application can be developed using the OTG HS in FS mode to achieve enhanced performance thanks to the large Rx/Tx FIFO and to a dedicated DMA controller.



## A.2 USB OTG high speed (HS) interface solutions

Figure 86. USB controller configured as peripheral, host, or dual-mode and used in high speed mode



It is possible to use MCO1 or MCO2 to save a crystal. It is however not mandatory to clock the STM32F446xx with a 24 or 26 MHz crystal when using USB HS. The above figure only shows an example of a possible connection.

2. The ID pin is required in dual role only.

47/

STM32F446xx Revision history

# 9 Revision history

Table 118. Document revision history

| Date        | Revision | Changes  |  |  |
|-------------|----------|--|--|--|
| 17-Feb-2015 | 1        | Initial release.   |  |  |
| 16-Mar-2015 | 2        | Added note 2 inside Table 2 Updated Table 11, Table 23, Table 24, Table 25, Table 26, Table 30, Table 51, Table 52, Table 53, and Table 61 Added condition inside Typical and maximum current consumption and Additional current consumption Added FMPI2C characteristics Added Table 62 and Figure 34   |  |  |
| 29-May-2015 | 3        | Updated:  - Section 6.3.15: Absolute maximum ratings (electrical sensitivity)  - Section 7: Package information  - Table 2: STM32F446xx features and peripheral counts  - Table 12: STM32F446xC/xE WLCSP81 ballout  - Figure 53: ESD absolute maximum ratings  - Figure 53: Synchronous multiplexed NOR/PSRAM read timings  Added:  - Figure 76: UQFP144 7 x 7 mm marking example (package top view),  - Figure 79: UQFP144 10 x 10 mm marking example (package top view),  - Figure 82: WLCSP81 10 x 10 mm marking example (package top view) |  |  |

#### **IMPORTANT NOTICE - PLEASE READ CAREFULLY**

STMicroelectronics NV and its subsidiaries ("ST") reserve the right to make changes, corrections, enhancements, modifications, and improvements to ST products and/or to this document at any time without notice. Purchasers should obtain the latest relevant information on ST products before placing orders. ST products are sold pursuant to ST's terms and conditions of sale in place at the time of order acknowledgement.

Purchasers are solely responsible for the choice, selection, and use of ST products and ST assumes no liability for application assistance or the design of Purchasers' products.

No license, express or implied, to any intellectual property right is granted by ST herein.

Resale of ST products with provisions different from the information set forth herein shall void any warranty granted by ST for such product.

ST and the ST logo are trademarks of ST. All other product or service names are the property of their respective owners.

Information in this document supersedes and replaces information previously supplied in any prior versions of this document.

© 2015 STMicroelectronics – All rights reserved

**577**